

August, 1985

HITACHI

 HITACHI LINEAR IC DATA BOOK

LINEAR IC DATA BOOK

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LINEAR IC DATA BOOK

■ GENERAL INFORMATION

■ DATA SHEETS



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HA17458PS Dual	46	HA178M07P	0.5A, 7V Fixed	121
HA17458GS Dual	46	HA178M08P	0.5A, 8V Fixed	121
HA17558 Dual	51	HA178M12P	0.5A, 12V Fixed	121
HA17558PS Dual	51	HA178M15P	0.5A, 15V Fixed	121
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GENERAL INFORMATION

- REFERENCE GUIDE
- PACKAGE INFORMATIONS
- RELIABILITY OF LINEAR ICs

REFERENCE GUIDE

Function			Type No.	Operating Temp. Range			Package				Cross-reference	Page
				0 to +70°C	-20 to +75°C	-40 to +85°C	Plastic DIP	Cerdip	Plastic SIP	Plastic Flat		
Operational Amplifier	J-FET Input	Single	HA17080PS				8				TL080	22
			HA17080GS					8			TL080	22
		Dual	HA17082PS				8				TL082	22
			HA17082GS					8			TL082	22
			HA17083P				14				TL083	22
			HA17083G					14			TL083	22
		Quad.	HA17084P				14				TL084	22
	General Purpose		HA17741				8				μA741C	28
			HA17741PS				8				μA741	28
			HA17741GS					8			μA741	28
			HA17741G					14			μA741	28
	High Slew Rate		HA17715G					14			μA715	39
	Dual		HA17747				14				μA747C	44
			HA17747P				14				μA747	44
			HA17747G					14			μA747	44
			HA17458				8				1458	46
			HA17458PS				8				1458	46
			HA17458GS					8			1458	46
			HA17558				8				4558	51
			HA17558PS				8				4558	51
			HA17558GS					8			4558	51
			HA17358				8				LM358	58
			HA17904PS				8				LM3904	58
			HA17904GS					8			LM2904	58
	Quad.		HA17301P				14				MC3401	60
			HA17301G					14			MC3301	60
			HA17324				14				LM324	66
			HA17324P				14				LM324	66
			HA17324G					14			LM324	66
			HA17902				14				LM3902	70
			HA17902P				14				LM3902	70
			HA17902G					14			LM2902	70
Voltage Comparator	Single		HA1813PS				8				Original	76
	Universal		HA1812PS				8				Original	84
			HA1812GS					8			Original	84
	Dual		HA1807		Note 1			14			Original	76
			HA17393				8				LM393	91
			HA17903PS				8				LM3903	91
			HA17903GS					8			LM2903	91
	Quad.		HA17339				14				LM339	95
			HA17901P				14				LM3901	95
			HA17901G					14			LM2901	95

Notes: 1. -30 to +80°C

(to be continued)

Function	Type No.	Operating Temp. Range			Package				Cross reference	Page
		0 to +70°C	20 to +75°C	40 to +85°C	Plastic DIP	Cerdip	Plastic SIP	Plastic Flat		
Voltage Regulator	Precision	HA17723			14				μA723C	100
		HA17723G				14			μA723	100
	1A	5V HA17805					3		μA7805C	108
		6V HA17806					3		μA7806C	108
		7V HA17807					3		μA7807C	108
		8V HA17808					3		μA7808C	108
		12V HA17812					3		μA7812C	108
		15V HA17815					3		μA7815C	108
		18V HA17818					3		μA7818C	108
		24V HA17824					3		μA7824C	108
		5V HA17805P					3		μA7805	108
		6V HA17806P					3		μA7806	108
		7V HA17807P					3		μA7807	108
		8V HA17808P					3		μA7808	108
		12V HA17812P					3		μA7812	108
		15V HA17815P					3		μA7815	108
		18V HA17818P					3		μA7818	108
		24V HA17824P					3		μA7824	108
	0.5A	5V HA178M05					3		μA78M05C	121
		6V HA178M06					3		μA78M06C	121
		7V HA178M07					3			121
		8V HA178M08					3		μA78M08C	121
		12V HA178M12					3		μA78M12C	121
		15V HA178M15					3		μA78M15C	121
		18V HA178M18					3		μA78M18C	121
		20V HA178M20					3		μA78M20C	121
		24V HA178M24					3		μA78M24C	121
		5V HA178M05P					3		μA78M05	121
		6V HA178M06P					3		μA78M06	121
		7V HA178M07P					3			121
		8V HA178M08P					3		μA78M08	121
		12V HA178M12P					3		μA78M12	121
		15V HA178M15P					3		μA78M15	121
		18V HA178M18P					3		μA78M18	121
		20V HA178M20P					3		μA78M20	121
		24V HA178M24P					3		μA78M24	121
Converter	Controller	HA17524P			16				SG3524	125
		HA17524G				16			SG3524	125
	A/D	4-bit High Speed HA19202	Note 2		22				Original	132
		HA19203MP	Note 2					18	Original	132
		12-bit Dual Slope HA16613A			28				Original	135
	D/A	8-bit HA17008RP			16				DAC08	139
		HA17008RG				16			DAC08	139
		HA17408P			16				MC1408	144
		HA17408G				16			MC1408	144
		12-bit HA17012P			20				Am6012	146
		HA17012G				20			Am6012	146

Notes 2, -10 to -75°C

to be continued

REFERENCE GUIDE

Function	Type No.	Operating Temp. Range			Package				Cross reference	Page
		0 to +70℃	-20 to +75℃	-40 to +85℃	Plastic DIP	Cerdip	Plastic SIP	Plastic Flat		
Micro processor Peripheral	Quad. Driver	HA13007			16				Original	152
		HA13415			16				Original	163
	9 ch Driver	HA13408	Note 3				23		Original	160
	Bridge Driver	HA13421A	Note 3		16				Original	166
		HA13421AMP	Note 3					18	Original	166
	3 phase Motor Driver	HA13406W	Note 3				23		Original	154
		HA13426	Note 3				23		Original	169
	3 phase Motor Driver with Speed Discriminator	HA13431	Note 3				23		Original	175
		HA13432	Note 3		24				Original	178
		HA13432MP	Note 3					28	Original	178
	Thermal Head Driver	HC16701 †	Note 3						Original	182
	DC Motor Controller	HA16628P			16				Original	186
		HA16629P			16				Original	188
		HA16631P			18				Original	192
		HA16631MP						18	Original	192
	Floppy Disk Controller	HA16632AP	Note 5		28				Original	202
		HA16640NT			42				Original	211
		HA16642MP						44	Original	217
		HA16642NT			42				Original	217
Other Function	Ground Fault Interrupter	HA16636P	Note 6				8		Original	208
	Voltage Regulator Control	HA1835P			14				Original	222
		HA17733			14				μA733C	230
	Differential Video Amp.	HA17733P			14				μA733	230
		HA17733G				14			μA733	230
	5 Transistor Array	HA1127		Note 7		14			CA3045	236
		HA17555			8				NE555	239
	Precision Timer	HA17555PS			8				NE555	239
		HA17555GS				8			NE555	239
	Burner Controller	HA16605W			20				Original	246
		HA16617P			18				Original	251
	Fluorescent Display Tube Driver	HA16619P			18				Original	251
		HA16617PJ			18				Original	254
		HA16619PJ			18				Original	254

Notes: 3. -20 to +70℃, 4. -20 to +80℃, 5. 0 to +60℃, 6. -20 to +85℃, 7. -55 to +125℃.

† The chip product for sale.

PACKAGE INFORMATION

HA 17741 P

Package Code; letters P: Plastic
letters G: Cerdip

17 × × × ; Standard Linear IC

Circuit Description of 1st Vendor's Name
; Three Figures of Low Rank:

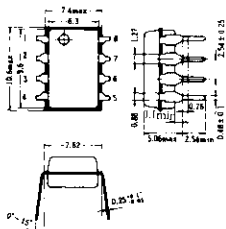
Other Circuit Description; Hitachi Original

Prefix: HA; Hitachi Linear Analog IC

■ DIMENSIONAL OUTLINE (Dimensions in mm)

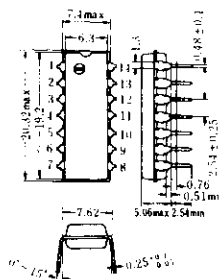
● Plastic Dual-in-line Package

8Pin



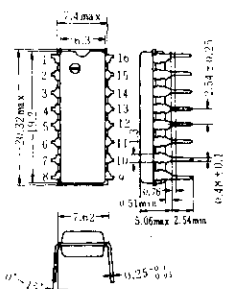
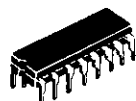
(DP-8)

14Pin

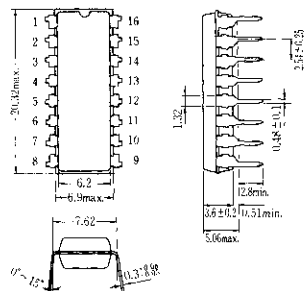
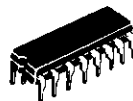


(DP-14)

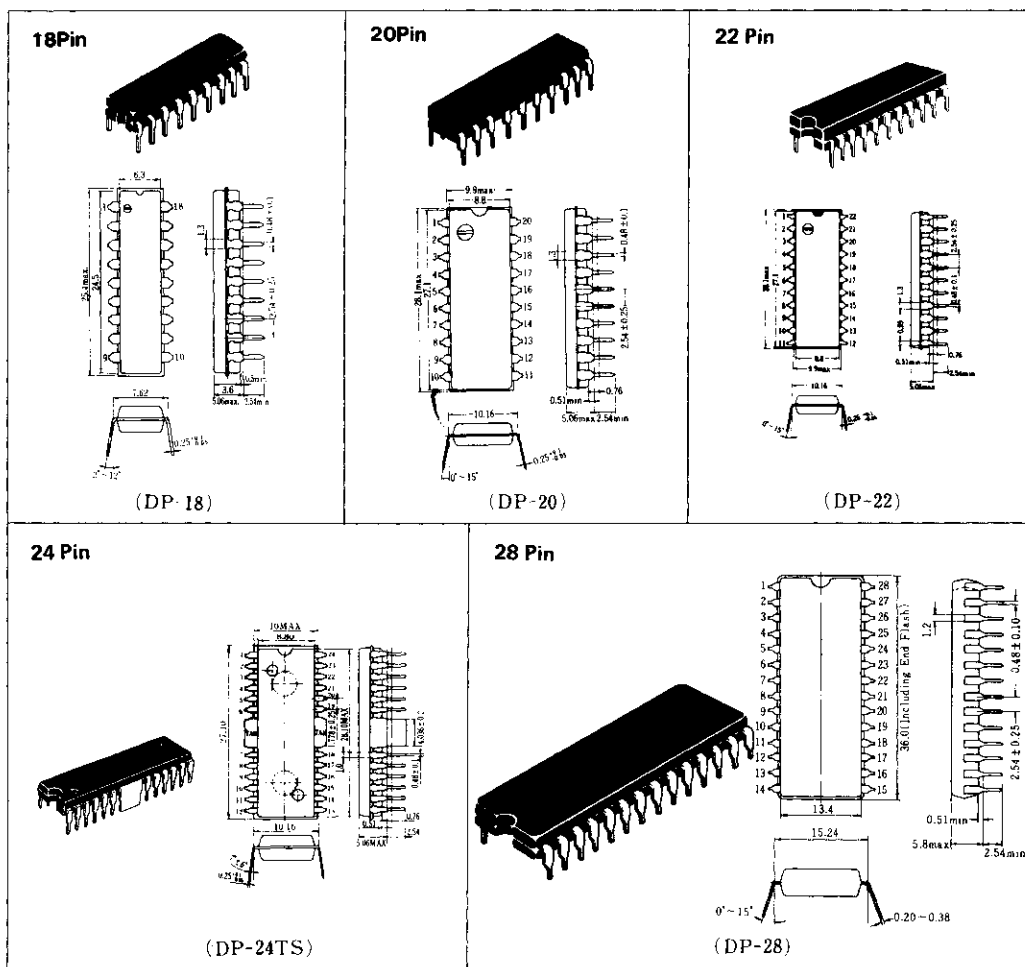
16Pin



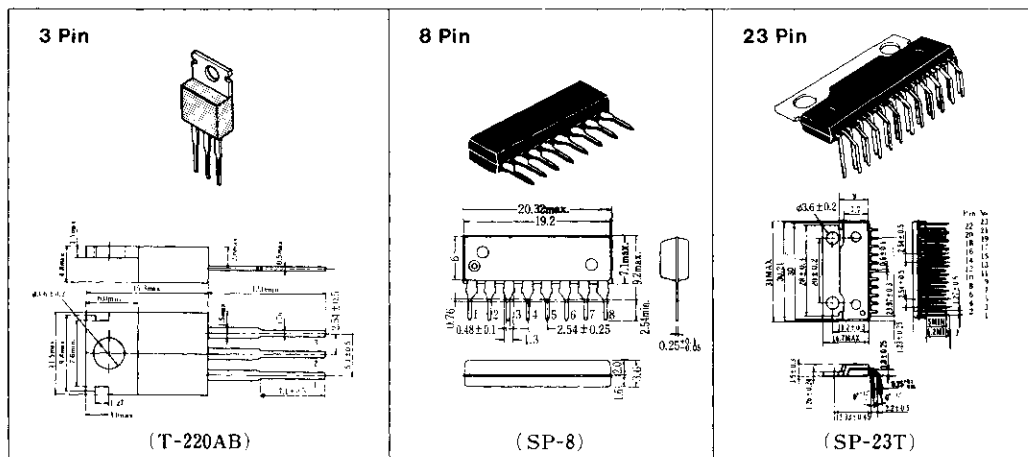
(DP-16)



(DP-16A)

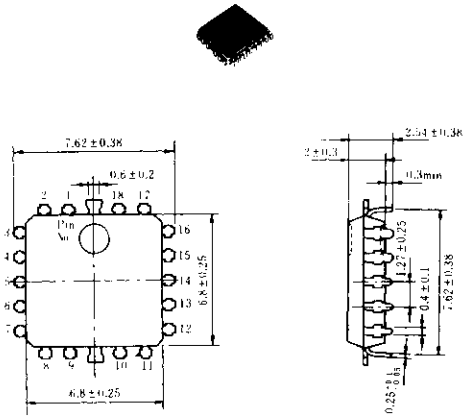


●Plastic Single-in-line Package



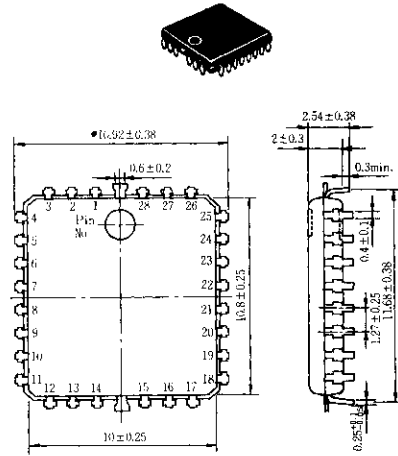
●Plastic Flat Package

18 Pin



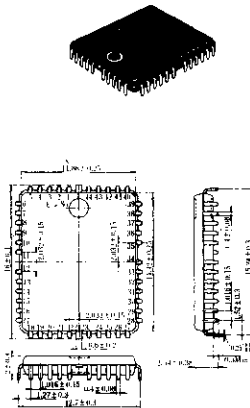
(MP-18)

28 Pin



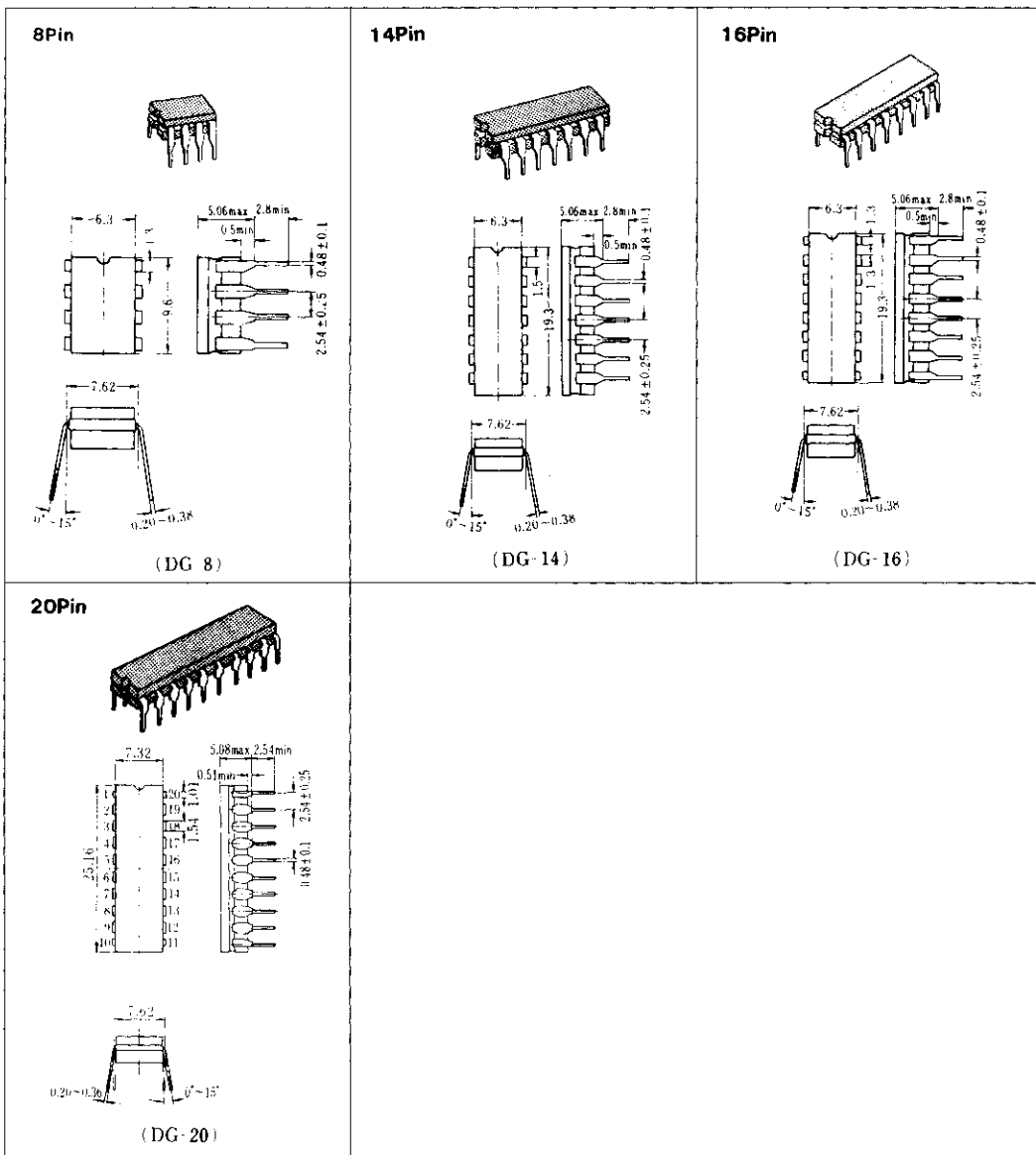
(MP-28)

44 Pin



(MP-44)

●Cerdip



RELIABILITY OF LINEAR ICs

In the following we review the reliability of linear ICs. The introduction of this linear IC series marks a big step forward in reliability and meets the user's needs through their improved reliability resulting from Hitachi's mass production technology and quality control.

1. CONCEPT OF QUALITY AND RELIABILITY

Hitachi's fundamental concept of product quality consists in meeting the requirements of individual users and maintaining a high quality of materials taking into consideration the marketability of the product from a broad and general aspect. The quality of product required by a user is determined according to the specifications listed in the agreement; however, there are occasions when it is not specified. In either case, our company makes every effort to ensure that the delivered semiconductor devices are able to display their full performance under the service environment in order to secure their reliability. Establishment of a quality control system in the process and enhanced quality, are keys to bringing about such reliable product quality in the manufacturing process. In the market of late, the user's requirements for quality of semiconductor devices have become steadily more stringent because the performance of electronic systems is rapidly improving and their scale and applications are widening. In order to cope with this trend, the following points have been adopted as the basic policy in Hitachi's actual operations.

- (1) In the design stage of developing new products, full consideration is given to their reliability.
- (2) The quality of product is made up at each step of the manufacturing process.
- (3) Inspection of finished products and confirmation of their reliability are to be intensified.
- (4) Field data should be fully utilized to improve the quality of products.

Table 1 gives an example of the reliability programs drawn up to meet the user's requirements. Moreover, we are making efforts to firmly establish higher quality and reliability of our semiconductor devices by pooling the efforts of our research and manufacturing departments. Based on the above concept and measures, our company is doing its utmost to meet the user's demand for product quality.

2. RELIABILITY OF SEMICONDUCTOR DEVICES

2.1 RELIABILITY TARGET

Reliability target is an important factor along with the function and price in the courses of manufacturing and selling products. It is not practical to classify the reliability target merely by the failure rate under a certain testing condition. Our company sets the reliability target by taking into account the design, manufacture, quality control in the process, screening, testing method, etc. with the contents corresponding to the characteristic nature of each item of equipment comprehensively considering the service environ-

ment of the equipment to which the device is applied, purpose design, operating, condition, maintenance, etc.

2.2 HOW TO CARRY FORWARD RELIABILITY DESIGN:

In order to achieve desired reliability based on the reliability target, timely examination and execution of such items as design standardization, device design (including process design and structural design), design review, reliability test are required beforehand.

(1) Standardization of design:

Establishment of design rule and standardization of parts, materials and processes are necessary. When establishing respective rules of design concerning circuit design, element design, layout design, critical items regarding the quality and reliability are always examined. Accordingly, where standardized processes or materials are used, even newly developed products can minimize risks affecting reliability unless special functional requests are made.

(2) Device design:

It is important to carry out device design taking into consideration the total balance between circuit, layout, process and structural designs. Particularly when using new processes and materials, technical examinations prior to development of the device are carried out to the full.

(3) Evaluation of reliability by TEG:

TEG (Test Element Group), sometimes called test pattern, is an effective method to evaluate the reliability of design and process of ICs and LSIs containing complicated functions. For transistors, it is useful to increase the sensitivity of detecting troubles caused when applying new processes. As to TEG, further explanation is provided in the following.

1. Purpose of use of TEG;

- Clarifying the basic failure mode.
- Grasping the relation between failure mode and manufacturing process condition.
- Obtaining a clue to analysis of failure mechanism to analyze the mechanism of failure.
- Establishing QC point for manufacture.

2. Effectiveness of evaluation by TEG;

- Possible to evaluate the basic failure mode and failure mechanism common to each type of products.
- Possible to compare the process having the failure with the process having records of marketability by clarifying the factors controlling the failure mode.
- Easy to grasp the connection between the cause of failure and that of the manufacturing process.
- Easy to perform test.

Here described several concrete examples of reliability evaluation by TEG.

Table.1 Example of Reliability Program

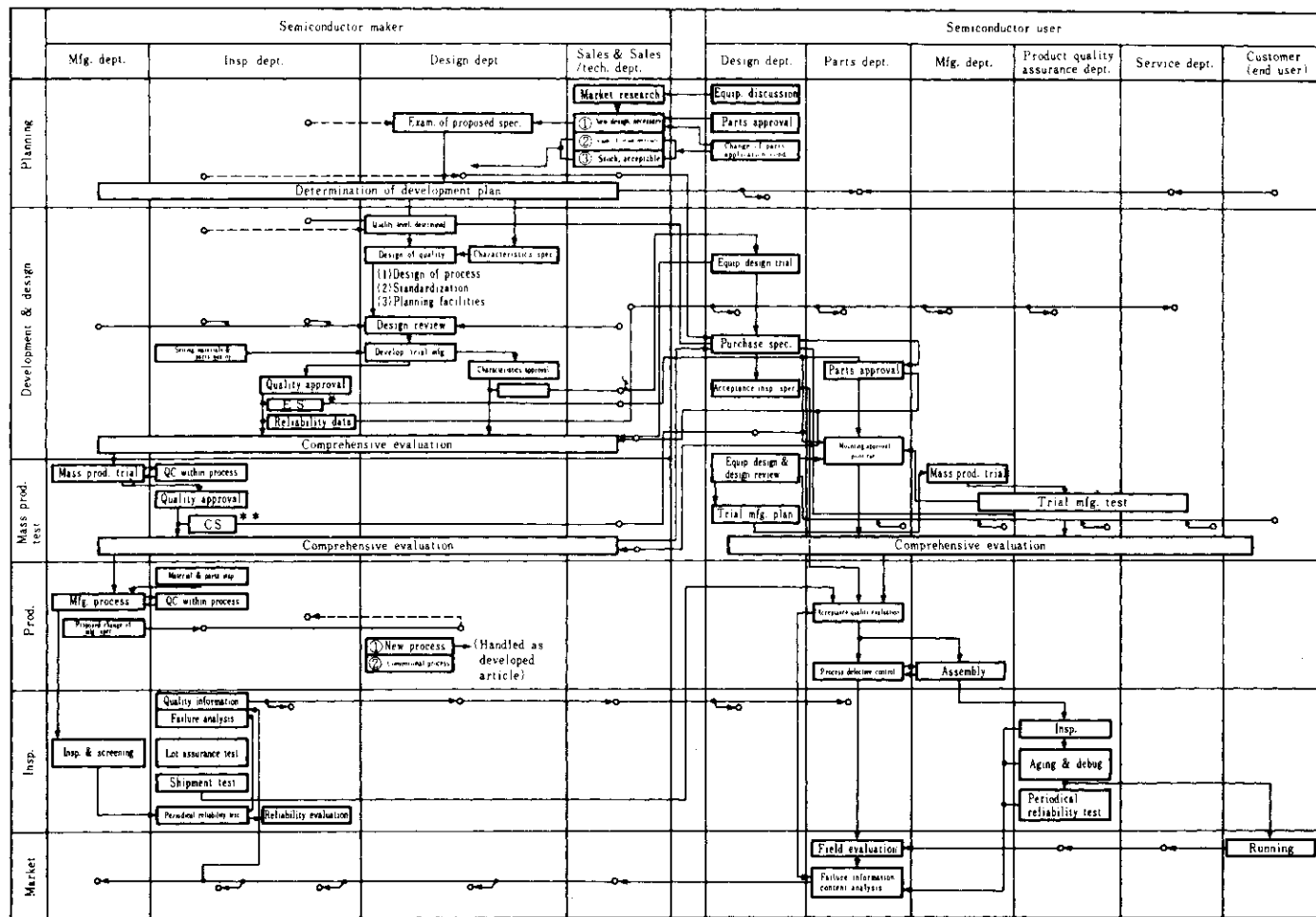


Table.2 Standard for Design Review

	Hitachi Standard for Design Review	NASA Space System Standard for Design Review.
Purpose	Securing reliability required in the market.	Assurance of performance required by the program.
Definition	Systematical and organic confirmation and promotion of broad technical capacity.	Systematical and orderly application of broad technical capacity.
Item of review	Correction of defects in design.	Correction of defects in design.
Subject of review	Designated types of products.	Contracted projects.
Time	Concept Intermediate design Final design.	Preliminary Before mounting Before release of drawing.
Composition	Chairman	Collector of designs.
	Member	Related responsible person and reliability technician.
Authority	Recommendation of improvement.	Presentation of advice.

2.3 DESIGN REVIEW:

Design review is a procedure to systematically check whether the design satisfies the performance required by a user, the designing work is performed according to the specified form, and the items of technical improvement which have been obtained from the accumulated experimental field data in each specialized department are efficiently used. It is also performed mainly for ensuring the quality and reliability of the products in order to strengthen the competitive power of our products. In Hitachi, new products and design-changed products are subjected to design review from conceptual stage. This method is extensively used by NASA. Table 2 shows the comparison between the standards for design review of our company and NASA: The following are the contents of the review.

- (1) Description of the contents of products according to the design document.
 - (2) The design document is reviewed from the standpoint of each specialist who participates in the review. If any unclear item is found, a sub-program for calculation, experiment or investigation is drawn up and executed.
 - (3) The contents or method of a reliability test is determined according to the design document and the contents of the drawing.
 - (4) Checking whether the process capacity of the manufacturing plant is sufficient to achieve the design goal.
 - (5) Conference for preparation of production.
 - (6) Planning and execution of a sub-program for test, or experiment, calculation, etc. for change and confirmation of the design proposed by each specialist.
 - (7) Reference to past failure examples of similar types of articles and confirmation of preventive measures against recurrence of such failures, and planning and execution of a testing program for confirmation.
- Careful discussions for the above made at the design review are carried out according to the check list specially device and prepared according to each subject.

3. QUALITY ASSURANCE STRUCTURE OF SEMICONDUCTOR DEVICES:

3.1 ACTIVE OF QUALITY ASSURANCE:

The general concept of Hitachi's overall quality assurance is described below.

- (1) The problems of each process are to be settled within the process concerned. Accordingly, in the stage of finally finished products, latent defective factors are eliminated.
- (2) In order to maintain the process capacity at a good level, feedback of information is performed.
- (3) Quality assurance aims at securing the desired reliability obtained as a result of the above.

Device design, recognition of quality at the time of mass production, quality control with the process inspection of products and assurance test of reliability are described below.

3.2 QUALITY RECOGNITION:

In order to secure the desired quality and reliability, quality of products recognition is carried out at the time of design and trial; manufacture of devices and their mass production according to the reliability design. The concept for recognition of the quality of products is described below.

- (1) Performing an objective recognition putting the company itself in its customer's place and by a third party.
- (2) Taking into full consideration past failure examples and field information.
- (3) Carrying out recognition of its quality, in case of change of design or operation.
- (4) In the case of parts, materials and process, emphasis is placed on the recognition of their quality.
- (5) The process capacity and causes of variations are examined, and the control points at the time of mass production are established.

Quality recognition is performed by incorporating the above concept.

3.3 QUALITY AND RELIABILITY CONTROL IN MASS PRODUCTION

For quality assurance of mass production, the quality control work is systematically and functionally assigned to the manufacturing and inspection departments including the related departments. The entire function is shown in the flow chart of Fig. 1.

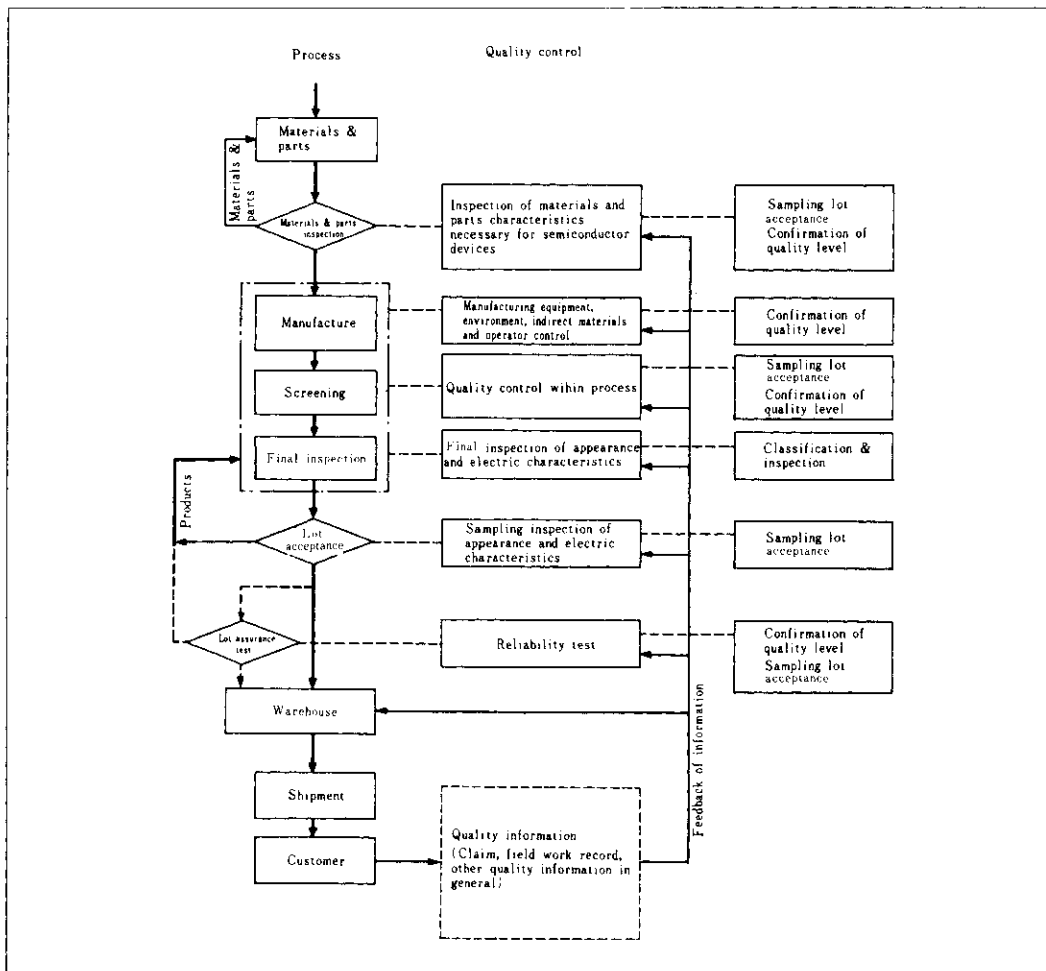


Fig.1 Flow Chart of Quality Control in Manufacturing Process

4. SELECTION OF PACKAGE TYPE AND RELIABILITY

4.1 SELECTION OF PACKAGE TYPE

Package types are generally classified into two; one is the hermetic sealed type using metal or glass, and the other is the plastic molded type. Selection of package types should be done with considering the purpose of system, environment, reliability cost etc. The reliability of plastic molded-type semiconductor devices has been greatly improved. Recently, their applications have also been expanded to automobiles, measuring and control systems, and computer terminal equipment operated under relatively severe conditions. Actually, field application data has revealed that their trouble factors under favorable indoor environmental conditions are equivalent to those of the hermetically sealed type. However, in the view of the guaranteed reliability (specifically,

durability against environmental conditions), the hermetically sealed type passes inspection on a leak test 100%. Due to poor screening technology, the plastic molded type involves problems of moisture absorption or permeation inherent to their plastics materials. Therefore, Hitachi recommends users employ hermetically sealed-type semiconductor devices for certain types of systems which require high durability against environmental conditions, long service life, and high reliability. On the other hand, it is obvious that production output and applications of plastic molded-type semiconductor devices will be increased or expanded over the years that lie ahead. To fulfill such demands, Hitachi has exerted considerable efforts to improve moisture resistance, resistance against humidity cycles, operation stability, and chips and plastics manufacturing process. At present, Hitachi is confident that products featuring high durability against

environmental conditions will be available in the near future.

4.2 RELIABILITY OF PLASTIC MOLDING TYPE IC

Open and intermittent open troubles are major causes of reliability failure of the plastic-molded type IC. Fig. 2 indicates open fraction failure rate in terms of year. In recent years, the reliability in this aspect has been remarkably improved. Fig. 3 shows the data of moisture resistance.

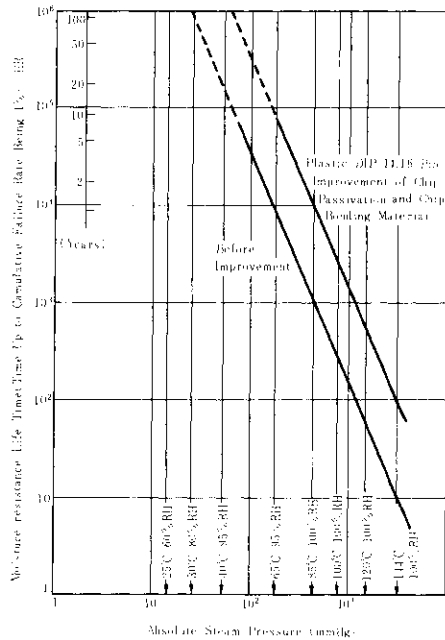


Fig. 3 Moisture Resistance of Plastic-encapsulated IC's

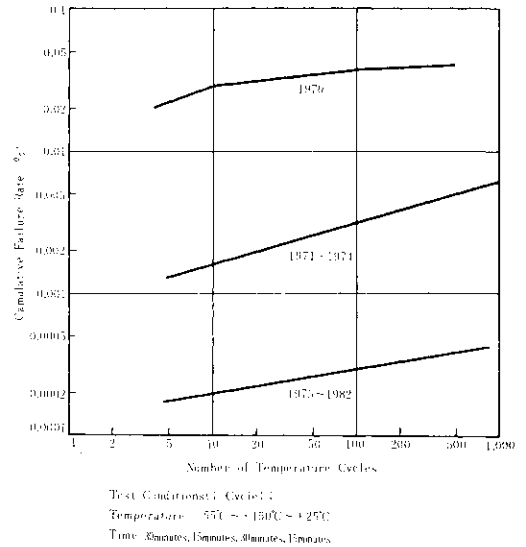


Fig. 2 Changes in Terms of Year of Open Failure Rate in Temperature Cycle Test

5. RELIABILITY DATA

Here, we describe the results of reliability tests, data of failure rate, failure mode etc.

5.1 CRITERIA OF FAILURES

Table 3 shows the failure criteria in linear IC reliability test. The items of criteria and measuring conditions vary with the types of products.

Table.3 Criteria for Failures of Linear ICs (Example)

Item	Criteria of failure (Note)		Unit	Remarks
	min	max		
Electric characteristics	Voltage gain	$U - 3$	$U + 3$	dB
	Rated output	$I \times 0.9$	—	W
	Total harmonic distortion	—	$U \times 1.5$	%
	Output noise voltage	—	$U \times 1.5$	V Including pulse noise.
	Input limiting voltage	—	$U + 3$	dB μ
	Power supply current	—	$U \times 1.1$	A
	Input offset voltage	—	$U \times 1.5$	V
	Input offset current	—	$U \times 1.5$	A
	Input current & input bias current	—	$U \times 1.3$	A
	Max. output voltage swing	$I \times 0.9$	$U \times 1.1$	V
	Common mode input voltage range	$I \times 0.9$	—	V
	Common mode rejection ratio	—	$U + 3$	dB
	Slew rate	—	$U \times 1.5$	V/ μ s
Appearance & others	Open & short	Open, Intermittent, Short, Half-short. Including high & low temp. defects.		—
	Airtight leak	Major leak & minor leak.		Applied to airtight sealing type devices.
	Appearance	According to limit sample.		—
	Rusting & discoloration	According to limit sample.		—
	Solderability	According to limit sample.		—
	Marking	According to limit sample.		—

Note: U: Initial limit max. value. I: Initial limit min. value.

Table.4 Results of Reliability Test on Linear ICs

Test Item	Test Condition	Plastic-molded Type				Hermetic sealed Type (Cerdip)			
		No. of samples [pcs]	Total testing time	No. of failures [pcs]	Failure rate* [1/hr]	No. of samples [pcs]	Total testing time	No. of failures [pcs]	Failure rate* [1/hr]
High temp. Operating life	$T_a = 125^\circ\text{C}$ $V_{CC} = V_{CC \text{ max}}$ $V_{EE} = V_{EE \text{ max}}$	1,660	1,190,000	5	5.3×10^{-6}	2,345	2,424,600	0	3.8×10^{-7}
Storage life	$T_a = 150^\circ\text{C}$	829	793,000	0	1.2×10^{-6}	485	463,700	0	2.0×10^{-6}
	$T_a = -55^\circ\text{C}$	509	509,000	0	1.8×10^{-6}	—	—	—	—
	$T_a = -65^\circ\text{C}$	—	—	—	—	376	376,000	0	2.4×10^{-6}
Humidity	$T_a = 65^\circ\text{C}$, 95%RH $T_a = 85^\circ\text{C}$, 85%RH	3,110	2,727,000	0	3.4×10^{-7}	—	—	—	—
Bias humidity	$V_{CC} = V_{CC \text{ max}}$ $V_{EE} = V_{EE \text{ max}}$	443	443,000	0	2.1×10^{-6}	—	—	—	—
Temp. cycle	$-55^\circ\text{C} \sim +150^\circ\text{C}$ 10 Cycles	10,043	—	0	—	2,198	—	0	—
Temp. cycle life	$55^\circ\text{C} \sim +150^\circ\text{C}$ 200 Cycles	4,280	—	0	—	900	—	0	—
	$0^\circ\text{C} \sim 100^\circ\text{C}$ 10 Cycles	398	—	0	—	311	—	0	—
Solder heat	260°C , 10sec	404	—	0	—	305	—	0	—
Free drop	1,500G, 0.5ms, directions of X, Y, and Z, each 3 times	160	—	0	—	260	—	0	—
Vibration fatigue	60Hz, 20G, directions of X, Y, and Z, each 32hrs	160	—	0	—	260	—	0	—
Variable freq. vibration	100 ~ 2,000Hz, 20G, directions of X, Y, and Z, each 3 times	160	—	0	—	260	—	0	—
Constant acceleration	20,000G, directions of X, Y, and Z, each 1 minute	160	—	0	—	260	—	0	—
PCT	$T_a = 121^\circ\text{C}$, 2atoms $t = 60\text{hrs}$	360	—	0	—	—	—	—	—
Solderability	230°C , 5sec with rosin flux	160	—	0	—	300	—	0	—
Lead bend	225g	90	—	0	—	45	—	0	—
	90° , 3 times								

* Confidence level: 60%.

5.2 RELIABILITY TEST DATA OF LINEAR IC:

Table 4 is the results of linear IC life test and environmental test.

The reliability data concerning individual test results are available as they have already been prepared.

6. FAILURE RATE AND DERATING

Fig. 4 indicates the relation between the failure rate and the operating junction temperature obtained from various types of reliability tests and field records. With respect to the plastic-molded type and metal package type, the operating junction temperature is selected as a stress factor, and then the above relation is obtained from test data (mainly the high temperature operating life test) and field data. In the case of linear IC, it greatly depends on temperature on the average, so that it is confidently anticipated that the reliability can be effectively improved by temperature derating.

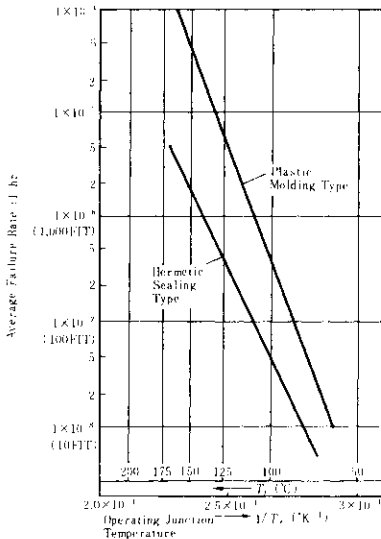


Fig. 4 Derating Characteristics of Linear IC

7. HANDLING FOR MEASUREMENTS

Special attention should be paid about static electricity, noise of surge-voltage when semiconductor devices are measured. It is possible to prevent device breakdown by shorting their terminals to equalize electrical potential during transportation. However, when the devices are to be measured or mounted, they have to be left with terminals open and there is the possibility that they may be accidentally touched by a worker, measuring instrument, work bench, soldering iron, belt conveyor, etc. The device will be broken if it touches

something which leaks current or has a static charge. Take care not to allow curve tracers, synchrosopes, pulse generators, D.C. stabilizing power supply units etc. to leak current through their terminals or housings. Especially, while the devices are being tested, take care not to apply surge voltage from the tester, or to attach a clamping circuit to the tester or not to apply any abnormal voltage through a bad contact from a current source. During measurement, pay special attention to miswiring and short-circuiting. When inspecting a printed circuit board, confirm that no soldering bridges or foreign matter is observed prior to turning the power switch ON. As these precautions depend upon the types of semiconductor devices, please contact Hitachi for further details.

8. PRECAUTIONS FOR PHYSICAL HANDLING

There are considerable precautions to install semiconductor devices to a printed circuit board. In order not to impair the reliability of a semiconductor device during installation, cares should be taken when forming or cutting the leads, soldering and removing surplus flux.

8.1 FORMING AND CUTTING LEADS

When forming and cutting the lead wires of semiconductor devices, be careful of the following points:

- (1) When bending the lead wires, hold the lead wires securely between the package and the point to be bent with a pair of pliers. Then, bend them, holding the open end of the leads with your fingers, so that no bending stress is applied to the package. Do not bend the leads by holding the package. The same consideration should be paid when many devices are simultaneously bent using lead forming machines.
- (2) When bending the lead wires at right angles, make the bend at least 3 mm away from the package end. Do not bend them more than 90° . When they must be bent less than 90° , allow a space of more than 1.5 mm.
- (3) Do not repeatedly bend the leads.
- (4) Do not bend them sideways.
- (5) Do not pull the leads with excessive force, to prevent the device from being broken. The prescribed tensile strength depends on their cross-sectional areas.
- (6) Take care not to use any improper jig or pliers for bending, since the surfaces in contact with the plated surfaces of the lead wires may be damaged. It is advisable to use a tool with a contact area of 0.5 mm radius.

8.2 SOLDERING

It is not desirable in general to leave semiconductor devices at high temperature for a long time. Regardless of the soldering method, whether it may be a soldering iron or the flowing solder method, soldering must be done in the shorter time and at the lowest temperature possible. Your soldering work must meet test conditions of soldering heat, tolerability, namely, 260°C for 10 seconds and 350°C for 3 seconds at a point 1 to 1.5 mm away from the end of the device. Use of a strong alkali or acid flux may corrode the lead wires, deteriorating device characteristics. The recommended soldering iron is the type that is operated with a secondary voltage supplied by a transformer and grounded to prevent current leads. Try to solder the lead wires at the farthest point from the device surface.

8.3 REMOVING RESIDUAL FLUX

To ensure the reliability and lifetime of electronic systems, residual flux must be removed from circuit boards. Detergent or ultrasonic cleaning is usually applied. If chlorous detergent is used for the plastic molded devices, package corrosion may occur. Since cleaning over extended periods or at high temperatures will cause swollen chip coating due to solvent permeation, pay special attention to these precautions prior to dissolution and toxicity. Do not use any trichlorethylene solvent. For ultrasonic washing, the following conditions are advisable:

Frequency: 28 to 29 kHz (to avoid device resonance)

Ultrasonic output: 15W/1 (once)

Do not allow the devices to contact the generator source directly.

Washing time: Less than 30 seconds

DATA SHEETS

Operational Amplifiers

HA17080PS, HA17082PS, HA17083P, HA17084P, HA17080GS, HA17082GS, HA17083G ● J-FET Input Operational Amplifiers

J-FET Input Operational Amp. provides excellent characteristics including high input impedance and low input bias current, since its input differential amp. is constructed by J-FET Pair Transistor. Accordingly it finds wide application of general controlling instrument, medical instrument. Especially it is optimum in signal precessing from sensor of high impedance. Hitachi prepares J-FET Input Operational Amp. series of one monolithic bipolar chip, HA17080, HA17082, HA17083, HA17084.

■ PRODUCT OUTLINE

J-FET Input Operational Amp. series provides single, dual, quad, and they are all internal phase compensated type excepting HA17080, and include condenser for phase compensation use. And HA17080 and HA17083 are capable of offset adjustment. Package provides two types of plastic sealing and glass sealing, and "A" glade with rigid electrical characteristic specification. Use satisfying uses.

Item	HA17080	HA17082	HA17083	HA17084
The number of Operational Amplifier (the number of channel)	Single	Dual		Quad.
Offset Adjusting Terminal	Exist	Not exist	Exist	Not exist
Phase Compensating Method	External	Internal		

■ FEATURES

- Wide operating supply voltage range ± 5 to $\pm 18V$
- Low input bias current 30pA
- Low input offset current 5pA
- High input impedance $10^{12}\Omega$
- High slew rate 13V/ μ s
- Wide common mode input voltage range
- Operation to input near supply voltage (V_{cc}) is possible.
- High voltage gain 106dB
- HA17080, HA17083 are capable of offset adjustment.
- Pin for pin compatible with Texas TL080 series

■ NOTE

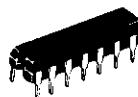
Since this IC is high input impedance operational amp, handling by hand may cause the input bias current and input offset current to be rise due dirt. Care shealed be taken for handling.

HA17080PS, HA17082PS



(DP-8)

HA17083P, HA17084P



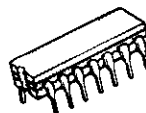
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HA17080GS, HA17082GS



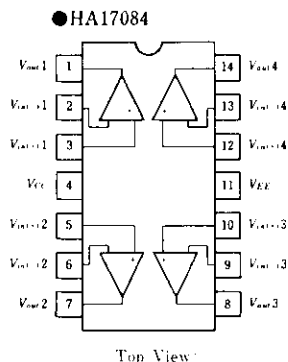
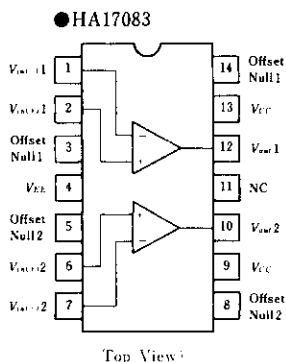
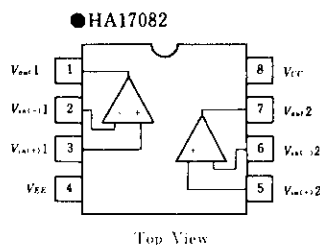
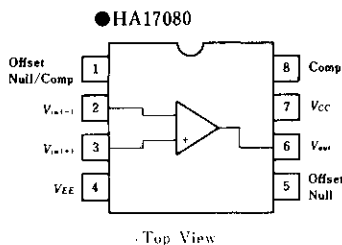
(DG-8)

HA17083G



(DG-14)

PIN ARRANGEMENT



ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Item	Symbol	P, PS series	G, GS series	Unit	Note
Supply Voltage	V_{CC}	-18	-18	V	
Supply Voltage	V_{EE}	-18	-18	V	
Differential Input Voltage	$V_{in, diff}$	± 30	± 30	V	
Input Voltage	V_{in}	± 15	+15	V	1
Power Dissipation	P_T	625	625	mW	2
Operating Temperature	T_{op}	20 to +75	-40 to +85	°C	
Storage Temperature	T_{stg}	-55 to +125	-65 to +150	°C	

Notes: 1. If supply voltage is less than -15V, input voltage is to supply voltage.
2. P and PS are permissible values to Ta=50°C, and beyond that, derate with 8.3mW/°C. G and GS are permissible values to Ta=70°C, and beyond that, derate with 7.8mW/°C.

ELECTRICAL CHARACTERISTICS (V_{CC}=-V_{EE}=-15V, Ta=25°C)

Item	Symbol	Test Condition	min	typ	max	Unit	Note
Input Offset Voltage	V_{io}	$R_S = 50\Omega$	Non A	5	15	mV	1
			A version	3	6		
Input Offset Current	I_{io}	$I_{io} = I_{i1} - I_{i2}$	Non A	5	200	pA	1
			A version	3	100		
Input Bias Current	I_i		Non A	30	400	pA	1, 2
			A version	30	200		
Common Mode Input Voltage Range	V_{CM}		Non A	-10	-	V	1
			A version	± 11	-		
Peak To Peak Output Voltage	V_{opp}	$R_L = 10k\Omega$		24	27	V	
		$R_L = 2k\Omega$		20	24		
Voltage Gain	A_{vL}	$R_L = 2k\Omega$ $V_{in} = +10V$	Non A	88	106	dB	1
			A version	94	106		
Common Mode Rejection Ratio	CMR	$R_S = 10k\Omega$	Non A	70	86	dB	1
			A version	80	86		

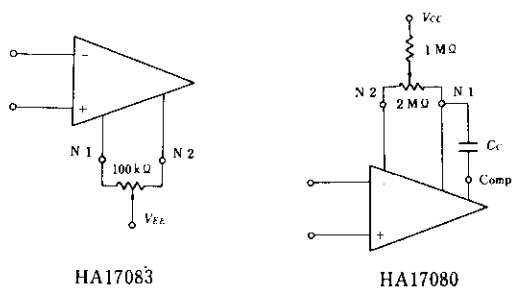
to be continued

■ ELECTRICAL CHARACTERISTICS (Continued)

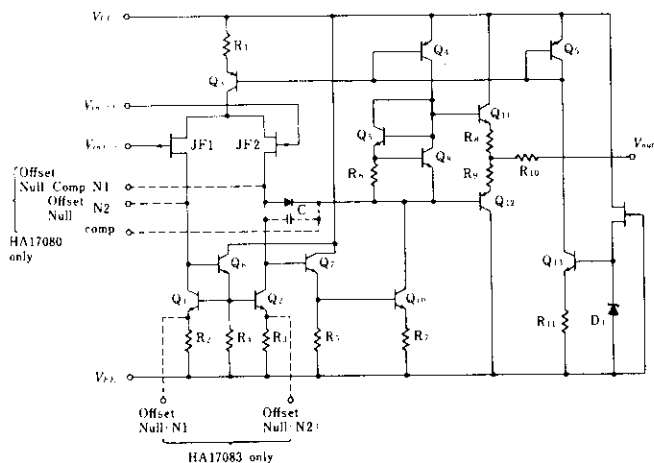
Item	Symbol	Test Condition	min	typ	max	Unit	Note
Line Regulation	$PSRR$	$R_S \leq 10k\Omega$	Non A	70	86	—	dB 1
			A version	80	86	—	
Supply Current	I_{CC}		—	1.4	2.8	mA	3
Band Width	BW	$A_{VD} = 1$	—	3	—	MHz	
Slew Rate	SR	$V_{in} = 10V, R_L = 2k\Omega, C_L = 100pF, A_{VD} = 1$	—	13	—	V/ μs	
Channel Separation	V_{o1}/V_{o2}	$A_{VD} = 100$	—	120	—	dB	
Rise Time	t_r	$V_{in} = 20mV, R_L = 2k\Omega, C_L = 100pF, A_{VD} = 1$	—	0.1	—	μs	
Overshoot	V_{over}	$C_L = 100pF, A_{VD} = 1$	—	10	—	%	
Input Resistance	R_{in}		—	10^{12}	—	Ω	
Input Noise Voltage	V_n	$R_S = 100\Omega, f = 1kHz$	—	35	—	nV/ $\sqrt{Hz}$	

Notes: 1. Non A is the standard to HA17080, HA17082, HA17083, HA17084.
 A version is the standard to HA17080A, HA17082A, HA17083A, HA17084A.
 2. It's Gate Leak Current of J-FET, and depends on temperature.
 At the time of measurement, it is necessary to keep junction temperature.
 3. It's the value per 1 channel.

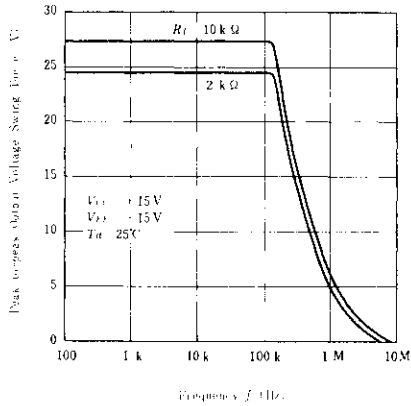
■ VOLTAGE OFFSET ADJUSTING CIRCUIT



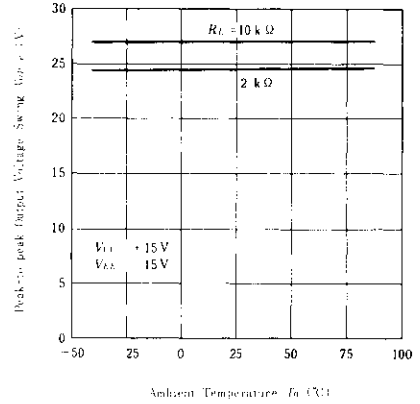
■ CIRCUIT SCHEMATIC



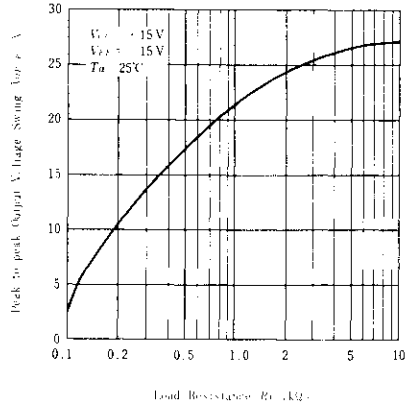
PEAK TO PEAK OUTPUT VOLTAGE SWING VS FREQUENCY



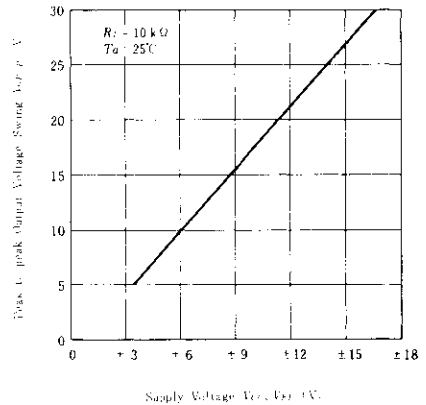
PEAK TO PEAK OUTPUT VOLTAGE SWING VS AMBIENT TEMPERATURE



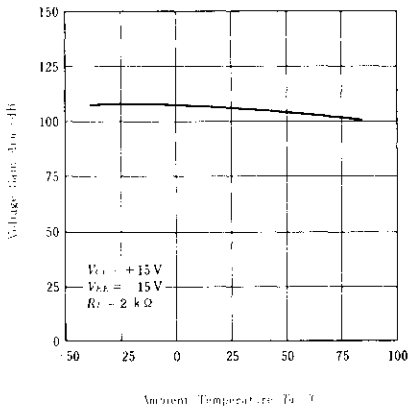
PEAK TO PEAK OUTPUT VOLTAGE SWING VS LOAD RESISTANCE



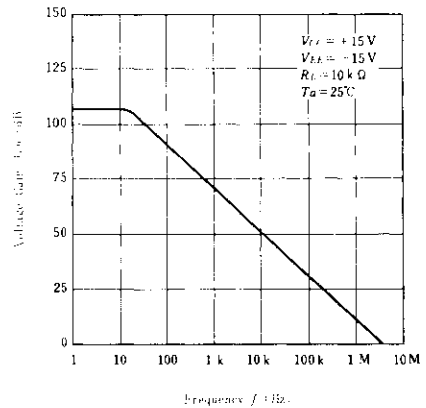
PEAK TO PEAK OUTPUT VOLTAGE SWING VS SUPPLY VOLTAGE

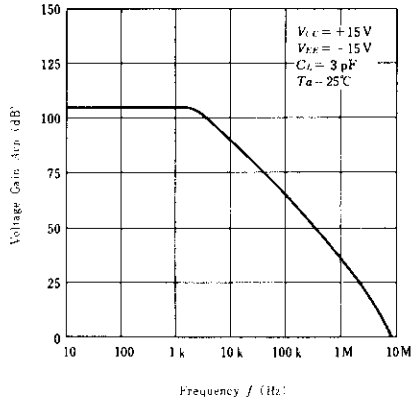
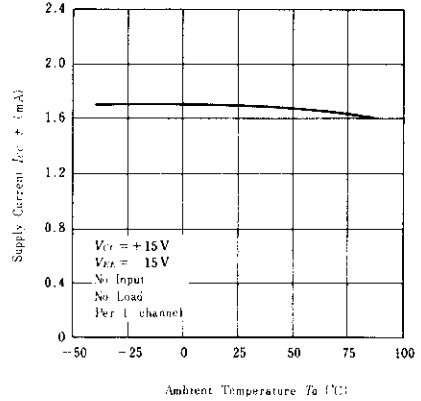
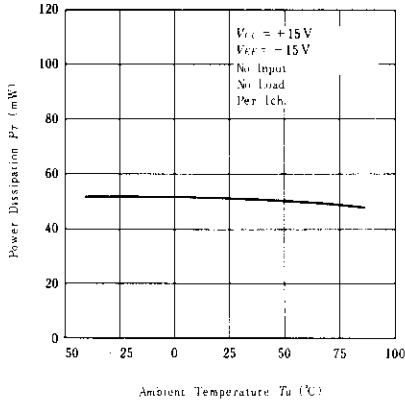
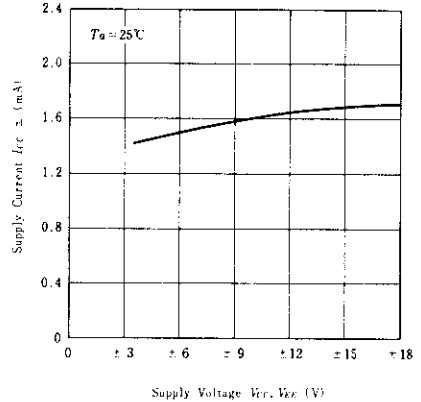
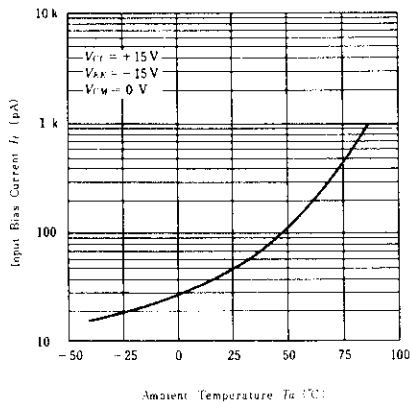
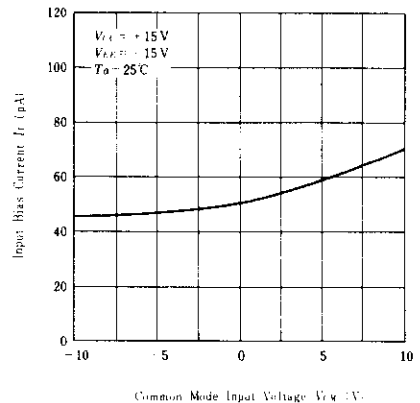


VOLTAGE GAIN VS AMBIENT TEMPERATURE

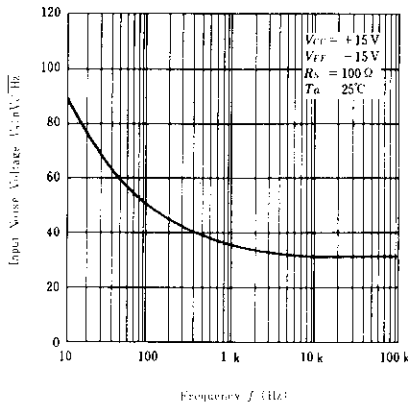


VOLTAGE GAIN VS FREQUENCY

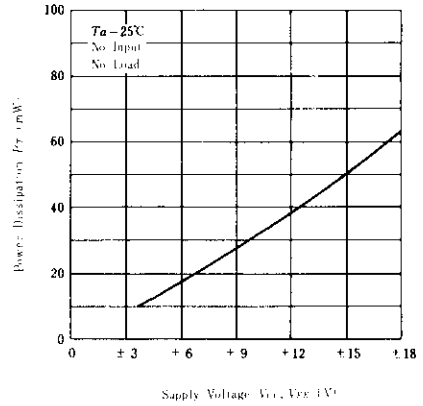


**HA17080 VOLTAGE GAIN VS
FREQUENCY**

**SUPPLY CURRENT VS AMBIENT
TEMPERATURE**

**POWER DISSIPATION VS AMBIENT
TEMPERATURE**

**SUPPLY CURRENT VS SUPPLY
VOLTAGE**

**INPUT BIAS CURRENT VS
AMBIENT TEMPERATURE**

**INPUT BIAS CURRENT VS COMMON
MODE INPUT VOLTAGE**


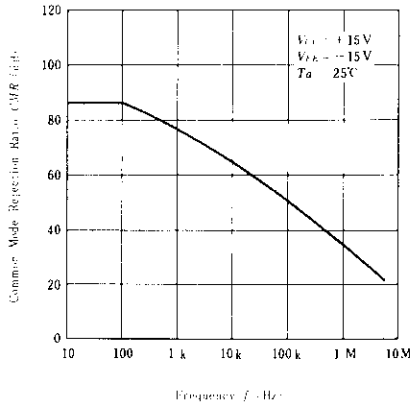
INPUT NOISE VOLTAGE VS FREQUENCY



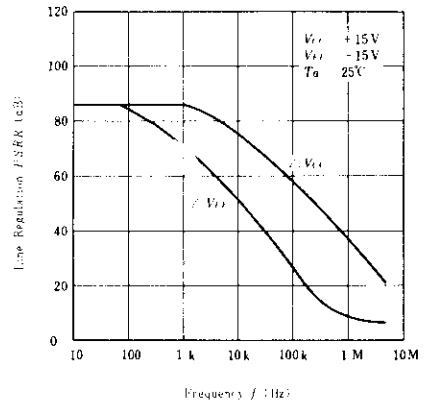
POWER DISSIPATION VS SUPPLY VOLTAGE



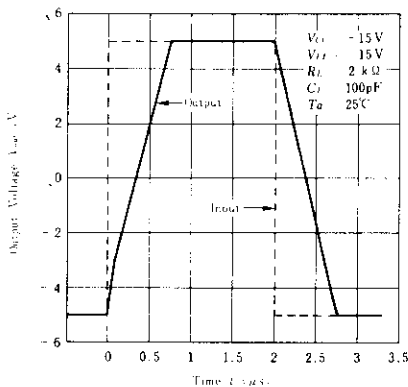
COMMON MODE REJECTION RATIO VS FREQUENCY



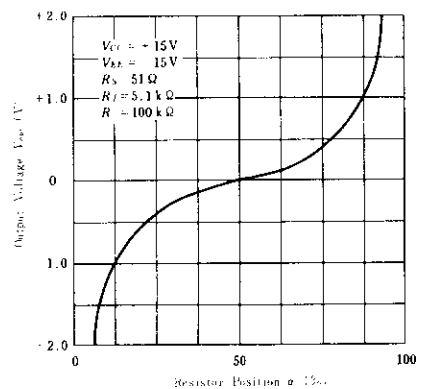
LINE REGULATION VS FREQUENCY



VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



HA17083 OFFSET ADJUSTING



HA17741G, HA17741GS, HA17741PS, HA17741

● General Purpose Operational Amplifier (Frequency Compensated)

HA17741 is internal phase compensated type, high performance operational amplifier. Its application is possible widely in the fields of instrumentation operation use and of general use.

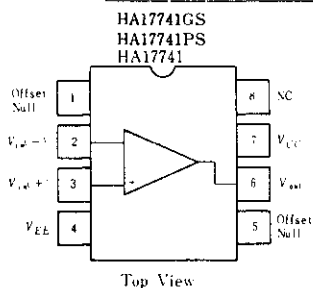
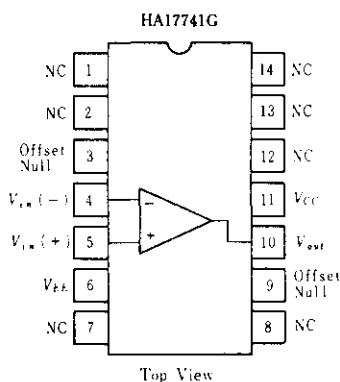
■ FEATURES

Industrial use; HA17741G, HA17741GS, HA17741PS

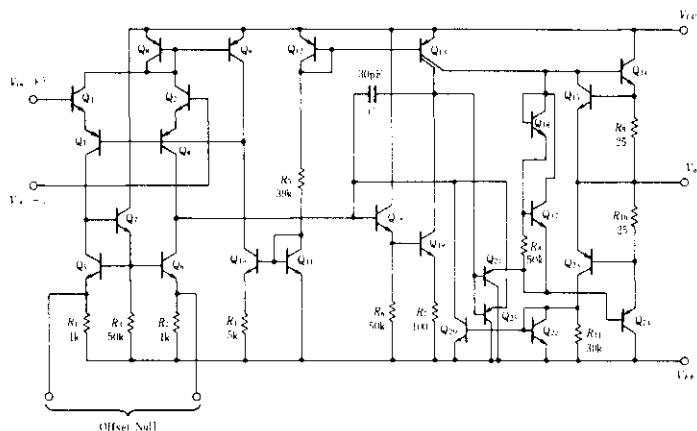
Commercial use; HA17741

- High Voltage Gain 106dB (typ)
- Wide Output Amplitude $\pm 13V$ (typ) [at $R_L \geq 2k\Omega$]
- Protected to Output Short
- Capable of adjusting Offset Voltage
- Internal phase compensated type

■ PIN ARRANGEMENT



■ CIRCUIT SCHEMATIC



■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	1: HA17741G, HA17741GS	2: HA17741PS	2: HA17741	Unit
Supply Voltage	V_{CC}	± 18	± 18	± 18	V
	V_{EE}	18	18	18	V
Power Dissipation	P_T	670	670	670	mW
Input Voltage	V_i	± 15	± 15	± 15	V
Differential Input Voltage	$V_{in, diff}$	± 30	± 30	± 30	V
Operating Temperature	T_{op}	20 to ± 75	20 to ± 75	0 to ± 70	$^\circ\text{C}$
Storage Temperature	T_{stg}	65 to ± 150	55 to ± 125	55 to ± 125	$^\circ\text{C}$

* 1 is the permissible value to $T_a = 65^\circ\text{C}$, and beyond that, derate with $7.6\text{mW}/^\circ\text{C}$.

2 is the permissible value to $T_a = 45^\circ\text{C}$, and beyond that, derate with $8.3\text{mW}/^\circ\text{C}$.

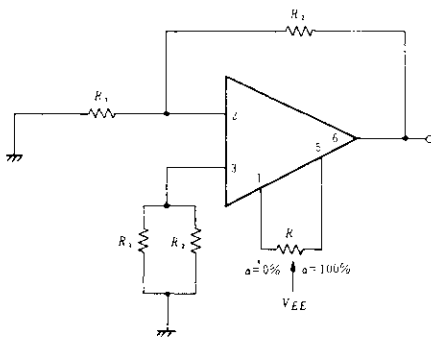
■ ELECTRICAL CHARACTERISTICS 1 ($V_{CC} = -V_{EE} = 15\text{V}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Test Condition	min	typ	max	Unit
Input Offset Voltage	V_{io}	$R_S \leq 10\text{k}\Omega$	—	1.0	6.0	mV
Input Offset Current	I_{io}		—	18	200	nA
Input Bias Current	I_i		—	75	500	nA
Line Regulation	$\Delta V_{io}/\Delta V_{CC}$	$R_S \leq 10\text{k}\Omega$	—	30	150	$\mu\text{V}/\text{V}$
	$\Delta V_{io}/\Delta V_{EE}$	$R_S \leq 10\text{k}\Omega$	—	30	150	$\mu\text{V}/\text{V}$
Voltage Gain	A_{vd}	$R_L \geq 2\text{k}\Omega$, $V_{out} = 10\text{V}$	86	106	—	dB
Common Mode Rejection Ratio	CMR	$R_S \leq 10\text{k}\Omega$	70	90	—	dB
Common Mode Input Voltage Range	V_{icm}	$R_S \leq 10\text{k}\Omega$	± 12	± 13	—	V
Peak To Peak Output Voltage	$V_{out, p-p}$	$R_L \geq 10\text{k}\Omega$	± 12	± 14	—	V
	$V_{out, p-p}$	$R_L \geq 2\text{k}\Omega$	± 10	± 13	—	V
Power Dissipation	P_T	at the time of no load	—	65	100	mW
Slew Rate	SR	$R_L \geq 2\text{k}\Omega$	—	0.5	—	$\text{V}/\mu\text{s}$
Rise Time	t_r	$V_{in} = 20\text{mV}$, $R_L = 2\text{k}\Omega$	—	0.3	—	μs
Overshoot	V_{over}	$C_L = 100\text{pF}$	—	5.0	—	%
Input Resistance	R_{in}		0.3	1.0	—	M Ω

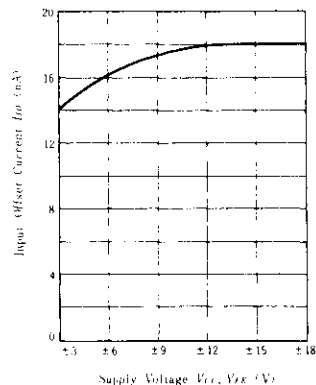
■ ELECTRICAL CHARACTERISTICS - 2 ($V_{CC} = -V_{EE} = 15\text{V}$, $T_a = -20$ to $+75^\circ\text{C}$, however as for HA17741, $T_a = 0$ to -70°C)

Item	Symbol	Test Condition	min	typ	max	Unit
Input Offset Voltage	V_{io}	$R_S \leq 10\text{k}\Omega$	—	—	9.0	mV
Input Offset Current	I_{io}		—	—	400	nA
Input Bias Current	I_i		—	—	1100	nA
Voltage Gain	A_{vd}	$R_L \geq 2\text{k}\Omega$, $V_{out} = 10\text{V}$	80	—	—	dB
Peak To Peak Output Voltage	$V_{out, p-p}$	$R_L \geq 2\text{k}\Omega$	± 10	—	—	V

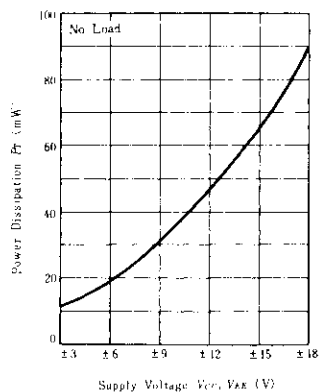
● VOLTAGE OFFSET ADJUSTING CIRCUIT



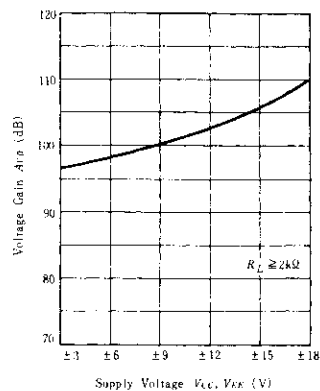
INPUT OFFSET CURRENT VS. SUPPLY VOLTAGE CHARACTERISTIC



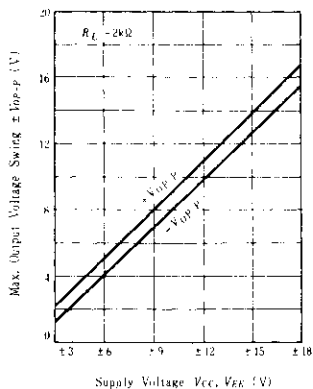
POWER DISSIPATION VS SUPPLY VOLTAGE



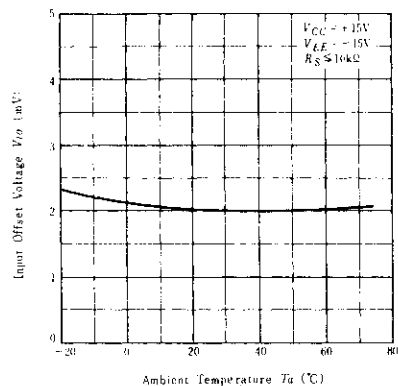
VOLTAGE GAIN VS SUPPLY VOLTAGE



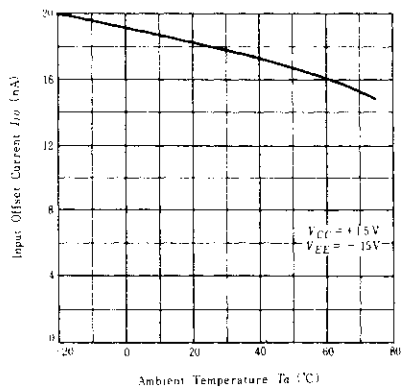
PEAK TO PEAK OUTPUT VOLTAGE VS SUPPLY VOLTAGE



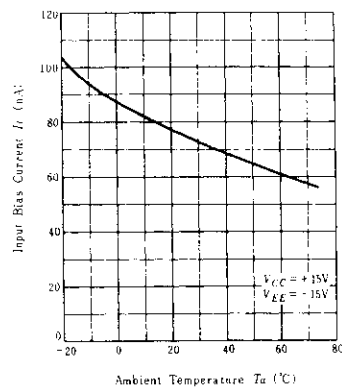
INPUT OFFSET VOLTAGE VS AMBIENT TEMPERATURE



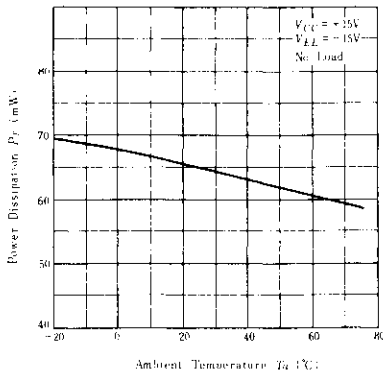
INPUT OFFSET CURRENT VS AMBIENT TEMPERATURE



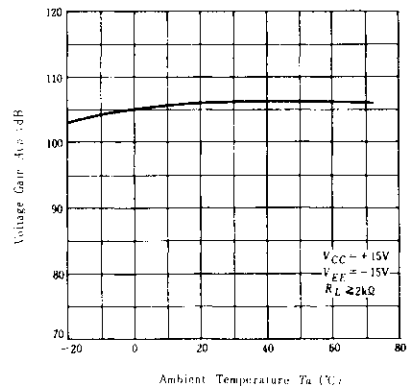
INPUT BIAS CURRENT VS AMBIENT TEMPERATURE



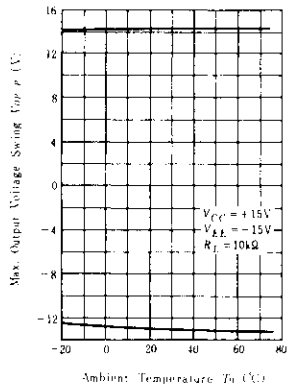
POWER DISSIPATION VS AMBIENT TEMPERATURE



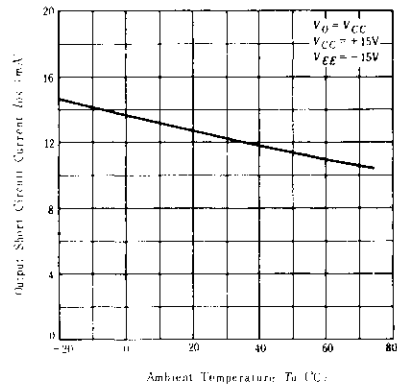
VOLTAGE GAIN VS AMBIENT TEMPERATURE



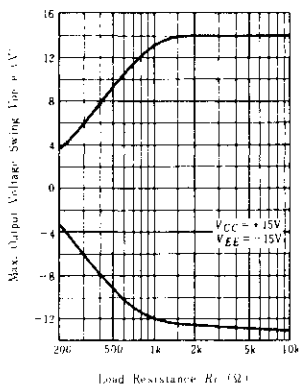
PEAK TO PEAK OUTPUT VOLTAGE VS AMBIENT TEMPERATURE



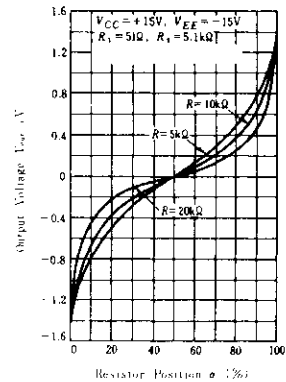
OUTPUT SHORT-CIRCUIT CURRENT VS AMBIENT TEMPERATURE



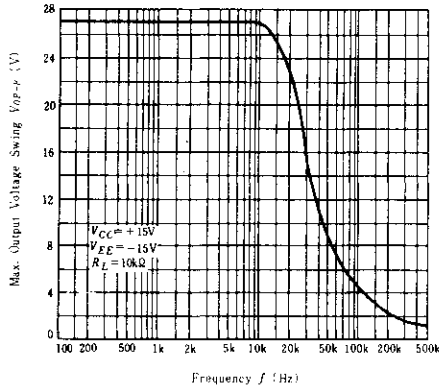
PEAK TO PEAK OUTPUT VOLTAGE VS LOAD RESISTANCE



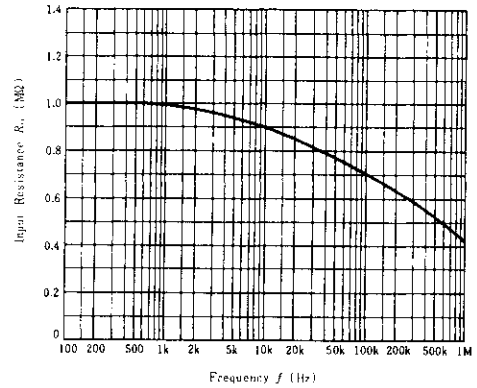
OFFSET ADJUSTING CHARACTERISTIC



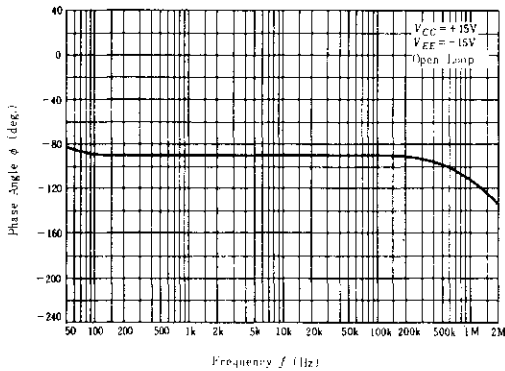
PEAK TO PEAK OUTPUT VOLTAGE VS FREQUENCY



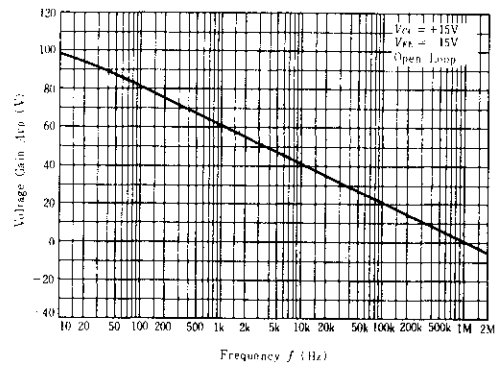
INPUT RESISTANCE VS FREQUENCY



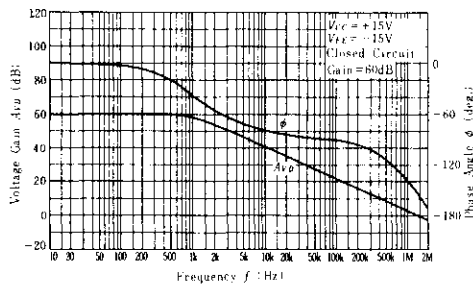
PHASE VS FREQUENCY



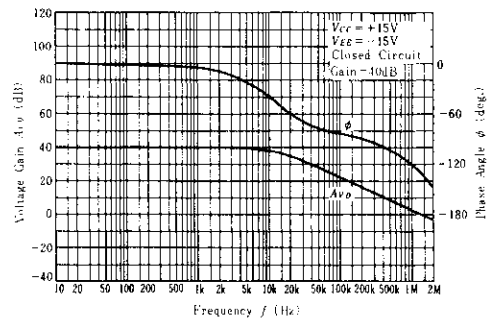
VOLTAGE GAIN VS FREQUENCY



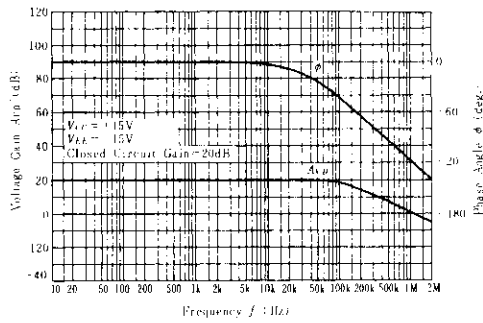
VOLTAGE GAIN, PHASE ANGLE VS FREQUENCY CHARACTERISTIC(1)



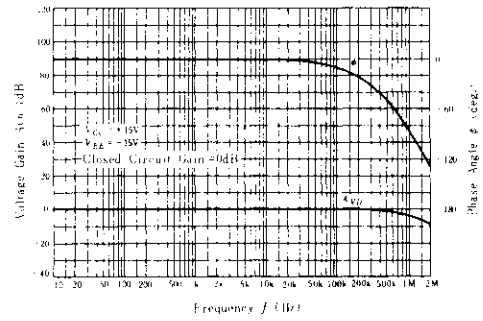
VOLTAGE GAIN, PHASE ANGLE VS FREQUENCY CHARACTERISTIC(2)



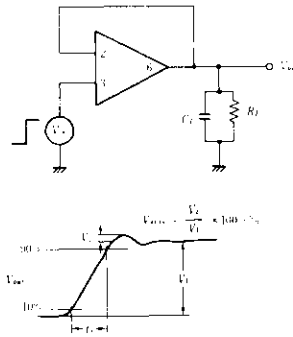
VOLTAGE GAIN, PHASE ANGLE VS
FREQUENCY CHARACTERISTIC(3)



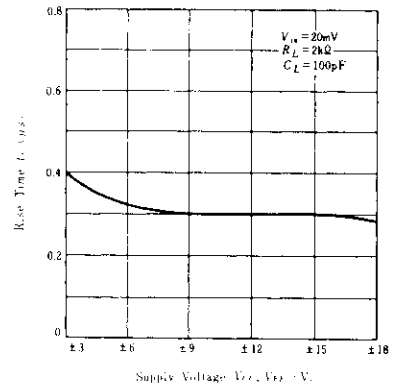
VOLTAGE GAIN, PHASE ANGLE VS
FREQUENCY CHARACTERISTIC(4)



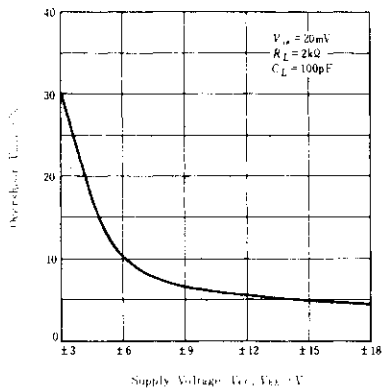
TRANSIENT RESPONSE CHARACTER-
ISTIC MEASURING CIRCUIT



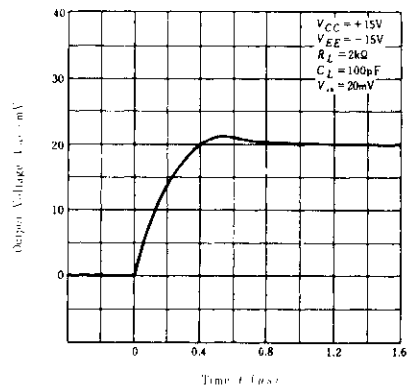
RISE TIME VS SUPPLY VOLTAGE



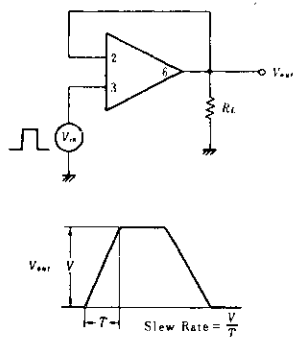
OVERSHOOT VS SUPPLY VOLTAGE



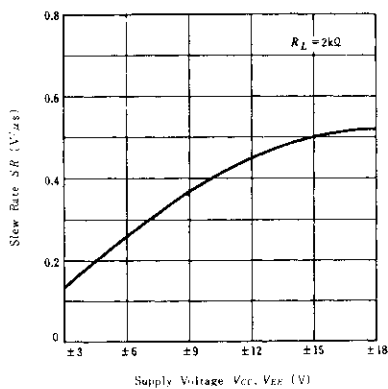
TRANSIENT RESPONSE
CHARACTERISTIC



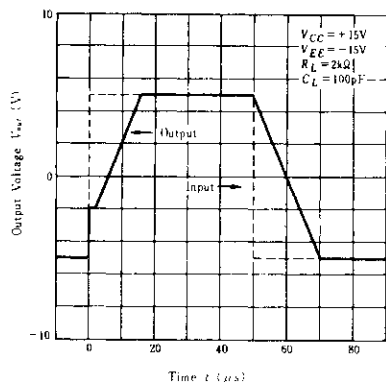
SLEW RATE MEASURING CIRCUIT



SLEW RATE VS. SUPPLY VOLTAGE



VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE CHARACTERISTIC



■ AN APPLICATION OF IC OPERATIONAL AMPLIFIER

1. Multivibrator

Multivibrator is the square wave generator utilizing the charge and discharge phenomenon of CR, and is widely used in power source of square wave, electromagnetic switch, etc. Multivibrator is classified by Astable Multivibrator without stable state, Monostable Multivibrator with one stable state, Bistable Multivibrator with two stable states.

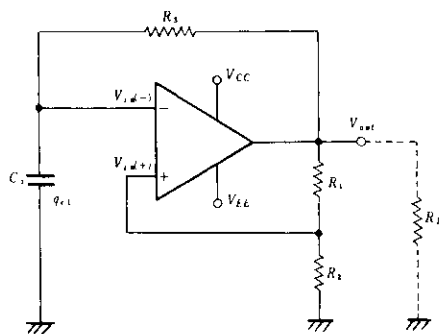
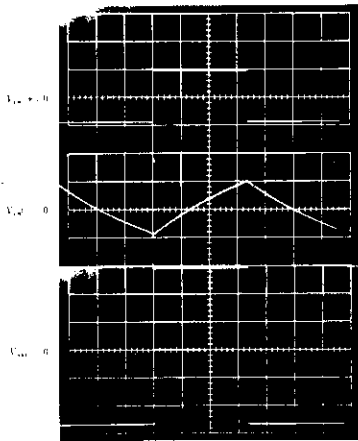


Fig.1 Astable Multivibrator Operating Circuit



axis of ordinates 5V/DIV
quadrature axis 2ms/DIV
circuit constant $\begin{cases} R_1=8k\Omega, R_2=4k\Omega \\ R_3=100k\Omega, C_1=0.1\mu F \\ R_L=\infty \end{cases}$
 $V_{CC}=15V, V_{EE}=-15V$

Fig.2 HA17741 Astable Multivibrator Operating Waveform

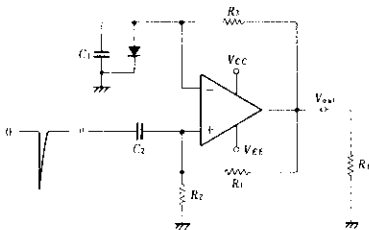
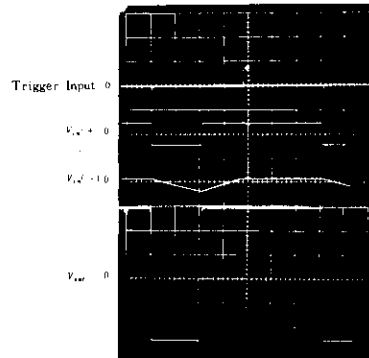


Fig.3 Monostable Multivibrator Operating Circuit



axis of ordinates 5V/DIV
quadrature axis 2ms/DIV
circuit constant $\begin{cases} R_1=10k\Omega, R_2=2k\Omega \\ R_3=40k\Omega, C_1=0.47\mu F \\ C_2=0.0068\mu F \\ R_L=\infty \end{cases}$
 $V_{CC}=15V, V_{EE}=-15V$

Fig.4 HA17741 Monostable Multivibrator Operating Waveform

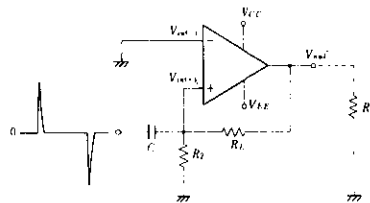
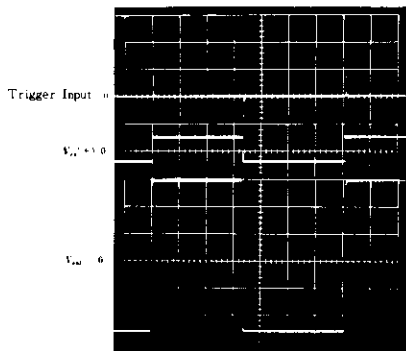


Fig.5 Bistable Multivibrator Operating Circuit



axis of ordinates 5V/DIV
quadrature axis 2ms/DIV
circuit constant
 $R_1=10k\Omega$, $R_2=2k\Omega$
 $C=0.0068\mu F$
 $R=\infty$
 $V_{CC}=15V$, $V_{BE}=-15V$

Fig.6 HA17741 Bistable Multivibrator Operating Waveform

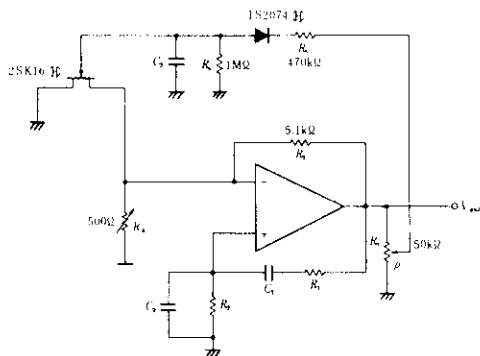


Fig.7 Wien bridge sine wave oscillator

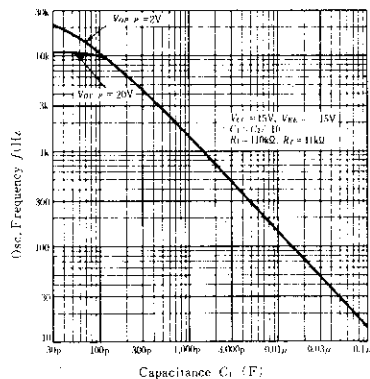
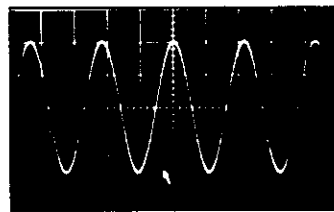


Fig.8 HA17741 Wien bridge sine wave oscillator f-c characteristic



axis of ordinates 5V/DIV
quadrature axis 0.5ms/DIV
measuring circuit condition
 $V_{CC}=15V$, $V_{BE}=-15V$
 $R_1=110k\Omega$, $R_2=11k\Omega$
 $C_1=0.0015\mu F$, $C_2=0.015\mu F$
measurement result
 $f=929.7Hz$, $T.H.D=0.06\%$

Fig.9 Operating Waveform of HA17741 Wien bridge sine wave oscillator

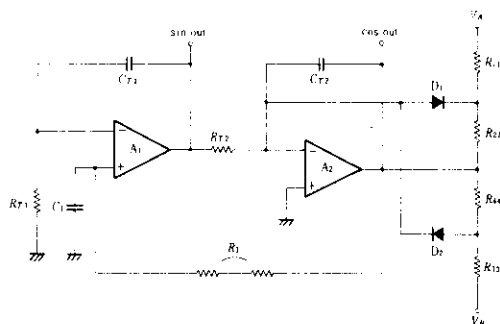


Fig.10 Quadrature Sine Wave Oscillator

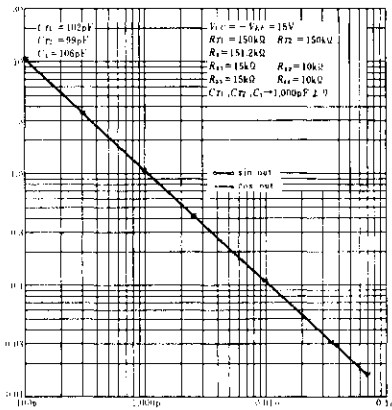
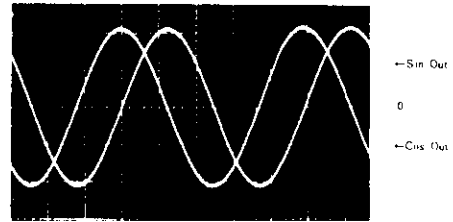


Fig.11 HA17747 Quadrature Sine Wave Oscillator
f-C₇₁, C₇₂, C₁ characteristic



axis of ordinates 5V/DIV
quadrature axis 0.2ms/DIV
circuit constant
C₇₁ = 1000pF (990) C₇₂ = 1000pF (990)
R₇₁ = 150kΩ R₇₂ = 150kΩ
C₁ = 1000pF (990) R₁ = 160kΩ
R₁₁ = 15kΩ R₂₂ = 10kΩ
R₃₃ = 16V R₄₄ = 10kΩ
V_{CC} = 15V V_{EE} = -15V

Fig.12 Output Waveform of Sine, Cos

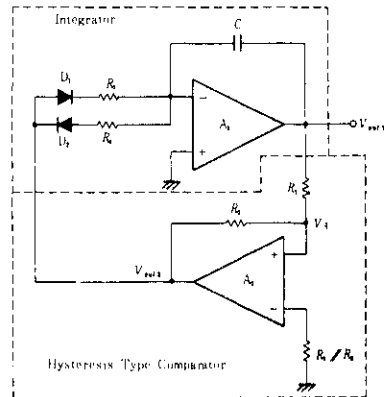
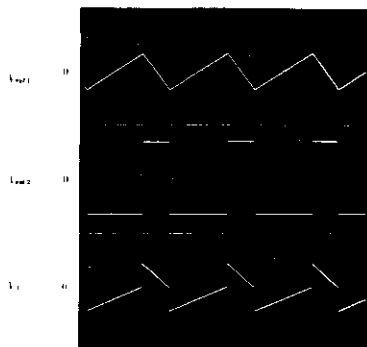
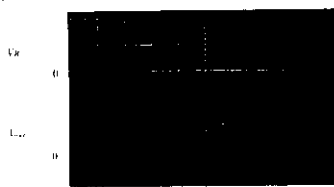


Fig.13 Triangular Wave Generator Operating
Circuit



axis of ordinates 10V/DIV
quadrature axis 10ms/DIV
measuring circuit condition
 $V_{CC}=15V$, $V_{EE}=-15V$
 $R_1=10k\Omega$, $R_2=20k\Omega$
 $R_3=100k\Omega$, $R_4=200k\Omega$
 $C=0.1\mu F$

Fig.14 Operating Waveform of HA17741 Triangular Wave Generator



axis of ordinates 5V/DIV
quadrature axis 2ms/DIV
circuit condition
 $V_{CC}=15V$, $V_{EE}=-15V$
 $R_1=100k\Omega$, $C_1=0.1\mu F$
 $V_{in}=10V$

Fig.16 HA17741 Saw Tooth Generator Operating Waveform

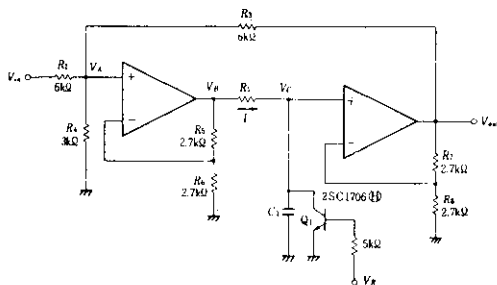


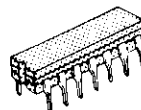
Fig.15 Saw Tooth Generator

HA17715G ● High Slew Rate Operational Amplifier

HA17715 is an operational amplifier of high speed and high gain, and its application is possible in A/D, D/A converter, active filter, wide band width amplifier, comparator, sample hold circuit, and general feedback circuit required wide band width from DC.

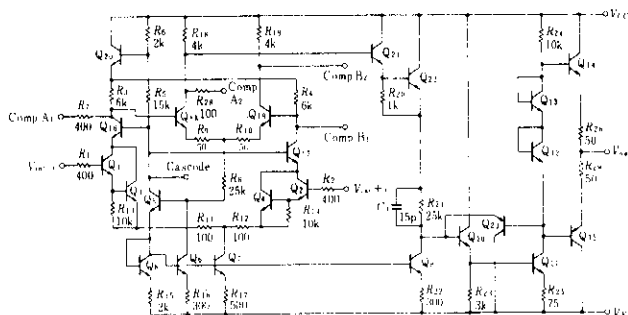
■ FEATURE

- Slew Rate 100V/μs (typ)
- Fast Settling Time 300 ns (typ)
- Wide Band Width 65MHz (typ)

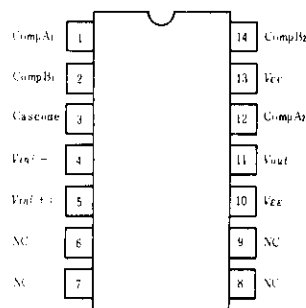


(DG-14)

■ CIRCUIT SCHEMATIC



■ PIN ARRANGEMENT



(Top View)

■ ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Item	Symbol	HA17715G	Unit
Supply Voltage	V_{CC}	-18	V
Supply Voltage	V_{EE}	-18	V
Power Dissipation	P_T	625	mW
Common Mode Input Voltage	V_{ICM}	+15	V
Differential Input Voltage	V_{ID}	+15	V
Operating Temperature	T_{op}	20 to +75	°C
Storage Temperature	T_{stg}	65 to +150	°C

* If supply voltage is less than -15V, input voltage is to supply voltage.

* It's a permissible value to Ta 70°C, and beyond that, derate with 7.6mW/°C

■ ELECTRICAL CHARACTERISTICS-1 (V_{CC} = -V_{EE} = 15V, Ta = 25°C)

Item	Symbol	Measuring Condition	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$R_s \leq 10k\Omega$		2.0	7.5	mV
Input Offset Current	I_{IO}			70	250	nA
Input Bias Current	I_b			0.4	1.5	μA
Line Regulation	$\frac{\Delta V_{IO}}{\Delta V_{CC}}, \frac{\Delta V_{IO}}{\Delta V_{EE}}$	$R_s \leq 10k\Omega$		45	400	μV/V
Voltage Gain	A_{vD}	$R_L \leq 2k\Omega, V_{out} \leq \pm 10V$	10000	30000		V/V
Common Mode Rejection Ratio	CMR	$R_s \leq 10k\Omega$	74	92		V
Common Mode Input Voltage Range	V_{ICM}		+10	+12		V
Supply Current	I_{CC}			5.5	10	mA

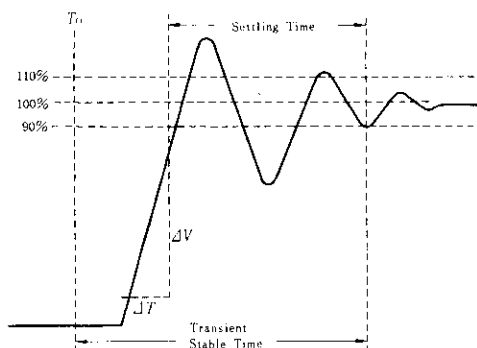
■ ELECTRICAL CHARACTERISTICS-1 (Continued)

Item	Symbol	Measuring Condition	min	typ	max	Unit
Power Dissipation	P_T			165	300	mW
Band Width	BW	$A_{v0}=1$	—	65	—	MHz
Slew Rate	SR	$A_{CL}=100$	—	70	—	V/ μ s
		$A_{CL}=10$	—	38	—	V/ μ s
		$A_{CL}=1$ (positive phase)	10	18	—	V/ μ s
		$A_{CL}=1$ (negative phase)	—	100	—	V/ μ s
Transient Stable Time	t_{ACT}	$V_{out}=5V$, $A_{CL}=1$	—	800	—	ns
Settling Time	t_{STL}	$A_{CL}=1$	—	300	—	ns
Rise Time	t_r	$V_{in}=400mV$, $A_{CL}=1$	—	30	75	ns
Overshoot	V_{over}	$V_{in}=400mV$, $A_{CL}=1$	—	25	50	%
Input Resistance	R_{in}		—	1.0	—	M Ω
Output Resistance	R_{out}			75	—	Ω
Temperature Drift	$\Delta V_{in}/\Delta T$		—	6	—	$\mu V/^\circ C$

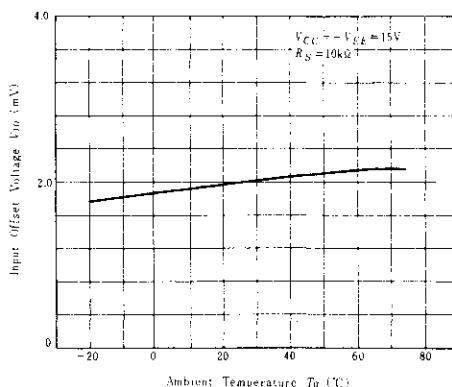
■ ELECTRICAL CHARACTERISTICS-2 ($V_{CC}=-V_{EE}=15V$, $T_a=-20$ to $+75^\circ C$)

Item	Symbol	Measuring Condition	min	typ	max	Unit
Input Offset Voltage	V_{io}	$R_S \leq 10k\Omega$		—	10	mV
Input Offset Current	I_{io}	$T_a=75^\circ C$		—	250	nA
		$T_a=-20^\circ C$		—	750	nA
Input Bias Current	I_I	$T_a=75^\circ C$		—	1.5	μA
		$T_a=0^\circ C$		—	7.5	μA
		$T_a=-20^\circ C$		—	10	μA
Voltage Gain	A_{v0}	$R_L \geq 2k\Omega$, $V_{out}=10V$	7000	—	—	V/V
Peak To Peak Output Voltage Amplitude	V_{OPP}	$R_L \geq 2k\Omega$	± 10	± 13	—	V

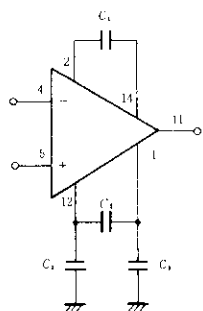
DEFINITION OF TRANSIENT RESPONSE WAVEFORM



INPUT OFFSET VOLTAGE VS. AMBIENT TEMPERATURE

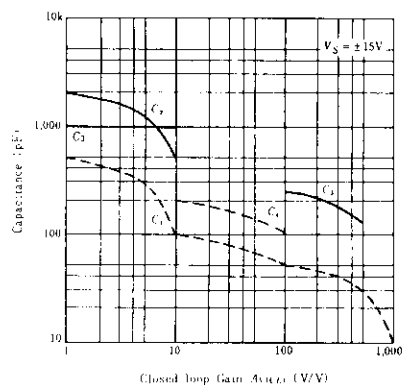


PHASE COMPENSATED CIRCUIT

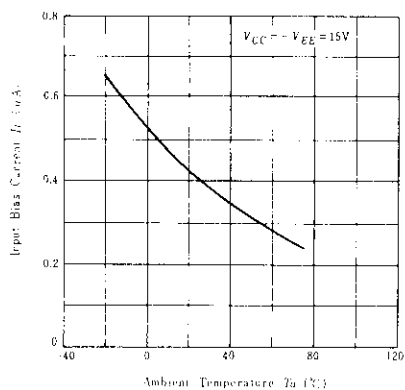


	C_1	C_2	C_3
1000	10pF		
100	50pF		250pF
10	100pF	500pF	1000pF
1	500pF	2000pF	1000pF

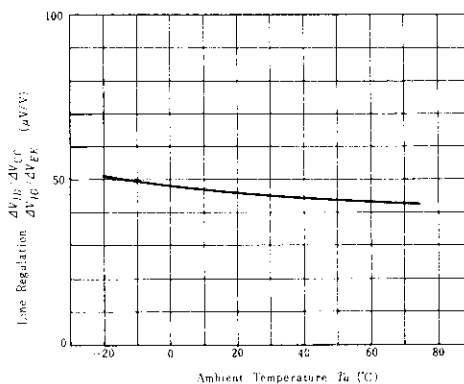
CLOSED LOOP GAIN VS. COMPENSATED CAPACITANCE



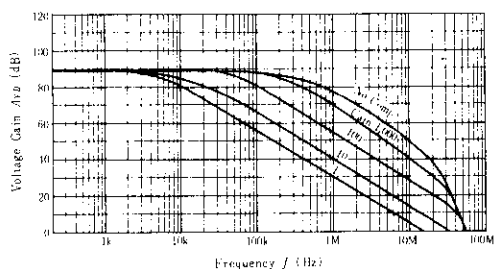
INPUT BIAS CURRENT VS. AMBIENT TEMPERATURE



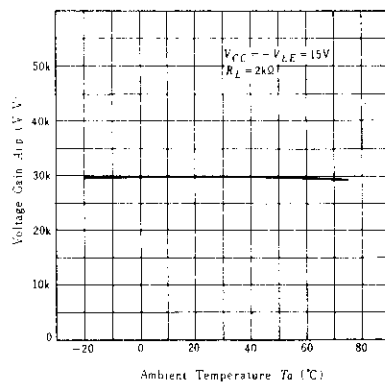
LINE REGULATION VS. AMBIENT TEMPERATURE



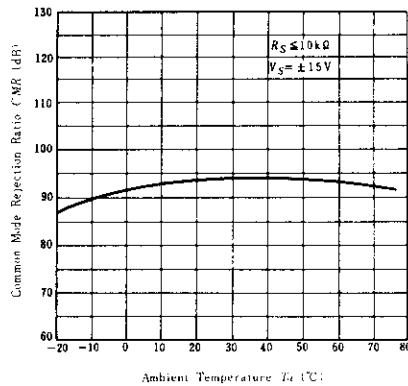
VOLTAGE GAIN VS. FREQUENCY



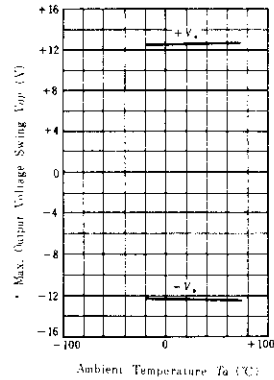
VOLTAGE GAIN VS. AMBIENT TEMPERATURE



COMMON MODE REJECTION RATIO VS. AMBIENT TEMPERATURE



PEAK TO PEAK OUTPUT VOLTAGE VS. AMBIENT TEMPERATURE



■ AN APPLICATION OF HA17715

HA17715 is an operational amplifier of high slew rate, and is optimum for the application in the field requiring high speed signal processing and wide band width. The following describes an application of HA17715.

1. Fundamental articles for using HA17715

1.1 Method of using phase compensated capacitance

Because HA17715 is high speed and high gain, it is especially necessary to notice the prevention of oscillation at the time of using it. On account of this, capacitance value for phase compensation is being recommended as shown in Fig. 1, satisfying the largeness of closed loop gain for use.

(1) In case voltage gain is 1,

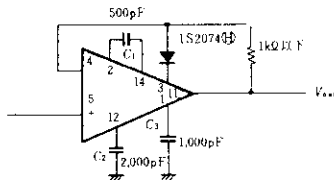


Fig.1 Phase Compensation in case voltage gain is 1

In case of voltage follower, in order not to have latch up occur at input stage even if output is increased, it is necessary to insert diode to cascode terminal as shown in the figure.

(2) In case voltage gain is 10

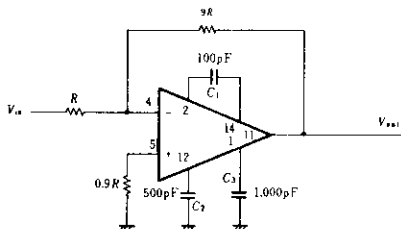


Fig.2 Phase Compensation in case voltage gain is 10

In case voltage gain is 10, it is allowable to insert capacitance of C_4 to between terminal 1 and 12, replacing C_2 and C_3 from the above figure. In that case, the value of C_4 is 200pF.

(3) In case voltage gain is 100

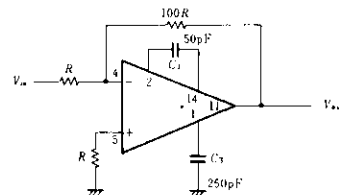


Fig.3 Phase Compensation in case voltage gain is 100

(4) In case voltage gain is 1000

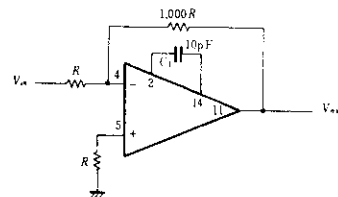


Fig.4 Phase Compensation in case voltage gain is 1000

1.2 Offset Adjustment

The adjustment of voltage offset can be performed by applying volume etc. for offset adjustment use to input terminal. In case of HA17715, it can be performed effectively by using terminals 1 and 2 for phase compensation use to input terminal. In case of HA17715, it can be performed effectively by using terminals 1 and 2 for phase compensation use as shown in Fig. 5

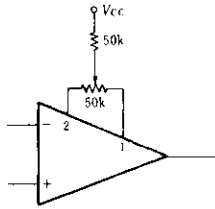


Fig.5 Offset Adjustment of HA17715

2. An application of HA17715

2.1 High Cycle Amplifier

Fig. 6 shows high cycle amplifier with progressed drive ability of output by applying PNP and NPN transistor to HA17715. Voltage Gain A_v of this amplifier can be.

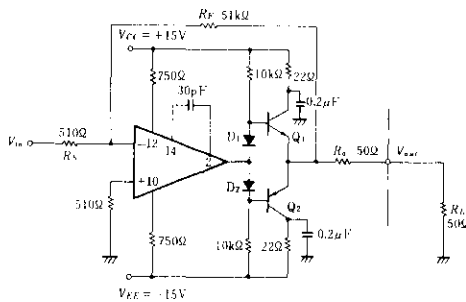
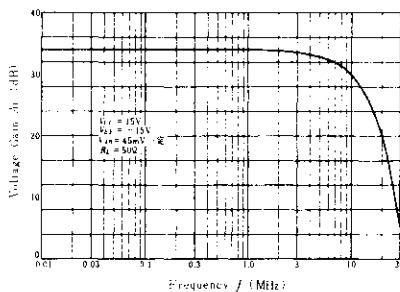


Fig.6 High Cycle Amplifier

expressed by $A_v = 20 \log \frac{R_F}{R_S} - 20 \log \left(1 + \frac{R_u}{R_L} \right)$

Fig. 7 shows frequency characteristic of voltage gain in the circuit of Fig. 6.

Fig.7 High Cycle Amplifier A_v - f Characteristic

2.2 Wide Band Width Oscillator

Fig. 8 shows oscillation circuit of wien bridge type theoretical equation

$$A_v = 1 + \frac{VR_1}{VR_2} + \frac{C_2}{C_1} = 6$$

$$f = \frac{1}{2\pi} \sqrt{\frac{1}{VR_1 \cdot VR_2 \cdot C_1 \cdot C_2}}$$

Table 1. Constant Table

Frequency Range	C_1	C_2
10 to 100Hz	$3\mu F$	$7.5\mu F$
100 to 1000Hz	$0.3\mu F$	$0.75\mu F$
1k to 10kHz	$0.03\mu F$	$0.075\mu F$
10k to 100kHz	$0.003\mu F$	$0.0075\mu F$
100k to 1000 kHz	$300pF + 150\Omega$	$750pF$

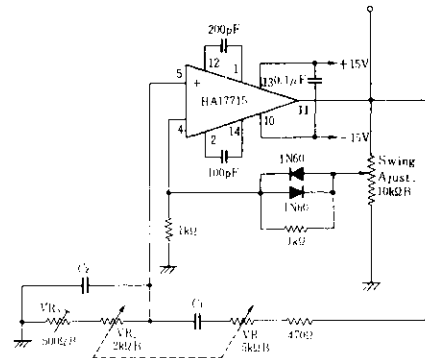


Fig.8 Wide Band Width Oscillator

- Note
1. By switching C_1 and C_2 , it is capable of oscillating the range of from 10 Hz to 1 MHz by 5 range.
 2. As for output amplitude, about 3 Vpp is optimum.
 3. The amplitude of each range is stabilized by the fine turning of C_2 .
 4. By the adjustment of VR_1 , uniformize amplitude change during VR_1 , VR_2 changes.

2.3 Waveform Shaping Circuit

Fig. 1 shows Waveform Shaping Circuit of Schmitt Trigger method. At no signal, this circuit becomes Astable Multi, since bias is put to it with the negative feedback type in order to make high cycle waveform shaping good. Fig. 11 shows the relation between minimum identification level and resistance.

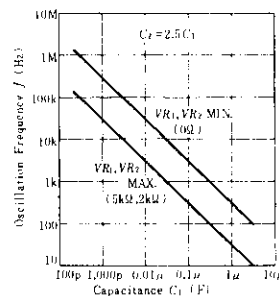


Fig.9 Oscillation Frequency vs Capacitance

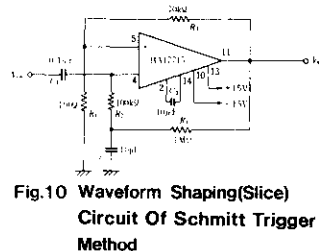


Fig.10 Waveform Shaping(Slice) Circuit Of Schmitt Trigger Method

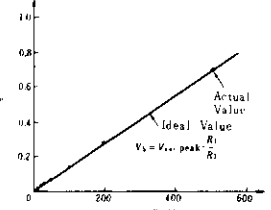


Fig.11 Minimum Identification Level vs Resistance

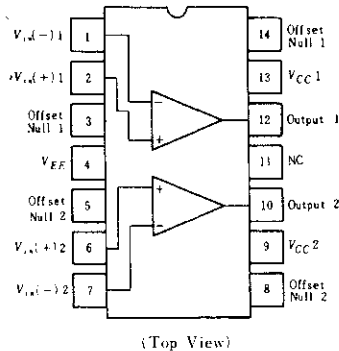
HA17747G, HA17747P, HA17747 ●Dual Operational Amplifier

HA17747 is an internal phase compensated type, high performance, dual operational amplifier, and its wide scope of application is possible in the field of measuring and control use.

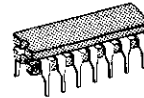
■FEATURES

- Industrial use HA17747G, HA17747P
- Commercial use HA17747
- High Voltage Gain 106dB (typ)
- Wide Output Amplitude . . . $\pm 13\text{V}$ (typ) [at $R_L \geq 2\text{k}\Omega$]
- Protected to Output Short
- Capable of adjusting Offset Voltage
- Internal Phase Compensated Type

■PIN ARRANGEMENT



HA17747G



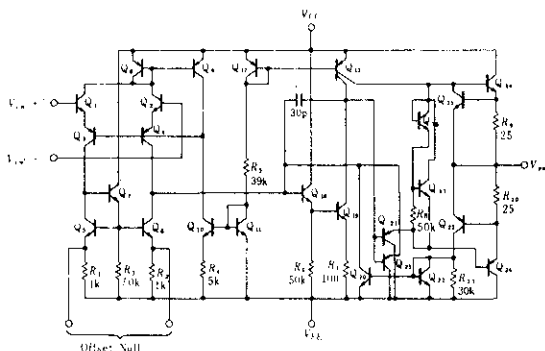
(PG-14)

HA17747P
HA17747



(DP-14)

■CIRCUIT SCHEMATIC(1/2)



■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

Item	Symbol	1: HA17747G	2: HA17747P	2: HA17747	Unit
Supply Voltage	V_{CC}	± 18	± 18	± 18	V
	V_{EE}	± 18	± 18	± 18	V
Power Dissipation	P_T^*	670	670	670	mW
Input Voltage	V_{IS}^{**}	± 15	± 15	± 15	V
Differential Input Voltage	$V_{ID(dif)}$	± 30	± 30	± 30	V
Voltage between Offset Adjusting Terminal and V_{EE}	$V_{OFF} - V_{EE}$	± 0.5	± 0.5	± 0.5	V
Operating Temperature	T_{op}	-20 to $+75$	-20 to $+75$	0 to $+70$	$^\circ\text{C}$
Storage Temperature	T_{stg}	65 to ± 150	55 to ± 125	55 to ± 125	$^\circ\text{C}$

*1 : Value under $T_a: 65^\circ\text{C}$. In case of more than it, $7.6\text{mW}/^\circ\text{C}$ derating shall be done.2 : Value under $T_a: 45^\circ\text{C}$. In case of more than it, $8.3\text{mW}/^\circ\text{C}$ derating shall be done.** If supply voltage is less than $\pm 15\text{V}$, input voltage is to supply voltage.■ ELECTRICAL CHARACTERISTICS-1 ($V_{CC} = -V_{EE} = 15\text{V}$, $T_a=25^\circ\text{C}$)

Item	Symbol	Measuring Condition	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$R_S \leq 10\text{k}\Omega$		1.0	6.0	mV
Input Offset Current	I_{IO}			20	200	nA
Input Bias Current	I_I			80	500	nA
Voltage Gain	$A_{v(d)}$	$R_L \leq 2\text{k}\Omega$, $V_{id} = \pm 10\text{V}$	88	106		dB
Supply Current	I_{CC}	at the time of no load		1.7	2.8	mA
Power Dissipation	P_T	It's the value per 1 channel.		50	85	mW
Input Resistance	R_{is}		0.3	2.0		M Ω
Input Capacitance	C_{is}			1.4		pF
Output Resistance	R_{od}			75		Ω
Slew Rate	SR	$R_L \leq 2\text{k}\Omega$		0.5		V/ μs
Rise Time	t_r	$V_{is} = 20\text{mV}$, $R_L = 2\text{k}\Omega$		0.3		μs
Overshoot	V_{ov}	$C_L = 100\text{pF}$		5.0		%
Input Offset Voltage Adjusting Range	$\Delta V_{IO(adj)}$			± 15		mV
Output Short Current	I_{os}			25		mA
Channel Separation	V_{cl}/V_{cs}			120		dB

■ ELECTRICAL CHARACTERISTICS-2 ($V_{CC} = -V_{EE} = 15\text{V}$, $T_a = -20$ to $+75^\circ\text{C}$,
however, as for HA17747, $T_a = 0$ to $+70^\circ\text{C}$)

Item	Symbol	Measuring Condition	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$R_S \leq 10\text{k}\Omega$		1.0	9.0	mV
Input Offset Current	I_{IO}			20	400	nA
Input Bias Current	I_I			80	1100	nA
Line Regulation	$\Delta V_{IO}/\Delta V_{CC}$, $\Delta V_{IO}/\Delta V_{EE}$	$R_L \leq 10\text{k}\Omega$		30	150	$\mu\text{V}/\text{V}$
Voltage Gain	$A_{v(d)}$	$R_L \leq 2\text{k}\Omega$, $V_{id} = \pm 10\text{V}$	80			dB
Common Mode Rejection Ratio	CMR	$R_S \leq 10\text{k}\Omega$	70	90		dB
Common Mode Input Voltage Range	V_{icm}		± 12	± 13		V
Peak To Peak Output Voltage Amplitude	V_{opp}	$R_L \leq 10\text{k}\Omega$	± 12	± 14		V
		$R_L \leq 2\text{k}\Omega$	± 10	± 13		V
Supply Current	I_{CC}	at the time of no load		2.1	3.7	mA
Power Dissipation	P_T	It's the value per 1 channel.		65	110	mW

Note: As for characteristic curve, refer to HA17741.

HA17458GS, HA17458PS, HA17458 ●Dual Operational Amplifier

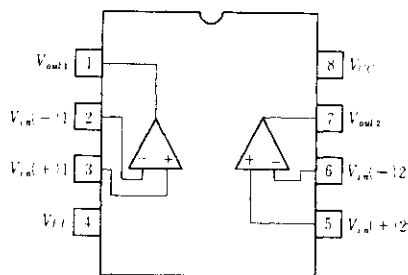
HA17458 is a dual operational amplifier which provides internal phase compensation and high performance. It can be applied widely to measuring control equipment and to general use.

Industrial Use HA17458GS, HA17458PS
Commercial Use HA17458

■ FEATURES

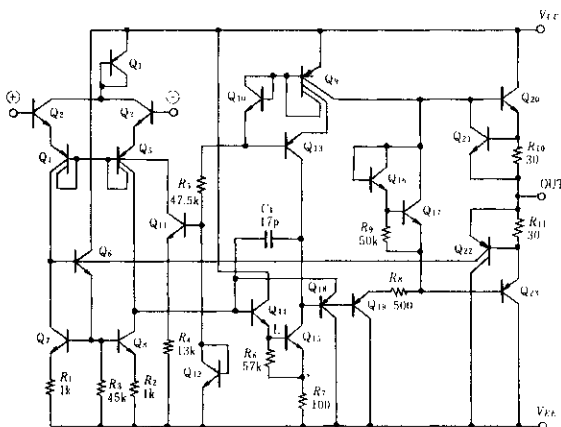
- High Voltage Gain 100dB (typ)
- Wide Output Amplitude . . . $\pm 13V$ (typ) [at $R_L \geq 2k\Omega$]
- Protected from output shortcircuit
- Internal Phase Compensation

■ PIN ARRANGEMENT



(Top View)

■ CIRCUIT SCHEMATIC(1/2)



HA17458GS



(DG-8)

HA17458PS

HA17458



(DG-8)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	1)HA17458GS	2)HA17458PS	2)HA17458	Unit
Supply Voltage	V_{CC}	+18	+18	+18	V
	V_{EE}	-18	-18	-18	V
Power Dissipation	P_T *	670	670	670	mW
Input Voltage	$V_{i,**}$	± 15	± 15	± 15	V
Differential Input Voltage	$V_{in(diff)}$	± 30	± 30	± 30	V
Operating Temperature	T_{op}	-20 to +75	-20 to +75	0 to +70	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	-55 to +125	-55 to +125	$^\circ\text{C}$

*1: Value under $T_a \leq 65^\circ\text{C}$. In case of more than it, 7.6mW/ $^\circ\text{C}$ derating shall be done.

2: Value under $T_a \leq 45^\circ\text{C}$. In case of more than it, 8.3mW/ $^\circ\text{C}$ derating shall be done.

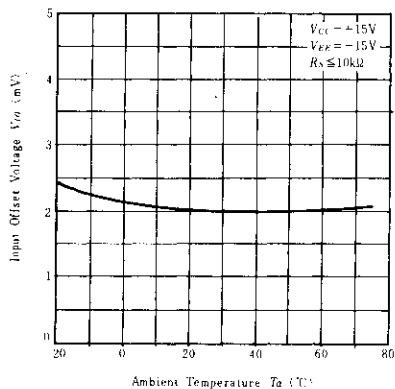
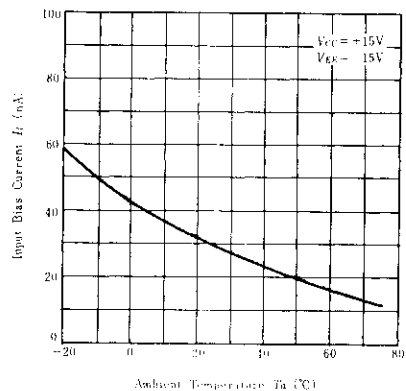
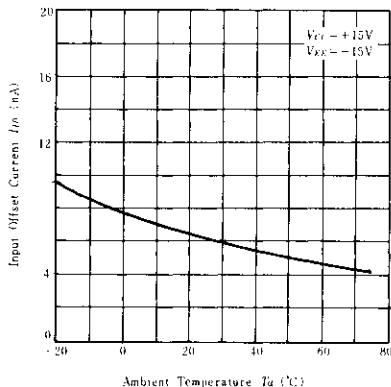
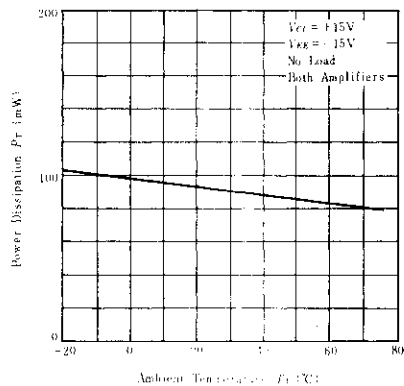
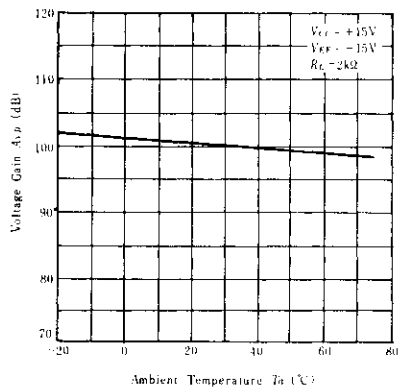
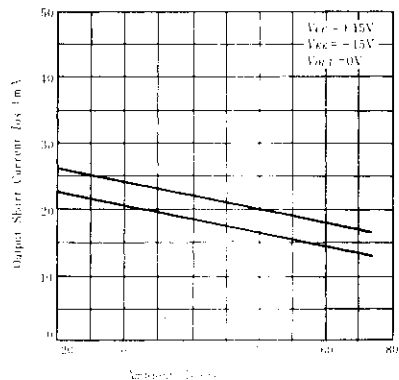
** If the Supply voltage is less than $\pm 15\text{V}$, input voltage shall be less than supply voltage.

■ ELECTRICAL CHARACTERISTICS-1 ($V_{CC} = V_{EE} = 15\text{V}$, $T_a = 25^\circ\text{C}$)

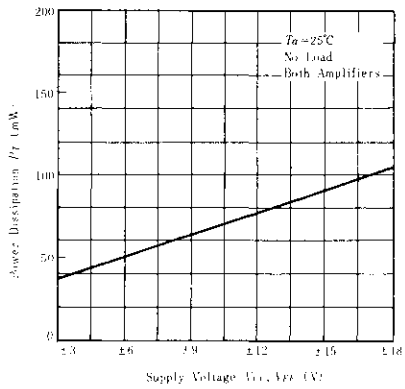
Item	Symbol	Test Condition	Min	Typ	Max	Unit
Input Offset Voltage	V_{io}	$R_L \leq 10\text{k}\Omega$	—	2.0	6.0	mV
Input Offset Current	I_{io}		—	6	200	nA
Input Bias Current	I_i		—	30	500	nA
Line Regulation	$\Delta V_{io}/\Delta V_{CC}$	$R_L \leq 10\text{k}\Omega$	—	30	150	$\mu\text{V}/\text{V}$
	$\Delta V_{io}/\Delta V_{EE}$	$R_L \leq 10\text{k}\Omega$	—	30	150	$\mu\text{V}/\text{V}$
Voltage Gain	A_{v0}	$R_L \geq 2\text{k}\Omega$, $V_{out} = \pm 10\text{V}$	86	100	—	dB
Common Mode Rejection Ratio	CMR	$R_L \leq 10\text{k}\Omega$	70	90	—	dB
Common Mode Input Voltage Range	V_{icm}		± 12	± 13	—	V
Peak-to-peak Output Voltage	V_{opp}	$R_L = 10\text{k}\Omega$	± 12	± 14	—	V
Power Dissipation	P_T	No load	—	90	200	mW
Slew Rate	SR	$A_v = 1$	—	0.6	—	V/ μs
Input Resistance	R_{in}		0.3	1.0	—	M Ω
Input Capacitance	C_{in}		—	6.0	—	pF
Output Resistance	R_{out}		—	75	—	Ω

■ ELECTRICAL CHARACTERISTICS-2 ($V_{CC} = -V_{EE} = 15\text{V}$, $T_a = -20$ to $+75^\circ\text{C}$, For HA17458, $T_a = 0$ to $+70^\circ\text{C}$)

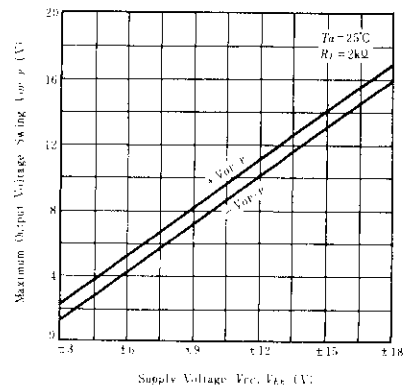
Item	Symbol	Test Condition	Min	Typ	Max	Unit
Input Offset Voltage	V_{io}	$R_L \leq 10\text{k}\Omega$	—	—	9.0	mV
Input Offset Current	I_{io}		—	—	400	nA
Input Bias Current	I_i		—	—	1100	nA
Voltage Gain	A_{v0}	$R_L \geq 2\text{k}\Omega$, $V_{out} = \pm 10\text{V}$	80	—	—	dB
Peak-to-peak Output Voltage	V_{opp}	$R_L = 2\text{k}\Omega$	± 10	± 13	—	V

**INPUT OFFSET VOLTAGE VS.
AMBIENT TEMPERATURE**

**INPUT BIAS CURRENT VS.
AMBIENT TEMPERATURE**

**INPUT OFFSET CURRENT VS.
AMBIENT TEMPERATURE**

**POWER DISSIPATION VS.
AMBIENT TEMPERATURE**

**VOLTAGE GAIN VS.
AMBIENT TEMPERATURE**

**OUTPUT SHORT CURRENT VS.
AMBIENT TEMPERATURE**


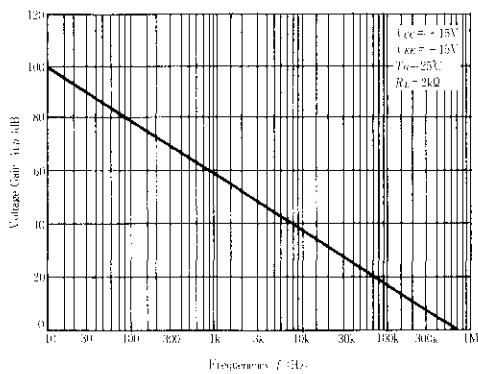
**POWER DISSIPATION VS.
SUPPLY VOLTAGE**



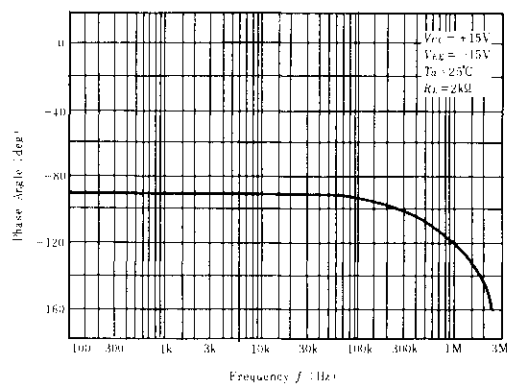
**MAXIMUM OUTPUT VOLTAGE SWING VS.
SUPPLY VOLTAGE**



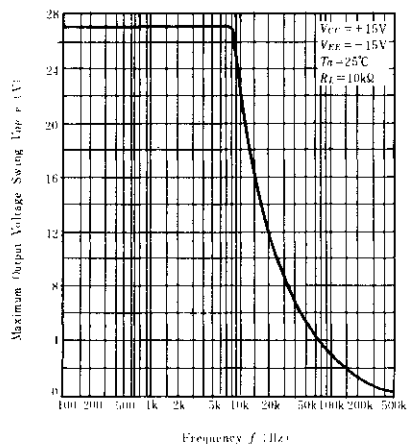
VOLTAGE GAIN VS. FREQUENCY



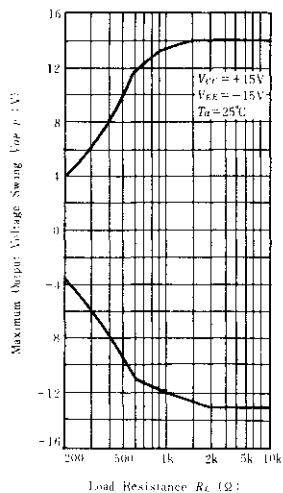
PHASE ANGLE VS. FREQUENCY



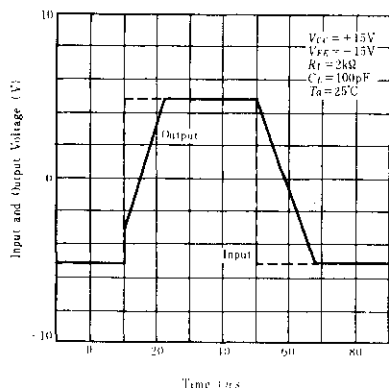
MAXIMUM OUTPUT VOLTAGE SWING VS. FREQUENCY



MAXIMUM OUTPUT VOLTAGE SWING VS. LOAD RESISTANCE



VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



HA17558GS, HA17558PS, HA17558 ●Dual Operational Amplifier

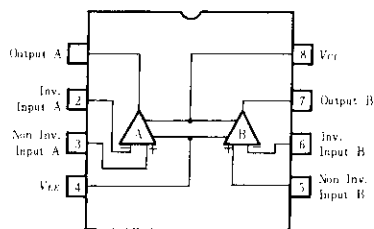
HA17558 is a dual operational amplifier which provides internal Frequency compensation and high performance. It can be applied widely to measuring control equipment and to general use. The two amplifiers share a common bias network and power supply leads.

Industrial Use HA17558GS, HA17558PS
Commercial Use HA17558

■FEATURES

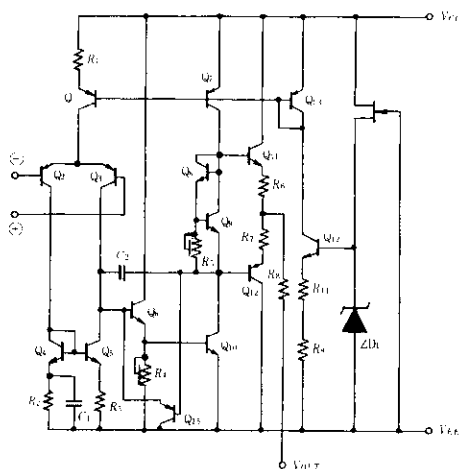
- High Voltage Gain 104dB (typ)
- High Speed 1V/ μ s
- Continuous Short-circuit Protection
- Low-noise operational amplifiers
- Internal Frequency Compensation

■PIN ARRANGEMENT



(Top View)

■CIRCUIT SCHEMATIC (1/2)



HA17558GS



(DG-8)

HA17558PS
HA17558



(DP-8)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA17558	HA17558PS	HA17558GS	Unit	Note
Power Supply	V_{CC}	-18	+18	+18	V	
	V_{EE}	-18	-18	-18	V	
Common-mode Differential Voltage	$V_{CM(dif)}$	+30	+30	+30	V	
Common-mode Input Voltage	V_{CM}	± 15	± 15	± 15	V	1
Power Dissipation	P_T	670 (3)	670 (3)	670 (2)	mW	2, 3
Operating Temperature Range	T_{op}	0 ~ +70	-20 ~ +75	-20 ~ +75	$^\circ\text{C}$	
Storage Temperature Range	T_{stg}	-55 ~ +125	-55 ~ +125	-65 ~ +150	$^\circ\text{C}$	

Note 1.) For supply voltage less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

Note 2.) Value under $T_a \leq 65^\circ\text{C}$. In case of more than it, 7.6mW/ $^\circ\text{C}$, derating shall be done.

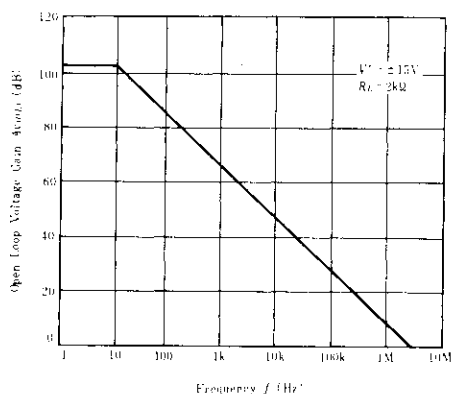
Note 3.) Value under $T_a \leq 45^\circ\text{C}$. In case of more than it, 8.3mW/ $^\circ\text{C}$, derating shall be done.

■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$, $V_{CC} = +15\text{V}$, $V_{EE} = -15\text{V}$)

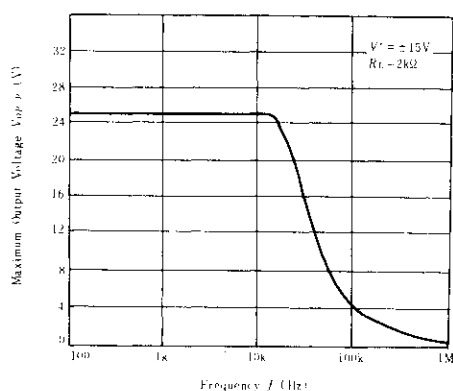
Test Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Offset Voltage	V_{io}	$R_L \leq 10\text{k}\Omega$	—	0.5	6	mV
Input Offset Current	I_{io}		—	5	200	nA
Input Bias Current	I_{IB}		—	50	500	nA
Voltage Gain	A_v	$R_L \geq 2\text{k}\Omega$, $V_i = \pm 10\text{V}$	86	104	—	dB
Maximum Output Voltage	V_{out-p}	$R_L \geq 10\text{k}\Omega$	± 12	± 14	—	V
Maximum Output Voltage	V_{out-p}	$R_L \geq 2\text{k}\Omega$	± 10	± 12.4	—	V
Common-mode Input Voltage Range	V_{CM}		± 12	± 14	—	V
Common-mode Rejection Ratio	CMR	$R_L \leq 10\text{k}\Omega$	70	100	—	dB
Supply Voltage Rejection Ratio	SVR	$R_L \leq 10\text{k}\Omega$	—	110	150	$\mu\text{V/V}$
Power Dissipation	P_T	2-channel, No Load	—	90	170	mW
Slew Rate	SR	$A_v = 1$	—	1.0	—	V/ μs
Equivalent Input Noise Voltage	V_{ni}	$R_s = 1\text{k}\Omega$	—	6	—	$\mu\text{Vp-p}$
Channel Separation	CS	$f = 1\text{kHz}$	—	105	—	dB

■ TYPICAL PERFORMANCE CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

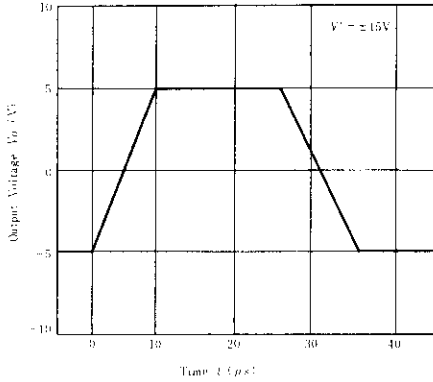
OPEN LOOP VOLTAGE GAIN VS. FREQUENCY



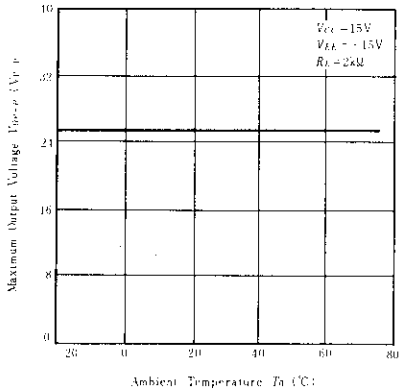
MAXIMUM OUTPUT VOLTAGE VS. FREQUENCY



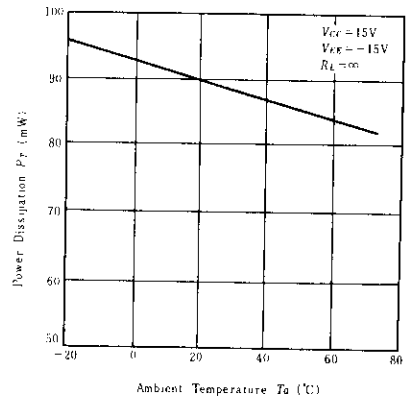
TRANSIENT RESPONSE



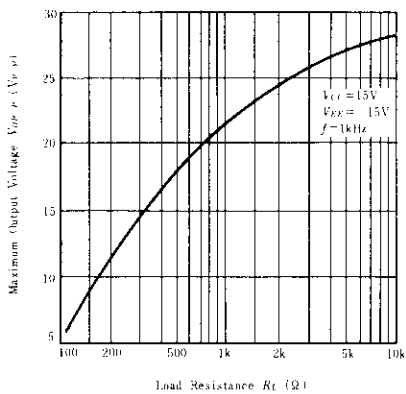
MAXIMUM OUTPUT VOLTAGE VS. AMBIENT TEMPERATURE



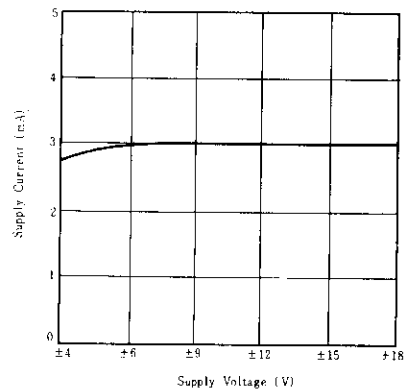
POWER DISSIPATION VS. AMBIENT TEMPERATURE

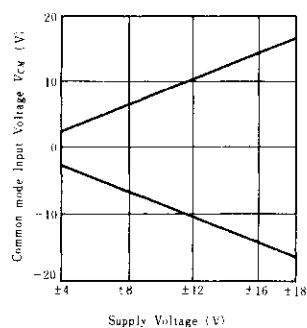
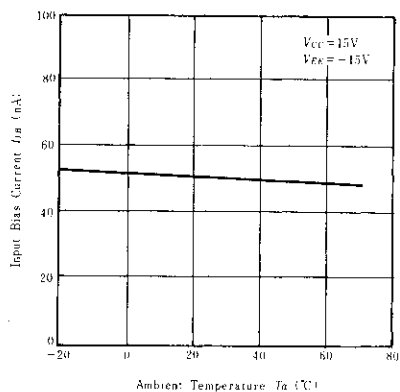


MAXIMUM OUTPUT VOLTAGE VS. LOAD RESISTANCE

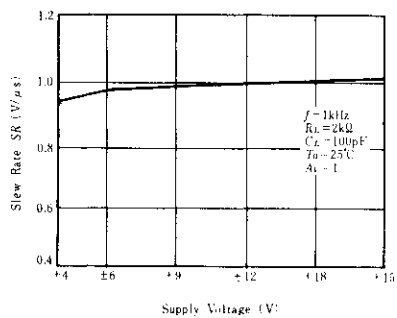
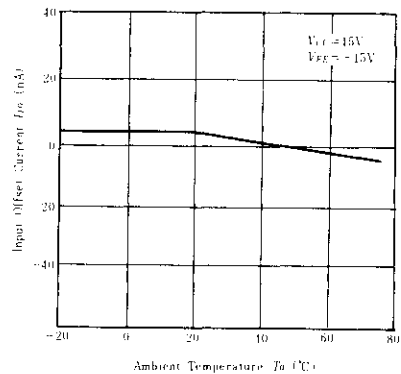
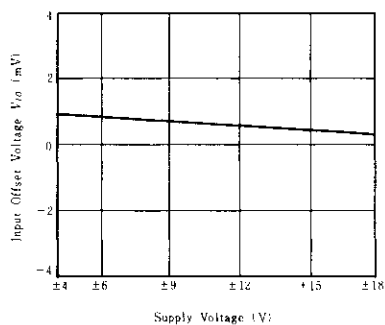
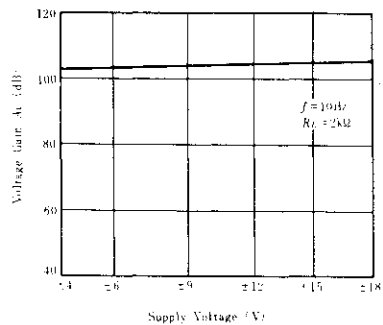


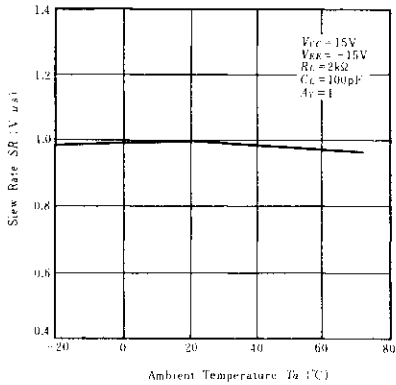
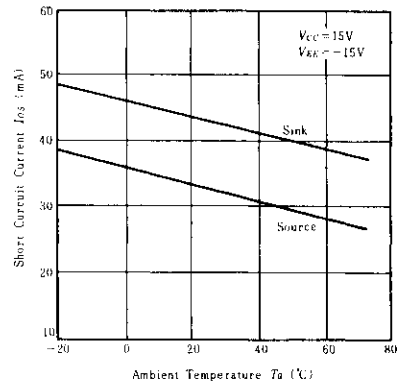
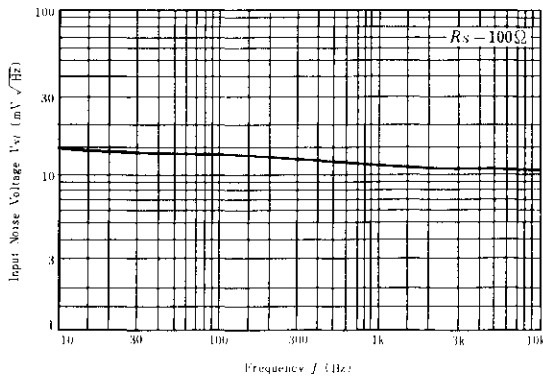
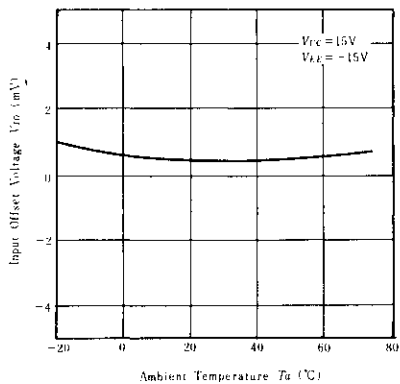
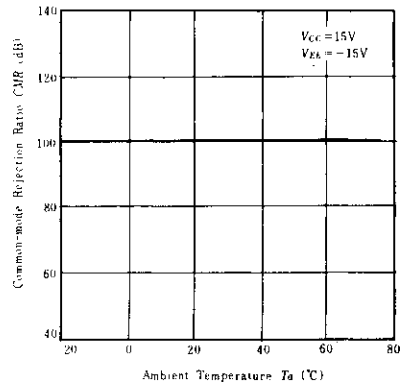
SUPPLY CURRENT VS. SUPPLY VOLTAGE

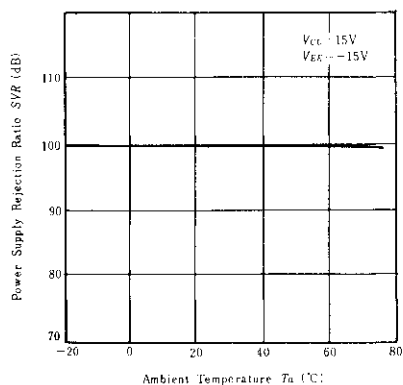
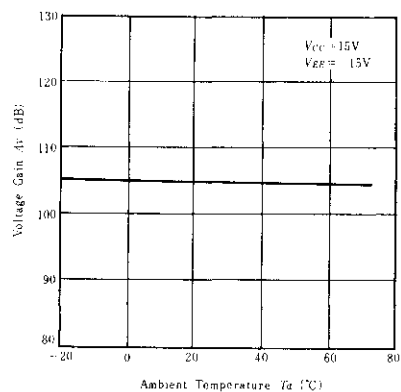
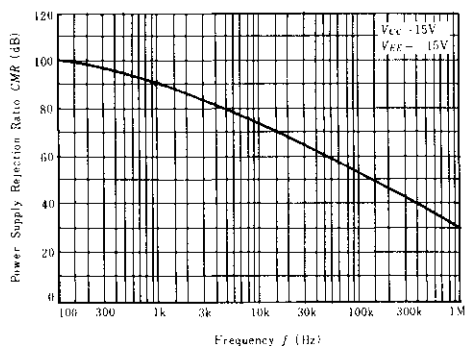
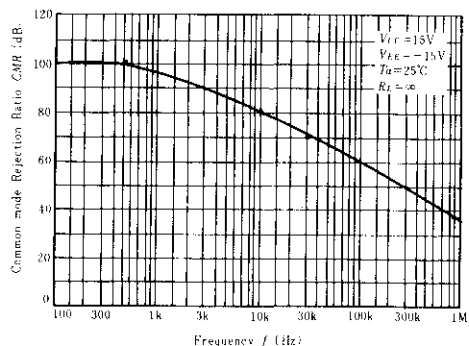


COMMON-MODE INPUT VOLTAGE VS.
SUPPLY VOLTAGEINPUT BIAS CURRENT VS.
AMBIENT TEMPERATURE

SLEW RATE VS. SUPPLY VOLTAGE

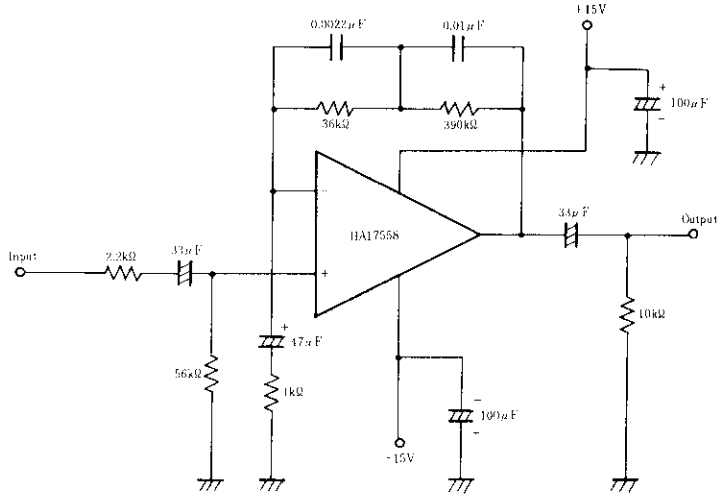
INPUT OFFSET CURRENT VS.
AMBIENT TEMPERATUREINPUT OFFSET VOLTAGE VS.
SUPPLY VOLTAGEVOLTAGE GAIN VS.
SUPPLY VOLTAGE

SLEW RATE VS. AMBIENT TEMPERATURE**SHORT CIRCUIT CURRENT VS. AMBIENT TEMPERATURE****INPUT NOISE VOLTAGE VS. FREQUENCY****INPUT OFFSET VOLTAGE VS. AMBIENT TEMPERATURE****COMMON-MODE REJECTION RATIO VS. AMBIENT TEMPERATURE**

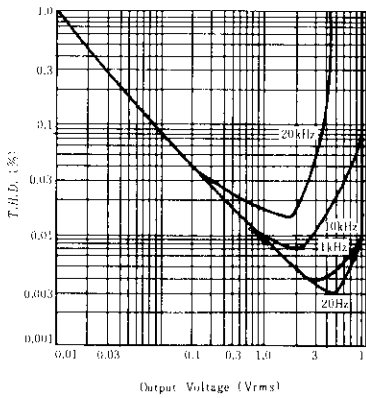
POWER SUPPLY REJECTION RATIO VS. AMBIENT TEMPERATURE**VOLTAGE GAIN VS. AMBIENT TEMPERATURE****POWER SUPPLY REJECTION RATIO VS. FREQUENCY****COMMON-MODE REJECTION RATIO VS. FREQUENCY**

CIRCUIT EXAMPLE

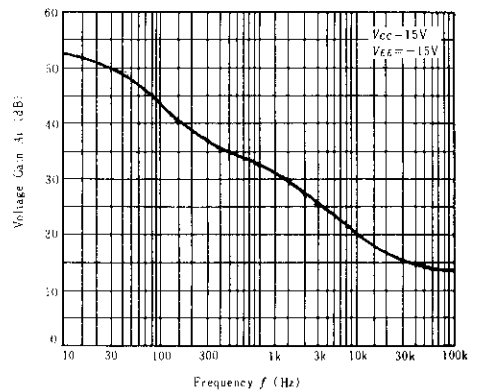
RIAA PRE-AMPLIFIER



T.H.D. VS. OUTPUT VOLTAGE
(RIAA PRE-AMP.)



VOLTAGE GAIN VS. FREQUENCY
(RIAA PRE-AMP.)



HA17904GS, HA17904PS, HA17358

●Dual Operational Amplifier

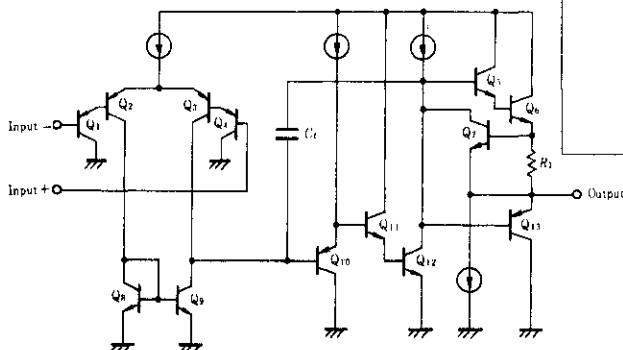
HA17904 is a dual operational amplifier, which provides internal phase compensation and high gain, and mono power source operation is possible. It can be widely applied to control equipment and to general use.

Industrial Use HA17904GS, HA17904PS
Commercial Use HA17358

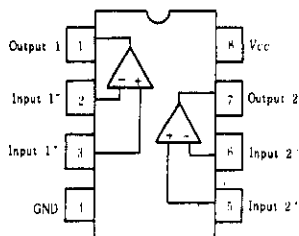
■ FEATURES

- Wide Range of Operating Supply Voltage and Mono Power Source Operation is possible.
- Wide range of Common Mode Input Voltage. Possible to operate with an input around 0V, and output around 0V is available.
- Frequency Characteristics and Input Bias Current are temperature compensated.

■ CIRCUIT SCHEMATIC (1/2)



■ PIN ARRANGEMENT



(Top View)

HA17904GS



(DG-8)

HA17904PS
HA17358



(DP-8)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	1) HA17904GS	2) HA17904PS	3) HA17358	Unit
Supply Voltage	V_{CC}	32	32	32	V
Output Sink Current	I_{out}	50	50	50	mA
Power Dissipation	P_T^*	570	570	570	mW
Common Mode Input Voltage	V_{CM}	0.3 to V_{CC}	0.3 to V_{CC}	0.3 to V_{CC}	V
Differential Input Voltage	$V_{in(diff)}$	$\pm V_{CC}$	$\pm V_{CC}$	$\pm V_{CC}$	V
Operating Temperature	T_{op}	-40 to $+85$	-20 to $+75$	0 to $+70$	$^\circ\text{C}$
Storage Temperature	T_{stg}	65 to $+150$	-55 to $+125$	-55 to $+125$	$^\circ\text{C}$

* 1: Value at $T_a = 75^\circ\text{C}$. In case of more than it, 7.6mW/ $^\circ\text{C}$ derating shall be done in HA17904GS.

2: Value at $T_a = 55^\circ\text{C}$. In case of more than it, 8.3mW/ $^\circ\text{C}$ derating shall be done in HA17904PS and HA17358.

■ ELECTRICAL CHARACTERISTICS ($V_{CC} = 15\text{V}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Test Condition	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$V_{IN} = 7.5\text{V}$, $R_S = 50\Omega$, $R_L = 50\text{k}\Omega$	—	3	7	mV
Input Offset Current	I_{IO}	$V_{IN} = 7.5\text{V}$, $I_{IN} = \{I_{I1}, \dots, I_{I4}\}$	—	5	50	nA
Input Bias Current	I_I	$V_{IN} = 7.5\text{V}$	—	30	250	nA
Power Source Rejection Ratio	$PSRR$	$f = 100\text{Hz}$, $R_S = 1\text{k}\Omega$, $R_L = 100\text{k}\Omega$	—	93	—	dB
Voltage Gain	A_{VS}	$R_L = \infty$, $R_S = 1\text{k}\Omega$, $R_L = 100\text{k}\Omega$	75	90	—	dB
Common Mode Rejection Ratio	CMR	$R_S = 50\Omega$, $R_L = 5\text{k}\Omega$	—	80	—	dB
Common Mode Input Voltage Range	V_{ICM1}	$R_S = 1\text{k}\Omega$, $R_L = 100\text{k}\Omega$	13.5	—	—	V
	V_{ICM2}	$R_S = 1\text{k}\Omega$, $R_L = 100\text{k}\Omega$	—	—	0.3	V
Peak-to-peak Output Voltage	V_{opp}	$f = 100\text{Hz}$, $R_L = 20\text{k}\Omega$, $R_S = 1\text{k}\Omega$, $R_L = 100\text{k}\Omega$	—	13.6	—	V
Output Source Current	$I_{out(s)}$	$V_{IN} = 1\text{V}$, $V_{IN} = 0\text{V}$	20	40	—	mA
Output Sink Current	$I_{out(s)}$	$V_{IN} = 1\text{V}$, $V_{IN} = 0\text{V}$	10	20	—	mA
Output Sink Current	$I_{out(s)}$	$V_{IN} = 1\text{V}$, $V_{IN} = 0\text{V}$, $V_{out} = 200\text{mV}$	15	50	—	μA
Supply Current	I_{CC}	$V_{IN} = \text{GND}$, $R_L = \infty$	—	0.8	2	mA
Power Dissipation at no Load	P_T	$R_L = \infty$, $V_{IN} = \text{GND}$	—	12	30	mW
Slew Rate	SR	$R_L = \infty$, $V_{CM} = 7.5\text{V}$, $f = 1.5\text{kHz}$	—	0.6	—	V/ μs
Channel Separation	V_{ch}/V_{oc}	$f = 1\text{kHz}$	—	65	—	dB

Note: As for the characteristic curve, see the HA17902.

HA17301P, HA17301G ● Quad. Operational Amplifier

HA17301 is a quad. operational amplifier which provides internal phase compensation, and mono power source operation is possible. Generally, it can be used for waveform generator, voltage regulator, logical operation circuit, voltage control oscillator, etc.

■ FEATURES

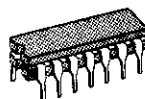
- Wide range of Operating Temperature
- Mono Power Source Operation is possible
- Internal Phase Compensation
- Small Input Bias Current

HA17301P



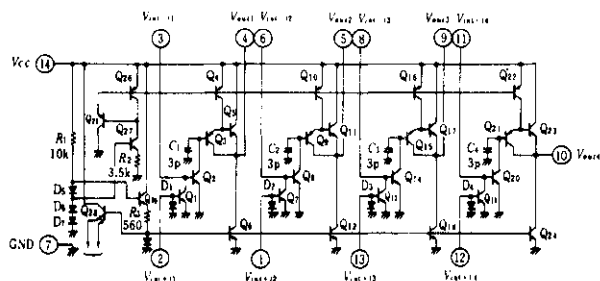
(DP-14)

HA17301G



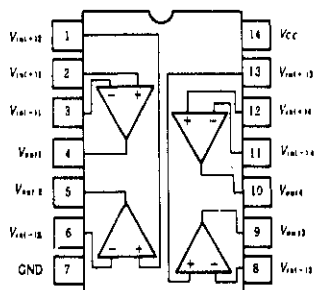
(DG-14)

■ CIRCUIT SCHEMATIC



Note: Eight emitters shall be connected to pin 1, 2, 3, 6, 8, 11, 12 and 13 respectively.

■ PIN ARRANGEMENT



(Top View)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA17301P	HA17301G	Unit
Supply Voltage	V_{CC}	28	28	V
Non-inverted Input Current	I_i	5	5	mA
Sink Current	I_{LSS}	50	50	mA
Source Current	I_{SSS}	50	50	mA
Power Dissipation*	P_d	625	625	mW
Operating Temperature	T_{op}	20 to +75	40 to +85	$^\circ\text{C}$
Storage Temperature	T_{stg}	55 to +125	65 to +150	$^\circ\text{C}$

* In HA17301P, it is a value under $T_a = 50^\circ\text{C}$. In case of more than it, $8.3\text{mW}/^\circ\text{C}$ derating shall be done.

In HA17301G, it is a value under $T_a = 70^\circ\text{C}$. In case of more than it, $7.6\text{mW}/^\circ\text{C}$ derating shall be done.

■ ELECTRICAL CHARACTERISTICS-1 ($V_{CC} = +15\text{V}$, $R_i = 5.0\text{k}\Omega$, $T_a = 25^\circ\text{C}$)

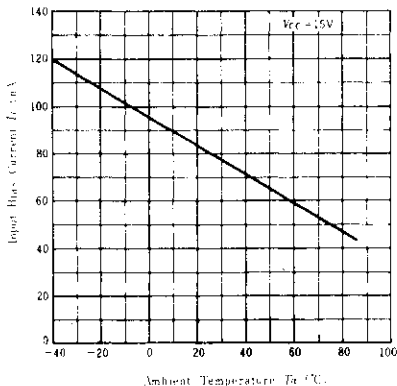
Item	Symbol	Test Condition	min	typ	max	Unit
Voltage Gain	A_{vL}		1000	1400	—	V/V
Supply Voltage	I_{LSS}	Non-inverted input: open	—	7.7	10	mA
	I_{SSS}	Non-inverted input: GND	—	8.3	14	mA
Input Bias Current	I_i	$R_i = 5.0\text{k}\Omega$	—	80	300	nA
Current Mirror Gain	A_i	$I_i = 200\mu\text{A}$	0.80	0.94	1.16	A/A
Source Current	I_{SSS}	$V_{in} = 0.4\text{V}$	3	13	—	mA
		$V_{in} = 9.0\text{V}$	—	10	—	mA
Sink Current	I_{LSS}	$V_{in} = 0.4\text{V}$	0.5	0.75	—	mA
		$V_{in} = 9.0\text{V}$	13.5	13.9	—	V
Output Voltage	V_{out}	Inverted Input Driving	—	0.04	0.1	V
	V_{out}	Non-inverted input Driving	—	0.55	—	V
Output Resistance	R_o	Inverted input Only	0.1	1.0	—	$\text{M}\Omega$
Slew Rate	SR	$C_L = 100\text{pF}$, $R_i = 5.0\text{k}\Omega$	—	0.2	—	V/ μs
Bandwidth	BW	$A_v = 1$	—	2.6	—	MHz
Phase Margin	ϕ_m		—	87	—	deg
Power Source Rejection Ratio	$PSRR$	$f = 100\text{Hz}$	—	63	—	dB
Channel Separation		$V_1/V_2 = f = 1.0\text{kHz}$	—	63	—	dB

■ ELECTRICAL CHARACTERISTICS-2 ($V_{CC} = +15\text{V}$, $R_i = 5.0\text{k}\Omega$, $-40^\circ\text{C} \leq T_a \leq 85^\circ\text{C}$)

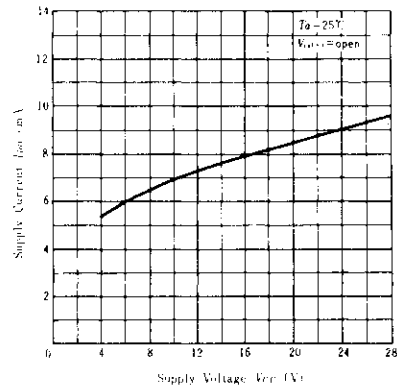
Item	Symbol	Test Condition	min	typ	max	Unit
Voltage Gain	A_{vL}		—	1400	—	V/V
Input Bias Current	I_i		—	80	—	nA
Current Mirror Gain Drift	A_i		—	2.1	—	%

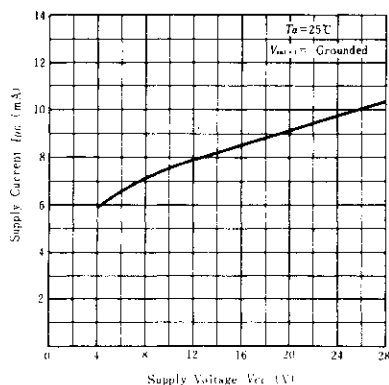
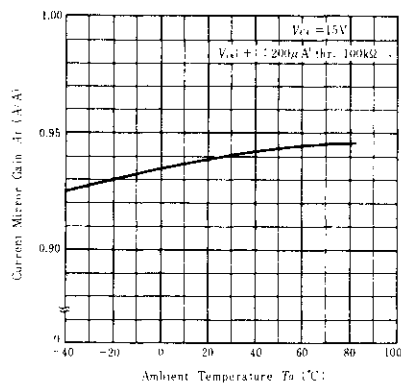
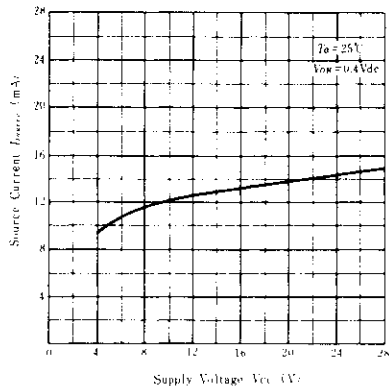
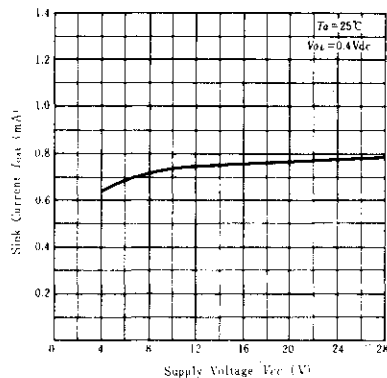
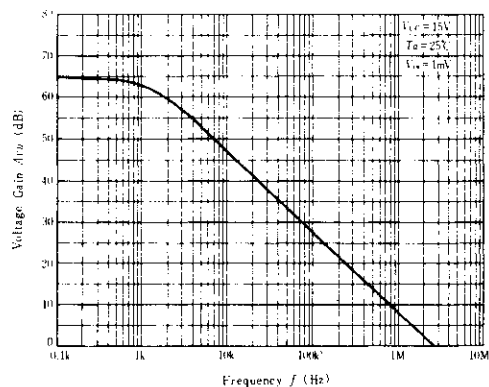
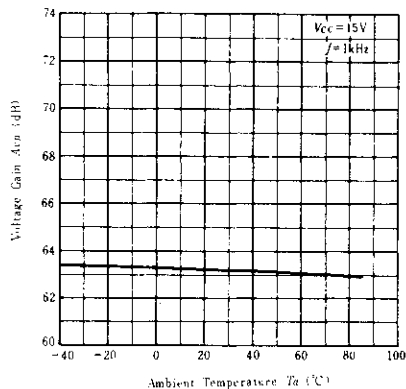
Note: In HA17301P, $V_{CC} = +15\text{V}$, $R_i = 5.0\text{k}\Omega$, $20^\circ\text{C} \leq T_a \leq 75^\circ\text{C}$.

**INPUT BIAS CURRENT VS.
AMBIENT TEMPERATURE**



**SUPPLY CURRENT VS.
SUPPLY VOLTAGE (1)**



**SUPPLY CURRENT VS.
SUPPLY VOLTAGE (2)**

**CURRENT MIRROR GAIN VS.
AMBIENT TEMPERATURE**

**SOURCE CURRENT VS.
SUPPLY VOLTAGE**

SINK CURRENT VS. SUPPLY VOLTAGE

VOLTAGE GAIN VS. FREQUENCY

**VOLTAGE GAIN VS.
AMBIENT TEMPERATURE**


■ HA17301 APPLICATION

HA17301 is a Quad. Operational Amplifier, and it's consisted of four operational amplifiers which operate independently, and a bias circuit. It can be widely used with the features such as wide range of operating temperature, mono power source operation, internal phase compensation, wide 0-cross bandwidth, small input bias current, large open loop voltage gain, etc.

HA17301 applications will be explained below.

1. HA17301 Circuit Operation

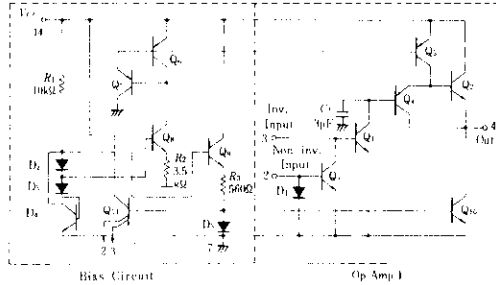


Fig.1 HA17301 Internal Equivalent Circuit

Fig.1 shows HA17301 Internal Equivalent Circuit; Bias Circuit & Operational Amplifier (Op Amp 1).

The Op Amp 1 is a emitter GND type amplifier. The Inversion Amp is consisted of Input Transistor (Q1), Buffer Transistor (Q4), Current Source Transistor (Q5), Output Emitter Follower Transistor (Q2) and Current Source Transistor (Q10). In this circuit, the voltage gain is all depend on TRS Q1, and large open loop gain will be obtained by current source load Q5, even if the supply voltage is small. Emitter Follower TRS Q2 lowers the input impedance. Using the Power Source TRS Q10 for load of Q2 enables to get very large dynamic range, which is actually from GND to (Vcc-1).

Buffer TRS Q4 is to lower the input current without raising the DC input voltage level. When the inversion amp is used in closed circuit, capacitor C1 is provided to keep the circuit stable, so no external compensation is required.

Next, we would like to look at Non-inverted Input.

The current flowing into a non-inverted input is, if current amplification of Q3 is large enough, flown through diode D1. The input current causes voltage drop at D1, which will be added to base-emitter junction of Q3. Therefore, if D1 and Q3 are matching, the current flown to Q3 emitter is the same as the input current. And if the current amplification of Q3 is large enough, the same current as the input current is flown to Q3 collector. This is known as "Current Mirror". When using an external feedback resistor, the same current as the non-inverted input current is flown to it, and the output voltage can be established.

Finally, we would like to explain a Bias Circuit. This circuit is to give bias voltage to current source Q5 and Q10 of operational amp, in which reference voltage is voltage drop of D2, D3 and D4.

Emitter current of Q8 (I_{E8}) is;

$$I_{E8} = \frac{V_{D3} + V_{D4} - V_{BE8}}{R_2} \quad (1)$$

where; V_{D3} voltage drop of D3
 V_{D4} voltage drop of D4
 V_{BE8} V_{BE} of Q8

When these elements are all matching;

$$V_{D3} = V_{D4} = V_{BE8} = V_{BE} \quad (2)$$

$$\therefore I_{E8} = \frac{V_{BE}}{R_2} \quad (3)$$

PNP Current Source Q5 will be set to be V_{BE}/R_2 by Q6. Emitter current of Q9 (I_{E9}) is;

$$I_{E9} = \frac{V_{D2} + V_{D3} + V_{D4} - V_{D5} - V_{BE9}}{R_1} \quad (4)$$

When these elements are all matching;

$$V_{D2} = V_{D3} = V_{D4} = V_{D5} = V_{BE9} = V_{BE} \quad (5)$$

$$\therefore I_{E9} = \frac{V_{BE}}{R_3} \quad (6)$$

NPN Current Source Q10 will be set to be V_{BE}/R_3 by D5. The most important feature of this bias circuit is that the value of current source is not depend on the supply voltage. Q11 is used for protection when a negative signal is applied.

2. Inversion Amplifier

Biasing of Inversion Amplifier can be performed by one of the following three methods; mono power source biasing method, NV_{BE} biasing method and negative voltage biasing method.

2.1 Mono Power Source Biasing Method

Fig.2 shows an AC amp biased with the power source which is used for amp operation.

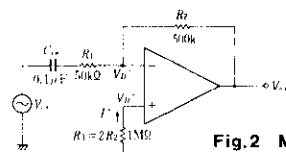


Fig.2 Mono Power Source Biasing Method

$$\frac{V_{out}}{V_{in}} = -\frac{R_2}{R_1} \quad (7)$$

2.2 NV_{BE} Biasing Method

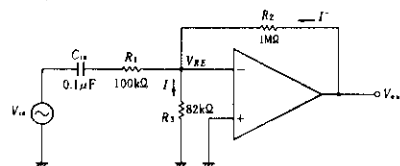


Fig.3 NV_{BE} Biasing Method

This is the most useful application of Inversion AC Amplifier. Bias voltage of the inverted input (V_{BE}) is determined by the current flowing through resistor R_3 to GND.

$$\frac{V_{out}}{V_{in}} = -\frac{R_2}{R_1} \quad (8)$$

3. Triangular Wave Generator

A triangular wave is made by integrating an AC voltage (in which positive & negative values are repeating one after the other). The relation between the input and the output is shown below.

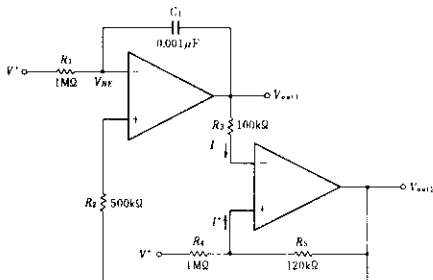


Fig.4 Triangular Wave Generator

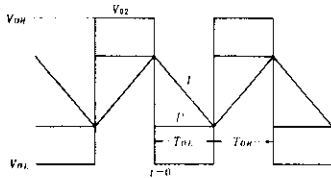


Fig.5 Operation of Triangular Wave Generator

$$T_{OL} = \frac{C_1 R_1 R_3 V_{OH}}{R_2 (V^+ - V_{BE})} \quad (9)$$

$$T_{OH} = \frac{C_1 R_3 V^+}{R_2 \left(\frac{V_{OH}}{R_2} - \frac{V^+ - V_{BE}}{R_1} \right)} \quad (10)$$

Under the conditions of $R_1 = 2R_2$, $V_{OH} = V^+$, $V^+ \gg V_{BE}$:

$$T_{OH} + T_{OL} = \frac{2C_1 R_1 R_3}{R_5} \quad (11)$$

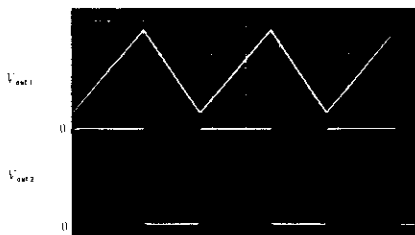


Fig.6 Operation Waveform of Triangular Wave Generator

Table 1

	Item	Test Condition	Measured Value	Calculated Value	Unit
Triangular Wave Generator	T_{OH}	$V_{CC} = 15V$, $V^+ = 15V$, $C_1 = 0.001 \mu F$, $R_1 = 1M\Omega$, $R_2 = 500k\Omega$, $R_3 = 100k\Omega$, $R_4 = 1M\Omega$, $R_5 = 120k\Omega$, Fig. 4	1.06	0.83	ms
	T_{OL}		0.82	0.83	ms
	V_{OH}		13.5	14	V
	V_{out}		1.5	1.5	V

4. Comparator

We would like to show applications of HA17301 to comparators; Positive Input Voltage Comparator, Negative Input Voltage Comparator and Power Comparator.

4.1 Positive Input Voltage Comparator

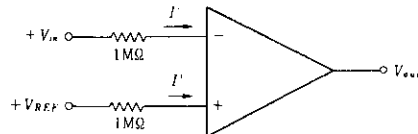


Fig.7 Positive Input Voltage Comparator

V_{out} is equal to V_{OH} under $I^- < I^+$, and V_{out} is equal to V_{OL} under $I^- > I^+$. For normal operation, the reference voltage should be more than V_{BE} .

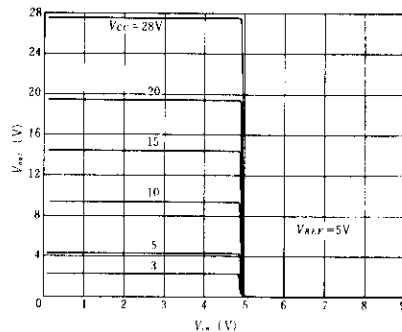


Fig.8 Operation Characteristics of Positive Input Voltage Comparator (1)

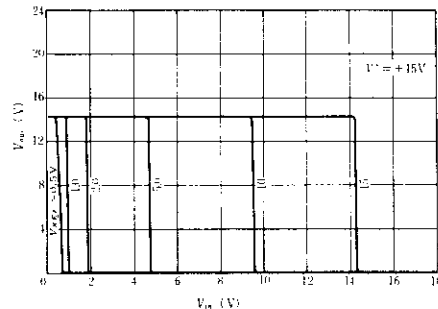


Fig.9 Operation Characteristics of Positive Input Voltage Comparator (2)

4.2 Negative Input Voltage Comparator

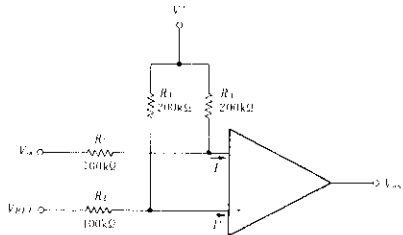


Fig.10 Negative Input Voltage Comparator

$$V_{IN} > R_1 \left\{ V_{REF} \left(\frac{1}{R_1} + \frac{1}{R_2} \right) - \frac{V^+}{R_4} \right\} \dots \dots \dots (12)$$

$$V_{REF} > R_2 \left\{ V_{REF} \left(\frac{1}{R_2} + \frac{1}{R_3} \right) - \frac{V^-}{R_3} \right\} \dots \dots \dots (13)$$

When using resistor R_4 and R_3 which meet Equation (12) and (13) respectively, negative values of V_{IN} and V_{REF} are available. As same as in the positive input voltage comparator, V_{out} is equal to V_{OH} under $I^- < I^+$ and V_{out} is equal to V_{OL} under $I^- > I^+$.

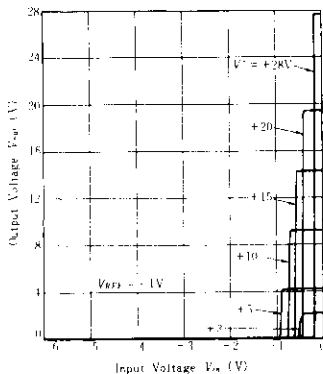


Fig.11 Operation Characteristics of Negative Input Comparator (1)

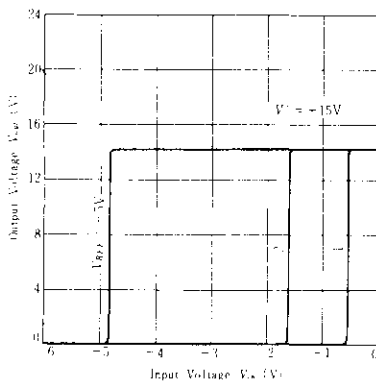


Fig.12 Operation Characteristics of Negative Input Comparator (2)

4.3 Power Comparator

By adding a TRS externally, a load that requires a current larger than the output current of HA17301 can be connected as shown below.

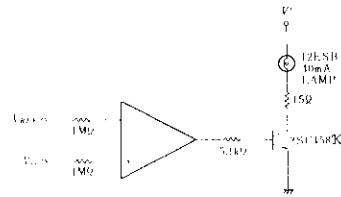


Fig.13 Power Comparator

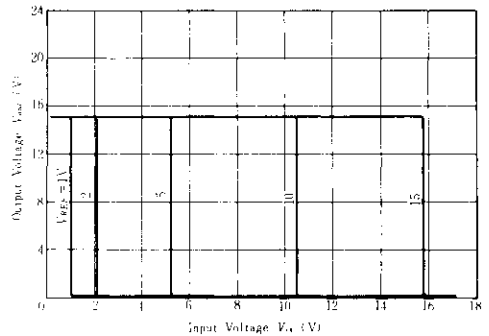


Fig.14 Operation Characteristics of Power Comparator $V_{CC} = 15V$

HA17324G, HA17324P, HA17324

● Quad. Operational Amplifier

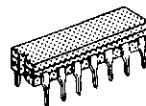
HA17324 is Quad. Operational Amplifier that provide high gain and internal phase compensation, and mono power source operation is possible. They can be widely used to control equipments.

Industrial use HA17324G, HA17324P
Commercial use; HA17324

■ FEATUERS

- Wide range of supply voltage, and mono power source operation is possible.
- Internal Phase Compensation
- Wide range of common mode voltage, and possible to operate with an input about 0V.
- Frequency and input bias current are temperature compensated.

HA17324G



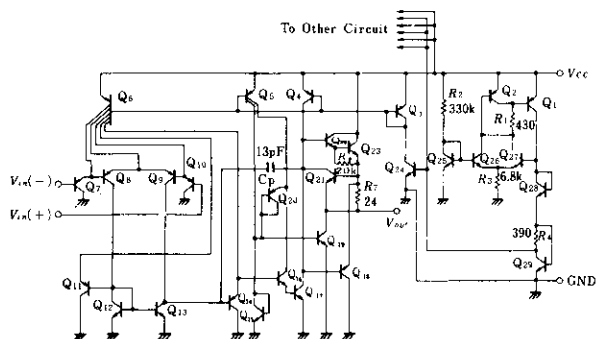
(DG-14)

HA17324P
HA17324

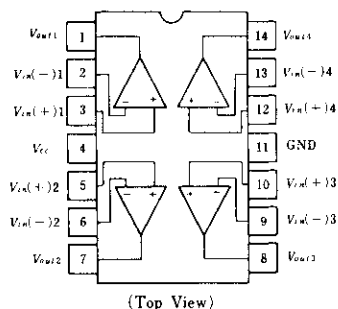


(DP-14)

■ CIRCUIT SCHEMATIC (1/4)



■ PIN ARRANGEMENT



■ ABSOLUTE MAXIMUM RATING ($T_a=25^{\circ}\text{C}$)

Item	Symbol	1) HA17324G	2) HA17324P	2) HA17324	Unit
Supply Voltage	V_{CC}	32	32	32	V
Sink Current	I_{out}	50	50	50	mA
Power Dissipation	P_T^*	625	625	625	mW
Common Mode Input Voltage	V_{CM}	-0.3 to V_{CC}	-0.3 to V_{CC}	-0.3 to V_{CC}	V
Differential Input Voltage	$V_{in(dif)}$	$\pm V_{CC}$	$\pm V_{CC}$	$\pm V_{CC}$	V
Operating Temperature	T_{op}	-20 to +75	-20 to +75	0 to +70	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-60 to +150	55 to +125	-55 to +125	$^{\circ}\text{C}$

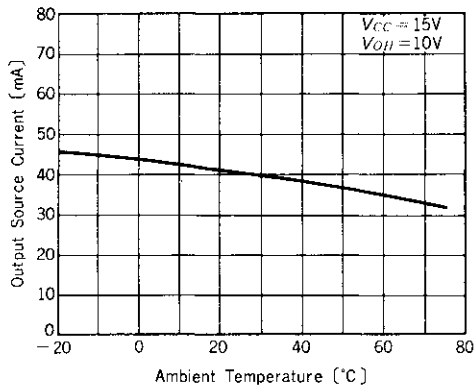
* 1): Value under $T_a=70^{\circ}\text{C}$. In case of more than it, 7.6mW/ $^{\circ}\text{C}$ derating shall be done.

2): Value under $T_a=50^{\circ}\text{C}$. In case of more than it, 8.3mW/ $^{\circ}\text{C}$ derating shall be done.

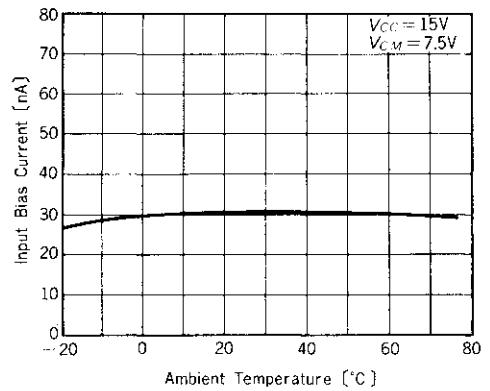
■ ELECTRICAL CHARACTERISTICS ($V_{CC}=+15\text{V}$, $T_a=25^{\circ}\text{C}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Offset Voltage	V_{io}	$V_{CM}=7.5\text{V}$, $R_S=50\Omega$, $R_f=50\text{k}\Omega$	—	2	7	mV
Input Offset Current	I_{io}	$I_{io}= I_{I1}-I_{I2} $, $V_{CM}=7.5\text{V}$	—	5	50	nA
Input Bias Current	I_I	$V_{CM}=7.5\text{V}$	—	30	500	nA
Power Source Rejection Ratio	$PSRR$	$f=100\text{Hz}$, $R_S=1\text{k}\Omega$, $R_f=100\text{k}\Omega$	—	93	—	dB
Voltage Gain	A_{VD}	$R_S=1\text{k}\Omega$, $R_f=100\text{k}\Omega$, $R_L=\infty$	75	90	—	dB
Common Mode Rejection Ratio	CMR	$R_S=50\Omega$, $R_f=5\text{k}\Omega$	—	80	—	dB
Common Mode Input Voltage Range	V_{CM}	$R_S=1\text{k}\Omega$, $R_f=100\text{k}\Omega$, $f=100\text{Hz}$	-0.3	—	13.5	V
Peak-to-peak Output Voltage	V_{opp}	$f=100\text{Hz}$, $R_S=1\text{k}\Omega$, $R_f=100\text{k}\Omega$, $R_L=20\text{k}\Omega$	—	13.6	—	V
Output Source Current	$I_{out(s)}$	$V_{in}=1\text{V}$, $V_{os}=0\text{V}$	20	40	—	mA
Output Sink Current	$I_{out(s)}$	$V_{in}=0\text{V}$, $V_{os}=1\text{V}$	10	20	—	mA
Supply Current	I_{CC}	$V_{in}=\text{GND}$, $R_L=\infty$	—	0.8	2	mA
Power Dissipation	P_T	$R_L=\infty$, $V_{in}=\text{GND}$	—	12	30	mW
Slew Rate	SR	$f=1.5\text{kHz}$, $V_{CM}=7.5\text{V}$, $R_L=\infty$	—	0.19	—	V/ μs
Channel Separation	V_{cl}/V_{cl}	$f=1\text{kHz}$	—	65	—	dB
Output Sink Current	I_{out}	$V_{in}=0\text{V}$, $V_{os}=1\text{V}$, $V_{os}=200\text{mV}$	15	50	—	μA

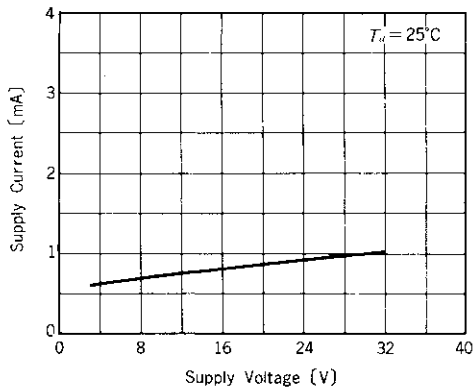
Output Source Current vs Ambient Temperature



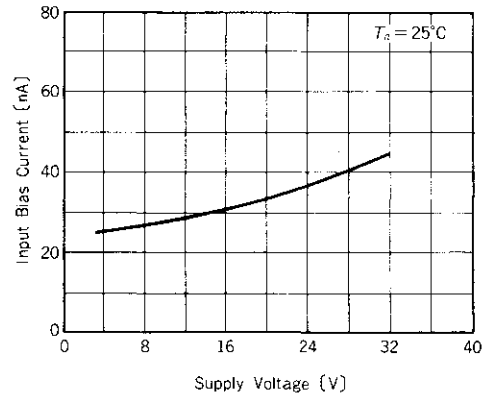
Input Bias Current vs Ambient Temperature.



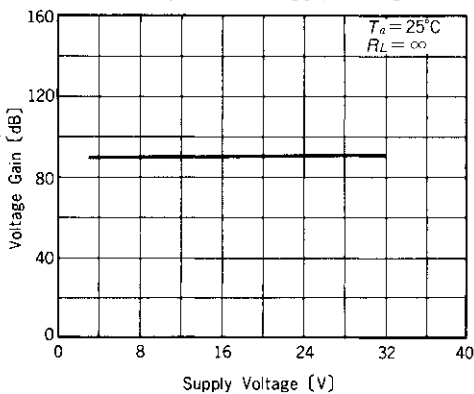
Supply Current vs Supply Voltage.



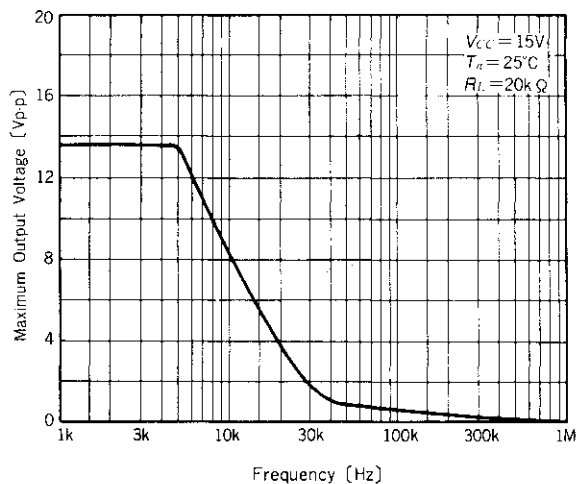
Input Bias Current vs Supply Voltage



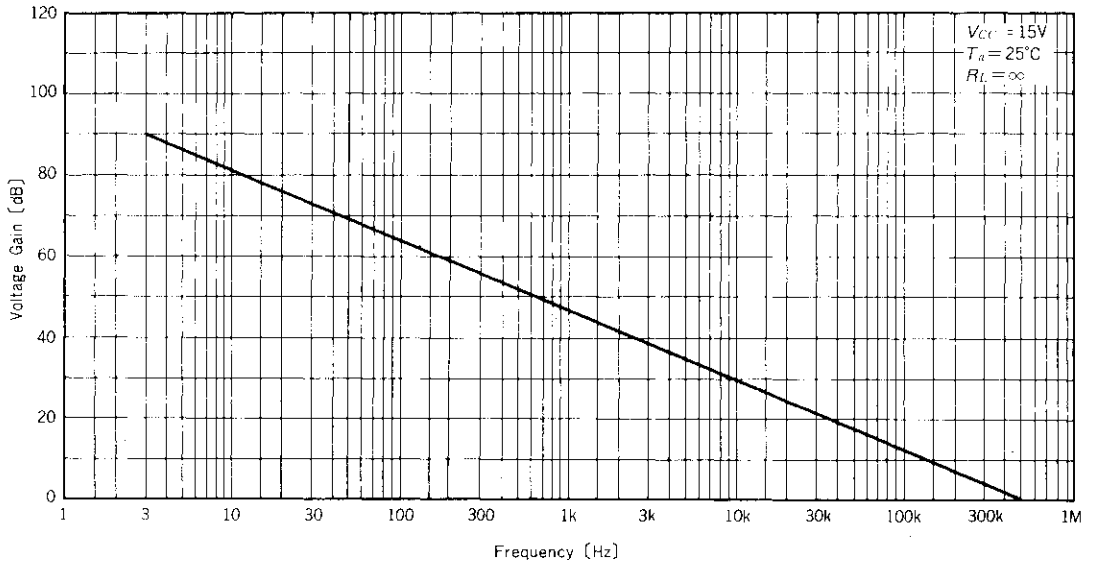
Voltage Gain vs Supply Voltage



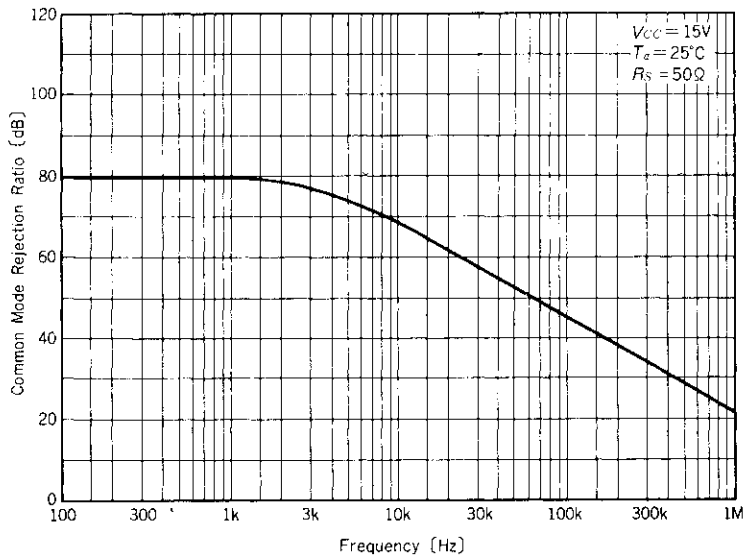
Maximum Output Voltage vs Frequency



Voltage Gain vs Frequency



Common Mode Rejection Ratio vs Frequency



HA17902G, HA17902P, HA17902 ●Quad. Operational Amplifier

HA17902 is Quad. Operational Amplifier that provide high gain and internal phase compensation, and mono power source operation is possible. They can be widely used to control equipments.

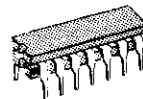
Industrial Use; HA17902G, HA17902P

Commercial Use; HA17902

■FEATURES

- Wide range of supply voltage, and mono power source operation is possible.
- Internal Phase Compensation
- Wide range of common mode voltage, and possible to operate with an input about 0V.
- Frequency and input bias current are temperature compensated.

HA17902G



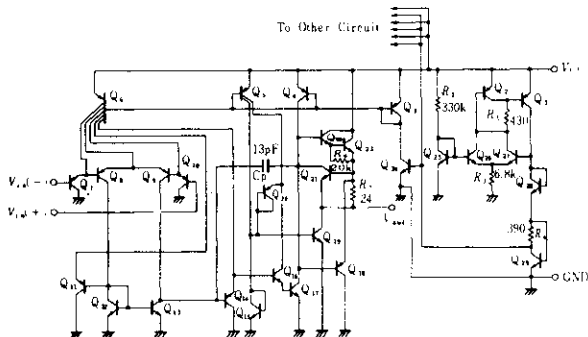
(DG-14)

HA17902P
HA17902

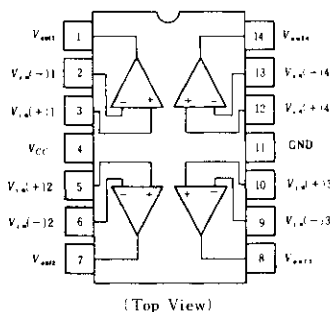


(DP-14)

■CIRCUIT SCHEMATIC(1/4)



■PIN ARRANGEMENT



■ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Item	Symbol	1 HA17902G	2 HA17902P	3 HA17902	Unit
Supply Voltage	V_{CC}	28	28	28	V
Sink Current	I_{sink}	50	50	50	mA
Power Dissipation	P_T^*	625	625	625	mW
Common Mode Input Voltage	V_{CM}	0.3 to V_{CC}	-0.3 to V_{CC}	-0.3 to V_{CC}	V
Differential Input Voltage	V_{id}	$\pm V_{CC}$	$\pm V_{CC}$	$\pm V_{CC}$	V
Operating Temperature	T_{op}	-40 to +85	-20 to +75	0 to +70	°C
Storage Temperature	T_{stg}	60 to +150	55 to +125	55 to +125	°C

* 1): Value under $T_a \leq 70^\circ\text{C}$. In case of more than it, 7.6mW/°C derating shall be done.

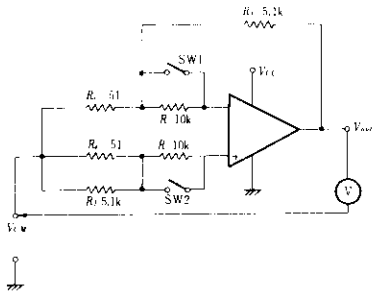
2): Value under $T_a \leq 50^\circ\text{C}$. In case of more than it, 8.3mW/°C derating shall be done.

■ ELECTRICAL CHARACTERISTICS ($V_{CC} = +15V$, $T_a = 25^\circ C$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$V_{CM} = 7.5V$, $R_S = 50\Omega$, $R_f = 50k\Omega$	—	3	8	mV
Input Offset Current	I_{IO}	$I_{IO} = I_{I1} - I_{I2} $, $V_{CM} = 7.5V$	—	5	50	nA
Input Bias Current	I_I	$V_{CM} = 7.5V$	—	30	500	nA
Power Source Rejection Ratio	$PSRR$	$f = 100Hz$, $R_S = 1k\Omega$, $R_f = 100k\Omega$	—	93	—	dB
Voltage Gain	A_{V0}	$R_S = 1k\Omega$, $R_f = 100k\Omega$, $R_L = \infty$	75	90	—	dB
Common Mode Rejection Ratio	CMR	$R_S = 50\Omega$, $R_f = 5k\Omega$	—	80	—	dB
Common Mode Input Voltage Range	V_{CM}	$R_S = 1k\Omega$, $R_f = 100k\Omega$, $f = 100Hz$	-0.3	—	13.5	V
Peak-to-peak Output Voltage	V_{opp}	$f = 100Hz$, $R_S = 1k\Omega$, $R_f = 100k\Omega$, $R_L = 20k\Omega$	—	13.6	—	V
Output Voltage	V_{OH1}	$I_{OH} = -1mA$	13.2	13.6	—	V
	V_{OH2}	$I_{OH} = -10mA$	12	13.3	—	V
	V_{OL1}	$I_{OL} = 1mA$	—	0.8	1	V
	V_{OL2}	$I_{OL} = 10mA$	—	1.1	1.8	V
Output Source Current	I_{source}	$V_{OH} = 10V$	15	40	—	mA
Output Sink Current	I_{sink}	$V_{OL} = 1V$	3	9	—	mA
Supply Current	I_{CC}	$V_{in} = GND$, $R_f = \infty$	—	0.8	2	mA
Power Dissipation	P_T	$R_L = \infty$, $V_{in} = GND$	—	12	30	mW
Slew Rate	SR	$f = 1.5kHz$, $V_{in} = 7.5V$, $R_L = \infty$	—	0.6	—	V/ μs
Channel Separation	V_{d1}/V_{d2}	$f = 1kHz$	—	65	—	dB

■ TEST CIRCUIT

1. Input Offset Voltage (V_{IO}), Input Offset Current (I_{IO}), Input Bias Current (I_I)



SW 1	SW 2	V_O
ON	ON	V_{O1}
OFF	OFF	V_{O2}
ON	OFF	V_{O3}
OFF	ON	V_{O4}

$$V_{CM} = \frac{1}{2} V_{CC}$$

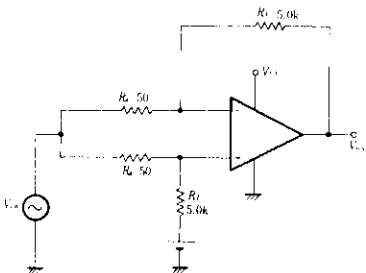
$$(1) V_{IO} = \frac{V_{O1}}{1 + R_f/R_S} \quad (V)$$

$$(2) I_{IO} = \frac{V_{O2} - V_{O1}}{R(1 + R_f/R_S)} \quad (A)$$

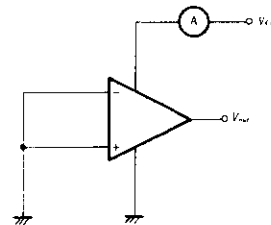
$$(3) I_I = \frac{|V_{O4} - V_{O3}|}{2 \cdot R(1 + R_f/R_S)} \quad (A)$$

2. Common Mode Input Rejection Ratio (CMR)

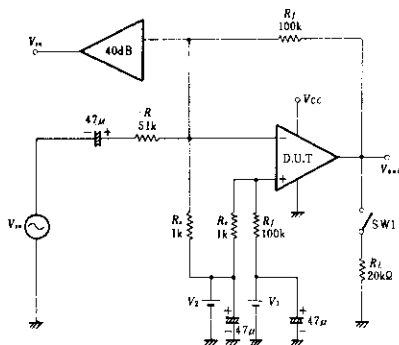
$$CMR = 20 \log \frac{V_{IS} \cdot R_f}{V_{IO} \cdot R_S} \quad (dB)$$



3. Supply Current (I_{CC})



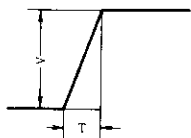
4. Voltage Gain (A_{VD}), Slew Rate (S.R.), Common Mode Input Voltage Range (V_{CM}), Peak-to-peak Output Voltage Range (V_{OPP})



- (1) A_{VD} : $R_S=1k\Omega$, $R_f=100k\Omega$, $R_L=\infty$,
 $V_1=V_2=\frac{1}{2}V_{CC}$

$$A_{VD} = 20 \log \frac{V_O}{V_{IN}} + 40 \text{ (dB)}$$

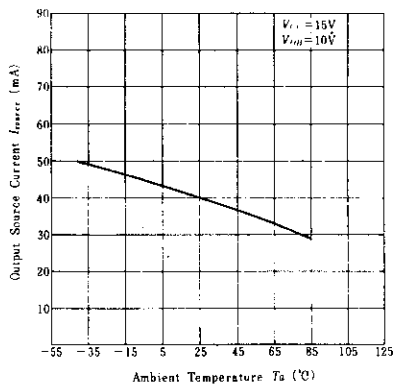
- (2) SR : $f=1.5kHz$, $R_L=\infty$,
 $V_1=V_2=\frac{1}{2}V_{CC}$



$$SR = \frac{V}{T} \text{ [V/}\mu\text{s]}$$

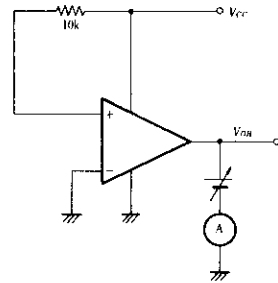
- (3) V_{CM} : $R_S=1k\Omega$, $R_f=100k\Omega$, $f=100Hz$,
 $V_1=\frac{1}{2}V_{CC}$, $R_L=\infty$, value of V_2 just before the waveform changes. $V_{CM(+)}$, $V_{CM(-)}$
- (4) V_{OPP} : $R_S=1k\Omega$, $R_f=100k\Omega$, $R_L=20k\Omega$,
 $f=100Hz$, $V_{OPP}=V_{OH} \leftrightarrow V_{OL}$ [V_{P-P}]

OUTPUT SOURCE CURRENT VS. AMBIENT TEMPERATURE



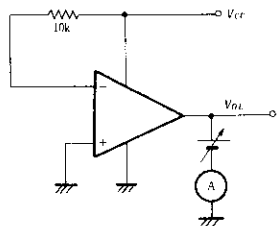
5. Output Source Current (I_{source})

$$I_{source} : V_{OH}=10V$$

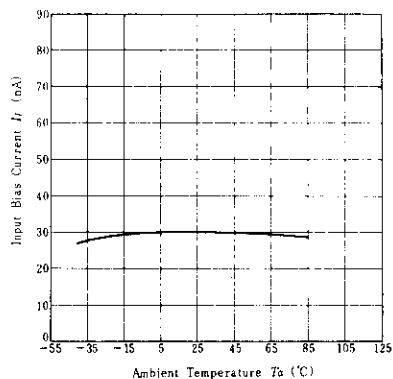


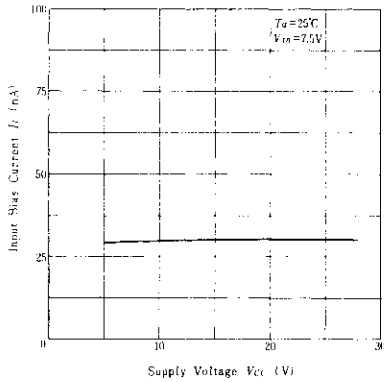
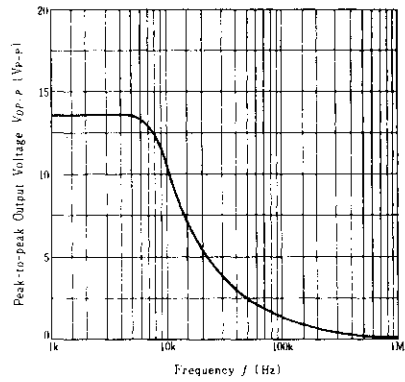
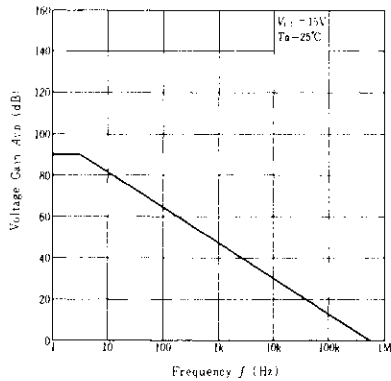
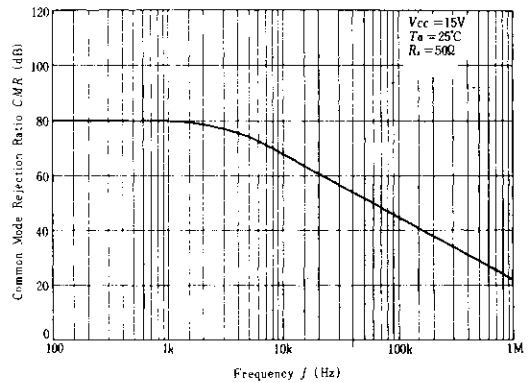
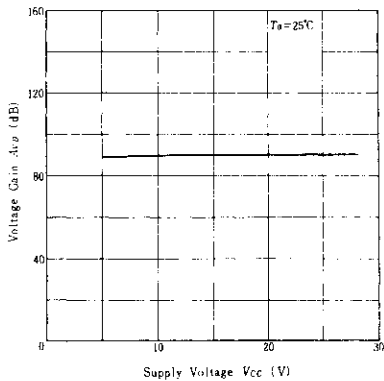
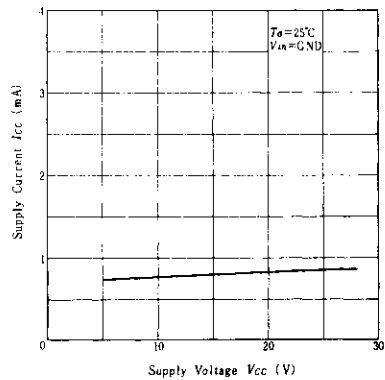
6. Output Sink Current (I_{sink})

$$I_{sink} : V_{OL}=1V$$



INPUT BIAS CURRENT VS. AMBIENT TEMPERATURE



INPUT BIAS CURRENT VS. SUPPLY VOLTAGE**PEAK-TO-PEAK OUTPUT VOLTAGE VS. FREQUENCY****VOLTAGE GAIN VS. FREQUENCY****COMMON MODE REJECTION RATIO VS. FREQUENCY****VOLTAGE GAIN VS. SUPPLY VOLTAGE****SUPPLY CURRENT VS. SUPPLY VOLTAGE**

■ HA17902 APPLICATION

HA17902 is a Quad. Operational Amplifier, and it's consisted of four operational amplifiers which operate independently, and a bias circuit. It can be widely used with the features such as wide range of operating temperature, mono power source operation, internal compensation, wide 0-cross bandwidth, small input bias current, large open loop voltage gain, etc. HA17902 applications will be explained below.

1. Non-inverted Amplifier

Fig.1 shows a non-inverted amplifier.

Voltage gain of the circuit is;
$$\frac{V_{out}}{V_{in}} = 1 + \frac{R_2}{R_1}$$

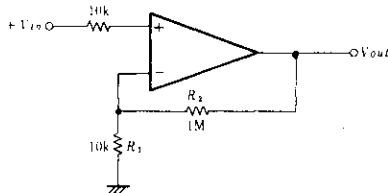


Fig.1 Non-inverted Amplifier

2. Adding & Subtracting Amplifier

In Fig.2, input +V1 and +V2 are applied to non-inversion circuit and input +V3 and +V4 are to inversion circuit.

The output is; $V_{out} = V_1 + V_2 - V_3 - V_4$

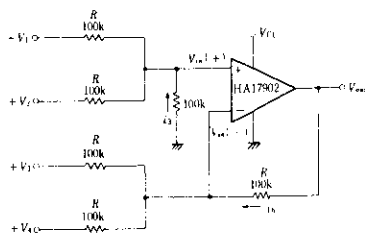


Fig.2 Adding & Subtracting Amplifier

3. High Input Impedance DC Differential Amplifier

Fig.3 shows a High Input Impedance DC Differential Amplifier which is consisted of two non-inverted amplifiers connected in cascade. The common mode rejection ratio (CMR) is depend on the matching of R_1/R_3 and R_4/R_3 .

The output is;

$$V_{out} = \left(1 + \frac{R_4}{R_3}\right) (V_2 - V_1)$$

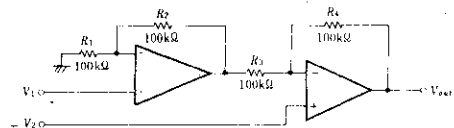


Fig.3 High Input Impedance DC Differential Amplifier

4. Voltage Control Generator

In Fig.4, Amp A_1 , A_2 and TRS Q_1 operate as an integrator, a comparator and a switch for control of oscillation frequency, respectively.

When V_{out1} is in "LOW" level, TRS Q_1 is cut off. The potential of inverted input of A_1 becomes higher than that of non-inverted input, and the output of A_1 will be integrated to be the "LOW" level.

When the output of integrator A_1 becomes smaller than the non-inverted input of comparator A_2 ($V_{cc}/2$), output of the comparator will be "HIGH" level and TRS Q_1 will turn ON. Then the output of A_1 will be integrated to be "HIGH" level.

In this way, a square wave and a triangular wave are generated at V_{out1} and V_{out2} respectively.

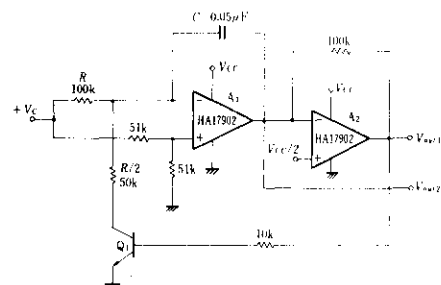


Fig.4 Voltage Control Oscillator

Voltage Comparators

HA1807, HA1813PS

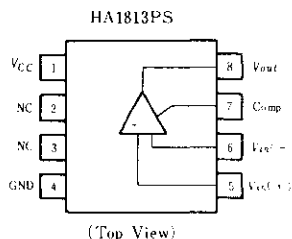
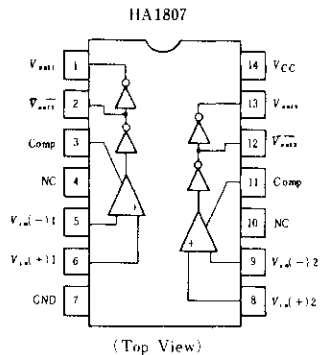
● Voltage Comparator

HA1807, Dual Comparator, and HA1813PS, Single Comparator, can be widely applied to control equipments, since they operate with a single power source.

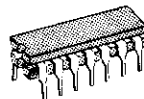
■ FEATURES

- Operate with single power source.
- Provide complementary outputs (V_{out} and $\bar{V}_{out}$) (HA1807)
- Common mode input voltage range is wide.

■ PIN ARRANGEMENT



HA1807



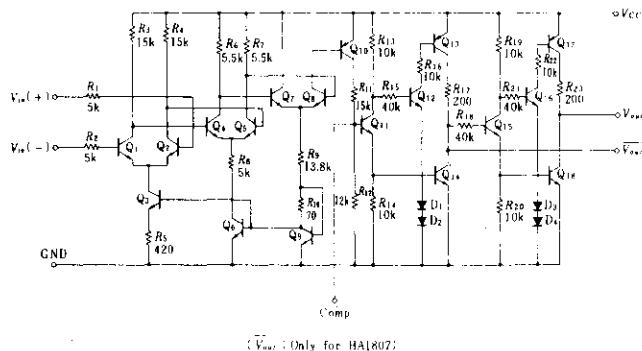
(DG-14)

HA1813PS



(DG-8)

■ CIRCUIT SCHEMATIC



■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA1807	HA1813PS	Unit
Supply Voltage	V_{CC}	18	18	V
Power Dissipation	P_T^*	500	500	mW
Common Mode Input Voltage	V_{CM}	V_{CC}	V_{CC}	V
Differential Input Voltage	$V_{in(diff)}^{**}$	± 10	± 10	V
Operating Temperature	T_{SO}	-30 to $+80$	-20 to $+75$	$^\circ\text{C}$
Storage Temperature	T_{stg}	65 to ± 150	55 to ± 125	$^\circ\text{C}$

Note: * HA1807: Value at $T_a = 70^\circ\text{C}$. In case of more than it, 7.6mW/ $^\circ\text{C}$ derating shall be performed.

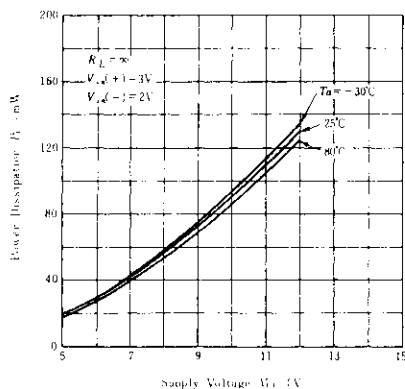
HA1813PS: Value at $T_a = 50^\circ\text{C}$. In case of more than it, 8.3mW/ $^\circ\text{C}$ derating shall be performed.

** Value at $V_{CC} = 10\text{V}$. In case of $V_{CC} = 10\text{V}$, $V_{in(diff)} = V_{CC}$.

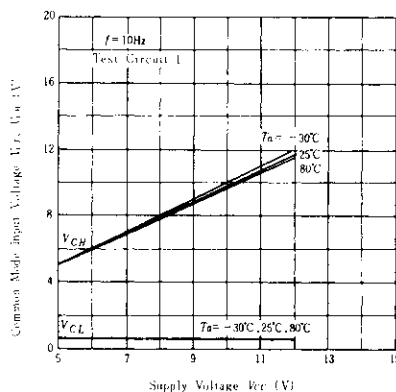
■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

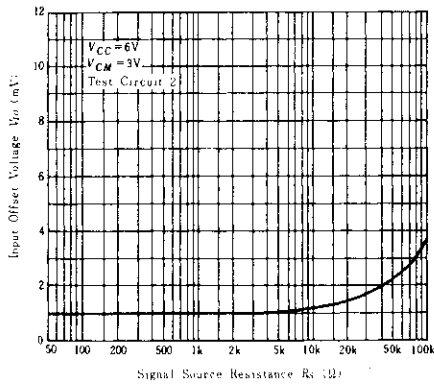
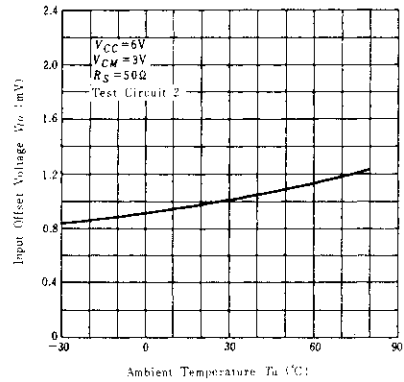
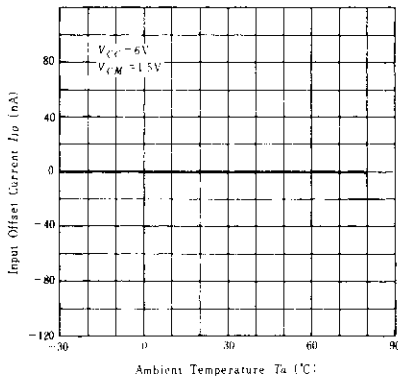
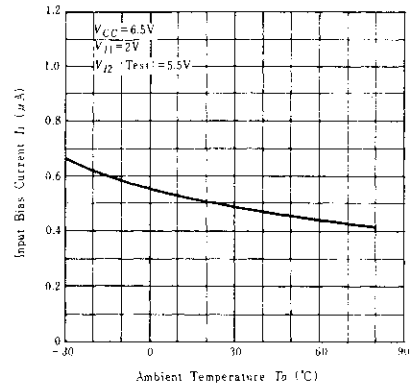
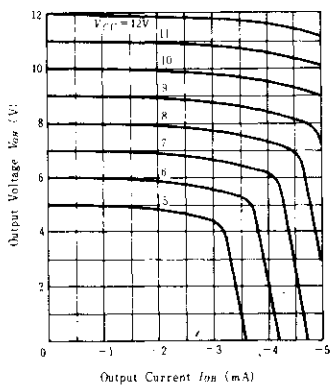
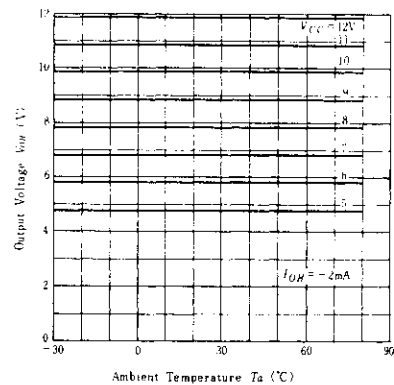
Item	Symbol	Test Condition	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$V_{CC} = 6\text{V}$, $V_{CM} = 3\text{V}$, $R_s = 50\Omega$	—	1	5	mV
Input Offset Current	I_{IO}	$V_{CC} = 6\text{V}$, $V_{CM} = 1.5\text{V}$	—	—	150	nA
Voltage Gain	A_v	$V_{CC} = 5.5\text{V}$, $f = 10\text{Hz}$	75	100	—	dB
Input Bias Current	I_b	$V_{CC} = 6.5\text{V}$, $V_{IO} = 2\text{V}$, $V_{CM(max)} = 5.5\text{V}$	—	0.5	3	μA
Common Mode Input Voltage	V_{CM}	$V_{CC} = 6.5\text{V}$, $f = 10\text{Hz}$	5.5	6.4	—	V
	V_{CL}		—	0.6	1	V
Output Voltage	V_{OH}	$V_{CC} = 5.5\text{V}$, $I_{OH} = 2\text{mA}$	4	5.3	—	V
	V_{OL}	$V_{CC} = 5.5\text{V}$, $I_{OL} = 10\text{mA}$	—	0.2	0.4	V
Power Dissipation	P_T	$V_{CC} = 6.5\text{V}$, $V_{CL} = 3\text{V}$, $V_{OL} = 2\text{V}$, $R_s = 50\Omega$	—	36	48.8	mW

**POWER DISSIPATION VS.
SUPPLY VOLTAGE**

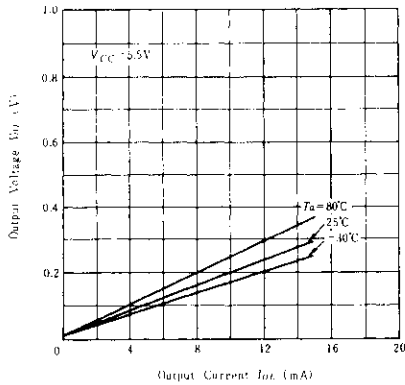


**COMMON MODE INPUT VOLTAGE
VS. SUPPLY VOLTAGE**

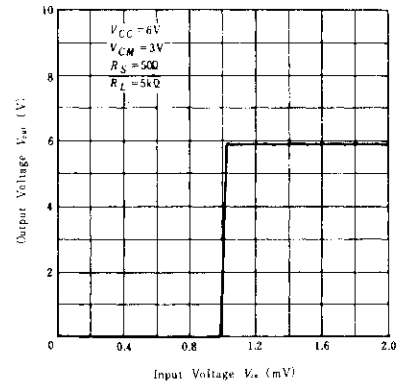


INPUT OFFSET VOLTAGE VS. SIGNAL SOURCE RESISTANCE**INPUT OFFSET VOLTAGE VS. AMBIENT TEMPERATURE****INPUT OFFSET CURRENT VS. AMBIENT TEMPERATURE****INPUT BIAS CURRENT VS. AMBIENT TEMPERATURE****OUTPUT VOLTAGE VS. OUTPUT CURRENT****OUTPUT VOLTAGE VS. AMBIENT TEMPERATURE**

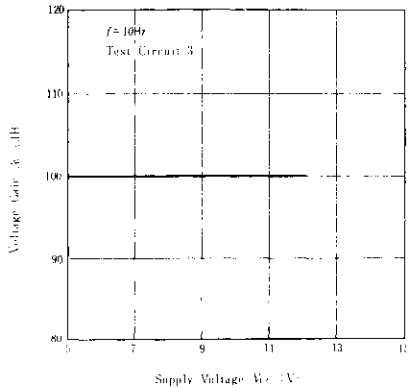
OUTPUT VOLTAGE VS. OUTPUT CURRENT



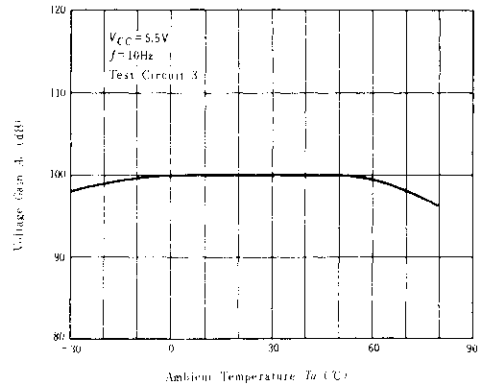
OUTPUT VOLTAGE VS. INPUT VOLTAGE



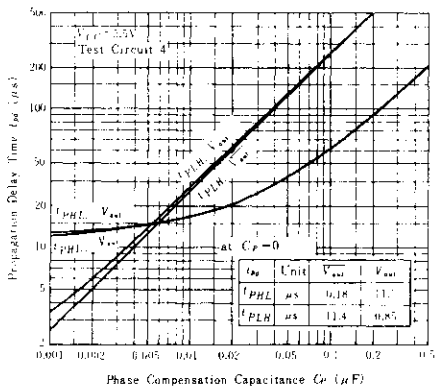
VOLTAGE GAIN VS. SUPPLY VOLTAGE



VOLTAGE GAIN VS. AMBIENT TEMPERATURE

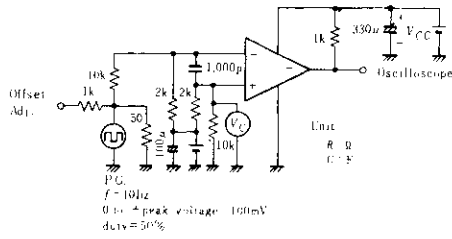


PROPAGATION DELAY TIME VS. PHASE COMPENSATION CAPACITANCE

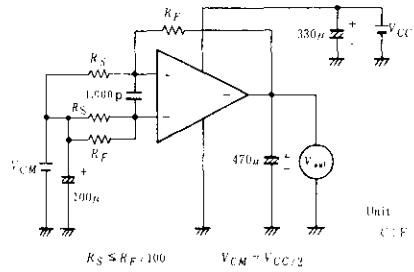


■ TEST CIRCUIT

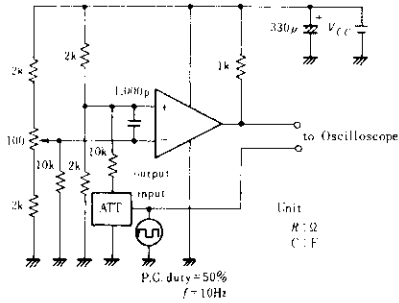
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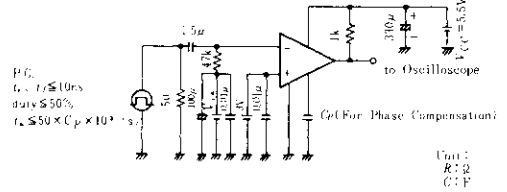
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3.

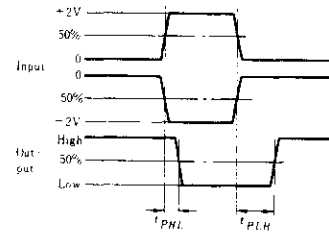


4.



Output	V_{in} (V)	V_{out} (V)
V_{in}	4	-2
V_{in}	2	+2

RESPONSE WAVEFORM



■ HA1807 APPLICATION

HA1807 operates with dual comparator and a power source. The operating supply voltage range is wide, 5 to 8V, and the output is a complementary output with two stages of gate connected in cascade.

1. Waveform Conversion Circuit

Fig. 1 shows a waveform conversion circuit. The input voltage range is maximum at $R_S = R_1$ and $V_S = V_{CC}$, and the output is inverted at the time when the input is zero-crossed.

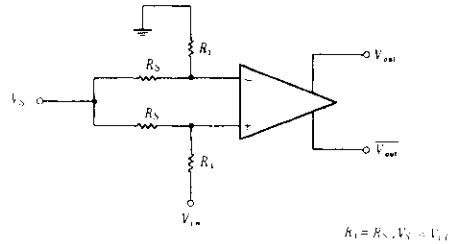


Fig.1 Wave form Converter

Fig. 2 shows Input and Output Waveforms at $V_S = V_{CC} = 6.0V$ and $R_1 \approx R_S = 100k\Omega$.

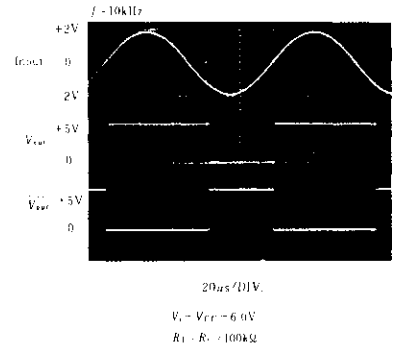
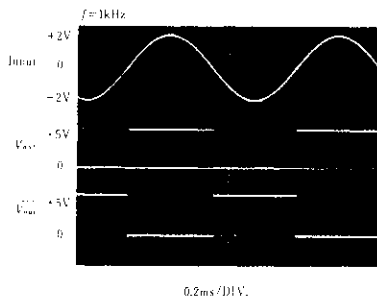
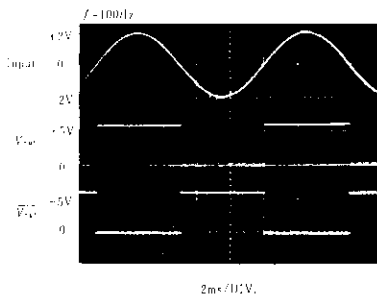


Fig.2 Operation Waveform of Waveform Converter

2. Schmitt Trigger Circuit

Schmitt Trigger Circuit is a circuit with hysteresis on the input and output characteristics by applying a positive feedback. Fig. 3 shows a Schmitt Trigger Circuit.

Fig. 4 shows an example of the Schmitt Trigger Circuit Operation.

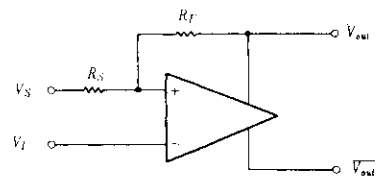


Fig.3 Schmitt Trigger Circuit

Fig.4 Shows an example of the Schmitt Trigger Circuit Operation

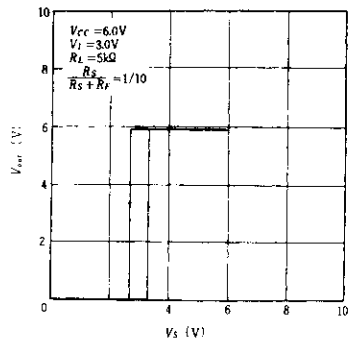


Fig.4(a) Operation Waveform of Schmitt Trigger Circuit ($V_{out} - V_s$)

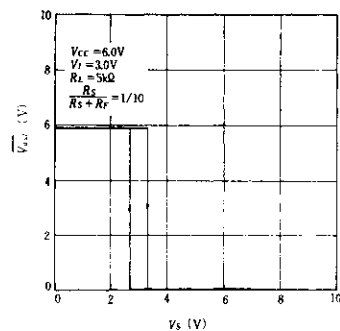


Fig.4(b) Operation Waveform of Schmitt Trigger Circuit ($V_{out} - V_s$)

3. Window Type Comparator

A window type comparator has two reference voltages. The output voltage level is determined according to that whether the voltage is smaller or larger than the two reference voltages.

Fig. 5 shows a circuit of window type comparator, and Fig. 6 shows an example of the operation.

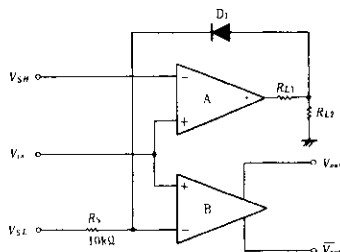


Fig. 5 Window Type Comparator

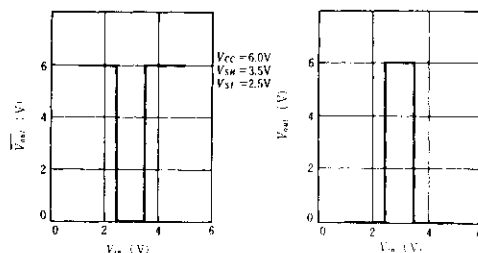


Fig.6 Operation Waveform of Window Type Comparator

4. Bistable Circuit

Fig. 7 shows a Bistable Circuit (R-S Flip-Flop Circuit), and Fig. 8 shows an example of the operation.

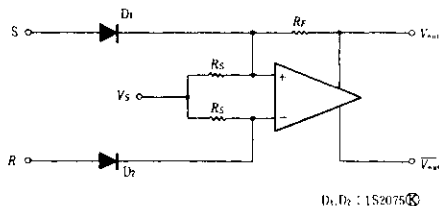


Fig.7 Bistable Circuit

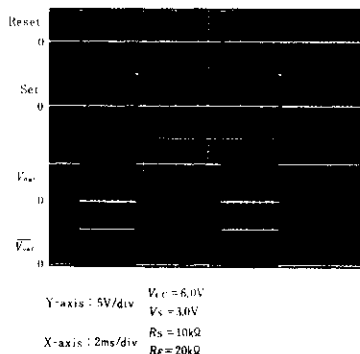


Fig.8 Operation Waveform of Bistable Circuit

5. Parallel Comparing A/D Converter

Fig. 9 and Fig. 10 show circuits of the parallel comparing A/D converters in which the comparator is applied. In this case, the output is converted to BCD (Binary Coded Decimal). This A/D converter can not be used suitably for a precise converter, but it has the features such as high speed conversion and a simple block diagram.

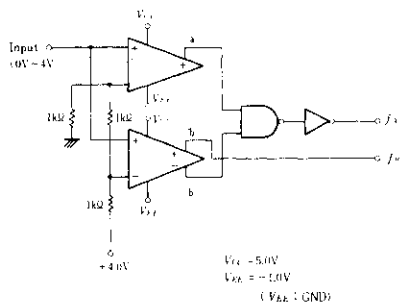


Fig.9 3Split & 2Bit A/D Converter

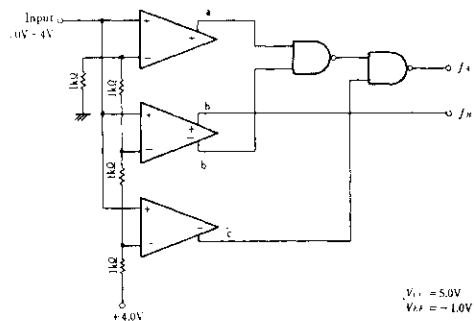


Fig.10 4Split & 2Bit A/D Converter

HA1812GS, HA1812PS ● Universal Comparator

HA1812 is general purpose IC, including comparator, buffer amplifier, reference voltage and is designed to be used widely as unit cell of circuit investigation and system designing.

■ FEATURES

- Large sink current of 200mA max.
- Capable of becoming Schmitt Trigger (Hysteresis characteristic) Circuit without external resistance.
- Includes reference voltage source.

HA1812GS



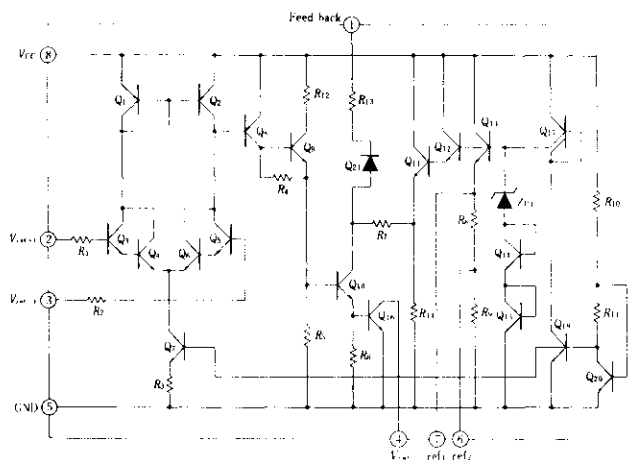
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HA1812PS

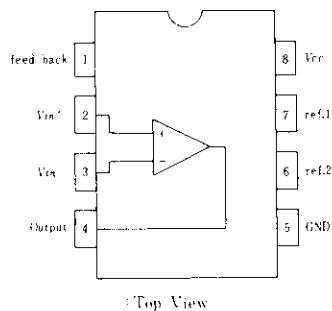


(DP-8)

■ CIRCUIT SCHEMATIC



■ PIN ARRANGEMENT



■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA1812GS	HA1812PS	Unit
Supply Voltage	V_{CC}	20	20	V
Output Sink Current	I_{out}	200	200	mA
Common Mode Input Voltage	V_{CM}	V_{CC}	V_{CC}	V
Differential Input Voltage	$V_{IN(dif)}$	$+V_{CC}^*$	$\pm V_{CC}^*$	V
Reference 1 Source Current	$I_{REF(REF1)}$	2.0	2.0	mA
Output Transistor Voltage	V_{out}	40	40	V
Feedback Terminal Current	I_{FB}	± 2.0	± 2.0	mA
Power Dissipation	P_T^{**}	800	800	mW
Operating Temperature	T_{op}	-20 to $+75$	-20 to $+75$	$^\circ\text{C}$
Storage Temperature	T_{stg}	65 to -150	-55 to $+125$	$^\circ\text{C}$

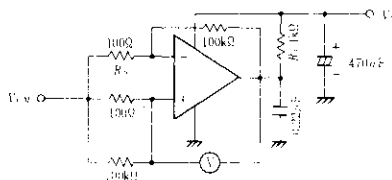
Note: * At $V_{CC} = 15\text{V}$, $V_{IN(dif)max} = +15\text{V}$.

** In HA1812GS, it is a value under the condition of $T_a = 65^\circ\text{C}$. When T_a is more than 65°C , $7.6\text{mW}/^\circ\text{C}$ derating shall be performed.
In HA1812PS, it is a value under the condition of $T_a = 45^\circ\text{C}$. When T_a is more than 45°C , $8.3\text{mW}/^\circ\text{C}$ derating shall be performed.

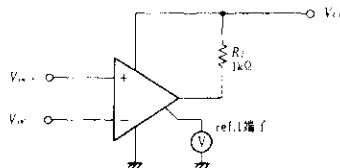
■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Measuring Circuit	Test Condition	min	typ	max	Unit	
Supply Current	I_{CC}		$V_{CC} = 20\text{V}$, $V_{IN(+)} = 0$, $V_{IN(-)} = 3\text{V}$, $R_L = \infty$	—	18	27	mA	
Output Leakage Current	I_{OL}		$V_{CC} = V_{OUT} = 20\text{V}$	—	—	1	μA	
"0" Level Output Voltage	V_{OL}		$V_{CC} = 8\text{V}$, $I_{OL} = 100\text{mA}$	—	0.3	0.5	V	
Input Bias Current	I_{IB}		$V_{CC} = 13.5\text{V}$, $V_{IO} = 6.75\text{V}$	—	—	100	nA	
Input Offset Current	I_{IO}		$V_{CC} = 13.5\text{V}$, $V_{IO} = 6.75\text{V}$	—	0.34	50	nA	
Input Offset Voltage	V_{IO}		$V_{CC} = 13.5\text{V}$, $V_{IO} = 6.75\text{V}$	—	3	15	mV	
Reference Voltage	V_{REF}		ref. 1 terminal	5.87	—	6.88	V	
			ref. 2 terminal	2.935	—	3.44	V	
	ΔV_{REF}	2	$V_{CC} = 13.5\text{V}$, $R_L = 1\text{k}\Omega$	1A	—	15	—	mV
		3	$V_{CC} = 8 \sim 20\text{V}$, $I_{REF(REF1)} = 0$	1A	—	50	—	mV
Voltage Gain	A_V	4	$V_{CC} = 13.5\text{V}$, $R_L = 1\text{k}\Omega$, $f = 10\text{Hz}$	80	100	—	dB	

■ TEST CIRCUIT

1. Input Offset Voltage V_{IO} 

Input Offset Voltage V_{IO} is 1/1000 of the indication of voltmeter V.

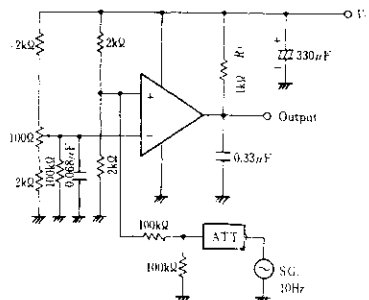
2. Reference Voltage V_{REF} 1A

Measure difference voltage of ref. 1 terminal at the time of inverting output with $V_{in}(+)$, $V_{in}(-)$ at 3V or 0V.

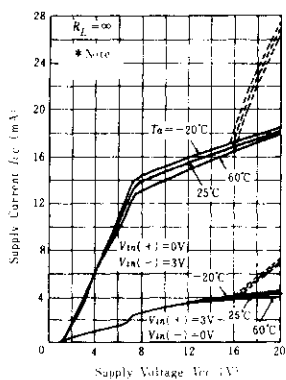
3. Reference Voltage V_{REF} 1B

In the same test circuit as V_{REF} 1A, with output established at 1 level, changing supply voltage V_{CC} from 8V to 20V, measure difference voltage of ref. 1 terminal.

4. Voltage Gain A_v

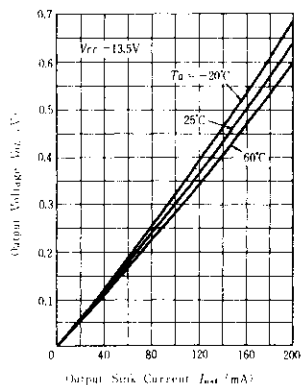


SUPPLY CURRENT VS. SUPPLY VOLTAGE

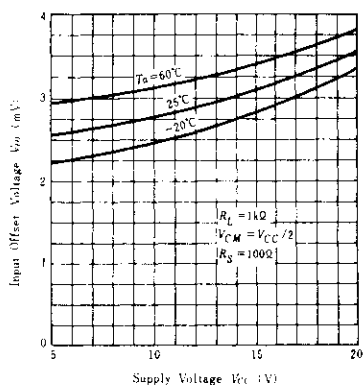


*Note The broken line is the characteristic at the time of connecting each Input Terminal to V_{CC} and GND.

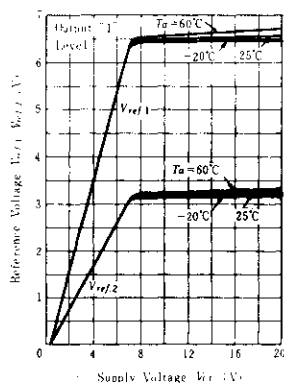
OUTPUT VOLTAGE VS. OUTPUT SINK CURRENT



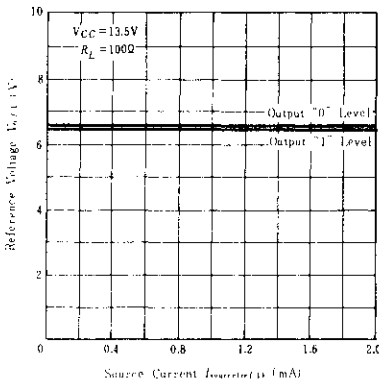
INPUT OFFSET VOLTAGE VS. SUPPLY VOLTAGE



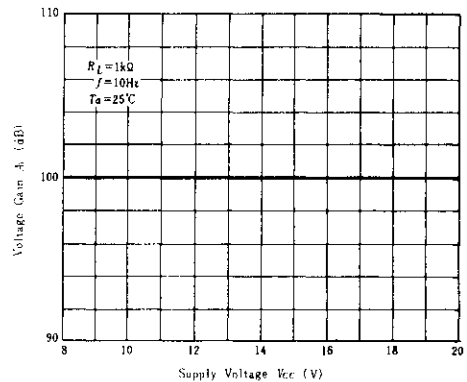
REFERENCE VOLTAGE VS. SUPPLY VOLTAGE



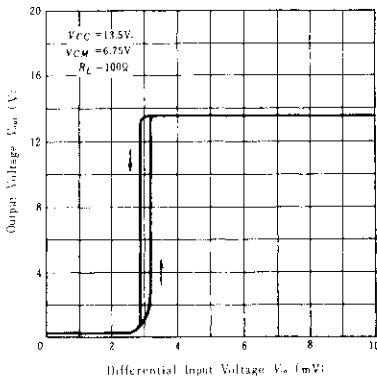
REFERENCE VOLTAGE VS. SOURCE CURRENT



VOLTAGE GAIN VS. SUPPLY VOLTAGE



OUTPUT VOLTAGE VS. DIFFERENTIAL INPUT VOLTAGE



■ BASIC OPERATION DESCRIPTION

The following describes the circuit operation of HA1812.

1. Differential Amplifier and Output Terminal V_{out}

Q_3 , Q_4 and Q_5 , Q_6 are Differential Amplifier of Darlington Connection, and signals amplified at this stage are further applied to the base of Q_{16} through Q_8 , Q_9 , Q_{10} . Q_{16} is the open collector in order to be able to drive load directly, and its sink current is designed largely with the maximum at 200mA when Ambient Temperature is $25^\circ C$.

Q_1 and Q_2 are provides current mirror connection at the collector load of Q_3 , Q_4 and Q_5 , Q_6 and the progress of voltage gain are designed.

2. Feedback Terminal

Feedback terminal is connected to the collector of Q_{10} through R_{13} and R_{21} . The phase of this Feedback terminal is the same phase as the collector of Output Transistor Q_{16} , and used by feedback to positive input terminal at the time of Schmitt Trigger connection. Further, since values of R_{13} , R_7 affect hysteresis characteristic, its resistance value is shown in the following.

$$R_{13} = 100\Omega \pm 30\%$$

$$R_7 = 470\Omega \pm 30\%$$

3. Constant-Current-Circuit

The circuit formed through R_{10} , R_{11} , Q_{20} , Q_{19} , Q_2 is constant-current circuits, and attracts currents with a small dependence on supply voltage from each circuit.

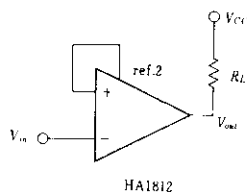
4. Reference Voltage

Q_{17} , ZD_1 , Q_{14} , Q_{15} are the circuits which produce reference voltage, and have almost constant current flown with a small dependence on supply voltage to ZD_1 , and so stabilize cathode voltage of Zener Diode ZD_1 .

Q_{14} and Q_{15} are diodes for temperature compensation of Zener Diode. Q_{13} is the transistor for supplying stabilized voltage through ZD_1 , to the two terminals of Reference 1 and Reference 2.

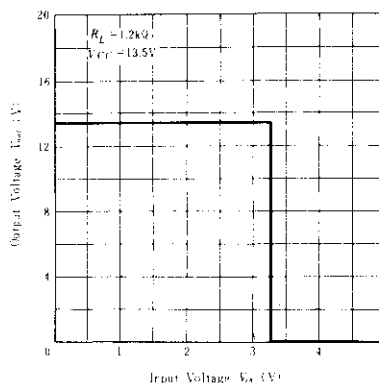
EXAMPLES OF APPLICATION CIRCUITS

1. Negative Input Comparator (When fundamental voltage is set at Vref.2)

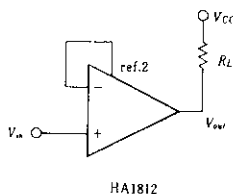


Note) $V_{ref.2}$ is 3.27V.

OUTPUT VOLTAGE VS. INPUT VOLTAGE

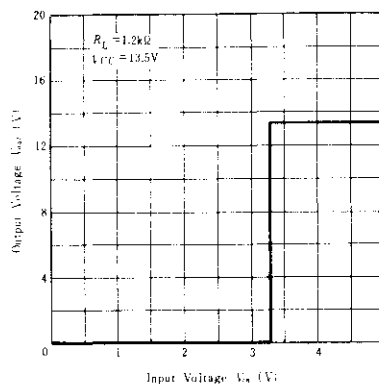


2. Positive Input Comparator (When reference voltage is set at Vref.2)

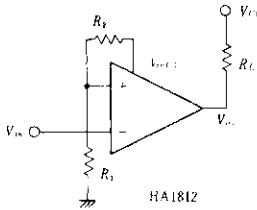


Note) $V_{ref.2}$ is 3.27V.

OUTPUT VOLTAGE VS. INPUT VOLTAGE



3. Comparator when Vref.1 is divided by resistance at R₁, R₂ and set at Reference Voltage.

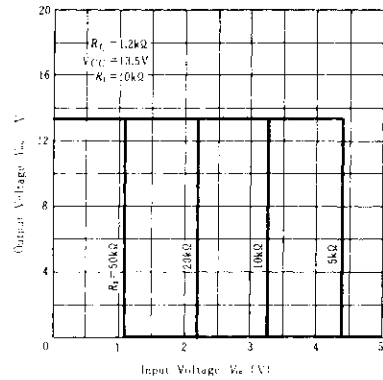


Note: V_{ref.1} is 6.5V

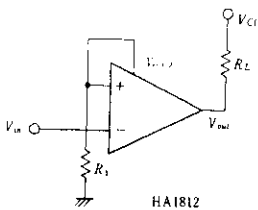
Threshold voltage V_{TH} is found by the following equation:

$$V_{TH} = \frac{6.5R_2}{R_1 + R_2} \text{ (V)}$$

OUTPUT VOLTAGE VS. INPUT VOLTAGE



4. Comparator established reference voltage by ref.2 and R₁.



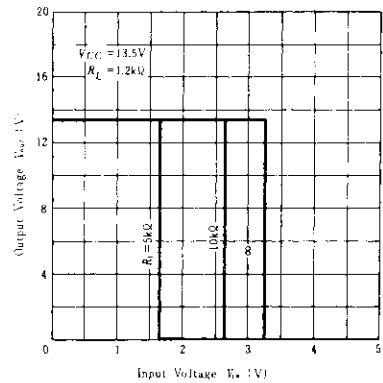
Note:

Threshold voltage V_{TH} is found by the following equation:

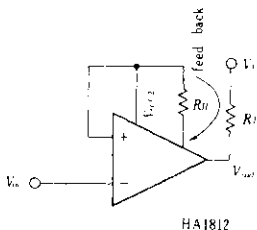
$$V_{TH} = \frac{6.5R_1}{10 + R_1} \text{ (V)}$$

Unit of R_1 : k Ω

OUTPUT VOLTAGE VS. INPUT VOLTAGE



5. Schmitt Trigger Circuit 1.



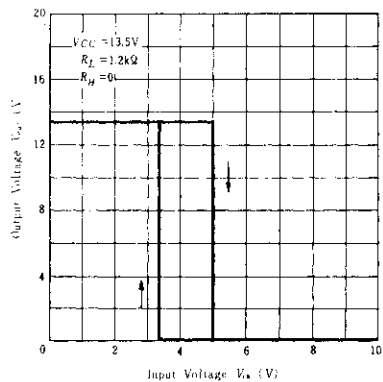
Note: Threshold voltage V_{TH} , V_{TL} are found by the following equations:

$$V_{TH} = V_{ref.1} + 3.2 \text{ (V)}$$

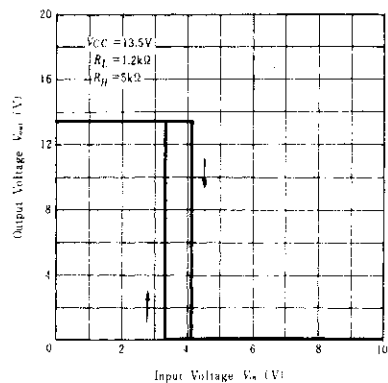
$$V_{TL} = V_{ref.1} - \frac{10}{R_f} \text{ (V)}$$

Unit of R_f : k Ω

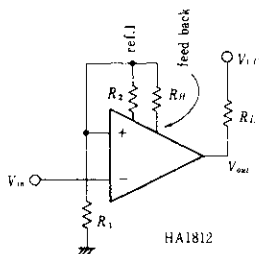
OUTPUT VOLTAGE VS. INPUT VOLTAGE (1)



OUTPUT VOLTAGE VS. INPUT VOLTAGE (2)



6. Schmitt Trigger Circuit.2.



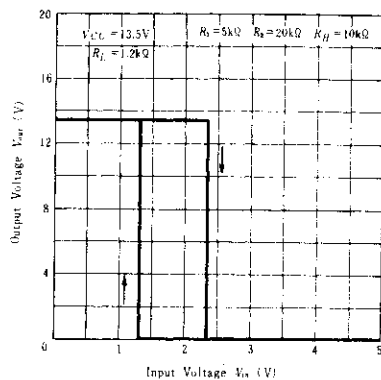
Note) Threshold voltage V_{TL}, V_{TH} are found by the following equation.

$$V_{TL} = \frac{6.53}{1 + (R_2/R_1)} \quad (V)$$

$$V_{TH} = \frac{6.53}{1 + (R_2/R_1) + a} \quad (V)$$

$$a = R_2 / (570 + R_H)$$

OUTPUT VOLTAGE VS. INPUT VOLTAGE



HA17903GS, HA17903PS, HA17393

● Dual Comparators

HA17903 and HA17393 are comparators designed for car use and control system use.

They provide wide voltage range with single power source, and the supply current is small, because it is independent of the supply voltage.

They can be widely applied, such as limit comparator, simple analog/digital converter, pulse/square wave/time delay generator, wide range VCO, MOS clock timer, multivibrator, high voltage logic gate, etc.

Industrial: HA17903GS, HA17903PS

Commercial: HA17393

■ FEATURES

- Wide Supply Voltage 2 to 36V
- Very Low Supply Current 0.8mA
- Small Input Bias 25nA
- Small Input Offset Current 3nA
- Small Input Offset Voltage 2mV
- Common Mode Input Voltage Range Including Ground.
- Small Output Saturation Voltage 1mV(5μA)
70mV(1mA)
- Output Voltage is Compatible with CMOS Logic System.

HA17903GS



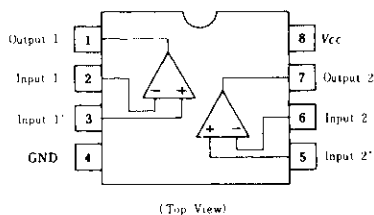
(DG-8)

HA17903PS
HA17393

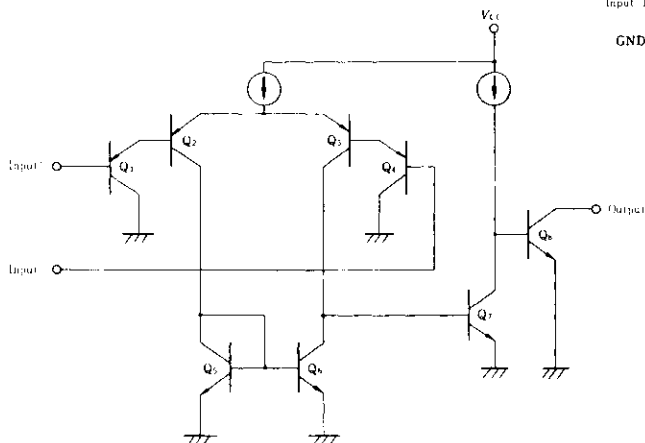


(DP-8)

■ PIN ARRANGEMENT



■ CIRCUIT SCHEMATIC(1/2)



■ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	1: HA17903GS	2: HA17903PS	2: HA17393	Unit	Note
Supply Voltage	V_{CC}	36	36	36	V	
Differential Input Voltage	$V_{IN(diff)}$	V_{CC}	V_{CC}	V_{CC}	V	
Input Voltage	V_{IN}	-0.3 to +36	-0.3 to +36	-0.3 to +36	V	
Power Dissipation	P_T	570	570	570	mW	1
Output Short-circuit Current	I_{OS}	Continuation possible	Continuation possible	Continuation possible		2
Operating Temperature	T_{OP}	-40 to +85	-20 to +75	0 to +70	$^\circ\text{C}$	
Storage Temperature	T_{STG}	-65 to +150	-55 to +125	-55 to +125	$^\circ\text{C}$	

Note) 1. 1): Value at $T_a \leq 75^\circ\text{C}$. In case of more than it, 7.6mW/ $^\circ\text{C}$ derating shall be performed.

2): Value at $T_a \leq 55^\circ\text{C}$. In case of more than it, 8.3mW/ $^\circ\text{C}$ derating shall be performed.

2. Short-circuit between the output and V_{CC} will be a cause to destroy the circuit.

The maximum output current is about 20mA for any supply voltage.

■ELECTRICAL CHARACTERISTICS-1 ($V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Test Condition	min	typ	max	Unit	Note
Input Offset Voltage	V_{IO}		—	2.0	5.0	mV	1
Input Bias Current	I_{IB}	$I_{IN(+)}$ or $I_{IN(-)}$	—	25	250	nA	2
Input Offset Current	I_{IO}	$ I_{IN(+)} - I_{IN(-)} $	—	3	50	nA	
Common Mode Input Voltage	V_{CM+}		3.5	—	—	V	3
	V_{CM-}		—	—	0	V	
Supply Current	I_{CC}	All Comparators: $R_L = \infty$, All Channels ON	—	0.8	2.0	mA	
Voltage Gain	A_{VD}	$V_{IC} = 15\text{V}$, $R_L \geq 15\text{k}\Omega$	—	200	—	V/mV	
Response Time	t_R	$V_{RL} = 5\text{V}$, $R_L = 5.1\text{k}\Omega$	—	1.3	—	μs	4
Large Signal Response Time	t_{RD}	$V_{IN} = \text{TTI}$, Threshold Width, $V_{REF} = 1.4\text{V}$	—	300	—	ns	
Output Sink Current	I_{OLK}	$V_{IN(+)} \geq 1\text{V}$, $V_{IN(-)} = 0$, $V_O \geq 1.5\text{V}$	6	16	—	mA	
Output Saturation Voltage	$V_{OL(sat)}$	$V_{IN(+)} \geq 1\text{V}$, $V_{IN(-)} = 0$, $I_{OLK} = 4\text{mA}$	—	—	400	mV	
Output Leak Current	I_{LO}	$V_{IN(+)} = 0$, $V_{IN(-)} \geq 1\text{V}$, $V_O = 5\text{V}$	—	0.1	—	nA	

Note) 1. $V_{REF} = 1.4\text{V}$ and $R_S = 50\Omega$, when $V_O = 1.4\text{V}$ at output switching point.

2. Under Linear Operation.

3. Common mode input voltage or each one of the input signal should not be less than -0.3V.

4. This is a value to 100mV Input Step Voltage with 5mV over drive.

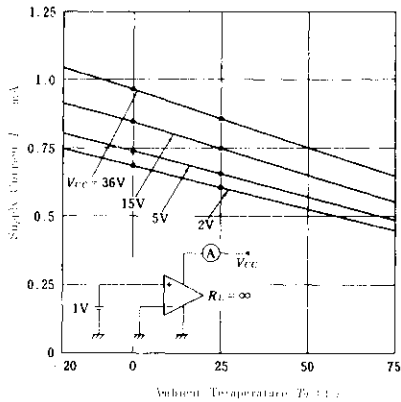
■ELECTRICAL CHARACTERISTICS-2

($V_{CC} = 5\text{V}$, HA17903GS; $T_a = -40$ to $+85^\circ\text{C}$, HA17903PS; $T_a = -20$ to $+75^\circ\text{C}$, HA17393; $T_a = 0$ to $+70^\circ\text{C}$)

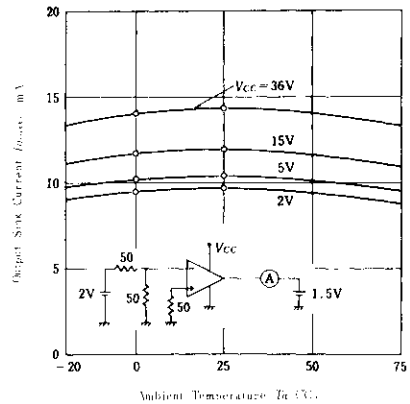
Item	Symbol	Test Condition	min	typ	max	Unit	Note
Input Offset Voltage	V_{IO}		—	9	15	mV	1
Input Offset Current	I_{IO}	$ I_{IN(+)} - I_{IN(-)} $	—	50	200	nA	
Input Bias Current	I_{IB}	Output Linear Range	—	200	500	nA	
Common Mode Input Voltage	V_{CM+}		$V_{CC} - 2.0$	—	—	V	
	V_{CM-}		—	—	0	V	
Output Saturation Voltage	$V_{OL(sat)}$	$V_{IN(+)} \geq 1\text{V}$, $V_{IN(-)} = 0$, $I_{OLK} \leq 4\text{mA}$	—	400	700	mV	
Output Leak Current	I_{LO}	$V_{IN(+)} = 0$, $V_{IN(-)} \geq 1\text{V}$, $V_O = 30\text{V}$	—	—	1.0	μA	
Differential Input Voltage	$V_{IN(diff)}$	All Inputs $\geq 0\text{V}$	—	—	V_{CC}	V	

Note) 1. $V_{REF} = 1.4\text{V}$ and $R_S = 50\Omega$, when $V_O = 1.4\text{V}$ at the output switching point.

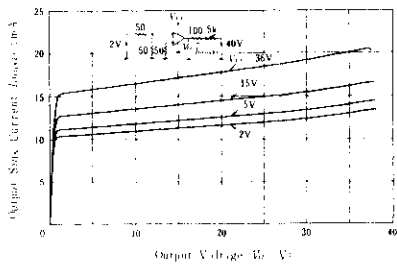
**SUPPLY CURRENT VS.
AMBIENT TEMPERATURE**



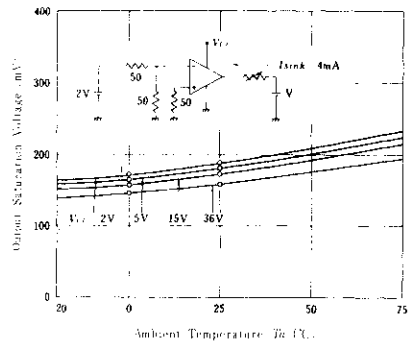
**OUTPUT SINK CURRENT VS.
AMBIENT TEMPERATURE**



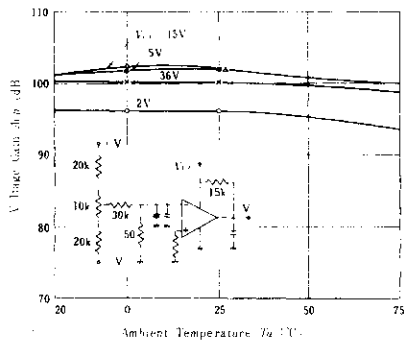
**OUTPUT SINK CURRENT VS.
OUTPUT VOLTAGE**



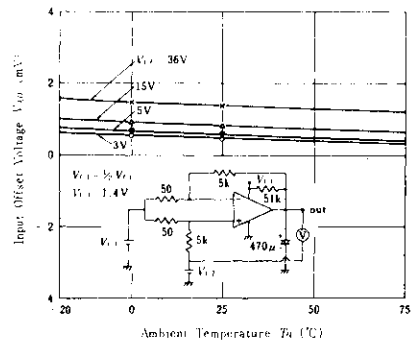
**OUTPUT SATURATION VOLTAGE VS.
AMBIENT TEMPERATURE**



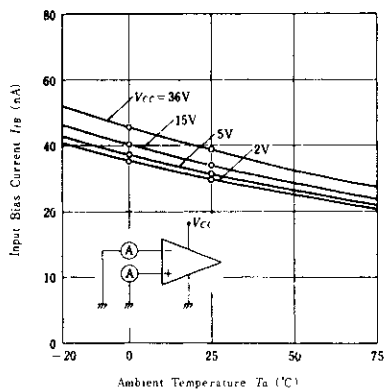
**VOLTAGE GAIN VS.
AMBIENT TEMPERATURE**



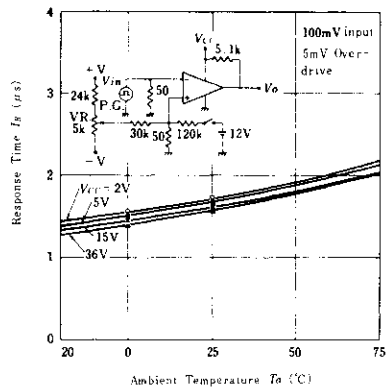
**INPUT OFFSET VOLTAGE VS.
AMBIENT TEMPERATURE**



INPUT BIAS CURRENT VS.
AMBIENT TEMPERATURE



RESPONSE TIME VS.
AMBIENT TEMPERATURE



HA17901G, HA17901P, HA17339

● Quadruple Comparators

HA17901 and HA17339 are comparators designed for car use and control system use.

They provide wide operating voltage with single power source, and the supply current is small because it is independent of the supply voltage.

They can be widely applied, such as limit comparator, simple analog/digital converter, pulse/square wave/time delay generator, wide range VCO, MOS clock timer, multivibrator, high voltage logic gate, etc.

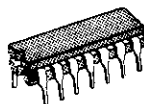
Industrial: HA17901G, HA17901P

Commercial: HA17339

■ FEATURES

- Wide Range of Supply Voltage 2 to 36V
- Very Small Supply Current 0.8mA
- Small Input Bias Current 25nA
- Small Input Offset Current 3nA
- Small Input Offset Voltage 2mV
- Common Mode Input Voltage Range Including Ground
- Differential Input Voltage Range Equal to Supply Voltage.
- Small Output Saturation Voltage 1mV(5μA)
70mV(1mA)
- The output voltage is compatible with that of CMOS Logic System

HA17901G



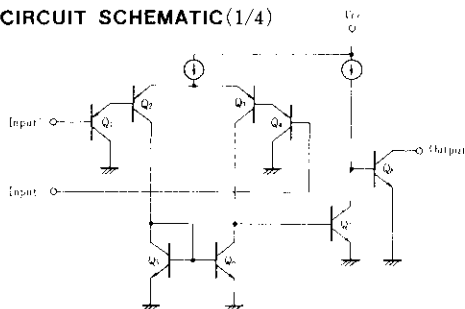
(DG-14)

HA17901P
HA17339

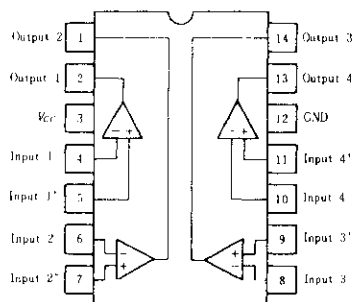


(DP-14)

■ CIRCUIT SCHEMATIC(1/4)



■ PIN ARRANGEMENT



(Top View)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	1: HA17901G	2: HA17901P	2: HA17339	Unit
Supply Voltage	V_{CC}	36	36	36	V
Differential Input Voltage	$V_{in(diff)}$	$\pm V_{CC}$	$\pm V_{CC}$	$\pm V_{CC}$	V
Input Voltage	V_{in}	-0.3 to -36	-0.3 to +36	-0.3 to +36	V
Power Dissipation	P_T^*	625	625	625	mW
Output Current	I_{out}^{**}	20	20	20	mA
Operating Temperature	T_{op}	-40 to +85	-20 to +75	0 to +70	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	-55 to +125	-55 to +125	$^\circ\text{C}$
Output Voltage	V_{out}	36	36	36	V

Note * 1: Value at $T_a = 70^\circ\text{C}$. In case of more than it, 7.6mW/ $^\circ\text{C}$ derating shall be performed.

2: Value at $T_a = 50^\circ\text{C}$. In case of more than it, 8.3mW/ $^\circ\text{C}$ derating shall be performed.

** 1: Short-circuit between the output and V_{CC} will be a cause to destroy the circuit.

The maximum output current is the permissible value for continuous operation.

■ ELECTRICAL CHARACTERISTICS ($V_{CC}=5V$, $T_a=25^{\circ}C$)

Item	Symbol	Test Condition	min	typ	max	Unit
Input Offset Voltage	V_{IO}	$V_{REF}=1.4V$ & $R_S=0\Omega$ when $V_O \approx 1.4V$ at the output switching point	—	2	7	mV
Input Bias Current (Note 1)	I_{IB}	$I_{IN(+)} \text{ or } I_{IN(-)}$	—	25	250	nA
Input Offset Current	I_{IO}	$I_{IN(+)} - I_{IN(-)}$	—	5	50	nA
Common Mode Input Voltage (Note 2)	V_{CM}		0	—	$V_{CC}-1.5$	V
Supply Current	I_{CC}	$R_L = \infty$	—	0.8	2	mA
Voltage Gain	A_V	$R_L = 15k\Omega$	—	200	—	V/mV
Response Time (Note 3)	t_k	$V_{RL}=5V$, $R_L=5.1k\Omega$	—	1.3	—	μs
Output Sink Current	$I_{O(sat)}$	$V_{IN(+)}=1V$, $V_{IN(-)}=0$, $V_O \geq 1.5V$	6	16	—	mA
Output Saturation Voltage	$V_{O(sat)}$	$V_{IN(+)}=1V$, $V_{IN(-)}=0$, $I_{O(sat)}=3mA$	—	200	400	mV
Output Leak Current	I_{LO}	$V_{IN(+)}=1V$, $V_{IN(-)}=0$, $V_O=5V$	—	0.1	—	nA

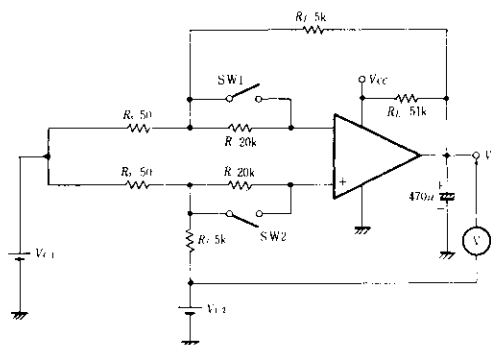
Note) 1. The input bias current is constant, because there is a reference line or input line without any change of load.

2. Common mode input voltage or either of the input signal voltages should not be less than $-0.3V$.

3. This is a value to 100mV input step voltage with 5mV overdrive.

■ TEST CIRCUIT

1. Input Offset Voltage (V_{IO}), Input Offset Current (I_{IO})
Input Bias Current (I_{IB})



SW 1	SW 2	V_{ref}
ON	ON	V_{D1}
OFF	OFF	V_{D2}
ON	OFF	V_{D3}
OFF	ON	V_{D4}

$$V_{C1} = 1/2 V_{CC}$$

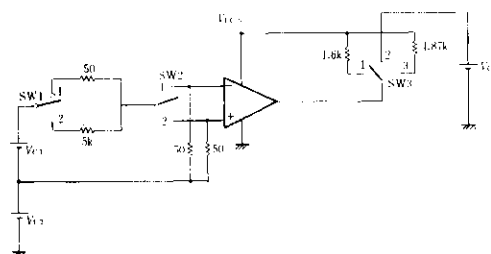
$$V_{C2} = 1.4V$$

$$(1) \quad V_{IO} = \frac{|V_{D1}|}{1 + \frac{R_f}{R_s}} \quad (V)$$

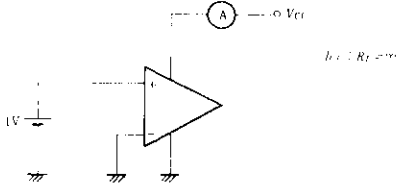
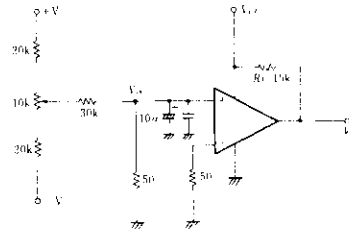
$$(2) \quad I_{IO} = \frac{|V_{D2} - V_{D1}|}{R \left(1 + \frac{R_f}{R_s} \right)} \quad (A)$$

$$(3) \quad I_{IB} = \frac{|V_{D4} - V_{D3}|}{2 \cdot R \left(1 + \frac{R_f}{R_s} \right)} \quad (A)$$

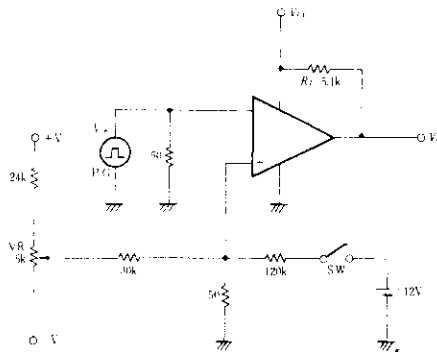
2. Output Saturation Voltage ($V_{O(sat)}$), Output Sink Current ($I_{O(sat)}$), Common Mode Input Voltage (V_{CM})



Item	V_{C1}	V_{C2}	V_{C3}	SW 1	SW 2	SW 3	Unit
$V_{O(sat)}$	2V	0V	—	1	1	1 at $V_{CC}=5V$ 3 at $V_{CC}=15V$	V
$I_{O(sat)}$	2V	0V	1.5V	1	1	2	mA
V_{CM}	2V	$-1 \sim V_{CC}$	—	2	1,2切换	3	V

3. Supply Current (I_{CC})4. Voltage Gain (A_V) ($R_L = 15k\Omega$)

$$A_V = 20 \log \frac{V_{OUT}}{V_{IN}} \quad (\text{dB})$$

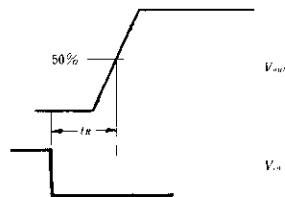
5. Response Time (t_R)

t_R : $R_L = 5.1k\Omega$,

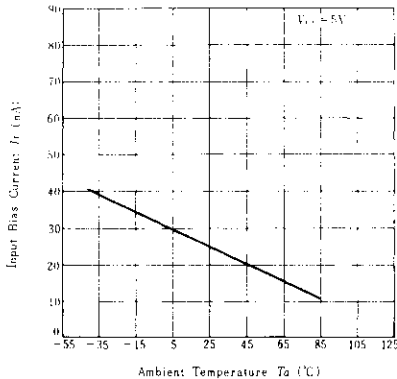
100mV input with 5mV overdrive

Turn the SW OFF without applying V_{IN} , and adjust the V_R to make V_O 1.4V approximately.

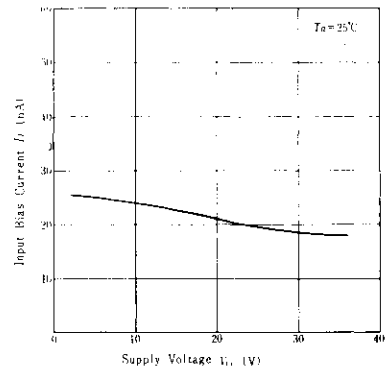
Apply V_{IN} , and turn the SW ON.



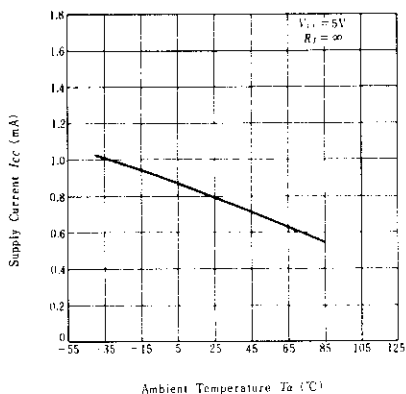
INPUT BIAS CURRENT VS:
AMBIENT TEMPERATURE



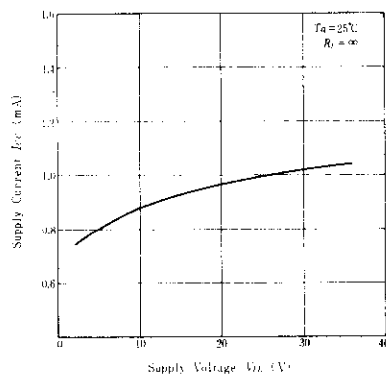
INPUT BIAS CURRENT VS.
SUPPLY VOLTAGE



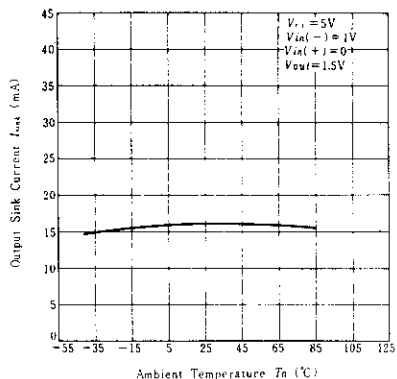
**SUPPLY CURRENT VS.
AMBIENT TEMPERATURE**



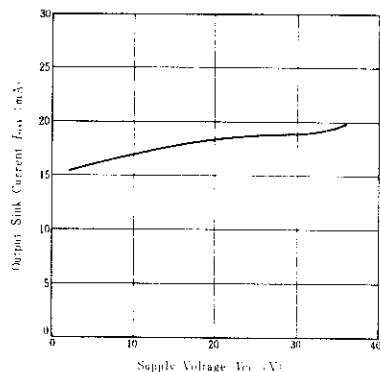
**SUPPLY CURRENT VS.
SUPPLY VOLTAGE**



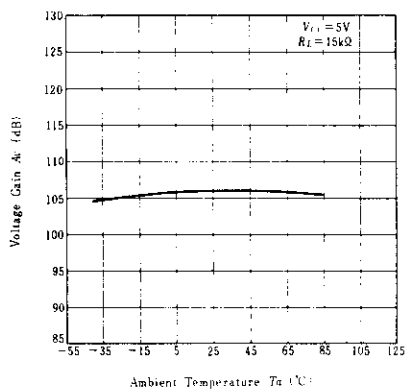
**OUTPUT SINK CURRENT VS.
SUPPLY VOLTAGE**



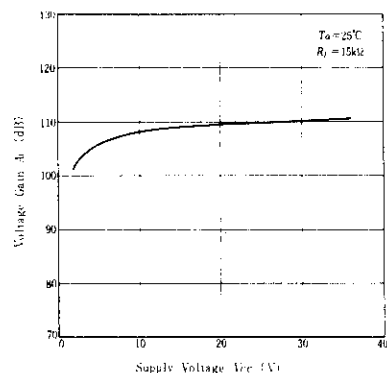
**OUTPUT SINK CURRENT VS.
SUPPLY VOLTAGE**



**VOLTAGE GAIN VS.
AMBIENT TEMPERATURE**



VOLTAGE GAIN VS. SUPPLY VOLTAGE



Voltage Regulators

HA17723G, HA17723 ● Voltage Regulator

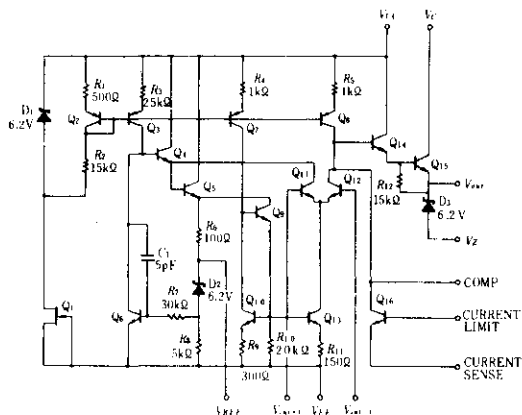
HA17723, high accuracy voltage regulator for general purposes, features low stand-by current — quiescent current, low temperature drift and high ripple rejection ratio.

Output current above 150mA is also available by adding PNP or NPN transistors externally. This voltage regulator finds wide application, using in series, parallel and as switches.

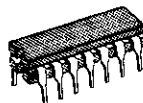
Industrial Use HA17723G

Commercial Use HA17723

■ CIRCUIT SCHEMATIC

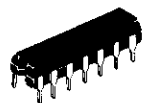


HA17723G



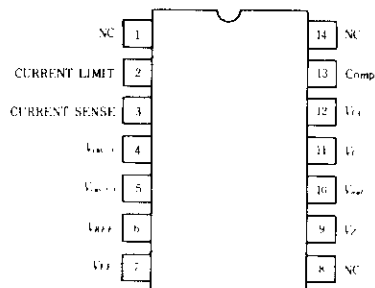
(DG-14)

HA17723



(DP-14)

■ PIN ARRANGEMENT



(Top View)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA17723G	HA17723	Unit
Supply Voltage	V_{CC}	40	40	V
Input/Output Voltage Differential	$V_{diff, I/O}$	40	40	V
Differential Input Voltage	$V_{in, diff}$	± 5	± 5	V
Maximum Output Current	I_{out}	150	150	mA
Current from V_{REF}	I_{REF}	15	15	mA
Power Dissipation*	P_T	950*	830**	mW
Operating Temperature	T_{opr}	-20 to $+75$	0 to $+70$	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to $+150$	-55 to $+125$	$^\circ\text{C}$

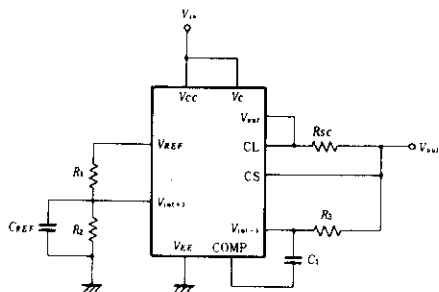
* Derating above 25°C will be $7.6\text{mW}/^\circ\text{C}$ ** Derating above 25°C will be $8.3\text{mW}/^\circ\text{C}$

■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Line Regulation	$\delta V_{O, Load}$	$V_{in} = 12$ to 15V	—	0.01	0.1	%
		$V_{in} = 12$ to 40V	—	0.1	0.5	%
		$V_{in} = 12$ to 15V , $T_a = -20$ to $+75^\circ\text{C}$	—	—	0.4	%
		$V_{in} = 12$ to 15V , $T_a = 0$ to $+70^\circ\text{C}$	—	—	0.3	%
Load Regulation	$\delta V_{O, Load}$	$I_{out} = 1$ to 50mA	—	0.03	0.2	%
		$I_{out} = 1$ to 50mA , $T_a = -20$ to $+75^\circ\text{C}$	—	—	0.7	%
		$I_{out} = 1$ to 50mA , $T_a = 0$ to $+70^\circ\text{C}$	—	—	0.6	%
Ripple Rejection	R_{REJ}	$f = 50\text{Hz}$ to 1kHz , $C_{REF} = 0$	—	74	—	dB
		$f = 50\text{Hz}$ to 1kHz , $C_{REF} = 5\mu\text{F}$	—	86	—	dB
Average Temperature Coefficient of Output Voltage	$\delta V_O / \delta T$	$T_a = -20$ to $+75^\circ\text{C}$	—	0.003	0.018	$\%/^\circ\text{C}$
		$T_a = 0$ to $+70^\circ\text{C}$	—	0.003	0.015	$\%/^\circ\text{C}$
Reference Voltage	V_{REF}	$V_{in} = V_{CC} = V_C = 12\text{V}$, $V_{ER} = 0$	6.80	7.15	7.50	V
Standby Current	I_{ST}	$V_{in} = 30\text{V}$, $I_L = 0$	—	—	4.0	mA
Short Circuit Current Limit	I_{SC}	$R_{SC} = 10\Omega$, $V_{out} = 0$	—	65	—	mA

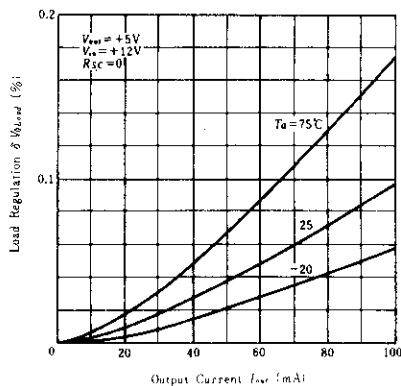
* HA17723G Only

ELECTRICAL CHARACTERISTICS MEASURING CIRCUIT

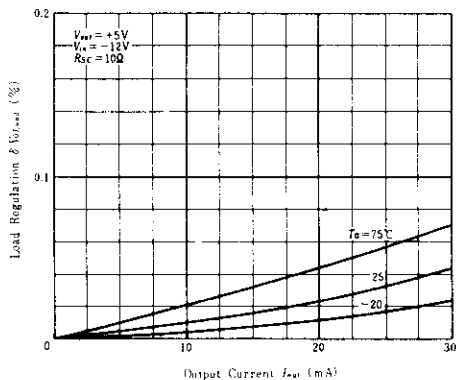


$V_{IN} - V_{CC} - V_{EE} = 12V$, $V_{REF} = 0$
 $V_{OUT} = 5.0V$, $I_L = 1mA$
 $R_{SC} = 0$, $C_1 = 100pF$, $C_{REF} = 0$
 $R_2 = 5k\Omega$, $R_1 = R_2 / (R_1 + R_2)$

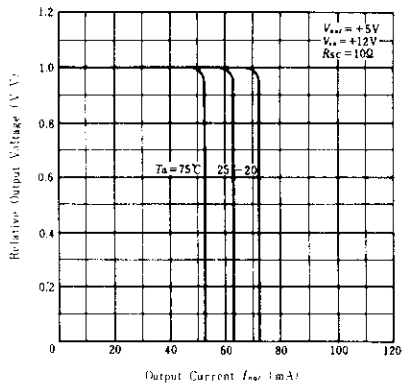
LOAD REGULATION VS. OUTPUT CURRENT-1



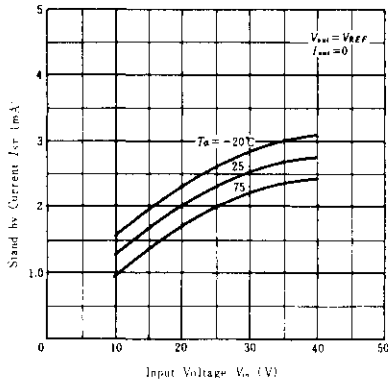
LOAD REGULATION VS. OUTPUT CURRENT-2



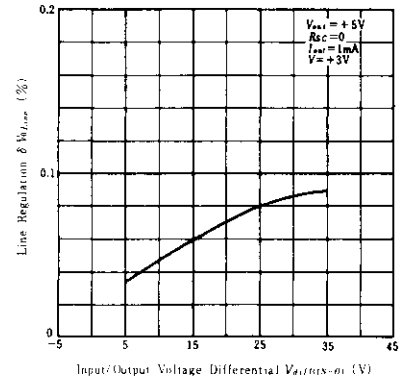
RELATIVE OUTPUT VS. OUTPUT CURRENT VOLTAGE



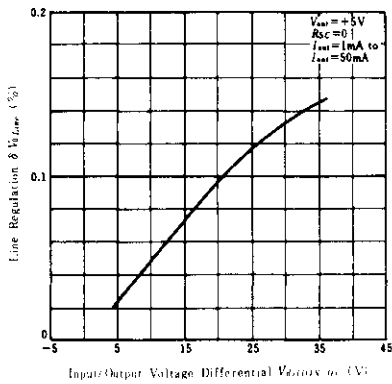
STAND-BY CURRENT VS. INPUT VOLTAGE



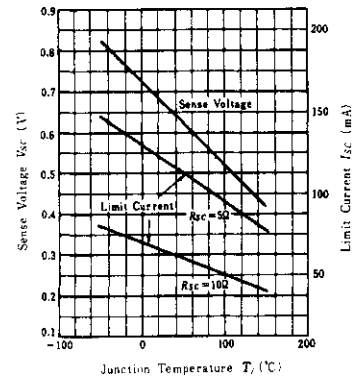
LINE REGULATION VS. INPUT/OUTPUT VOLTAGE DIFFERENTIAL



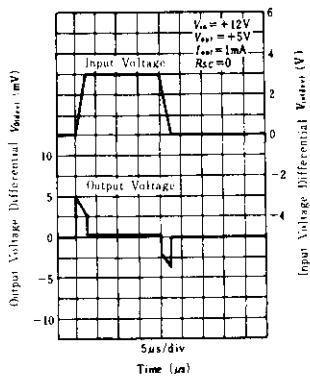
LINE REGULATION VS. INPUT/OUTPUT VOLTAGE DIFFERENTIAL



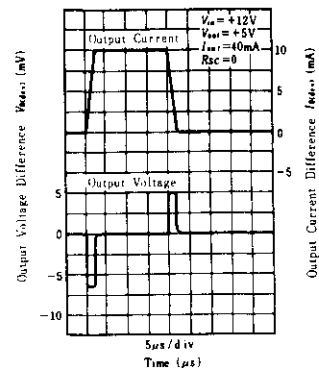
CURRENT LIMITING CHARACTERISTICS



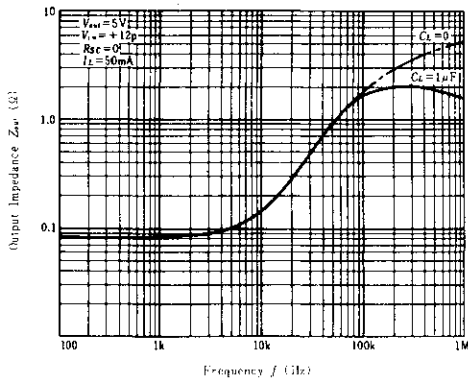
LINE TRANSIENT RESPONSE



LOAD TRANSIENT RESPONSE



OUTPUT IMPEDANCE VS. FREQUENCY



■ HA17723, APPLICATIONS

HA17723 is high accuracy voltage regulator for general purposes and may be used as voltage sources in various types.

1. Fixed Voltage Source in Series

1.1 Low Voltage, 2 to 7 volts, Regulator

Fig. 1 shows the construction of a basic low voltage regulator. The divider by resistors R_1 and R_2 from V_{REF} is to make the reference voltage which will be provided to non-inverted input of the error amplifier, be less than output voltage. In the fixed voltage source where the output voltage will be fed back to the error amplifier directly as shown in Fig. 1. Output voltage will be divided V_{REF} since the output voltage is equal to the reference voltage.

Thus, the output voltage V_{out} is;

$$V_{out} = nV_{REF}, \quad n = \frac{R_2}{R_1 + R_2} \quad (1)$$

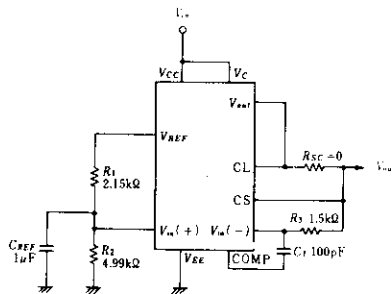


Fig.1 Low Voltage (2 to 7V) Regulator

1.2 High Voltage, 7 to 37V, Regulator

Fig. 2 shows the construction of a regulator when output voltage is higher than the reference voltage, V_{REF} . The V_{REF} shall be added to the non-inverted input of the error amplifier via a resistor, R_3 . The feedback voltage is available by dividing the output voltage with resistors R_1 and R_2 .

Thus output voltage V_{out} is:

$$V_{out} = \frac{V_{REF}}{n}, \quad n = \frac{R_2}{R_1 + R_2} \quad (2)$$

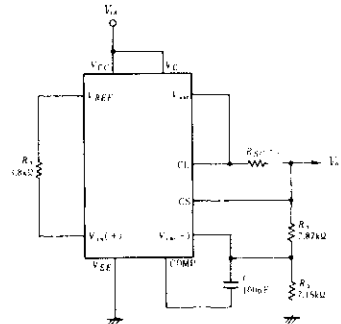


Fig.2 High Voltage (7 to 37V) Regulator

1.3 Negative Voltage Regulator

Fig. 3 shows the construction of a so-called negative voltage regulator which generates negative output voltage with regard to the GND. Assuming that the output voltage, $-V_{out}$ increased in the negative directions. As the voltage across the R_1 is larger than that across the R_3 which provides the reference voltage, output current of the error amplifier increases. In the control circuit, the impedance decreases with increase of input current, which makes the base current of the external transistor Q approach to the potential at GND. As the results, the output voltage returns to the established value and stable output voltage is available.

The output voltage $-V_{out}$ in this circuit is;

$$-V_{out} = \left(\frac{R_1 + R_2}{R_3 + R_4} \times \frac{R_3}{R_1} \right) V_{REF} - \frac{(R_1 + R_2) \cdot (R_3 + R_4)}{R_2 \cdot (R_3 + R_4) - R_4 \cdot (R_1 + R_2)} \times \frac{R_3}{R_3 + R_4} V_{REF} \quad (2)$$

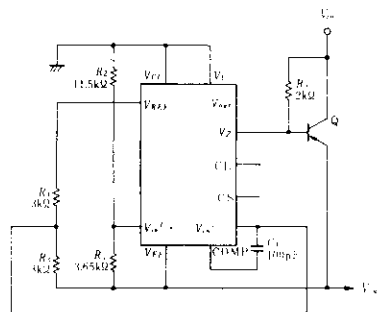


Fig.3 Negative Voltage Regulator

1.4 How to Increase the Output Current

It is necessary for increase of output current to increase the current capacitance in the control circuit. Fig. 4 and Fig. 5 show examples, where transistors are externally added.

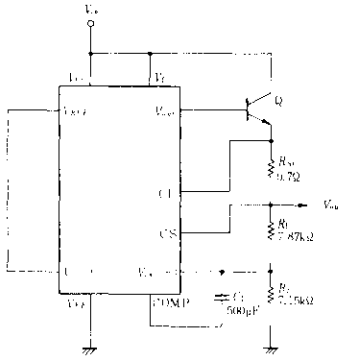


Fig.4 Method to Increase Output Current (1)

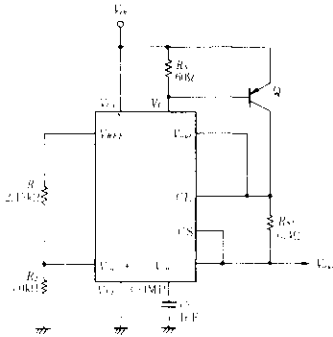


Fig.5 Method to Increase Output Current (2)

2. Fixed Voltage Source in Parallel Control

Fig. 6 shows the circuit of fixed voltage source in parallel control.

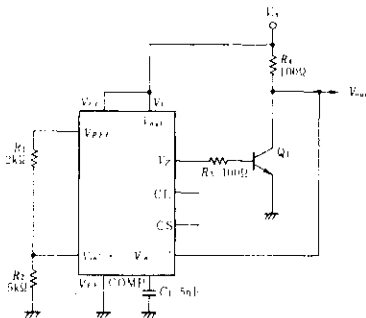


Fig.6 Fixed Voltage Source in Parallel Control

3. Switching Regulator

Fig. 7 shows the circuit of a switching regulator. The error amplifier, control circuit and forward feedback circuit R_4 and R_3 operate in together as a comparator, and make the external transistors Q_1 and Q_2 operate as switching elements to turn ON/OFF. In this circuit, the self-oscillation stabilizes the output voltage and the change in output is absorbed by the changes of conducted period of switches.

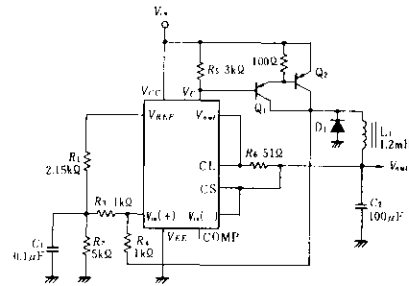


Fig.7 Positive Voltage Switching Regulator

Fig. 8 and Fig. 9 show the circuit of negative voltage switching regulator and its characteristics.

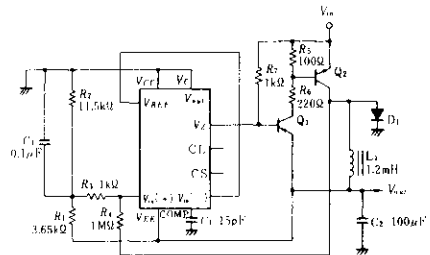


Fig.8 Negative Voltage Switching Regulator

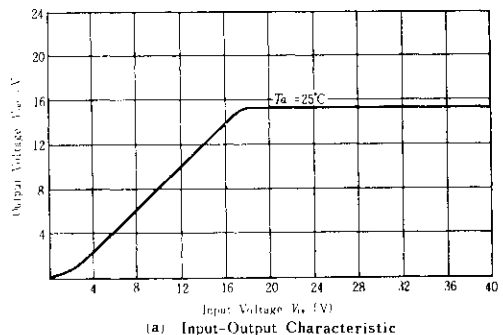
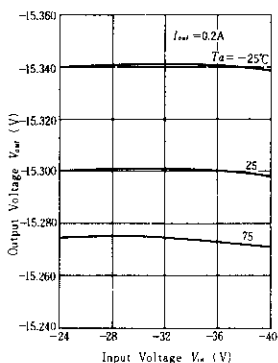
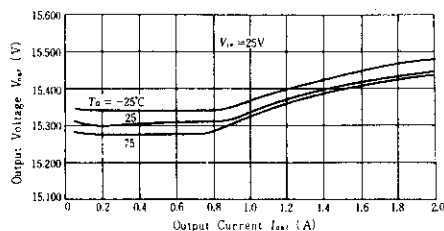


Fig.9 Operating Characteristics of Negative Voltage Switching Regulator



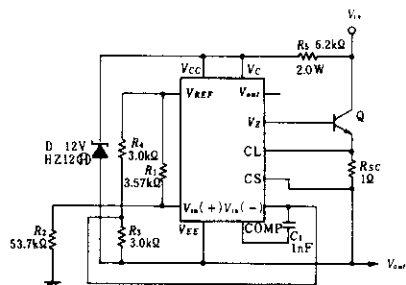
(b) Line Regulation



(c) Load Regulation

Fig.9 Operating Characteristics of Negative Voltage Switching Regulator**4. Fixed Voltage Source in Floating Type**

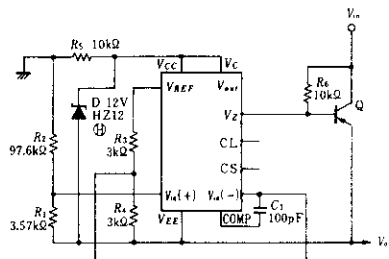
Voltage sources in floating type or boost type are typically employed when high voltage output is required. Fig. 10 shows the circuit of a fixed voltage source in the floating type. For considering the stabilization in this circuit, assuming that the output voltage increased. At the input terminal of the error amplifier, non-inverted input will become low compared with inverted input, and the output current of the error amplifier decrease. Then, the current from the terminal V_Z in the control circuit decrease. As the results, the base current of the external resistor Q_1 will decrease and collector current will decrease, resulting to control increase of the output voltage.

**Fig.10 Positive Voltage Floating Regulator**

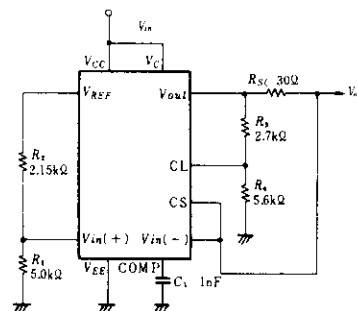
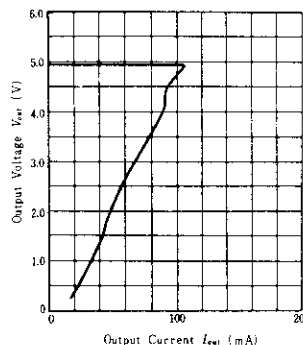
The output voltage V_{out} in the circuit, Fig. 10 is;

$$V_{out} = \left(\frac{R_1 + R_2}{R_3 + R_4} \times \frac{R_4}{R_1} - 1 \right) V_{REF} \quad (3)$$

Fig. 11 shows the circuit diagram of the negative fixed voltage source in floating type.

**Fig.11 Negative Voltage Floating Regulator****5. Other Applications**

Other applications are follows.

5.1 Fixed Voltage Source with Reduction Type Current Limiter**Fig.12 Fixed Voltage Source with Reduction Type Current Limiter****Fig.13 Current Control Characteristics of Fixed Voltage Source with Reduction Type Current Limiter**

5.2 Fixed Voltage Source Turning ON/OFF External Control

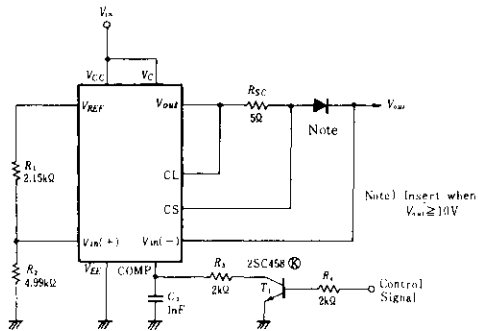


Fig.14 Fixed Voltage Source Turning ON/OFF External Control

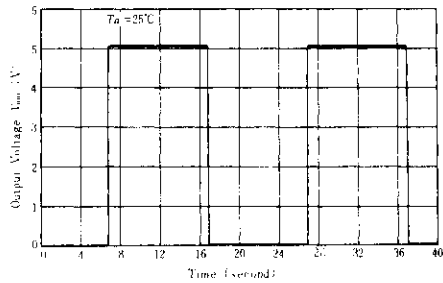


Fig.15 Operating Characteristics of Fixed Voltage Source Turning ON/OFF External Control

HA17800P, HA17800 Series ● 3-terminal Fixed Voltage Regulators

HA17800P and HA17800 series, 3-terminal fixed voltage regulators provides 8 kinds of output voltage; 5, 6, 7, 8, 12, 15, 18 and 24 volts. When a heat sink is used, output current above 1A is available, which enables wide applications are a power source of various equipments.

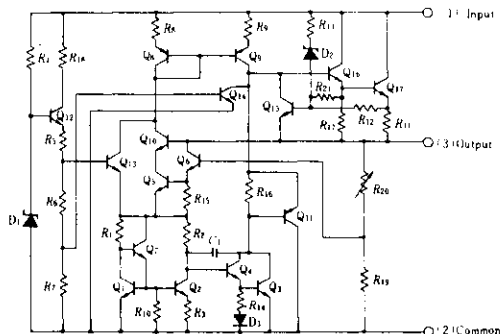
For all devices in this series, three protection circuit; one to limit current, another to limit temperature at chip junctions and the other to limit internal power dissipation, are built-in and elements are protected against the destructions.

Industrial Use HA17800P Series
Commercial Use HA17800 Series

■ FEATURES

- Output Current above 1A is available.
- 8 kinds of output voltages, 5, 6, 7, 8, 12, 15, 18 and 24V will be provided to offer wide applications as various sources.
- Eliminates external compensating circuit.
- TO-220AB package enables easy mounting and radiation design like transistors.
- Built-in Current Limiter prevents elements from destruction when load is short circuited.
- Built-in Chip Junctions Temperature Limiting Circuit protects elements against thermal destruction.
- Built-in Internal Power Dissipation Limiting Circuit protects transistors at output driver.

■ CIRCUIT SCHEMATIC



■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA17800P, HA17800 Series	Unit
Input Voltage	V_{in}^*	35	V
Input Voltage	V_{in}^{**}	40	V
Power Dissipation	P_T^{***}	15	W
Operating Ambient Temperature	T_{op}	-20 to +75	$^\circ\text{C}$
Operating Junction Temperature	T_j	-20 to +125	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

Note) * HA17805P to HA17818P and HA17805 to HA17818

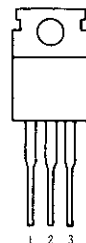
** HA17824P and HA17824

*** Follow the derating curve

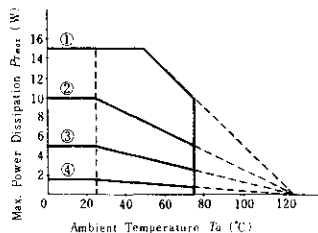


(T-220AB)

■ PIN ARRANGEMENT



1. Input
2. Common
3. Output

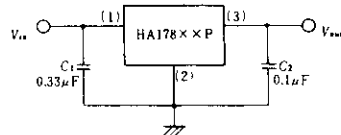


- (1) With Infinitely Large Heat Sink
- (2) 5 $^\circ\text{C}/\text{W}$ Heat Sink
- (3) 15 $^\circ\text{C}/\text{W}$ Heat Sink
- (4) Without Heat Sink

$$\begin{aligned} \theta_{JA} &= 3.0^\circ\text{C}/\text{W} \text{ (typ.)} \\ &= 5.0^\circ\text{C}/\text{W} \text{ (max.)} \\ \theta_{JA} &= 60^\circ\text{C}/\text{W} \text{ (typ.)} \\ &= 65^\circ\text{C}/\text{W} \text{ (max.)} \end{aligned}$$

Thermal Resistance

■ TYPICAL CONNECTING CIRCUIT



■ HA17805P, HA17805 ELECTRICAL CHARACTERISTICS

($V_{in}=10V$, $I_{out}=500mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$; unless otherwise specified.)

Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^{\circ}C$	4.8	5.0	5.2	V
		$7V \leq V_{in} \leq 20V$, $5mA \leq I_{out} \leq 1.0A$, $P_T \leq 15W$	4.75	—	5.25	V
Line Regulation	$\delta V_{o, line}$	$T_j = 25^{\circ}C$	—	3	100	mV
		$7V \leq V_{in} \leq 25V$ $8V \leq V_{in} \leq 12V$	—	1	50	mV
Load Regulation	$\delta V_{o, load}$	$T_j = 25^{\circ}C$	—	15	100	mV
		$5mA \leq I_{out} \leq 1.5A$ $250mA \leq I_{out} \leq 750mA$	—	5	50	mV
Quiescent Current	I_Q	$T_j = 25^{\circ}C$	—	4.2	8.0	mA
Quiescent Current Change	δI_Q	$7V \leq V_{in} \leq 25V$	—	—	1.3	mA
		$5mA \leq I_{out} \leq 1.0A$	—	—	0.5	mA
Output Noise Voltage	V_n	$T_a = 25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	40	—	μV
Ripple Rejection Ratio	R_{RRJ}	$f = 120Hz$	62	78	—	dB
Voltage Drop	V_{DROPP}	$I_{out} = 1.0A$, $T_j = 25^{\circ}C$	—	2.0	—	V
Output Resistance	R_{out}	$f = 1kHz$	—	17	—	m Ω
Output Short Circuit Current	I_{OS}	$T_j = 25^{\circ}C$	—	750	—	mA
Peak Output Current	I_{OPK}	$T_j = 25^{\circ}C$	—	2.2	—	A
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-1.1	—	mV/ $^{\circ}C$

■ HA17806P, HA17806 ELECTRICAL CHARACTERISTICS

($V_{in}=11V$, $I_{out}=500mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$; unless otherwise specified.)

Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^{\circ}C$	5.75	6.0	6.25	V
		$8V \leq V_{in} \leq 21V$, $5mA \leq I_{out} \leq 1.0A$, $P_T \leq 15W$	5.7	—	6.3	V
Line Regulation	$\delta V_{o, line}$	$T_j = 25^{\circ}C$	—	5	120	mV
		$8V \leq V_{in} \leq 25V$ $9V \leq V_{in} \leq 13V$	—	1.5	60	mV
Load Regulation	$\delta V_{o, load}$	$T_j = 25^{\circ}C$	—	14	120	mV
		$5mA \leq I_{out} \leq 1.5A$ $250mA \leq I_{out} \leq 750mA$	—	4	60	mV
Quiescent Current	I_Q	$T_j = 25^{\circ}C$	—	4.3	8.0	mA
Quiescent Current Change	δI_Q	$8V \leq V_{in} \leq 25V$	—	—	1.3	mA
		$5mA \leq I_{out} \leq 1.0A$	—	—	0.5	mA
Output Noise Voltage	V_n	$T_a = 25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	45	—	μV
Ripple Rejection Ratio	R_{RRJ}	$f = 120Hz$	59	75	—	dB
Voltage Drop	V_{DROPP}	$I_{out} = 1.0A$, $T_j = 25^{\circ}C$	—	2.0	—	V
Output Resistance	R_{out}	$f = 1kHz$	—	19	—	m Ω
Output Short Circuit Current	I_{OS}	$T_j = 25^{\circ}C$	—	550	—	mA
Peak Output Current	I_{OPK}	$T_j = 25^{\circ}C$	—	2.2	—	A
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-0.8	—	mV/ $^{\circ}C$

■ HA17807P, HA17807 ELECTRICAL CHARACTERISTICS

($V_{in}=12.5V$, $I_{out}=500mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Conditions	max	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	6.72	7.0	7.28	V
		$9V \leq V_{in} \leq 22V$, $5mA \leq I_{out} \leq 1.0A$, $P_T \leq 15W$	6.65	—	7.35	V
Line Regulation	$\delta V_{o \text{ line}}$	$T_j=25^{\circ}C$	—	5.5	140	mV
		$10V \leq V_{in} \leq 15V$	—	1.7	70	mV
Load Regulation	$\delta V_{o \text{ load}}$	$T_j=25^{\circ}C$	—	13	140	mV
		$250mA \leq I_{out} \leq 750mA$	—	4	70	mV
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.3	8.0	mA
Quiescent Current Change	δI_Q	$9V \leq V_{in} \leq 25V$	—	—	1.3	mA
		$5mA \leq I_{out} \leq 1.0A$	—	—	0.5	mA
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	48.5	—	μV
Ripple Rejection Ratio	RR_{REJ}	$f=120Hz$	57	73	—	dB
Voltage Drop	V_{DROP}	$I_{out}=1.0A$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Resistance	R_{out}	$f=1kHz$	—	17	—	m Ω
Output Short Circuit Current	I_{OS}	$T_j=25^{\circ}C$	—	500	—	mA
Peak Output Current	$I_{o \text{ peak}}$	$T_j=25^{\circ}C$	—	2.2	—	A
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-0.8	—	mV/ $^{\circ}C$

■ HA17808P, HA17808 ELECTRICAL CHARACTERISTICS

($V_{in}=14V$, $I_{out}=500mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	7.7	8.0	8.3	V
		$10.5V \leq V_{in} \leq 23V$, $5mA \leq I_{out} \leq 1.0A$, $P_T \leq 15W$	7.6	—	8.4	V
Line Regulation	$\delta V_{o \text{ line}}$	$T_j=25^{\circ}C$	—	6.0	160	mV
		$11V \leq V_{in} \leq 17V$	—	2.0	80	mV
Load Regulation	$\delta V_{o \text{ load}}$	$T_j=25^{\circ}C$	—	12	160	mV
		$250mA \leq I_{out} \leq 750mA$	—	4.0	80	mV
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.3	8.0	mA
Quiescent Current Change	δI_Q	$10.5V \leq V_{in} \leq 25V$	—	—	1.0	mA
		$5mA \leq I_{out} \leq 1.0A$	—	—	0.5	mA
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	52	—	μV
Ripple Rejection Ratio	RR_{REJ}	$f=120Hz$	56	72	—	dB
Voltage Drop	V_{DROP}	$I_{out}=1.0A$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Resistance	R_{out}	$f=1kHz$	—	16	—	m Ω
Output Short Circuit Current	I_{OS}	$T_j=25^{\circ}C$	—	450	—	mA
Peak Output Current	$I_{o \text{ peak}}$	$T_j=25^{\circ}C$	—	2.2	—	A
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-0.8	—	mV/ $^{\circ}C$

■ HA17812P, HA17812 ELECTRICAL CHARACTERISTICS

($V_{in} = 19V$, $I_{out} = 500mA$, $0^\circ C \leq T_j \leq 125^\circ C$, $C_{in} = 0.33\mu F$, $C_{out} = 0.1\mu F$; unless otherwise specified.)

Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^\circ C$	11.5	12.0	12.5	V
		$14.5V \leq V_{in} \leq 27V$, $5mA \leq I_{out} \leq 1.0A$, $P_T \leq 15W$	11.5	—	12.6	V
Line Regulation	$\delta V_{o, line}$	$T_j = 25^\circ C$	—	10	240	mV
		$14.5V \leq V_{in} \leq 30V$ $16V \leq V_{in} \leq 22V$	—	3.0	120	mV
Load Regulation	$\delta V_{o, load}$	$T_j = 25^\circ C$	—	12	240	mV
		$5mA \leq I_{out} \leq 1.5A$ $250mA \leq I_{out} \leq 750mA$	—	4.0	120	mV
Quiescent Current	I_Q	$T_j = 25^\circ C$	—	4.3	8.0	mA
Quiescent Current Change	δI_Q	$14.5V \leq V_{in} \leq 30V$	—	—	1.0	mA
		$5mA \leq I_{out} \leq 1.0A$	—	—	0.5	mA
Output Noise Voltage	V_n	$T_a = 25^\circ C$, $10Hz \leq f \leq 100kHz$	—	75	—	μV
Ripple Rejection Ratio	R_{RRJ}	$f = 120Hz$	55	71	—	dB
Voltage Drop	V_{DROP}	$I_{out} = 1.0A$, $T_j = 25^\circ C$	—	2.0	—	V
Output Resistance	R_{out}	$f = 1kHz$	—	18	—	m Ω
Output Short Circuit Current	I_{OS}	$T_j = 25^\circ C$	—	350	—	mA
Peak Output Current	$I_{o, peak}$	$T_j = 25^\circ C$	—	2.2	—	A
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	—	-1.0	—	mV/ $^\circ C$

■ HA17815P, HA17815 ELECTRICAL CHARACTERISTICS

($V_{in} = 23V$, $I_{out} = 500mA$, $0^\circ C \leq T_j \leq 125^\circ C$, $C_{in} = 0.33\mu F$, $C_{out} = 0.1\mu F$; unless otherwise specified.)

Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^\circ C$	14.4	15.0	15.6	V
		$17.5V \leq V_{in} \leq 30V$, $5mA \leq I_{out} \leq 1.0A$, $P_T \leq 15W$	14.25	—	15.75	V
Line Regulation	$\delta V_{o, line}$	$T_j = 25^\circ C$	—	11	300	mV
		$17.5V \leq V_{in} \leq 30V$ $20V \leq V_{in} \leq 26V$	—	3	150	mV
Load Regulation	$\delta V_{o, load}$	$T_j = 25^\circ C$	—	12	300	mV
		$5mA \leq I_{out} \leq 1.5A$ $250mA \leq I_{out} \leq 750mA$	—	4	150	mV
Quiescent Current	I_Q	$T_j = 25^\circ C$	—	4.4	8.0	mA
Quiescent Current Change	δI_Q	$17.5V \leq V_{in} \leq 30V$	—	—	1.0	mA
		$5mA \leq I_{out} \leq 1.0A$	—	—	0.5	mA
Output Noise Voltage	V_n	$T_a = 25^\circ C$, $10Hz \leq f \leq 100kHz$	—	90	—	μV
Ripple Rejection Ratio	R_{RRJ}	$f = 120Hz$	54	70	—	dB
Voltage Drop	V_{DROP}	$I_{out} = 1.0A$, $T_j = 25^\circ C$	—	2.0	—	V
Output Resistance	R_{out}	$f = 1kHz$	—	19	—	m Ω
Output Short Circuit Current	I_{OS}	$T_j = 25^\circ C$	—	230	—	mA
Peak Output Current	$I_{o, peak}$	$T_j = 25^\circ C$	—	2.1	—	A
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	—	-1.0	—	mV/ $^\circ C$

■ HA17818P, HA17818 ELECTRICAL CHARACTERISTICS

(V_{in}=27V, I_{out}=500mA, 0°C ≤ T_j ≤ 125°C, C_{in}=0.33μF, C_{out}=0.1μF; unless otherwise specified.)

Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V _{out}	T _j =25°C	17.3	18.0	18.7	V
		21V ≤ V _{in} ≤ 33V, 5mA ≤ I _{out} ≤ 1.0A, P _T ≤ 15W	17.1	—	18.9	V
Line Regulation	δV _{s line}	T _j =25°C	—	15	360	mV
		21V ≤ V _{in} ≤ 33V	—	5.0	180	mV
Load Regulation	δV _{s load}	T _j =25°C	—	12	360	mV
		5mA ≤ I _{out} ≤ 1.5A	—	4.0	180	mV
Quiescent Current	I _q	T _j =25°C	—	4.5	8.0	mA
Quiescent Current Change	δI _q	21V ≤ V _{in} ≤ 33V	—	—	1.0	mA
		5mA ≤ I _{out} ≤ 1.0A	—	—	0.5	mA
Output Noise Voltage	V _n	T _a =25°C, 10Hz ≤ f ≤ 100kHz	—	110	—	μV
Ripple Rejection Ratio	R _{REJ}	f=120Hz	53	69	—	dB
Voltage Drop	V _{DROP}	I _{out} =1.0A, T _j =25°C	—	2.0	—	V
Output Resistance	R _{out}	f=1kHz	—	22	—	mΩ
Output Short Circuit Current	I _{OS}	T _j =25°C	—	200	—	mA
Peak Output Current	I _{s peak}	T _j =25°C	—	2.1	—	A
Temperature Coefficient of Output Voltage	δV _{out} /δT _j	I _{out} =5mA, 0°C ≤ T _j ≤ 125°C	—	-1.0	—	mV/°C

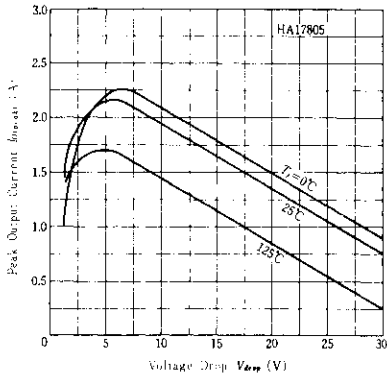
■ HA17824P, HA17824 ELECTRICAL CHARACTERISTICS

(V_{in}=33V, I_{out}=500mA, 0°C ≤ T_j ≤ 125°C, C_{in}=0.33μF, C_{out}=0.1μF; unless otherwise specified.)

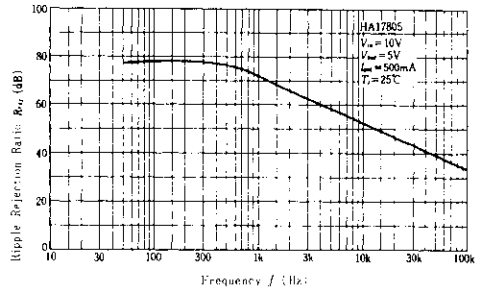
Item	Symbol	Test Conditions	min	typ	max	Unit
Output Voltage	V _{out}	T _j =25°C	23.0	24.0	25.0	V
		27V ≤ V _{in} ≤ 38V, 5mA ≤ I _{out} ≤ 1.0A, P _T ≤ 15W	22.8	—	25.2	V
Line Regulation	δV _{s line}	T _j =25°C	—	18	480	mV
		27V ≤ V _{in} ≤ 38V	—	6	240	mV
Load Regulation	δV _{s load}	T _j =25°C	—	12	480	mV
		5mA ≤ I _{out} ≤ 1.5A	—	4	240	mV
Quiescent Current	I _q	T _j =25°C	—	4.6	8.0	mA
Quiescent Current Change	δI _q	27V ≤ V _{in} ≤ 38V	—	—	1.0	mA
		5mA ≤ I _{out} ≤ 1.0A	—	—	0.5	mA
Output Noise Voltage	V _n	T _a =25°C, 10Hz ≤ f ≤ 100kHz	—	170	—	μV
Ripple Rejection Ratio	R _{REJ}	f=120Hz	50	66	—	dB
Voltage Drop	V _{DROP}	I _{out} =1.0A, T _j =25°C	—	2.0	—	V
Output Resistance	R _{out}	f=1kHz	—	28	—	mΩ
Output Short Circuit Current	I _{OS}	T _j =25°C	—	150	—	mA
Peak Output Current	I _{s peak}	T _j =25°C	—	2.1	—	A
Temperature Coefficient of Output Voltage	δV _{out} /δT _j	I _{out} =5mA, 0°C ≤ T _j ≤ 125°C	—	-1.5	—	mV/°C

■ CHARACTERISTICS CURVE

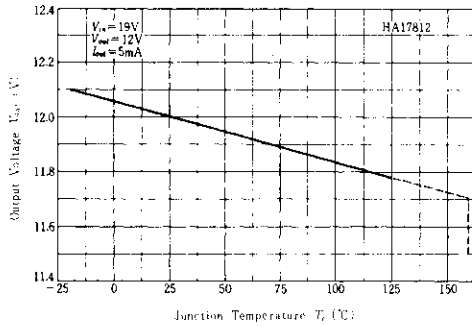
PEAK OUTPUT VS. VOLTAGE DROP CURRENT



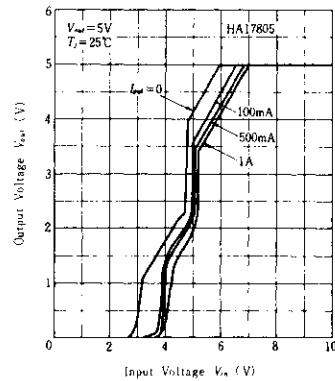
RIPPLE REJECTION VS. FREQUENCY RATIO



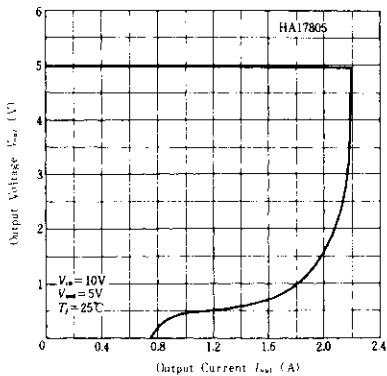
OUTPUT VOLTAGE VS. JUNCTION TEMPERATURE



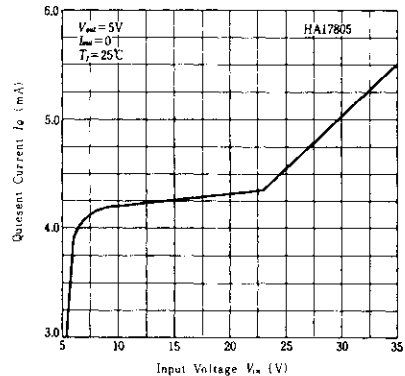
OUTPUT VOLTAGE VS. INPUT VOLTAGE



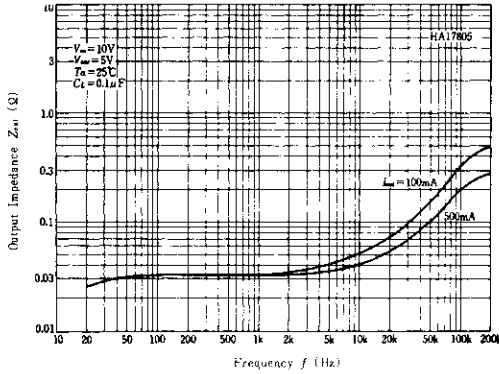
OUTPUT VOLTAGE VS. OUTPUT CURRENT



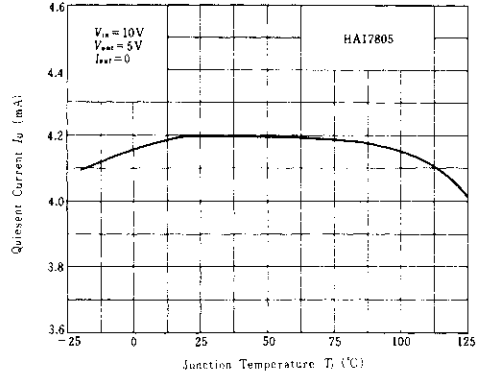
QUIESCENT CURRENT VS. INPUT VOLTAGE



OUTPUT IMPEDANCE VS. FREQUENCY



QUIESCENT CURRENT VS. JUNCTION TEMPERATURE



APPLICATION NOTE

In HA17800P and HA17800 Series, external compensating circuits are eliminated and easy mounting and radiation design like transistors are enabled by employing the TO-220AB package. Output current above 1A is available when using a heat sink. To protect devices from destruction, three protection circuit; current limiter, one against load short circuit and one to control the operating junction temperature, are built-in. HA17800P and HA17800 series are usable fixed voltage sources and the followings shall explain some examples of circuit constructions and applications for further use.

1. Circuit Constructions of HA17800P and HA17800 Series

Fig. 1 shows the internal equivalent circuit and Fig. 2 shows its block diagram of HA17800P and HA17800 Series.

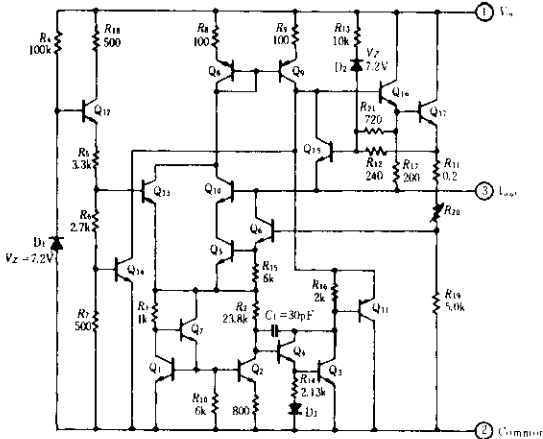


Fig.1 Internal Equivalent Circuit of HA17800P and HA17800 Series

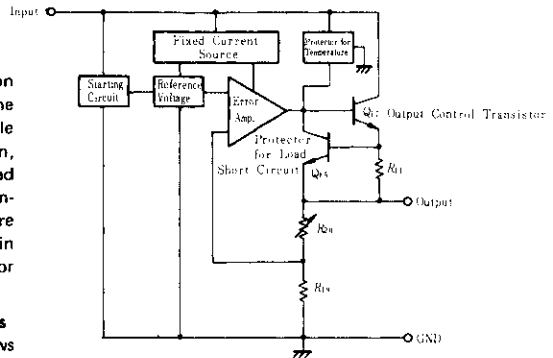


Fig.2 Block Diagram of HA17800P and HA17800 Series

(1) Reference Voltage Circuit

For exemplaining the part generating the reference voltage, the equivalent circuit shall be shown in Fig. 3. As this figure shows clearly, the difference from the conventional method using zener diodes is that the reference voltage is generated by only the base-emitter forward characteristics of transistors. The reference voltage VREF is;

$$V_{REF} = V_{BE4} + V_{BE5} + V_{BE6} + V_{BE3} + R_2 I_{C2} \dots \dots \dots (1)$$

$$R_1 I_{C1} + V_{BE1} = R_2 I_{C2} + V_{BE3} \dots \dots \dots (2)$$

$$V_{BE3} = V_{BE2} + R_3 I_{E2} \dots \dots \dots (3)$$

$$V_{BE} = \frac{kT}{q} \ln \frac{I_C}{I_0} \dots \dots \dots (4)$$

where, assuming that $V_{BE1} \approx V_{BE3}$

$$I_{E2} \approx \frac{kT}{q} \frac{1}{R_3} \ln \frac{R_2}{R_1} \dots \dots \dots (5)$$

$$V_{REF} = V_{BE3} + V_{BE4} + V_{BE5} + V_{BE6} + \frac{kT}{q} \frac{R_2}{R_3} \ln \frac{R_2}{R_1} \dots \dots \dots (6)$$

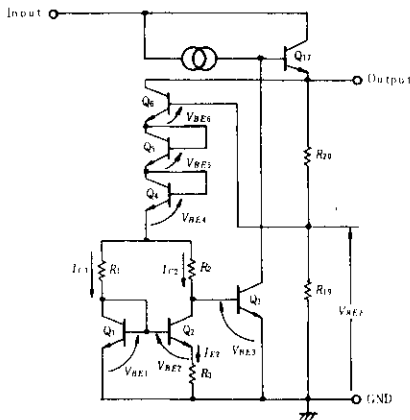


Fig.3 Circuit Generating Reference Voltage

In equation (6), the first four terms in the right to equal sign are V_{BE} and have negative temperature coefficient. On the other hand, the last term has positive temperature coefficient. Then, give value to R_1 , R_2 and R_3 so that $V_{REF} \cong 5V_8 V_{REF}/\delta T = 0$. This reference voltage source which utilize the base-emitter forward voltage of transistors has less noise than the conventional ones using zener diodes. The output voltage is as shown in Fig. 3;

$$V_{out} = V_{REF} \left(1 + \frac{R_{20}}{R_{19}} \right) \dots\dots\dots (7)$$

(2) Protection Circuit

In the HA17800P and HA17800 Series three kinds of protection circuit are provided. One is current limiter constructed by R₁₁, R₁₂, R₂₁ and Q₁₅. Another is one to control output when load is short circuited or the power dissipation of output transistor Q₁₇ exceeds a limit value, constructed by R₁₃ and D₂. The other is one constructed by Q₁₄ which prevents temperature rise on the whole chip.

(3) Other Circuits

The Darlington connection, Q₄—Q₃ in the Fig. 1 operates as an error amplifier as well as a reference voltage generator. As the collector load of Q₃ is a load with high impedance constructing the fixed current source from Q₉, MOS capacitance shall be applied to compensate the frequency characteristics of the error amplifier. It is aiming at stable operation when load conditions changes. Q₁₃ operates as the so-called ignition circuit which flows current to Q₈ when a regulator turns ON and is turned OFF by the rised emitter potential when regulator provides output.

2. CAUTIONS ON USE

Package used in HA17800P and HA17800 Series are TO-220AB, which is used for mid-power transistors and, therefore, the mechanical treatment is as same as in the case of transistors. The other important points are radiation design and the way to by-pass.

2.1 Radiation Design

When the power dissipation of HA17800P and HA17800 series exceeds to 1.67W, a radiator or a heat sink must be

attached so that the junction temperature is below the specified value. If you use the radiators on the market, you must select one with required thermal resistance and pay attention to mounting. If you design by yourself, you can utilize the data in Figs. 4 thru 6.

(An Example of Designing a Heat Sink)

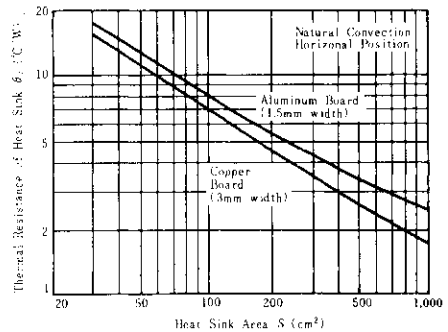


Fig.4 Areas vs Thermal Resistance of Heat Sink

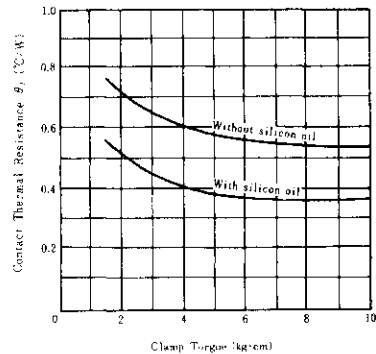


Fig.5 Clamp Torque vs Contact Thermal Resistance

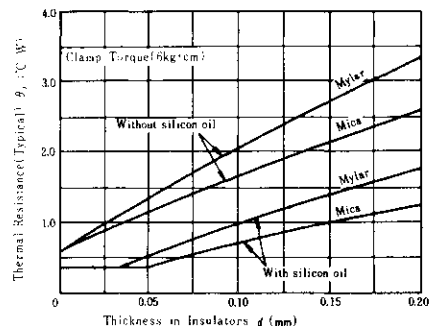


Fig.6 Thickness in Insulators vs Thermal Resistance (Typical)

Assuming to design a radiator which is required when HA17800P and HA17800 Series dissipates 10W in the condition of the maximum ambient temperature is 50°C.

- (1) Ratings of HA17800P and HA17800 Series Junction Temperature $T_j = 125^\circ\text{C}$
Thermal Resistance $\theta_{j-c} = 5^\circ\text{C/W}$
Junction - Case
- (2) When a radiator is used, the relationship between the junction temperature rise and power dissipation will be;

$$\therefore \theta_j = \frac{T_j - T_a}{P_r} \quad \theta_{j-c} - \theta_s$$

Thus the thermal resistance of the required radiator is;

$$\theta_j = \frac{125 - 50}{10} - 5 - 0.4 = 2.1^\circ\text{C/W}$$

- (3) As Fig. 4 indicates, the required area of the heat sink will be 760cm^2 when copperplate of thickness; 3 mm. Then, the heat sink is placed horizontally. If this area is too large, it can be smaller by air-cooling by wind from a fan.

2.2 Way to By-Pass

HA17800P and HA17800 Series may be used as regulators in a simple form, but stable operation requires connection of capacitors for by-passing at input and output as shown in Fig. 7. The capacitor at input, C_{in} must be at least $0.22\mu\text{F}$ to improve the stability in operations and the large capacitance capacitor for smoothing, C may be used at input. The capacitor at output, C_{out} is provided aiming at preventing oscillation and improving transfer characteristics. The output impedance of the regulator increases with increase of frequency. This phenomenon is caused that the gain with devices decreases with the increase of frequency. So, adding a capacitor of about $50\mu\text{F}$ to output as shown in Fig. 8 improves it. When supplying voltage to load which switches in high speed as TTL load, ceramic capacitor or film capacitor with good frequency characteristics shall be connected at output.

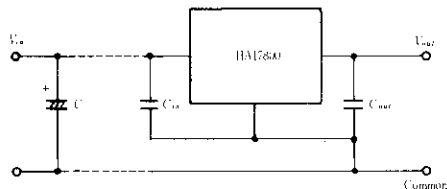


Fig.7 Way to By-pass in HA17800P and HA17800 Series

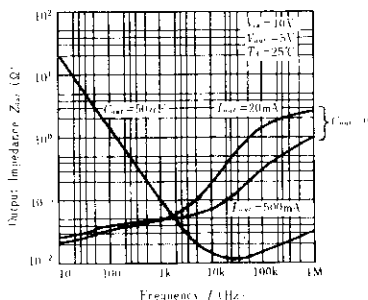


Fig.8 Frequency Characteristics of Output Impedance

3. APPLICATIONS

3.1 Fixed Output Regulators

Fig. 9 shows the most basic form of the 3-terminal fixed output regulator. Fig. 10 shows the operational characteristics of this type regulators.

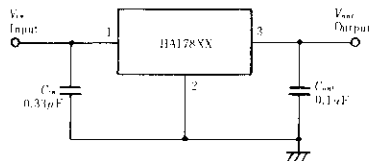
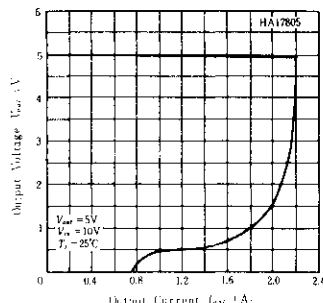
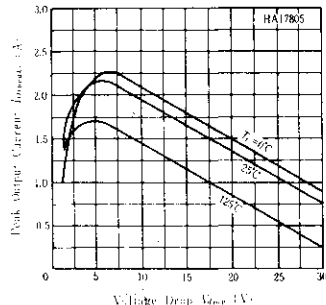


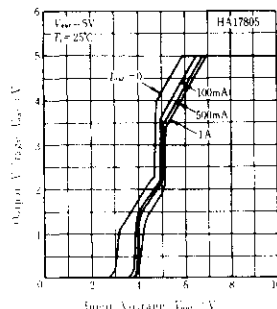
Fig.9 Fixed Output Regulator



(a) Output Voltage vs Output Current



(b) Peak Output Current vs Voltage Drop



(c) Output Voltage vs Input Voltage

Fig.10 Operational Characteristics of Fixed Output Regulator

3.2 A Regulator with Increased Output Voltage

Fig. 11 shows the circuit diagram to increase output voltage utilizing fixed output voltage. The output voltage V_{out} is;

$$V_{out} = \left(1 + \frac{R_2}{R_1}\right) V_{XX} + I_Q R_2$$

where, V_{XX} : Output voltage in HA17800P and HA17800 Series

I_Q : Quiescent Current in HA17800P and HA17800 Series

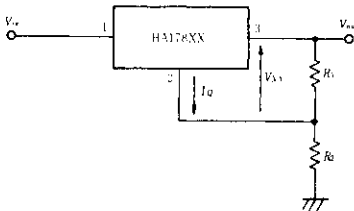


Fig.11 Regulator with Increased Output Voltage

If the resistance ratio, R_2/R_1 are equal, adopting smaller R_1 and R_2 value enables to ignore the voltage drop because of quiescent current, $I_Q R_2$.

However, as smaller resistance causes the larger power dissipation at the resistor, attention must be paid to the power capacitance of the resistor.

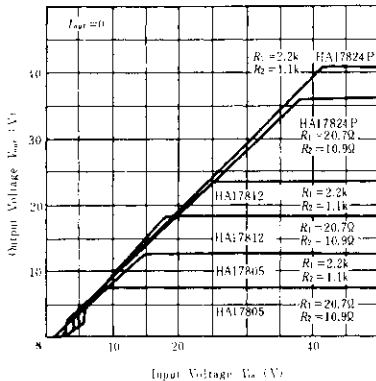


Fig.12 Operational Characteristics of the Regulator with Increased Voltage

3.3 Fixed Current Regulator

Fig. 13 shows the circuit of a fixed current regulator to provide a fixed current. This circuit utilizes the fixed output voltage of HA17800P and HA17800 series to generate a fixed current and is easily designed.

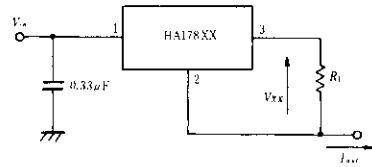


Fig.13 Fixed Current Regulator

The fixed current output, I_{out} is;

$$I_{out} = \frac{V_{XX}}{R_1} + I_Q$$

where, V_{XX} : Output Voltage of HA17800P and HA17800 Series

I_Q : Quiescent Current of HA17800P and HA17800 Series

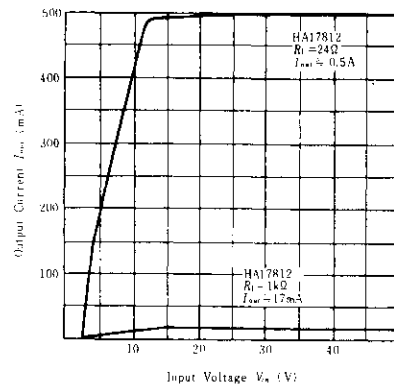


Fig.14 Operational Characteristics of Fixed Current Regulator

If the resistance of R_1 is small and V_{XX}/R_1 is far larger than I_Q , I_{out} is nearly equal to V_{XX}/R_1 . The maximum value of the fixed current output, I_{out} is maximum output current of HA17800P and HA17800 Series, 1.5A. Then, the power of the resistor R_1 and the maximum power dissipation of HA17800P and HA17800 Series must be considered.

3.4 Variable Output Voltage (7 to 30V, 0.5 to 10V) Regulator

Fig. 15 shows the circuit of a regulator whose output voltage is variable from 7 to 30 volts and Fig. 17 shows that of a regulator whose output voltage is variable from 0.5 to 10V. In each case, output voltage is controlled by an operational amplifier and the output voltage is;

$$V_{out} = \left(1 + \frac{R_2}{R_1}\right) V_{XX} \quad (\text{In case of Fig. 15})$$

$$V_{out} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \times \frac{R_3}{R_1} V_{XX} \quad (\text{In case of Fig. 17})$$

The relationships of the adjusting point potential of the variable resistor, R , V_R and output voltage, V_{out} are shown in Fig. 16 and Fig. 18. Operational amplifiers should be selected considering supply voltage, common mode input voltage range, output voltage range and so on. When oscillation happened, inserting a capacitor between V_{in} and Common Terminal is an effective measure.

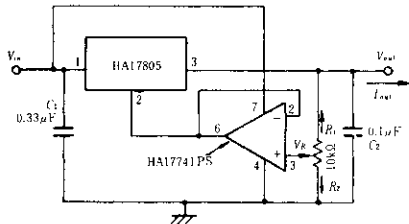


Fig.15 Variable Output Voltage (7 to 30V) Regulator

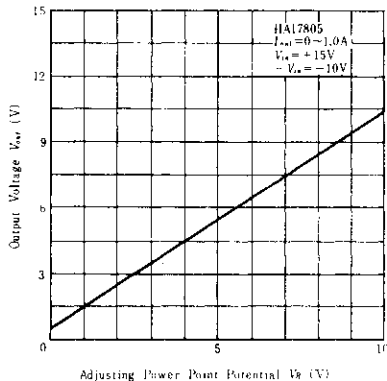


Fig.16 The Variable Output Voltage (7 to 30V) Regulator—Adjusting Power Point Potential, V_R Characteristics

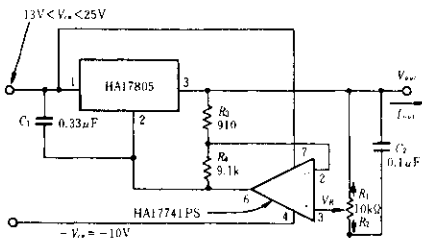


Fig.17 Variable Output Voltage (0.5 to 10V) Regulator

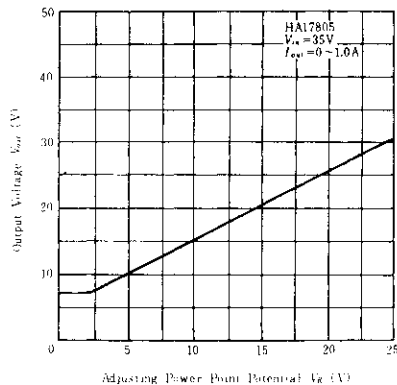


Fig.18 The Variable Output Voltage (0.5 to 10V) Regulator—Adjusting Power Point Potential, V_R Characteristics

3.5 Regulator with Increased Output Current

In HA17800P and HA17800 Series, output current above 1A is available and larger current is available by externally adding a transistor as shown in Fig. 19. Then, the relationship of the current amplification factor, h_{FE} of the transistor Q_1 and current in each parts must be

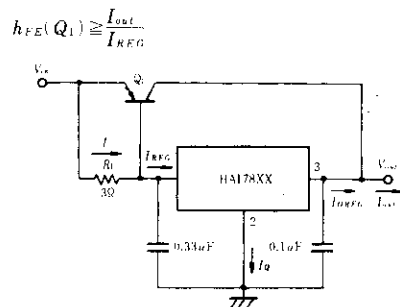


Fig.19 Regulator with Increased Output Current (1)

$$I_{out} = (1 + h_{FE}) I_{OREG} + h_{FE} I_Q + h_{FE} I$$

$$I_{OREG} = \frac{h_{FE}}{1 + h_{FE}} \left(\frac{I_{out}}{h_{FE}} + I + I_Q \right)$$

The output current decreases from I_{out} to I_{OREG} in appearance and the load regulation will be improved.

A circuit where a current limiter is added to the basic regulator with increased output current in Fig. 19 shall be shown in Fig. 20. The limit value of the output current I_{out} limit is determined as;

$$I_{out} \text{ limit} = \frac{V_{BE} \cdot Q_2}{R_{SC}}$$

Fig. 21 shows the operational characteristics of the circuit in Fig. 20. On determining R_{CS} , line impedance and contact resistance should be considered.

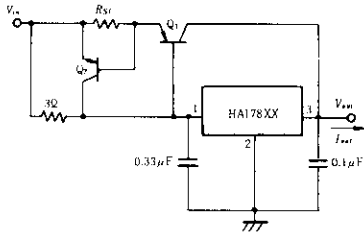


Fig. 20 Regulator with Increased Output Current (2)

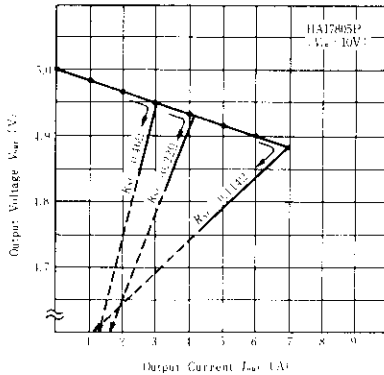


Fig. 21 Operational Characteristics of the Regulator with Increased Output Current (2)

3.6 Positive and Negative Voltage Regulator

Fig. 22 shows the circuit of a regulator which provides both positive and negative output, constructed by 2 devices of HA17800P and HA17800 Series. The portion providing positive output is basically the same as in 3.1 the fixed output regulator.

In the portion providing negative output, the input of HA17800P and HA17800 series is floating state, output terminal V_{out} is grounded and the negative voltage is taken out of the common terminal.

Fig. 22 shows the circuit to get larger power than the commercial source. Its ripple voltage at output will be determined by the characteristics of the smoothing circuit and ripple rejection ratio in HA17800P and HA17800 series – 78 dB typ: in case of 05P, 05.

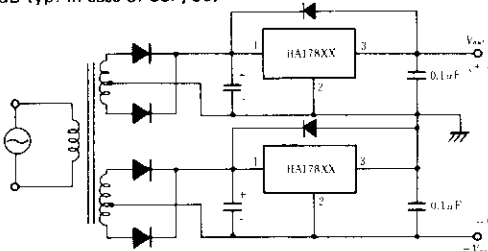
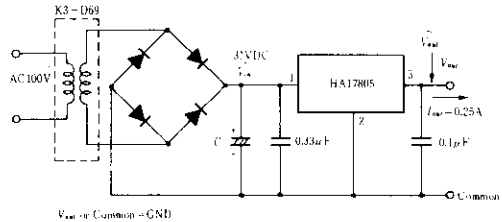
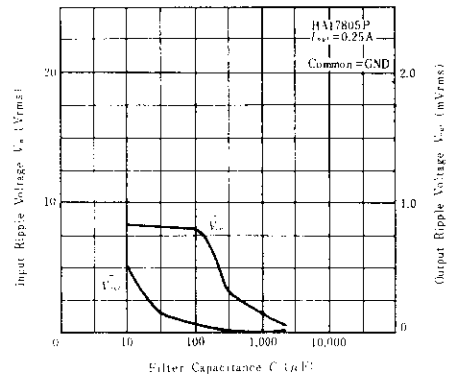


Fig. 22 Positive and Negative Voltage Regulator

Fig. 23 shows the smoothing capacitance C and ripple characteristics at input and output when the transformer K3-D69 is employed.



(a) Fixed Output Regulator



(b) Input Output Ripple Characteristics

Fig. 23 Characteristics of Fixed Output Regulator with a Rectifier

3.7 Switching Regulator

Fig. 24 shows the circuit of a switching regulator. This circuit stabilizes the output voltage with self-oscillating and the change in output voltage will be absorbed by changing the conducting period of the switching transistor Q . The minimum operational input voltage, $V_{in \min}$ is;

$$V_{in \min} = V_{XX} + V_{Z1} ZD_1 + V_{EB} Q$$

The zener diode, ZD_1 is to reduce the voltage applied to HA17800P and HA17800 series. The period during the switching element Q is ON becomes longer with the increment of load current and the oscillation cycle is nearly proportional to the inductance L . The current capacitance of Q must be twice as large as the load current.

Fig. 25 shows the operational characteristics of the circuit in Fig. 24.

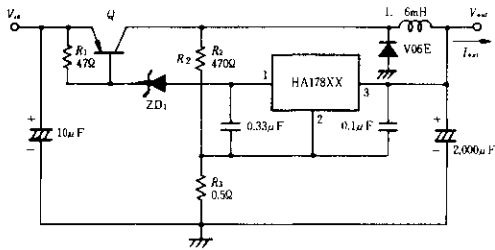


Fig.24 Switching Regulator

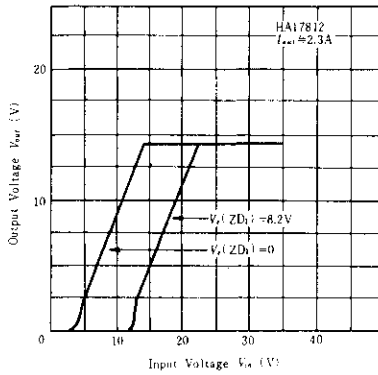


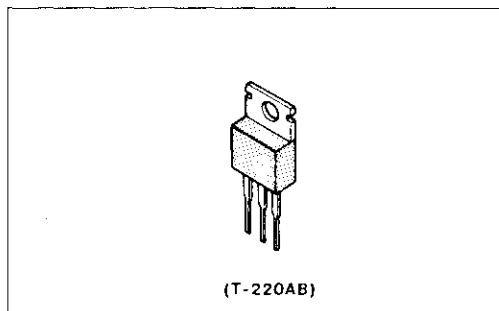
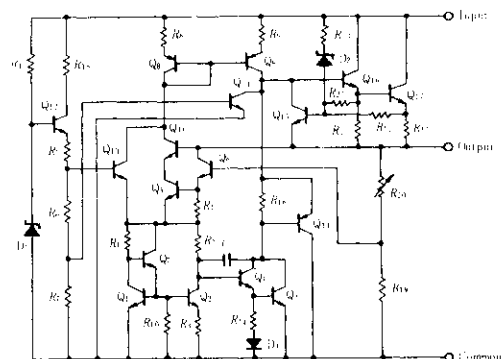
Fig.25 Operational Characteristics of the Switching Regulator

HA178M00P, HA178M00 Series 3-terminal Fixed Voltage Regulators

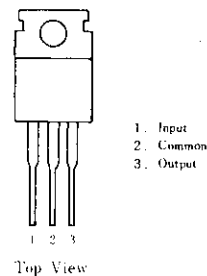
FEATURES

- Output Current more than 500mA
- Possible to be widely used as power source with various output voltage; 5V, 6V, 7V, 8V, 12V, 15V, 18V, 20V & 24V
- No external compensation circuit required.
- TO-220AB package and easy mounting & easy design for heat sink, as same as a transistor.
- Built-in current control circuit protects elements from destruction by short circuit.
- Chip junction temperature limiting circuit built in protects elements from thermal destruction.
- Internal power dissipation limiting circuit built in protects transistors in output stage.
- Industrial Use; HA178M00P Series
- Commercial Use; HA178M00 Series

CIRCUIT SCHEMATIC



PIN ARRANGEMENT



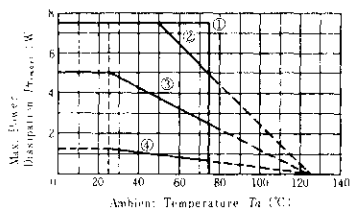
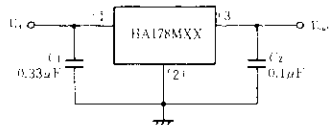
ABSOLUTE MAXIMUM RATINGS (Ta = -25°C)

Item	Symbol	Rating	Unit
Input Voltage	V_{in}^*	35	V
Input Voltage	V_{in}^{**}	40	V
Power Dissipation	P_T^{***}	7.5	W
Operating Temperature	T_{op}	20 to +75	°C
Junction Temperature	T_j	20 to +125	°C
Storage Temperature	T_{stg}	-55 to -125	°C

Note

- * For HA178M05P, HA178M18P, HA178M05, HA178M18
- ** For HA178M20P, HA178M24P, HA178M20, HA178M24
- *** Follow the derating curve shown below.

STANDARD CONNECTING CIRCUIT



- (1) Infinity heat sink
 - (2) 5°C/W heat sink } Included fixed thermal
 - (3) 15°C/W heat sink } resistance
 - (4) No heat sink
- thermal resistance
- θ_{JA} : 3.0°C/W typ.
 5.0°C/W max.
 θ_{JA} : 62°C/W typ.
 72°C/W max.

■ HA178M05P, HA178M05 ELECTRICAL CHARACTERISTICS

($V_{in}=10V$, $I_{out}=350mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	4.8	5.0	5.2	V
		$7V \leq V_{in} \leq 20V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	4.75	—	5.25	
Line Regulation	$\delta V_{o, I_{out}}$	$T_j=25^{\circ}C$	—	3	100	mV
		$7V \leq V_{in} \leq 25V$, $I_{out}=200mA$	—	1	50	
Load Regulation	$\delta V_{o, I_{load}}$	$T_j=25^{\circ}C$	—	20	100	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	50	
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.5	6.0	mA
Quiescent Current Change	δI_Q	$8V \leq V_{in} \leq 25V$, $I_{out}=200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	40	—	μV
Ripple Rejection Ratio	R_{REJ}	$f=120Hz$, $I_{out}=100mA$	62	80	—	dB
		$T_j=25^{\circ}C$, $I_{out}=300mA$	62	80	—	
Drop Out Voltage	V_{drop}	$I_{out}=350mA$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j=25^{\circ}C$, $V_{in}=35V$	—	300	—	mA
Peak Output Current	$I_{O peak}$	$T_j=25^{\circ}C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-1.0	—	mV/ $^{\circ}C$

■ HA178M06P, HA178M06 ELECTRICAL CHARACTERISTICS

($V_{in}=11V$, $I_{out}=350mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	5.75	6.0	6.25	V
		$8V \leq V_{in} \leq 21V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	5.7	—	6.3	
Line Regulation	$\delta V_{o, I_{out}}$	$T_j=25^{\circ}C$	—	5	100	mV
		$9V \leq V_{in} \leq 25V$, $I_{out}=200mA$	—	1.5	50	
Load Regulation	$\delta V_{o, I_{load}}$	$T_j=25^{\circ}C$	—	20	120	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	60	
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.5	6.0	mA
Quiescent Current Change	δI_Q	$9V \leq V_{in} \leq 25V$, $I_{out} \leq 200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	45	—	μV
Ripple Rejection Ratio	R_{REF}	$f=120Hz$, $I_{out}=100mA$	59	80	—	dB
		$T_j=25^{\circ}C$, $I_{out}=300mA$	59	80	—	
Drop Out Voltage	V_{drop}	$I_{out}=350mA$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j=25^{\circ}C$, $V_{in}=35V$	—	270	—	mA
Peak Output Current	$I_{O peak}$	$T_j=25^{\circ}C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-0.5	—	mV/ $^{\circ}C$

■ HA178M07P, HA178M07 ELECTRICAL CHARACTERISTICS

($V_{in}=12.5V$, $I_{out}=350mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	6.72	7.0	7.28	V
		$9V \leq V_{in} \leq 22V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	6.65	—	7.35	
Line Regulation	$\delta V_{o, I_{out}}$	$T_j=25^{\circ}C$	—	5.5	100	mV
		$10V \leq V_{in} \leq 25V$, $I_{out}=200mA$	—	1.7	50	
Load Regulation	$\delta V_{o, I_{load}}$	$T_j=25^{\circ}C$	—	23	140	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	70	
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.6	6.0	mA
Quiescent Current Change	δI_Q	$10V \leq V_{in} \leq 25V$, $I_{out}=200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	48.5	—	μV
Ripple Rejection Ratio	R_{REF}	$f=120Hz$, $I_{out}=100mA$	57	80	—	dB
		$T_j=25^{\circ}C$, $I_{out}=300mA$	57	80	—	
Drop Out Voltage	V_{drop}	$I_{out}=350mA$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j=25^{\circ}C$, $V_{in}=35V$	—	260	—	mA
Peak Output Current	$I_{O peak}$	$T_j=25^{\circ}C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-0.5	—	mV/ $^{\circ}C$

■ HA178M08P, HA178M08 ELECTRICAL CHARACTERISTICS

($V_{in} = 14V$, $I_{out} = 350mA$, $0^\circ C \leq T_j \leq 125^\circ C$, $C_{in} = 0.33\mu F$, $C_{out} = 0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^\circ C$	7.7	8.0	8.3	V
		$10.5V \leq V_{in} \leq 23V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	7.6	—	8.4	
Line Regulation	$\delta V_{L, load}$	$T_j = 25^\circ C$	—	6.0	100	mV
		$10.5V \leq V_{in} \leq 25V$, $I_{out} = 200mA$	—	2.0	50	
Load Regulation	$\delta V_{L, load}$	$T_j = 25^\circ C$	—	25	160	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	80	
Quiescent Current	I_Q	$T_j = 25^\circ C$	—	4.6	6.0	mA
Quiescent Current Change	δI_Q	$10.5V \leq V_{in} \leq 25V$, $I_{out} = 200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a = 25^\circ C$, $10Hz \leq f \leq 100kHz$	—	52	—	μV
Ripple Rejection Ratio	R_{RRF}	$f = 120Hz$, $I_{out} = 100mA$	56	80	—	dB
		$T_j = 25^\circ C$, $I_{out} = 300mA$	56	80	—	
Drop Out Voltage	V_{drop}	$I_{out} = 350mA$, $T_j = 25^\circ C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j = 25^\circ C$, $V_{in} = 35V$	—	250	—	mA
Peak Output Current	I_{peak}	$T_j = 25^\circ C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	—	-0.5	—	mV/ $^\circ C$

■ HA178M12P, HA178M12 ELECTRICAL CHARACTERISTICS

($V_{in} = 19V$, $I_{out} = 350mA$, $0^\circ C \leq T_j \leq 125^\circ C$, $C_{in} = 0.33\mu F$, $C_{out} = 0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^\circ C$	11.5	12.0	12.5	V
		$14.5V \leq V_{in} \leq 27V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	11.4	—	12.6	
Line Regulation	$\delta V_{L, load}$	$T_j = 25^\circ C$	—	8.0	100	mV
		$14.5V \leq V_{in} \leq 30V$, $I_{out} = 200mA$	—	2.0	50	
Load Regulation	$\delta V_{L, load}$	$T_j = 25^\circ C$	—	25	240	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	120	
Quiescent Current	I_Q	$T_j = 25^\circ C$	—	4.8	6.0	mA
Quiescent Current Change	δI_Q	$14.5V \leq V_{in} \leq 30V$, $I_{out} = 200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a = 25^\circ C$, $10Hz \leq f \leq 100kHz$	—	75	—	μV
Ripple Rejection Ratio	R_{RRF}	$f = 120Hz$, $I_{out} = 100mA$	55	80	—	dB
		$T_j = 25^\circ C$, $I_{out} = 300mA$	55	80	—	
Drop Out Voltage	V_{drop}	$I_{out} = 350mA$, $T_j = 25^\circ C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j = 25^\circ C$, $V_{in} = 35V$	—	440	—	mA
Peak Output Current	I_{peak}	$T_j = 25^\circ C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	—	-1.0	—	mV/ $^\circ C$

■ HA178M15P, HA178M15 ELECTRICAL CHARACTERISTICS

($V_{in} = 23V$, $I_{out} = 350mA$, $0^\circ C \leq T_j \leq 125^\circ C$, $C_{in} = 0.33\mu F$, $C_{out} = 0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j = 25^\circ C$	14.4	15.0	15.6	V
		$17.5V \leq V_{in} \leq 30V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	14.25	—	15.75	
Line Regulation	$\delta V_{L, load}$	$T_j = 25^\circ C$	—	10	100	mV
		$17.5V \leq V_{in} \leq 30V$, $I_{out} = 200mA$	—	3.0	50	
Load Regulation	$\delta V_{L, load}$	$T_j = 25^\circ C$	—	25	300	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	150	
Quiescent Current	I_Q	$T_j = 25^\circ C$	—	4.8	6.0	mA
Quiescent Current Change	δI_Q	$17.5V \leq V_{in} \leq 30V$, $I_{out} = 200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a = 25^\circ C$, $10Hz \leq f \leq 100kHz$	—	90	—	μV
Ripple Rejection Ratio	R_{RRF}	$f = 120Hz$, $I_{out} = 100mA$	54	70	—	dB
		$T_j = 25^\circ C$, $I_{out} = 300mA$	54	70	—	
Drop Out Voltage	V_{drop}	$I_{out} = 350mA$, $T_j = 25^\circ C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j = 25^\circ C$, $V_{in} = 35V$	—	240	—	mA
Peak Output Current	I_{peak}	$T_j = 25^\circ C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out} = 5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	—	-1.0	—	mV/ $^\circ C$

■ HA178M18P, HA178M18 ELECTRICAL CHARACTERISTICS

($V_{in}=27V$, $I_{out}=350mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	17.3	18.0	18.7	V
		$21V \leq V_{in} \leq 33V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	17.1	—	18.9	
Line Regulation	$\delta V_{o, line}$	$T_j=25^{\circ}C$	—	10	100	mV
		$21V \leq V_{in} \leq 33V$, $I_{out}=200mA$	—	5.0	50	
Load Regulation	$\delta V_{o, load}$	$T_j=25^{\circ}C$	—	25	360	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	180	
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.8	6.0	mA
Quiescent Current Change	δI_Q	$21 \leq V_{in} \leq 33V$, $I_{out}=200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	110	—	μV
Ripple Rejection Ratio	R_{REF}	$f=120Hz$, $I_{out}=100mA$	53	70	—	dB
		$T_j=25^{\circ}C$, $I_{out}=300mA$	53	70	—	
Drop Out Voltage	V_{drop}	$I_{out}=350mA$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j=25^{\circ}C$, $V_{in}=35V$	—	240	—	mA
Peak Output Current	I_{peak}	$T_j=25^{\circ}C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-1.0	—	mV/ $^{\circ}C$

■ HA178M20P, HA178M20 ELECTRICAL CHARACTERISTICS

($V_{in}=29V$, $I_{out}=350mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	19.2	20	20.8	V
		$23V \leq V_{in} \leq 35V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	19	—	21	
Line Regulation	$\delta V_{o, line}$	$T_j=25^{\circ}C$	—	10	100	mV
		$23V \leq V_{in} \leq 35V$, $I_{out}=200mA$	—	5.0	50	
Load Regulation	$\delta V_{o, load}$	$T_j=25^{\circ}C$	—	30	400	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	200	
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.9	6.0	mA
Quiescent Current Change	δI_Q	$23V \leq V_{in} \leq 35V$, $I_{out}=200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	110	—	μV
Ripple Rejection Ratio	R_{REF}	$f=120Hz$, $I_{out}=100mA$	53	70	—	dB
		$T_j=25^{\circ}C$, $I_{out}=300mA$	53	70	—	
Drop Out Voltage	V_{drop}	$I_{out}=350mA$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j=25^{\circ}C$, $V_{in}=35V$	—	240	—	mA
Peak Output Current	I_{peak}	$T_j=25^{\circ}C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-1.1	—	mV/ $^{\circ}C$

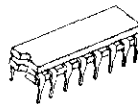
■ HA178M24P, HA178M24 ELECTRICAL CHARACTERISTICS

($V_{in}=33V$, $I_{out}=350mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$, $C_{in}=0.33\mu F$, $C_{out}=0.1\mu F$, unless otherwise specified.)

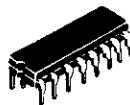
Item	Symbol	Test Condition	min	typ	max	Unit
Output Voltage	V_{out}	$T_j=25^{\circ}C$	23.0	24.0	25.0	V
		$27V \leq V_{in} \leq 38V$, $P_T \leq 7.5W$, $5mA \leq I_{out} \leq 350mA$	22.8	—	25.2	
Line Regulation	$\delta V_{o, line}$	$T_j=25^{\circ}C$	—	10	100	mV
		$27V \leq V_{in} \leq 38V$, $I_{out}=200mA$	—	5.0	50	
Load Regulation	$\delta V_{o, load}$	$T_j=25^{\circ}C$	—	30	480	mV
		$5mA \leq I_{out} \leq 500mA$	—	10	240	
Quiescent Current	I_Q	$T_j=25^{\circ}C$	—	4.6	8.0	mA
Quiescent Current Change	δI_Q	$27V \leq V_{in} \leq 38V$, $I_{out}=200mA$	—	—	0.8	mA
		$5mA \leq I_{out} \leq 350mA$	—	—	0.5	
Output Noise Voltage	V_n	$T_a=25^{\circ}C$, $10Hz \leq f \leq 100kHz$	—	170	—	μV
Ripple Rejection Ratio	R_{REF}	$f=120Hz$, $I_{out}=100mA$	50	70	—	dB
		$T_j=25^{\circ}C$, $I_{out}=300mA$	50	70	—	
Drop Out Voltage	V_{drop}	$I_{out}=350mA$, $T_j=25^{\circ}C$	—	2.0	—	V
Output Short-circuit Current	I_{OS}	$T_j=25^{\circ}C$, $V_{in}=35V$	—	240	—	mA
Peak Output Current	I_{peak}	$T_j=25^{\circ}C$	—	700	—	mA
Temperature Coefficient of Output Voltage	$\delta V_{out}/\delta T_j$	$I_{out}=5mA$, $0^{\circ}C \leq T_j \leq 125^{\circ}C$	—	-1.2	—	mV/ $^{\circ}C$

● Switching Regulator Controller

- Pulse Width Modulation (PWM)
- Wide Operating Frequency Range 450kHz (typ)
- Low Quiescent Current 5mA typ
- Good Line Regulation (0.2% typ) and Load Regulation (0.4% typ)
- Provides independent output stage of 2 channels. Wide external circuit application including single end method and push-pull method.
- Reference Power Source Output Stage and Switching Output Stage include current limiting protection circuit.
- Compatible with SG3524



(DG-16)



(DP-16)

[illegible]

Pin diagram of the 74VHC04 hex inverters. The diagram shows a rectangular package with 14 pins. Pin 1 is labeled 'INV Input', pin 2 'NON-INV Input', pin 3 'OSC Out', pin 4 'V1+', pin 5 'V1+', pin 6 'Rt', pin 7 'GND', pin 8 'GND', pin 9 'V2+', pin 10 'V2+', pin 11 'Rt', pin 12 'SHUT DOWN', pin 13 'COMP', and pin 14 'V2+'. The package is labeled '74VHC04' at the top and 'TIP VIEW' at the bottom.

(Unless otherwise specified, $T_a = +25^\circ\text{C}$.)

Item	Symbol	Rating	Unit	Note No
Supply Voltage	V_{CC}	40	V	1, 2
Collector Output Current	I_C	100	mA	
Reference Output Current	I_{REF}	50	mA	
Current through C_3 Terminal	I_{C3}	5	mA	
Continuous Total Power Dissipation	P_T	600	mW	3
Operating Free-Air Temperature Range	T_{op}	20 to +75	°C	
Storage Temperature Range	Cerdip	65 to +150	°C	
	Plastic	55 to +125		

Package	Power Rating	Derating Factor	Above T_u
P	600mW	8.3mW/°C	52.7°C
G	600mW	7.6mW/°C	71°C

Note 1. With respect to network ground terminal.
2. The reference voltage can be given by connecting the V_{cc} and 5V reference output pins both to the Supply Voltage. In this configuration, V_{cc} = 6V_{max}.
3. HAI17524P: Value at T_a: -52...71 °C. In case of more than it, 8.3mV/°C derating shall be performed.
4. HAI17524G: Value at T_a: -71°C. In case of more than it, 7.6mV/°C derating shall be performed.

■ ELECTRICAL CHARACTERISTICS ($V_{CC}=20V$, $f=20kHz$, $T_a=25^\circ C$)

	Item	Symbol	Test Conditions	min	typ	max	Unit
Regulator	Output Voltage	V_{REF}		4.6	5.0	5.4	V
	Input Regulation	$\delta V_{OL,reg}$	$V_{CC}=8$ to $40V$	—	10	30	mV
	Ripple Rejection	R_{REJ}	$f=120Hz$	—	66	—	dB
	Output Regulation	δV_{OLoad}	$I_{out}=0$ to $20mA$	—	20	50	mV
	Output Voltage Change With Output Temperature	$\delta V_o/\delta T_a$	$T_a=0$ to $+70^\circ C$ $T_a=-20$ to $+75^\circ C$	—	0.3 0.4	1.0 1.36	%
	Short-Circuit* Output Current	I_{OS}	$V_{REF}=0$	—	100	—	mA
Error Amplifier	Input Offset Voltage	V_{IO}	$V_{IC}=2.5V$	—	2	10	mV
	Input Bias Current	I_I	$V_{IC}=2.5V$	—	2	10	μA
	Open-Loop Voltage Gain	A_{VD}		—	60	—	dB
	Common-Mode Input Voltage Range	V_{CM}	$T_a=25^\circ C$	1.8 to 3.4	—	—	V
	Common-Mode Rejection Ratio	CMR		—	70	—	dB
	Unity-Gain Bandwidth	BW		—	3	—	MHz
Oscillator	Output Swing	V_{OPP}		0.5	—	3.8	V
	OSC. Frequency	f	$C_T=0.001\mu F$, $R_T=2k\Omega$	—	450	—	kHz
	Standard Deviation of Frequency	Δf	$V_{CC}=8$ to $40V$ $R_T=1.8$ to $100k\Omega$ $C=Const$	—	5	—	%
	Frequency Change with Temperature	δf_{Line}	$V_{CC}=8$ to $40V$	—	—	1.0	%
		$\delta f/\delta T_a$	$T_a=0$ to $+70^\circ C$ $T_a=-20$ to $+75^\circ C$	—	5.0 5.0	10 13.6	%
	Output Amplitude	V_{3Pin}	3Pin	—	3.5	—	V
Comparator	Output Pulse Width	T_P	$C_T=0.01\mu F$, 3Pin	—	0.5	—	μs
	Maximum Duty Cycle	D_{MAX}		45	—	—	%
	Input Threshold Voltage	V_{th0}	duty = 0	—	1.0	—	V
		V_{thmax}	duty = max	—	3.5	—	V
Current Limiter	Input Bias Current	I_I		—	-1	—	μA
	Input Voltage Range	V_{IS}		-0.7 to ± 1.0	—	—	V
	Sense Voltage	V_S	$V(Pin9)=2V$, $T_a=25^\circ C$ $V(Pin2) - V(Pin1) \geq 50mV$	180	200	220	mV
Output	Sense Voltage Change with Temperature	$\delta V_S/\delta T_a$	$T_a=-20$ to $+75^\circ C$	—	0.2	—	mV/ $^\circ C$
	Collector-Emitter Breakdown Voltage	V_{CE}		40	—	—	V
	Collector Off-State Current	I_{Leak}	$V_{CE}=40V$	—	0.01	50	μA
	Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=20mA$	—	1	2	V
	Emitter Output Voltage	V_E	$V_{CC}=20V$, $I_F=250\mu A$	17	18	—	V
	Turn-off Voltage Rise Time	t_r	$R_T=2k\Omega$	—	0.2	—	μs
Total Device	Turn-on Voltage Fall Time	t_f		—	0.1	—	μs
	Standby Current	I_{ST}	$V_{CC}=40V$, $V_2=2V$, Pins 1,4,7,8,9,11,14, grounded All other pins open.	—	5.0	10	mA

Note: *Duration of the short-circuit should not exceed one second.

APPLICATION NOTE

● Principal in HA17524 Operation

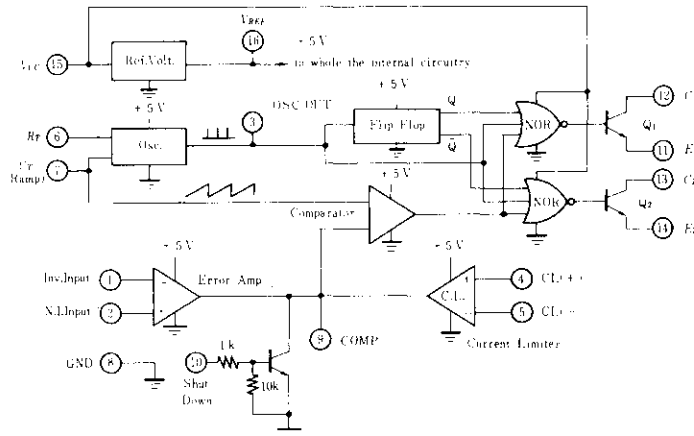


Fig. 1 HA17524 Block Diagram

HA17524 is a switching regulator circuit using Pulsewidth Modulating Method (P.W.M) constructed by the block shown in Fig. 1.

Timing resistance, R_T and timing capacitance, C_T control the oscillating frequency and the C_T is charged by a constant current generated by the R_T . Lump signals (saw-teeth wave) at C_T terminal generated in this oscillator is available for reference input signal to comparators which control the pulse-width.

Commonly connected outputs from the error-amplifier, the current limiter and the shut-down circuit is provided to the comparator, which enable to break output stage by input signal in any one of those circuits.

● Blocks Description

Oscillator; The oscillating frequency f is calculated from the following equations. Fig. 3 shows one example.

$$f \approx 1.15 / (R_T \cdot C_T)$$

$$R_T = 1.8\text{k}\Omega \text{ to } 100\text{k}\Omega$$

$$C_T = 0.001 \text{ to } 0.1\mu\text{F}$$

$$f = 140\text{Hz to } 500\text{kHz}$$

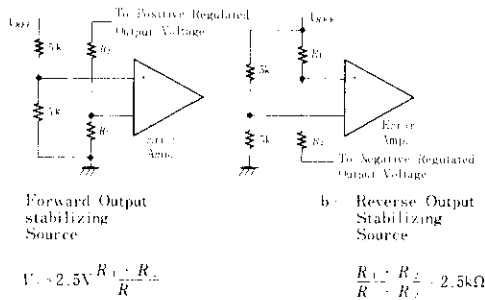


Fig. 2 Biasing in Error-Amplifier

As shown in Fig. 2 the reference voltage connects to non-inverted on inverted input terminal of error-amplifier via resistance divider.

The output voltage from the error-amplifier is compared with the lump signal of the Timing Capacitance C_T , as shown in Fig. 1 and comparator can provide a signal with modulated pulse width.

This signal, then, control output transistors Q_1 and Q_2 , making an open loop to stabilize output voltage.

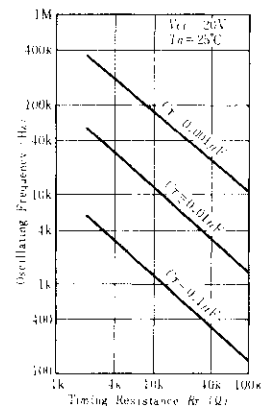


Fig. 3 Oscillating Frequency vs Timing Resistance

Then the lump wave shown in Fig. 4 is available at pin 7, C_T Terminal since the C_T is charged by the constant current I generated by the R_T .

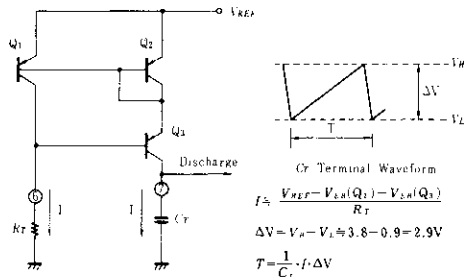


Fig. 4 Oscillating Circuit and C_T Terminal Waveform

The output pulse signal at oscillator is used as elements in Flip-flop circuit and (a synchronous signal of clock-pulse) switching. The pulse-width which can be controlled by the timing capacitor C_T as shown in Fig. 5 provides function to gain a dead time of output.

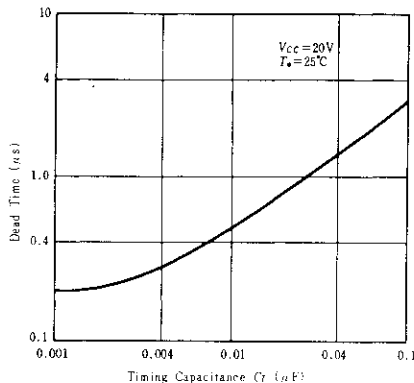


Fig. 5 Dead Time vs Timing Capacitance

Reference Voltage: The regulator (reference voltage: $V_{REF} = 5 \pm 0.4V$) is built in Integrated Circuit. It can be used as reference power supply of error amplifier which determines Output Voltage Output (V_{OUT}). And also, it is connected as bias source of another circuit in IC.

Error Amplifier: Biasing in error amplifier is shown in the Fig. 2. Input Applied Voltage is required to be set within the range of common-mode Input Voltage (1.8V to 3.4V). To control gain of error amplifier, shunt resistor is inserted between phase compensation terminal (Pin 9) and GND. If resistor and capacitor are inserted between phase compensation terminal (Pin 9) and GND in series, phase compensation is available.

Current Limiter: Threshold Voltage (V_S) of sense amplifier for current limiter is calculated as follows;

$$V_S = V_{BE}(Q_1) + I_1 R_2 - V_{BE}(Q_2)$$

$$= I_1 R_2$$

$$= 200mV \text{ typ.}$$

At Current limiter Sense Amp shown in the Fig. 6, when $V + - V \geq 200mV$, Q_1 turns "ON", Phase compensation terminal becomes low level and Output Switching element is cut off.

Fig. 7 shows an example of detecting current limit. As the range of Input Voltage is $-0.7V$ to $+1.0V$; detection output of current limit is provided from GND Line.

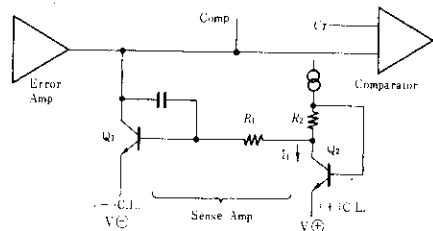
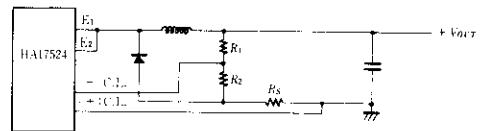


Fig. 7 An Example of detecting current limit



$$I_{O(max)} = \frac{1}{R_S} \left(V_{sense} + \frac{V_O R_2}{R_1 + R_2} \right)$$

$$I_{OS} = \frac{V_{sense}}{R_S}$$

$$V_{sense} = 200mV$$

● Operating waveform at every part

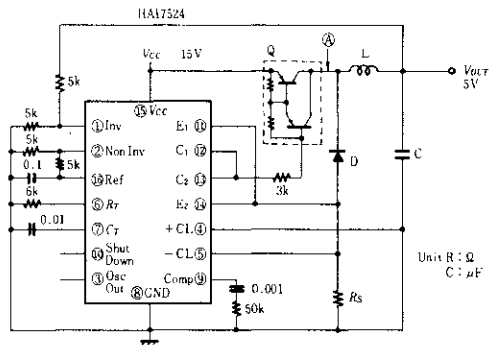


Fig. 8 Breakdown Voltage types Chopper Switching Regulator

Fig. 6 Sense Amplifier for Current Limiter

Fig. 9 shows operating waveform at every part, when the circuit configuration of breakdown voltage type chopper switching regulator (shown in the Fig. 8) is used. Operating Conditions are as follows, $f = 20\text{kHz}$, $V_{OUT} = 5\text{V}$. At output section, two channels are connected in parallel. Operating waveform inside IC is shown at the same time.

CAUTIONS

Compared with the conventional series regulator, switching regulator generates high frequency noise by switching current quickly. To reduce noise, the following shall be followed.

- 1) As a general rule, insert line filter in order to reduce noise at the side of Input.
- 2) To reduce noise at the side of output,
 - (a) Output wiring should be twisted.
 - (b) Power Source and output wiring should not be bundled.
 - (c) Capacitor should be inserted at the side of load.
 - (d) Power frame should be grounded.
- 3) When grounding frame, output (0V) and Shielding wire, Only one of them should be grounded. Impedance must be as low as possible. And also, Power frame should be grounded. In case of choosing external parts-external switching transistor, diode, coil and etc. -, it is necessary to consider their capacitance and characteristics.

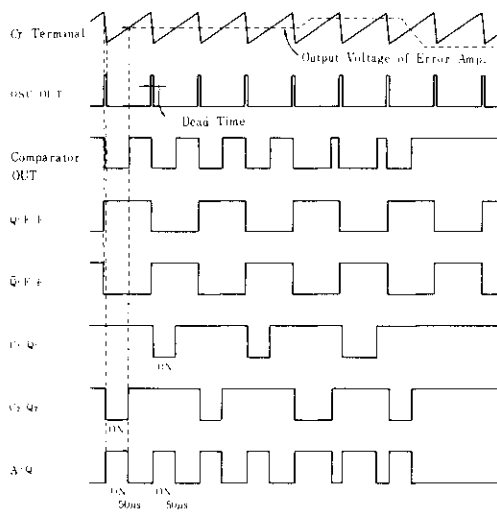


Fig.9 Operating Timing Chart of each part

Circuit Applications

Simple polarity switching regulator: Fig. 10 shows the circuit configuration of HA17524 polarity switching regulator which has small current capacitance ($V_{OUT} = -5\text{V}$).

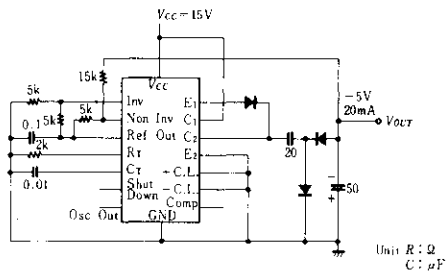
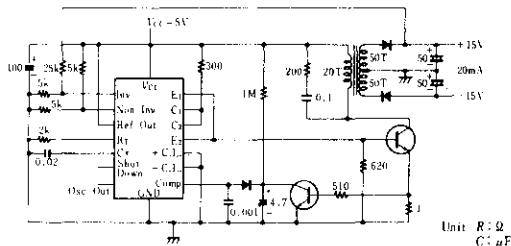
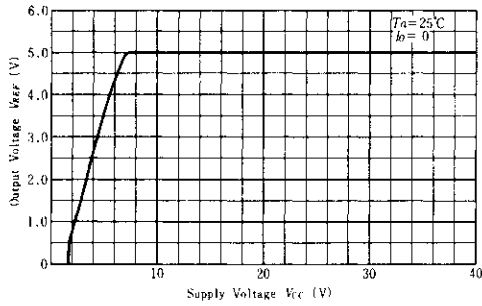


Fig.10 Simple Type Polarity Conversion

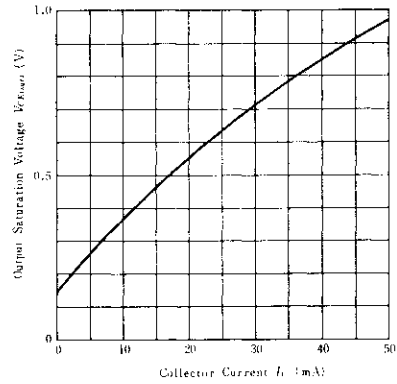
Tracking switching regulator: The circuit configuration of tracking regulator which uses transformer is shown in the Fig. 11 ($V_{OUT} = \pm 5\text{V}$).



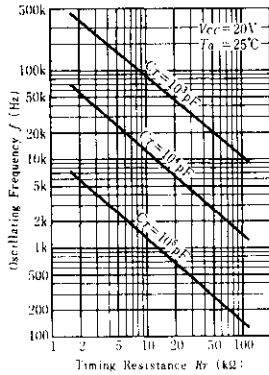
OUTPUT VOLTAGE VS. SUPPLY VOLTAGE



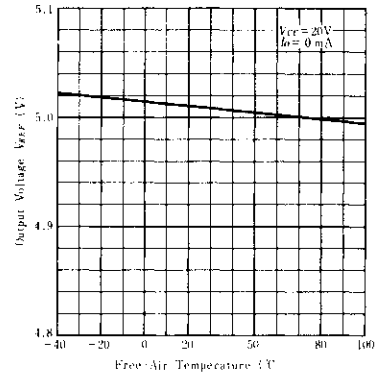
OUTPUT SATURATION VOLTAGE VS. COLLECTOR CURRENT



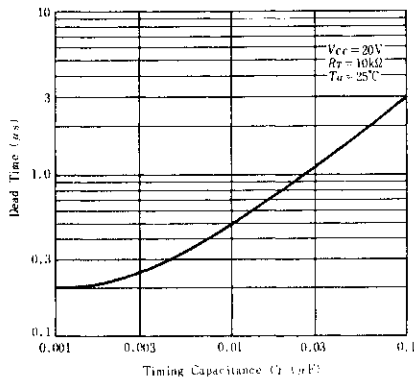
OSCILLATING FREQUENCY VS. TIMING RESISTANCE



OUTPUT VOLTAGE VS. FREE AIR TEMPERATURE



DEAD TIME VS. TIMING CAPACITANCE



A/D,D/A Converters

HA19202, HA19203MP ● 4-bit A/D Converter

With development of the digital electronic technique, A/D converters have been playing an important role of interfacing analog-to-digital conversion. Requirement for the high-speed, high-performance and low cost A/D converters is increasing especially in color TV applications which need analog-to-digital conversion for video signal processing.

The Hitachi A/D Converter HA19202 has a 4-bit parallel sampling system. The HA19202 is useful for video signal processing.

FUNCTIONS

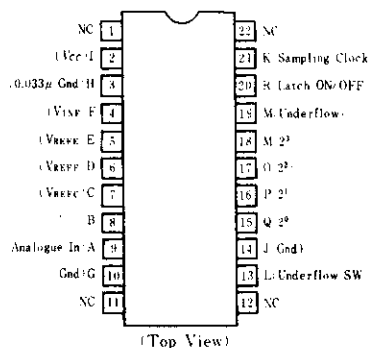
- 4-bit Comparators
- Gray Code Converter
- ECL-to-TTL Converter
- Latch Circuits
- Gray-to-binary Code Converter
- Sampling Clock Pulse Shaper
- Underflow Output Switch

FEATURES

- Conversion Time
The sampling rate is 10 million samples/sec (max).
- Output Stages
Open-collector type, TTL compatible
- Expansion to 5-bit A/D Converter
Two HA19202's easily make a 5-bit A/D converter, as shown in Fig. 2. Table 1 shows the output patterns in the 4-bit application. The output patterns in the expanded 5-bit A/D converter is shown in Table 2. V_L is the lowest reference voltage and V_H is the highest reference voltage.
- High-performance
The comparator utilizes an ECL circuit. The output conversion to Gray code is achieved by an AND/OR circuit. The error at the middle converting point will not exceed an LSB.
- Reference Voltage of Comparator
The power supplies, V_L and V_H , should have a low impedance to prevent the external influence.

PIN ARRANGEMENT

HA19202



HA19202



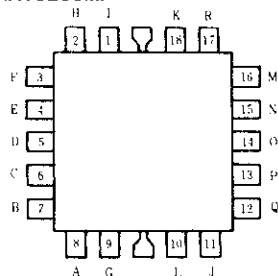
(DP-22)

HA19203MP



(MP-18)

HA19203MP



■ BLOCK DIAGRAM

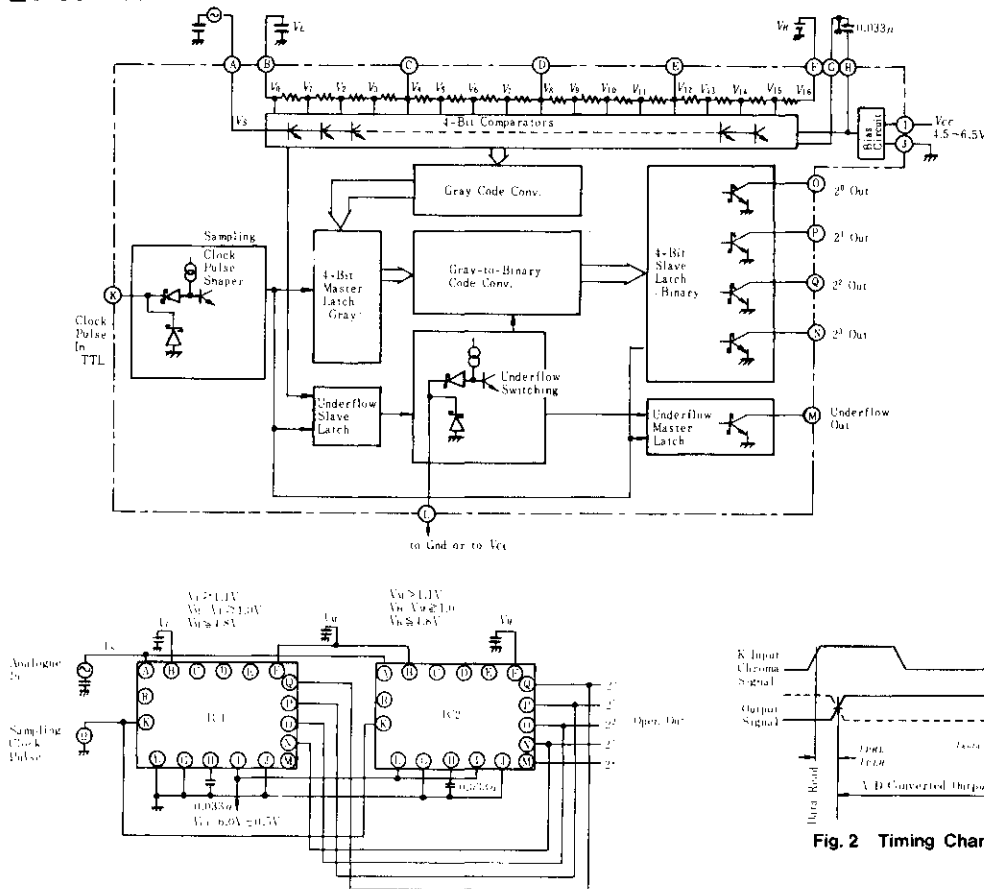


Fig. 1 Expansion to 5-bit A/D Converter

Fig. 2 Timing Chart

■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Rating	Unit
Supply Voltage	V_{cc}	7.0	V
Input Voltage at K,L	V_{IN}	7.0	V
Output Voltage at M,Q	V_o	15.0	V
Power Dissipation	P_T	350	mW
Operating Temperature Range	T_{op}	- 10 ~ +75	°C
Storage Temperature Range	T_{stg}	- 55 ~ + 150	°C
Operating Supply Voltage Range	V_i	4.5 ~ 6.5	V

Table 1: Output Patterns (4-bit)

a) L: GND

	V_S															
	V_0	V_1	V_2	V_3	V_4	V_5	V_6	V_7	V_8	V_9	V_{10}	V_{11}	V_{12}	V_{13}	V_{14}	V_{15}
Ⓐ	L	L	H	L	H	L	H	L	H	L	H	L	H	L	H	L
Ⓑ	L	L	L	H	H	L	L	H	H	L	L	H	H	L	L	H
Ⓒ	L	L	L	L	L	H	H	H	H	L	L	L	L	H	H	H
Ⓓ	L	L	L	L	L	L	L	L	H	H	H	H	H	H	H	H
Ⓔ	H	H	H	H	H	H	H	H	H	H	H	H	H	H	H	H

b) L: Vcc

	V_S															
	V_0	V_1	V_2	V_3	V_4	V_5	V_6	V_7	V_8	V_9	V_{10}	V_{11}	V_{12}	V_{13}	V_{14}	V_{15}
Ⓐ	H	L	H	L	H	L	H	L	H	L	H	L	H	L	H	L
Ⓑ	H	L	L	H	H	L	H	H	L	L	H	H	L	L	H	H
Ⓒ	H	L	L	L	L	H	H	H	H	L	L	L	L	H	H	H
Ⓓ	H	L	L	L	L	L	L	L	H	H	H	H	H	H	H	H
Ⓔ	L	H	H	H	H	H	H	H	H	H	H	H	H	H	H	H

Table 2: Output Patterns (5-bit)

	V_S																			
	V_L					V_M														
	V_0	V_1	V_2	V_3	V_4	V_5	V_6	V_7	V_8	V_9	V_{10}	V_{11}	V_{12}	V_{13}	V_{14}	V_{15}	V_{16}	V_{17}	V_{18}	V_{19}
2 ⁰	L	L	H	L	H	L	H	L	H	L	H	L	H	L	H	L	H	L	H	L
2 ¹	L	L	L	H	H	L	L	H	H	L	L	H	H	L	L	H	H	L	L	H
2 ²	L	L	L	L	L	H	H	H	H	L	L	L	L	H	H	H	H	L	L	H
2 ³	L	L	L	L	L	L	L	L	L	H	H	H	H	H	H	L	L	L	L	H
2 ⁴	L	L	L	L	L	L	L	L	L	L	L	L	L	L	L	H	H	H	H	H

■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

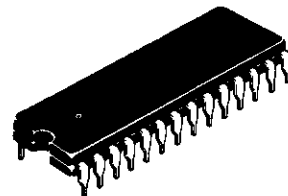
Item	Symbol	Test Conditions	min	typ	max	Unit
Supply Current	I_{CC}	$V_{CC} = 5.0\text{V}$; Input Clock Pulse = 10MHz	—	33	48	mA
Maximum Sampling Frequency	f_{SC}	$V_{CC} = 5.0\text{V}$; duty = 50%	10	—	—	MHz
Pin-B Minimum Input Voltage	$V_{IN\ B}$	$V_{CC} = 5.0\text{V}$	1.1	—	—	V
Pin-F Maximum Input Voltage	$V_{IN\ F}$		—	—	$V_{CC} - 0.7$	V
Pin-A Maximum Input Voltage	$V_{IN\ A}$		—	—	$V_{CC} - 0.7$	V
Minimum Input Voltage Difference between Pins E and F	ΔV_{EF}		1.0	—	—	V
Pins K and L Input Voltage("H"Level)	V_{IH}		2.0	—	—	V
Pins K and L Input Voltage("L"Level)	V_{IL}		—	—	0.8	V
Pins K and L Input Current("H"Level)	I_{IH}	$V_{CC} = 5.25\text{V}$; $V_I = 2.7\text{V}$	—	—	20	μA
Pins K and Input L Input Current("L"Level)	I_{IL}	$V_{CC} = 5.25\text{V}$; $V_I = 0.4\text{V}$	—	—	-0.4	mA
Pin-K Input Clamp Voltage	V_{IK}	$V_{CC} = 4.75\text{V}$; $I_{IS} = -18\text{mA}$	—	—	-1.5	V
Pins M~Q Output Voltage	V_{OL}	$V_{CC} = 4.75\text{V}$; Low Output Level; $I_{OL} = 8.0\text{mA}$	—	—	0.5	V
Pins M~Q Output Voltage	V_{OL}	$V_{CC} = 4.75\text{V}$; Output Low Level; $I_{OL} = 4.8\text{mA}$	—	—	0.4	V
A-to-D Switching Threshold Voltage		$V_{CC} = 5.0\text{V}$; $V_B = 1.8\text{V}$; $V_A = 3.8\text{V}$	-50	0	+50	mV
Resistance between Pins B and C	R_{BC}		300	400	500	Ω
Resistance between Pins C and D	R_{CD}		300	400	500	Ω
Resistance between Pins D and E	R_{DE}		300	400	500	Ω
Resistance between Pins E and F	R_{EF}		300	400	500	Ω
A-to-D Converter Frequency Response(1MHz)	f_{1H}	$V_{CC} = 5.0\text{V}$; Referred to $f = 100\text{kHz}$	-1.1	0	+1.0	dB
A-to-D Converter Frequency Response(3MHz)	f_{3H}	$V_{CC} = 5.0\text{V}$; Referred to $f = 100\text{kHz}$	-3.0	0	+1.0	dB
Pin-A Maximum Input Impedance	$Z_{i\ A}$	$V_{CC} = 5.0\text{V}$; $V_{i\ A} = 2.8\text{V}_{DC}$	—	—	100	Ω

HA16613A ● 8-bit Dual Slope Type A/D Converter

HA16613A is a 8-bit Dual Slope Type A/D Converter, which is bipolar IIL structure and is designed for +5V mono power source. It is suitable for microcomputer, home appliance, industrial equipment, etc.

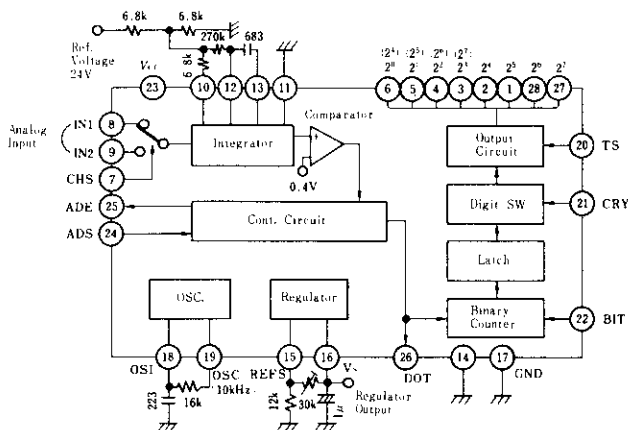
■ FEATURES

- Two-channel analog input
- Series count output and 4-bit parallel output as well as 8-bit parallel output are possible.
- Oscillator and regulator are built in.

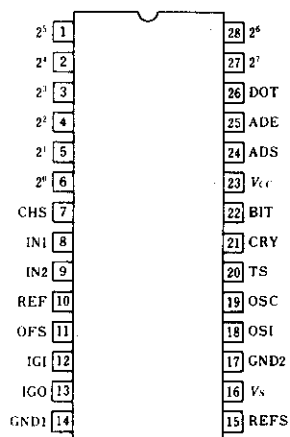


(DP-28)

■ BLOCK DIAGRAM



■ PIN ARRANGEMENT



(Top View)

■ ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Item	Symbol	Rating	Unit
Terminal Voltage	V_I	-0.3 to V_{CC}	V
Supply Voltage	V_{CC}	7	V
Standard Current of Power Source	I_S	-5	mA
Logic Output Current	I_O	± 500	μA
Integrated Output Current	I_{IO}	± 200	μA
Operating Temperature	T_{OP}	-20 to +75	°C
Storage Temperature	T_{STG}	-55 to +125	°C

■ ELECTRICAL CHARACTERISTICS ($V_{CC}=5V$, $V_{FS}=2.0V$, $V_{ZS}=0.8V$, $V_i=2.4V$ constant,
 $f_{OSC}=10kHz$, $T_a=25^\circ C$)

Item	Symbol	Test Condition		min	typ	max	Unit
Conversion Time		$f_{osc}=200kHz$		—	—	5.2	ms
Resolution				—	—	8or6	bit
Accuracy	$N_2 \geq 16$	$T_a = 0 \sim +40^\circ C$		—	0.39	—	%
		$T_a = -20 \sim +75^\circ C$		—	0.39+1step	—	
Analog Input Voltage Range	$V_{IN(apt)}$			0	—	$V_{CC}-2$	V
Standard Voltage Tmperature Dependency	$\Delta V_S/\Delta T_a$	Short circuit between Pin 15&16 $R_L=2.4k\Omega$	$T_a = 0 \sim +40^\circ C$	—	± 50	—	ppm/ $^\circ C$
			$T_a = -20 \sim +75^\circ C$	—	± 100	—	
Standard Voltage Spply Voltage Dependency	$\Delta V_S/\Delta V_{CC}$		$V_{CC}=4 \sim 6V$ $I_{O(source)} = -500\mu A$ $I_L = 1 \sim 5mA$	-7	0	+7	mV/V
Standard Voltage Internal Resistance	$\Delta V_S/\Delta I_L$			—	2.4	5	Ω
Oscillation Frequency Temperature Dependency	$\Delta f_{osc}/\Delta T_a$	$f_{osc}=100kHz$, $T_a = -20 \sim +75^\circ C$		—	± 0.3	—	$\%/^\circ C$
Oscillation Frequency Voltage Dependency	$\Delta f_{osc}/\Delta V_{CC}$	$f_{osc}=100kHz$		—	± 1.8	—	$\%/V$
Reference Voltage	V_{REF}	Short circuit between Pin 15&16, $I_{O(source)} = -500\mu A$		1.110	1.20	1.340	V
Analog Input Current	I_{IN}	$V_{IN}=0V$		-0.2	—	—	μA
Logic Output Current*	$I_{O(source)}$	$V_{OH}=V_{CC}/2$		—	-100	-50	μA
	$I_{O(sink)}$	$V_{OL}=0.4V$		500	—	—	μA
Logic Input Current*	I_{IL}	$V_{IN}=0V$		-20	—	—	μA
	I_{IH}	$V_{IN}=V_{CC}$		—	—	20	μA
Input Voltage**	V_{IH}			1.0	—	—	V
	V_{IL}			—	—	0.4	V
Operating Supply Voltage Range	$V_{CC(apt)}$	$T_a = -20 \sim +75^\circ C$		4	5	$V_{CC max}$	V
Maximum Operating Frequency	$f_{osc(apt)}$			200	—	—	kHz
Power Dissipation	P_T	$V_{CC}=5V$		—	30	60	mW
Three-state Output Leak Current	I_{OL}	$V_i=0 \sim V_{CC}$		-5	—	5	μA

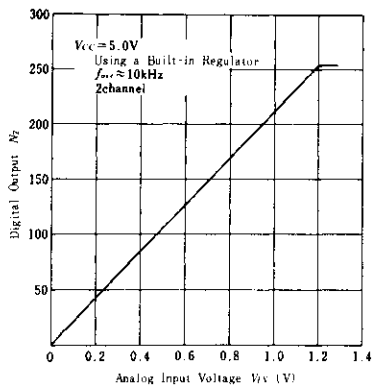
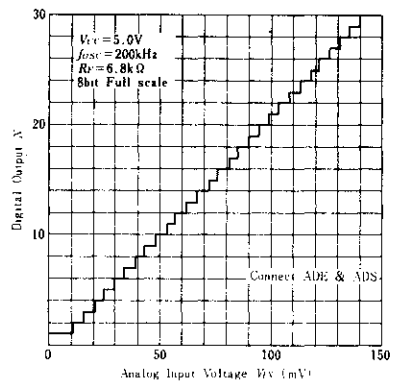
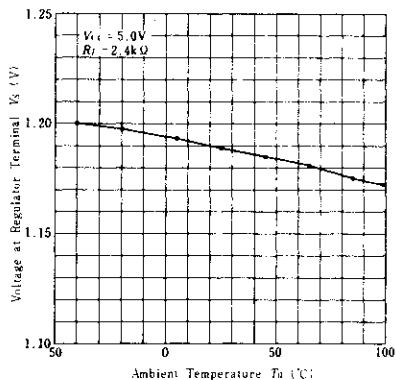
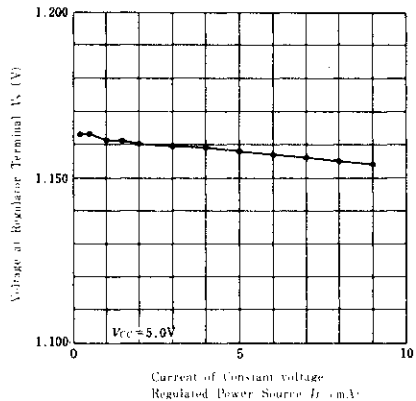
Note) * : Applied to 2⁰~2⁷, ADE, & DOT.

** : Applied to ADS, TS, CRY, BIT, & CHS.

■ TERMINAL DESCRIPTION

Terminal	Description
IN1 - IN2	Analog input voltage is applied. (IN 1 1 channel) (IN 2 2 channel)
CHS	For switching the analog input terminal. (0 : 1 channel) (1 : 2 channel)
ADE	A/D Conversion end signal is applied. (0 : End) (1 : under conversion)
ADS	A/D Conversion start signal is applied. When ADE=1, A/D conversion starts at negative edge of ADS input signal.
DOT	A/D converted pulse is directly outputted between ADS and ADE. (3 state is impossible.)
BIT	For switching 6-bit or 8-bit full scale. (0 : 8 bit) (1 : 6 bit)
CRY	Digit switching at 4-bit parallel transfer. (0 : 4 bit lower + 4 bit upper) (1 : 4 bit upper + 4 bit upper)
TS	Make 8-bit output terminal to be high impedance. (0 : Output) (1 : High Impedance)
$2^0 \sim 2^7$	Binary output terminal During A/D conversion, the previous data is available.
OSI, OSC	Oscillator external terminal. When a clock is applied from external part, a resistor of some hundred k Ω shall be added to OSI.
REFS · Vs	Regulator terminal
REF	Reference voltage for integrator is applied.
IGI · IGO	Input & output terminal of integrator
OFS	Generally connected to GND. Terminal for offset adjustment, in case of small digital output through A/D conversion.

LINEARITY CHARACTERISTICS

LINEARITY CHARACTERISTICS
(LEADING EDGE)CONSTANT VOLTAGE-TEMPERATURE
DEPENDENCYCONSTANT-VOLTAGE INTERNAL
RESISTANCE

■ HINTS FOR USE

1. In the equation on the preceding page (Note 1), if $R_s = 0$, $V_{zs} = 0V$ (possible to convert from input of 0V). However, the linearity around $V_{IN} = 0V$ will worsen. It is recommended to use under condition V_{zs} is more than 0.1V.
2. After Three State is applied, the time required for changing from digital output to high impedance and vice versa is 4 ~ 8 μs . The quantity of current flowing through digital output terminal is equal to that of a LSTTL. Therefore, when connecting digital output to a busline and reading it into a microprocessor in a high speed, a three-state buffer is required for it.
3. If an analog input changes during A/D conversion, there may occur some troubles in the output data. In this case, Sample & Hold is necessary.
4. Timing from CHS (Channel Switch) to ADS (A/D Conversion Start) is more than or equal to 0 seconds. It may be accepted that CHS and ADS are performed at the same time.

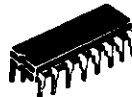
■ NOTE

When input analog voltage of 2S or less, input analog voltage of 2S or more and A/D conversion is done, after the maximum conversion time perform A/D conversion.

●8-bit Multiplying Digital-to-Analog Converter

HA17008R provides a wide scope of application including CRT display, control of step motor, programmable power source, audio instrument, attenuator, etc.

- Wide Operating Temperature range & a linearity of $\pm 0.19\%$ ($\pm 1/2$ LSB) is guaranteed.
- Since the settling time is short, 85ns typ, and fast conversion is possible.
- Low power dissipation, 135mW typ.
- Compatible with TTL, CMOS logic.
- Reference Supply Voltage is;
 $V_{CC} = +15V$, $V_{EE} = -15V$.
- Output Voltage Range with Accuracy Guaranteed is wide;
 $-10V$ to $+18$.



(DP-16)

(DG-16)

[illegible]

(Top View)

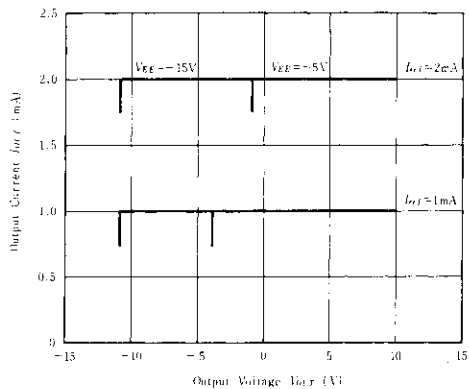
■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

Item	Symbol	Rating	Unit
Supply Voltage	V_{CC}	+18	V
	V_{EE}	-18	V
Digital Input Voltage	V_i, V_{i2}	V_{EE} to $V_{EE}+36\text{V}$	V
Reference Current	I_{14}	5	mA
Input Voltage Range of Reference Amplifier	V_{REF}	V_{CC}, V_{EE}	V
Power Dissipation	P_T	500	mW
Operating Temperature	T_{op}	-20 to +75	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

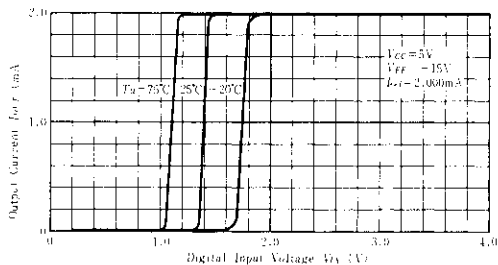
* : In HA17008RG, -65 to +150 $^\circ\text{C}$ ■ ELECTRICAL CHARACTERISTICS ($V_{CC}=15\text{V}$, $V_{EE}=-15\text{V}$, $I_{REF}=2\text{mA}$, $V_{THC}=0\text{V}$, $T_a=25^\circ\text{C}$)

Item	Symbol	Test Condition	min	typ	max	Unit
Relative Error	E_R		—	—	± 0.19	%FS
Settling Time($\pm 1/2\text{LSB}$)	t_s	All Bits OFF to ON	—	85	150	ns
Propagation Delay Time	t_{PLH}, t_{PLL}		—	35	60	ns
Maximum Output Current Drift	T_{C10}		—	± 10	± 50	ppm/ $^\circ\text{C}$
Digital Input Level	V_{IH}		2.0	—	—	V
	V_{IL}		—	—	0.8	V
Digital Input Current (MSB)	I_{IH}	$V_{IH}=5.0\text{V}$	—	0.002	10	μA
	I_{IL}	$V_{IL}=0.8\text{V}$	-10	2.0	—	μA
Reference Bias Current	I_{15}		-3.0	-1.0	—	μA
Output Current with Accuracy Guaranteed	I_{OR}	$V_{EE} = -5.0\text{V}$	0	2.0	2.1	mA
		$V_{EE} = -8.0$ to -18V	0	2.0	4.2	
Output Current	I_L	$V_{ref}=10.000\text{V}$ $R_{11}, R_{12}=5.000\text{k}\Omega$	1.94	1.99	2.04	mA
	$I_{L, max}$	All Bits Low	—	0	2.0	
Output Voltage with Accuracy Guaranteed	V_o	$E \leq 0.19\%$ $V_{EE} = -15\text{V}$ $T_a = 25^\circ\text{C}$	-10	—	+18	V
Reference Current Slew Rate	SRI_{ref}		4.0	8.0	—	mA/ μs
Supply Current	I_{CC}	$V_{CC} = +5\text{V}$ $I_{REF} = 1\text{mA}$	—	2.3	3.8	mA
	I_{EK}	$V_{EE} = -5\text{V}$	-5.8	-4.3	—	
	I_{VC}	$V_{CC} = +5\text{V}$ $I_{REF} = 2\text{mA}$	—	2.4	3.8	
	I_{EK}	$V_{EE} = -15\text{V}$	-7.8	-6.4	—	
	I_{CC}	$V_{CC} = +15\text{V}$ $I_{REF} = 2\text{mA}$	—	2.5	3.8	
	I_{EK}	$V_{EE} = -15\text{V}$	-7.8	-6.5	—	
Supply Voltage	V_{CC}		4.5	15	18	V
	V_{EE}		-18	-15	-4.0	V
Power Dissipation	P_{T1}	$V_{CC} = +5\text{V}$ $I_{REF} = 1\text{mA}$ $V_{EE} = -5\text{V}$	—	33	48	mW
	P_{T2}	$V_{CC} = +5\text{V}$ $I_{REF} = 2\text{mA}$ $V_{EE} = -15\text{V}$	—	108	136	
	P_{T3}	$V_{CC} = +15\text{V}$ $I_{REF} = 2\text{mA}$ $V_{EE} = -15\text{V}$	—	135	174	
Full Scale Current Difference	I_{FSS}	$I_{FSL} - I_{FSH}$	-8.0	± 1.0	-8.0	μA
Digital Input Scale	V_{IS}	$V_{THC} = -10$ to $+13.5\text{V}$	-10	—	+18	V
Threshold Control Voltage	V_{THC}		-10	0	13.5	V
Digital Input Threshold Voltage	V_{THL}		—	$V_{THC} - 1.3$	—	V

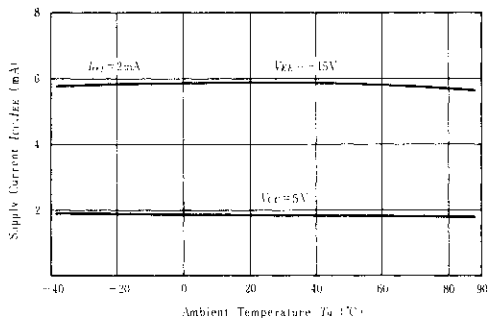
OUTPUT CURRENT VS. OUTPUT VOLTAGE



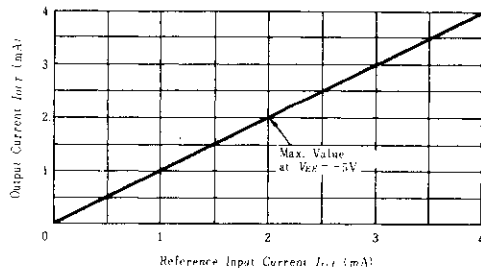
OUTPUT CURRENT VS. DIGITAL INPUT VOLTAGE



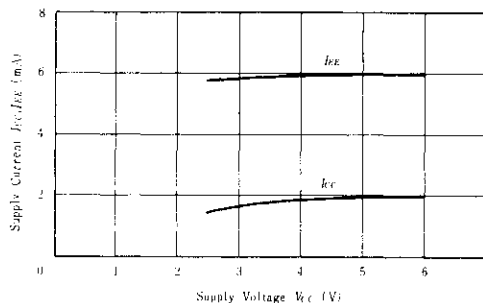
SUPPLY CURRENT VS. AMBIENT TEMPERATURE



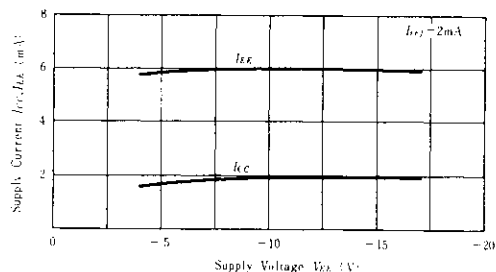
OUTPUT CURRENT VS. REFERENCE INPUT CURRENT



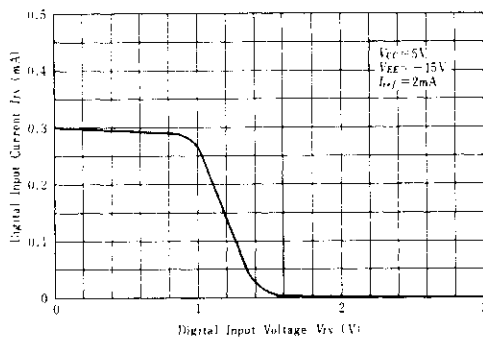
SUPPLY CURRENT VS. SUPPLY VOLTAGE (1)



SUPPLY CURRENT VS. SUPPLY VOLTAGE (2)



DIGITAL INPUT CURRENT VS. DIGITAL INPUT VOLTAGE



■ EXPLANATION OF FUNCTIONS

● **Reference Differential Amplifier and Phase Compensation**
Reference Amplifier is for converting the reference voltage added to pin 14 from voltage to current. And its converted current is supplied to each bit by current mirror and ladder resistor. Further, use pin 14 with positive or negative polarity according to the current flown to it. The reference power source supplies all currents to pin 14. (Refer to Fig. 1)

To input a positive pulse to the reference voltage, as multiplying mode, R_{15} is capable of being connected to the lowest electric potential of input voltage which is equivalent to the negative voltage.

Without R_{15} , the accuracy and the temperature drift is little influenced. To keep the phase margin proper, the capacitance for phase compensation shall be increased with accordance to the increase of R_{14} . For example, when R_{14} is $1\text{k}\Omega$, $2.5\text{k}\Omega$, $5\text{k}\Omega$, the lowest capacitance is 15pF , 37pF , and 75pF respectively. The capacitor shall be connected to V_{EE} or GND. When a high impedance is required, connect R_{14} to GND, and R_{15} , to the negative reference voltage. (Refer to Fig. 2) In this case, capacitor for phase compensation must be connected between V_{EE} and pin 16. In case of using a DC reference voltage, insert by-pass capacitor. It is not recommended to use logic power source of 5V. In case of using a high stable 5V power source for logic control, connect the resistor to the reference power source, and ground $0.1\mu\text{F}$ capacitance from the connecting point.

As for a reference voltage of 5V or more, ground a clamp diode from pin 14.

When pin 14 is controlled by a high impedance such as a power source, phase compensation can not be performed in a way described above. Amplifier shall be fully phase-compensated in all frequency bands.

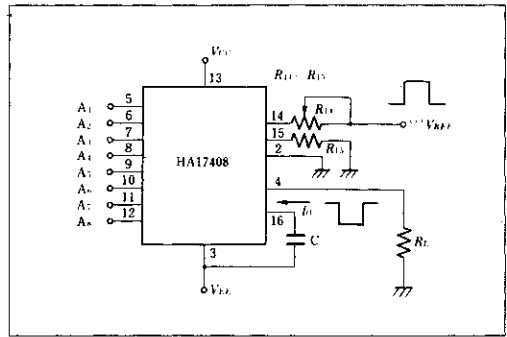


Fig. 1 Positive Reference Voltage

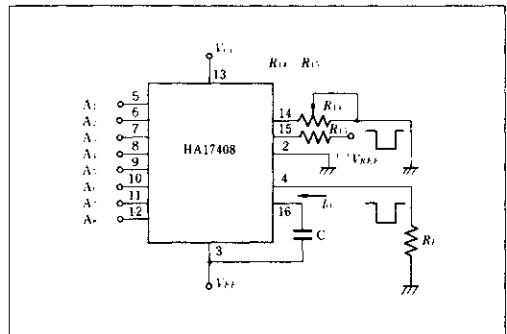


Fig. 2 Negative Reference Voltage

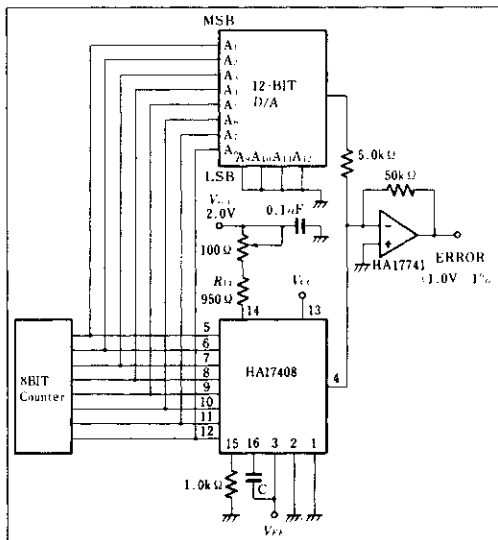


Fig. 3 Circuit to Measure Relative Accuracy

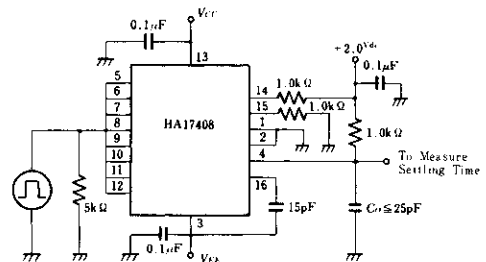
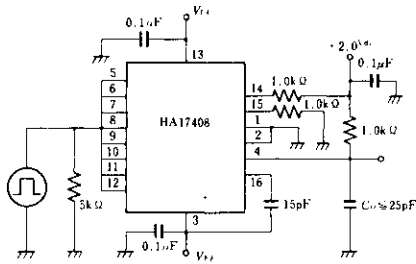


Fig. 4 Circuit to Measure Settling Time

■ AN EXAMPLE OF OPERATION

- Current → Voltage Conversion by an Operational Amplifier



The theoretical output is;

$$V_o = \frac{V_{REF}}{R_{14}} (R_o) \left(\frac{A_1}{2} + \frac{A_2}{4} + \frac{A_3}{8} + \frac{A_4}{16} + \frac{A_5}{32} + \frac{A_6}{64} + \frac{A_7}{128} + \frac{A_8}{256} \right)$$

Once values of V_{REF} , R_{14} and R_o is determined, the output voltage will be 9.961V under the condition of all bits High.

$$V_o = \frac{2V}{1k} (5k) \left(\frac{1}{2} + \frac{1}{4} + \frac{1}{8} + \frac{1}{32} + \frac{1}{64} + \frac{1}{128} + \frac{1}{256} \right)$$

HA17408P, HA17408G ●8-bit Multiplying Digital-to-Analog Converter

HA17408 is a 8-bit monolithic D/A converter, with reference current amplifier and a ladder resistor of R-2R, and eight high speed current switches built in. By establishing a reference current and a reference resistor, it is possible to change the maximum output current according to the applications. And it is compatible with MC1508/1408, AM1408, and its power dissipation is small and realizes high settling speed.

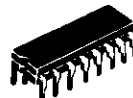
Reference current is divided into current value each bit by the ladder resistor or R-2R and maximum output current will be 255/256 of the reference current. For example, the maximum output current gained from reference input current of 2.0mA will be 1.992mA.

HA17408 provides a wide scope of application including CRT display, control of step motor, programmable power source, audio instrument, attenuator, etc.

■ FEATURES

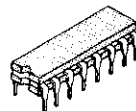
- Wide operating temperature range & a linearity of $\pm 0.19\%$ ($\pm 1/2$ LSB) is guaranteed.
- Since settling time is short, 250ns typ, and fast conversion is possible.
- Low Power dissipation, 157mW typ.
- Compatible with TTL, CMOS logic.
- Reference Supply Voltage is;
 $V_{CC} \approx +5.0V$, $V_{EE} \approx 5.0V$, $-15.0V$
- Output Voltage Range with Accuracy Guaranteed is wide;
 -5.0 to $+0.5V$

HA17408P



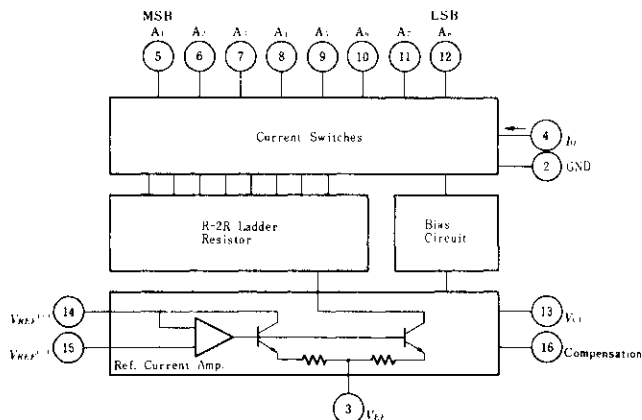
(DP-16)

HA17408G

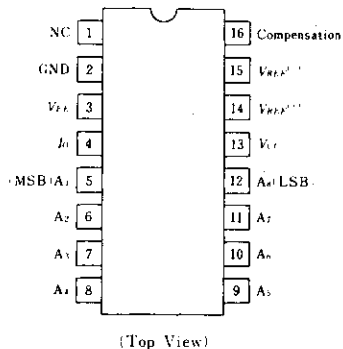


(DG-16)

■ BLOCK DIAGRAM



■ PIN ARRANGEMENT



■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Rating	Unit
Supply Voltage	V_{CC}	5.5	V
	V_{EE}	-16.5	V
Digital Input Voltage	V_I to V_{IL}	0 to +5.5	V
Output Voltage	V_O	-0.5, -5.2	V
Reference Current	I_{REF}	5.0	mA
Input Voltage Range of Reference Amplifier	V_{REF}	V_{CC} , V_{EE}	V
Power Dissipation	P_T	625	mW
Operating Temperature	T_{op}	-20 to +75	$^\circ\text{C}$
Storage Temperature	T_{stg} *	-55 to +125	$^\circ\text{C}$

* : In HA17408G: - 65 to +150 $^\circ\text{C}$ ■ ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0\text{V}$, $V_{EE} = -15\text{V}$, $I_{REF} = 2\text{mA}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Relative Error	E_R				± 0.19	%FS
Settling Time (1/2LSB)	t_s	All bits; OFF to ON	—	250	—	ns
Propagation Delay Time	t_{PLH} , t_{PHL}		—	30	100	ns
Maximum Output Current Drift	T_{CO}		—	± 20	—	pp/ $^\circ\text{C}$
Digital Input Level	V_{IH}		2.0	—	—	V
	V_{IL}		—	—	0.8	V
Digital Input Current (MSB)	I_{IH}	$V_{IH} = 5.0\text{V}$	—	0	0.04	mA
	I_{IL}	$V_{IL} = 0.8\text{V}$	-0.8	-0.002	—	mA
Reference Input Bias Current	I_{IS}		-3.0	1.0	—	μA
Output Current with Accuracy Guaranteed	I_{OVR}	$V_{EE} = -5.0\text{V}$	0	2.0	2.1	mA
		$V_{IF} = -7.0$ to -15V	0	2.0	4.2	
Output Current	I_O	$V_{REF} = 2.000\text{V}$ $R_{L1} = 1000\Omega$	1.9	1.99	2.1	mA
	I_{LOW}	All Bits Low	—	0	4.0	μA
Output Voltage with Accuracy Guaranteed	V_O	$E_R \leq 0.19\%$ $T_a = 25^\circ\text{C}$	$V_{EE} = -5\text{V}$ -0.6	—	+0.5	V
			$V_{EE} < -10\text{V}$ -5.0	—	+0.5	
Reference Current Slew Rate	STI_{REF}		—	4.0	—	mA/ μs
Supply Current	I_{CC}			1.9	14	mA
	I_{EE}		13	-5.8	—	mA
Supply Voltage	V_{CC}		4.5	5.0	5.5	V
	V_{EE}		-16.5	-15	-4.5	V
Power Dissipation	P_T	All Bits Low	$V_{EE} = -5.0\text{V}$ $V_{REF} = -15\text{V}$	34	136	mW
		All Bits High	$V_{EE} = -5.0\text{V}$ $V_{REF} = -15\text{V}$	34	—	
				108	265	
				108	—	

HA17012P, HA17012G ● 12-bit Multiplying Digital-to-Analog Converter

HA17012 is a monolithic high speed multiplying D/A converter which provides 12-bit resolution and current output. It is divided into two groups according to the accuracy of linearity and the differential error.

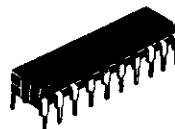
■ FEATURES

- With differential current attraction terminals (I_o , T_o)
- 4mA full scale output is gained with 1mA reference input current.
- The settling time is short, 250ns (typ), and fast conversion is possible.
- Possible to connect a digital input to TTL and CMOS directly.
- Compatible with Am6012 of AMD Ltd.

■ ACCURACY

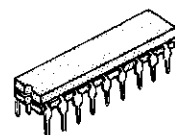
Type No.	Linearity Accuracy		Differential Accuracy	
	Bit	LSB	Bit	LSB
HA17012B	11	± 2	12	± 1
HA17012C	10	± 4	11	$+2, -1$

HA17012P



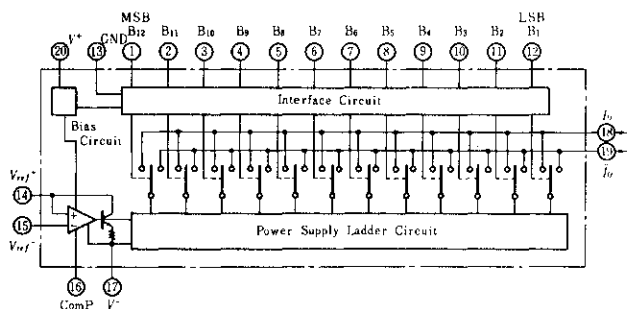
(DP-20)

HA17012G

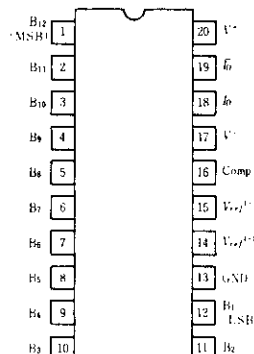


(DG-20)

■ BLOCK DIAGRAM



■ PIN ARRANGEMENT



(Top View)

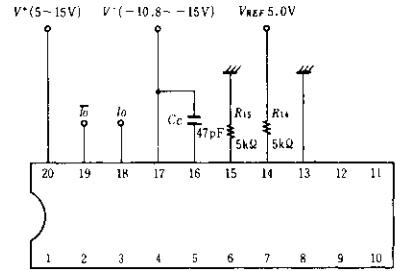
■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Rating	Unit
Supply Voltage	V^+	± 18	V
Logic Input Voltage	$V_{I, LV}$	-5 to +15	V
Analog Output Voltage	$V_{O, LV}$	-8 to +12	V
Reference Input Voltage	V_{ref}	V to V^+	V
Reference Input Current	I_{ref}	1.25	mA
Differential Reference Input Voltage Range	$V_{I, V, ref}$	± 18	V
Operating Temperature	T_{op}	-20 to +75	$^\circ\text{C}$
Storage Temperature *	T_{stg}	-65 to +150	$^\circ\text{C}$

* In HA17012P: -55 to +125 $^\circ\text{C}$

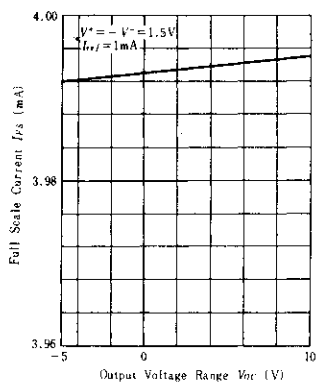
RECOMMENDED OPERATING CONDITIONS

Item	Symbol	Recommended Value	Unit
Supply Voltage	V^+	5 to 15	V
	V^-	-15 to -10.8	V
Logic Input Voltage	V_i	0 to V^-	V
Reference Voltage	V_{REF}	5.0	V
Reference Current	I_{REF}	1.0	mA
Reference Input Resistance	R_{14}, R_{15}	5.0	k Ω
Phase Compensation Capacitance	C_C	47	pF
Output Voltage	V_{out}	0	V

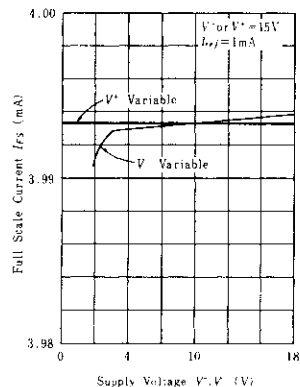
ELECTRICAL CHARACTERISTICS ($V^+ = -V^- = 15V$, $I_{REF} = 1mA$, $T_a = 25^\circ C$)

Item	Symbol	Test Condition	HA17012B			HA17012C			Unit
			min	typ	max	min	typ	max	
Resolution			12	12	12	12	12	12	bits
Differential Error	DNL	$V_{out} = 0V$	-0.025	-	+0.025	-0.025	-	+0.05	%FS
Non Linearity	NL	$V_{out} = 0V$	-0.05	-	+0.05	-0.1	-	+0.1	%FS
Full Scale Current	I_{FS}	$V_{REF} = 15V$, $R_{14} = R_{15} = 15k\Omega$	3.935	3.999	4.063	3.871	3.999	4.127	mA
Full Scale Temperature Dependency	$\Delta I_{FS}/I_{FS}$		-	± 10	-	-	± 20	-	ppm/ $^\circ C$
Output Voltage Range	V_{out}	$R_{out} > 10M\Omega$	-5	-	+10	-5	-	+10	V
Full Scale Subtracted Current	I_{FSS}	$I_{FS} - I_{FS}$	-2.0	± 0.4	+2.0	-4.0	± 0.8	+4.0	μA
Offset Current	I_{LS}		-	-	0.1	-	-	0.4	μA
Settling Time	t_s	to $\pm \frac{LSB}{2}$ All bits ON, OFF	-	250	-	-	250	-	ns
Delay Time	t_{PLH}, t_{MIL}	50% to 50%	-	25	-	-	25	-	ns
Output Capacitance	C_{out}		-	20	-	-	20	-	pF
Logic Input Voltage	V_{IL}		-	-	0.8	-	-	0.8	V
	V_{IH}		2.0	-	-	2.0	-	-	V
Logic Input Current	I_{IN}	$-5V \leq V_{IN} \leq +15V$	-60	-	+20	-60	-	+20	μA
Logic Input Voltage Range	V_{IS}	$-5V \leq V_{IS} \leq +15V$	-5	-	+15	-5	-	+15	V
Reference Current Range	I_{REF}		0.2	1.0	1.1	0.2	1.0	1.1	mA
Bias Current at Reference Terminal	I_{15}		-3	-	0	-3	-	0	μA
Supply Voltage Dependency	$PSS \cdot I_{FS}^+$	$13.5V \leq V^+ \leq 16.5V$	-10	-	+10	-10	-	+10	ppmFS/%V
	$PSS \cdot I_{FS}^-$	$-16.5V \leq V^- \leq -13.5V$	-10	-	+10	-10	-	+10	ppmFS/%V
Supply Voltage Range	V^+	$V_{out} = 0V$	4.5	-	18	4.5	-	18	V
	V^-		-18	-	-10.8	-18	-	-10.8	V
Supply Current	I^+	$V^+ = 15V$	-	5.2	8.5	-	5.2	8.5	mA
	I^-	$V^- = -15V$	23	-17.2	-	23	-17.2	-	mA
Power Dissipation	P_T	$V^+ = 15V$ $V^- = -15V$	-	336	473	-	336	473	mW

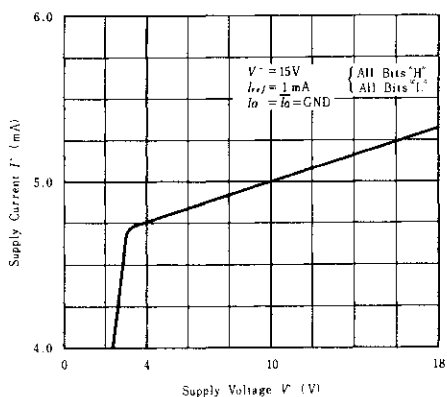
FULLSCALE CURRENT VS. OUTPUT VOLTAGE RANGE



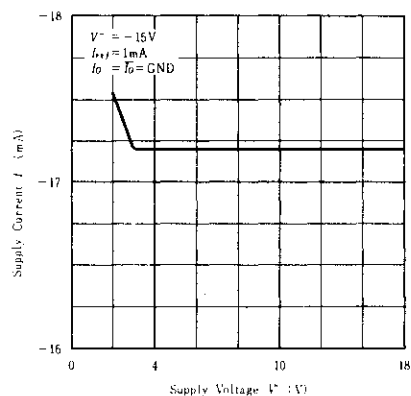
FULLSCALE CURRENT VS. SUPPLY VOLTAGE



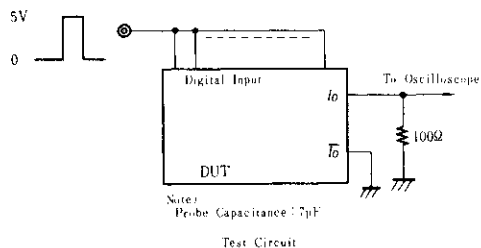
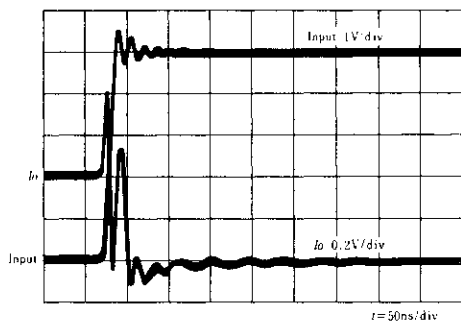
SUPPLY CURRENT VS. SUPPLY VOLTAGE(1)



SUPPLY CURRENT VS. SUPPLY VOLTAGE(2)



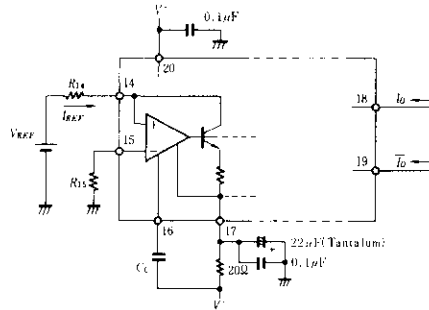
SETTLING WAVEFORM(ALL BITS ON-OFF)



APPLICATION NOTES

1. Method to Apply a Reference Input

● Positive Reference Voltage



The full scale output current ($I_O + \bar{I}_O$) is four times as large as the reference input current (I_{REF}) on account of the internal circuit.

$$I_{FS} = I_O + \bar{I}_O \approx 4I_{REF}$$

V_{REF} is converted to the reference input current (I_{REF}) by R_{14} .

$$I_{REF} \approx \frac{V_{REF}}{R_{14}}$$

To erase the input bias current error of the input operational amplifier, $R_{14} = R_{15}$.

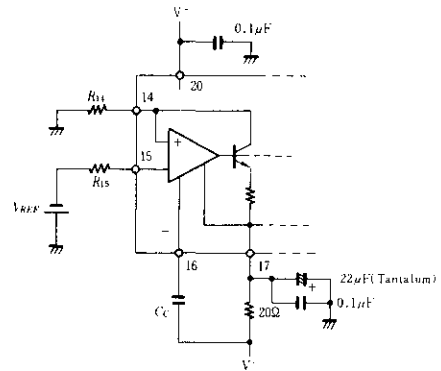
The phase correction capacitance C_C is $0.01\mu F$ generally and the minimum value can be found by;

$$C_C = 5 \times R_{14} \text{ (k}\Omega\text{)} \text{ (pF)}$$

For example, when R_{14} 0.5k Ω , the minimum value of C_C is;

$$C_C = 5 \times 5 = 25 \text{ (pF)}$$

● Negative Reference Voltage



$$I_{REF} = 1.0000 \text{ mA}$$

Input Code		I_O (mA)	$\bar{I}_O$ (mA)	V_{OUT} (V)	$\bar{V}_{OUT}$ (V)
MSB	LSB				
111111111111		3.999	0.000	3.999	0.000
111111111110		3.998	0.001	-3.998	-0.001
100000000000		2.000	1.999	-2.000	-1.999
000000000001		0.001	3.998	-0.001	-3.998
000000000000		0.000	3.999	0.000	-3.999

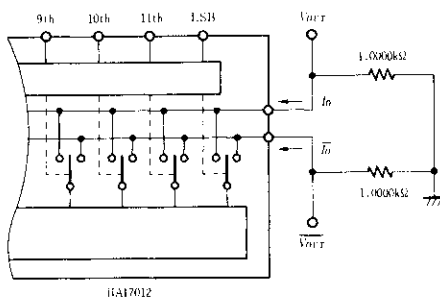
$$I_{REF} = 1.0000 \text{ mA}$$

Input Code		I_O (mA)	$\bar{I}_O$ (mA)	V_{OUT} (V)	$\bar{V}_{OUT}$ (V)
MSB	LSB				
111111111111		3.999	0.000	-1.999	+2.000
111111111110		3.998	0.001	-1.998	+1.999
100000000001		2.001	1.998	-0.001	+0.002
100000000000		2.000	1.999	0.000	+0.001
011111111111		1.999	2.000	+0.001	0.000
000000000001		0.001	3.998	+1.999	-1.998
000000000000		0.000	3.999	+2.000	-1.999

2. Method to Connect Output Circuit

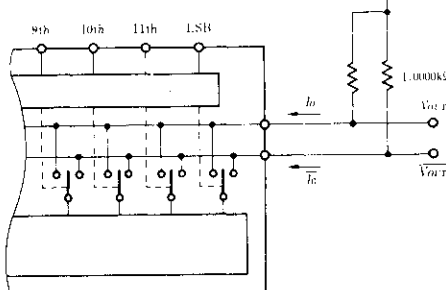
(1) Resistor

● Unipolar Negative Output Voltage



HA17012

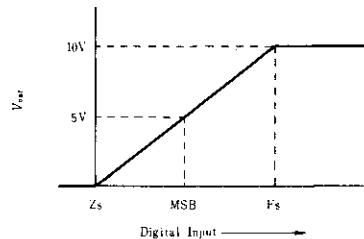
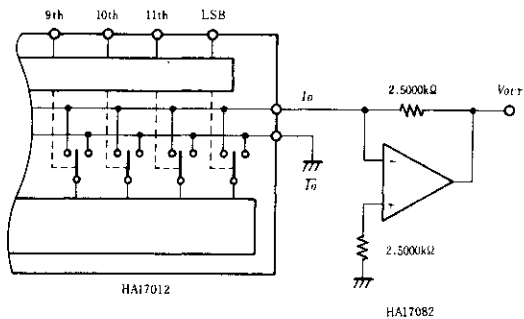
● Bipolar Output



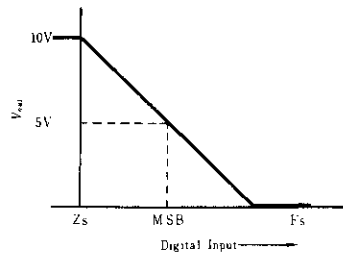
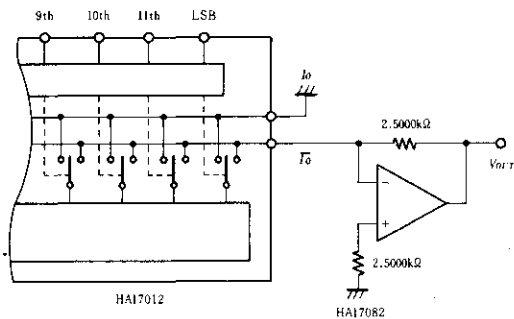
HA17012

(2) Method to Connect Output Buffer and Amplifier

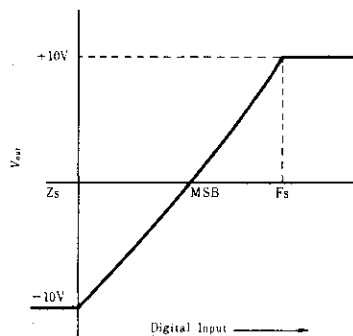
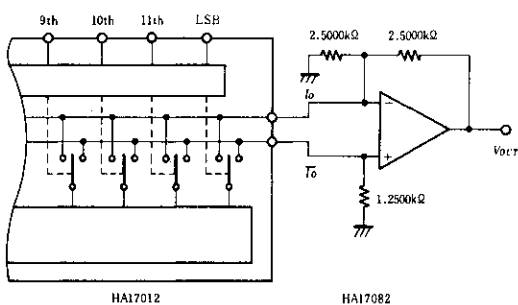
● Unipolar Positive Output Voltage (Straight Binary)



● Unipolar Positive Output Voltage (Complementary Binary)



● Symmetrical Offset Output Voltage



Microprocessor Peripheral

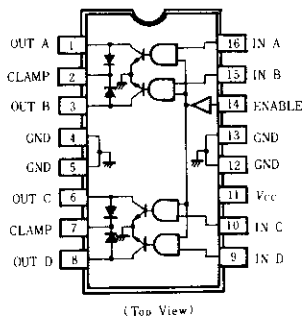
HA13007 ●Quad. Driver

HA13007 is a monolithic, bipolar, high voltage, high current Quad. Driver especially designed for switching applications. This device is recommended for the interfacing from low-level logic to peripheral loads such as relays, solenoids, stepping motors, LED, heaters and other similar high voltage, high current loads.

■ FEATURES

- Guaranteed minimum output breakdown of 50V, and maximum output current of 0.7A.
- Low output collector-emitter saturation voltage.
- Compatible inputs with TTL, LSTTL and 5V CMOS.
- Included integral transient suppression diodes for inductive loads.
- Less input current.

■ PIN ARRANGEMENT



■ TRUTH TABLE

ENABLE	IN	OUT
H	H	L
H	L	H
L	×	H

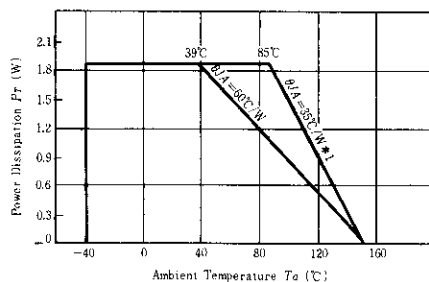
for each input:

H = High level: 2.0V
L = Low level: 0.8V
× = Irrelevant

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Item	Symbol	Rating	Unit	Note
Supply Voltage	V_{CC}	7.0	V	1
Input Voltage	V_{IN}	0 to V_{CC}	V	
Output Voltage	V_{CEX}	60	V	
Output Current	I_{OUT}	0.7	A	
Power Dissipation	P_T	1.85	W	1
Thermal Resistance	Junction-Case	θ_{JC}	15	°C/W
	Junction-Ambient	θ_{JA}	60	°C/W
Junction Temperature	T_J	150	°C	
Operating Junction Temperature Range	T_{JP}	-40 to +125	°C	
Storage Temperature Range	T_{stg}	-55 to +125	°C	

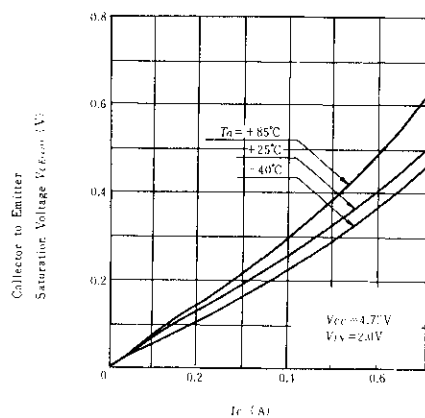
Note) 1. The derating curve is shown below.



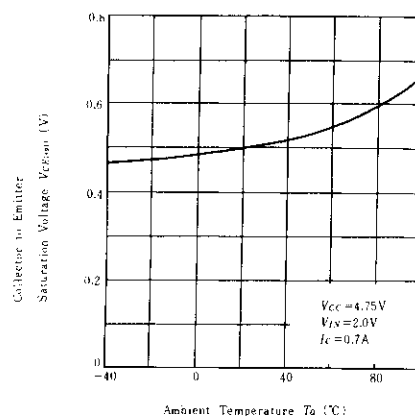
*1 A maximum thermal resistance junction to ambient of 35°C/W with the device soldered into a P.C. board is achievable provided there is enough copper on the P.C. board.

■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$, $V_{CC} = 5.5\text{V}$)

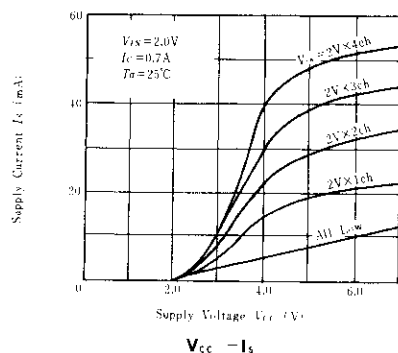
Item	Symbol	Test Condition	min	typ	max	Unit
Output Leakage Current	I_{CEX}	$V_{CE} = 60\text{V}$, $V_{IN} = 0.8\text{V}$	—	—	100	μA
Output Sustaining Voltage	$V_{CE(sat)}$	$V_{IN} = 0.8\text{V}$, $I_C = 10\text{mA}$	60	—	—	V
Output Saturation Voltage	$V_{CE(sat)}$	$V_{CC} = 4.75\text{V}$, $V_{IN} = 2.0\text{V}$	$I_C = 0.4\text{A}$	—	0.3	V
			$I_C = 0.7\text{A}$	—	0.5	
Input Low Voltage	V_{IL}		—	—	0.8	V
Input Low Current	I_{IL}	$V_{IN} = 0.8\text{V}$, $I_C = 0$	—	-1	± 10	μA
Input High Voltage	V_{IH}		2.0	—	—	V
Input High Current	I_{IH}	$I_C = 0.7\text{A} \times 4$	$V_{IN} = 2.0\text{V}$	—	0	μA
			$V_{IN} = 5.0\text{V}$	—	1.0	
Supply Current (All Output ON)	I_S	$I_C = 0.7\text{A} \times 4$, $V_{IN} = 5.5\text{V}$ (All Inputs)	—	50	65	mA
Supply Current (All Outputs OFF)	I_{SD}	$V_{IN} = 0.8\text{V}$ (All Inputs)	—	8.0	—	mA
Clamp Diode Leakage Current	I_R	$V_R = 50\text{V}$	—	—	50	μA
Clamp Diode Forward Voltage	V_F	$V_{IN} = 0.8\text{V}$	$I_F = 1.0\text{A}$	—	1.2	V
			$I_F = 1.5\text{A}$	—	1.3	
Turn-On Delay	$t_{F(on)}$		—	1.0	—	μs
Turn-Off Delay	$t_{F(off)}$		—	0.3	—	μs



$$I_C - V_{CE(sat)}$$



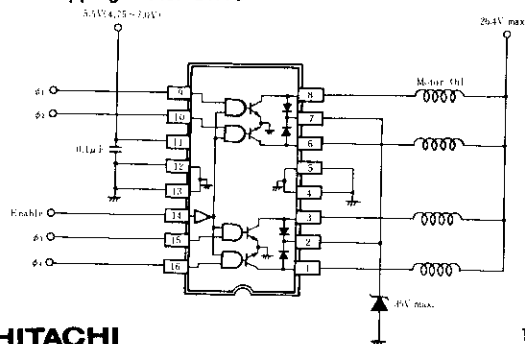
$$T_a - V_{CE(sat)}$$



$$V_{CC} - I_S$$

■ APPLICATION

• Stepping Motor Drive



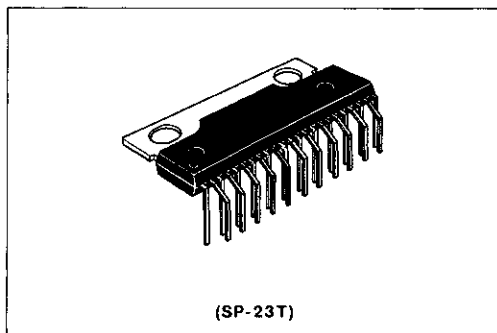
HA13406W ● Three-phase Brushless Motor Driver

HA13406W is a power IC developed for use in the three phase brushless motor driving.

This provides hall amp, logic part, output amp, control amp, and forward and back rotation circuit functions in one chip. As the maximum driving current and voltage is as much as 3A x 12V per phase. Therefore, this finds best use in the spindle motor driving of 5.25 inches HDD.

■ FEATURES

- 3A Output Current Capability.
- Low Output Saturation Voltage.
- Hall Amp with Hysteresis.
- With Thermal Shutdown.
- Low Thermal Resistance Package.



■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item		Symbol	Ratings	Unit
Control Stage Supply Voltage (Note 1)		V_{CC1}	7	V
Output Stage Supply Voltage (Note 1)		V_{CC2}	15	V
Output Current		I_O	3	A
Power Dissipation (Note 2)		P_T	25	W
Thermal Resistance	Junction-Case	θ_{j-c}	3.0	$^\circ\text{C}/\text{W}$
	Junction-Ambient	θ_{j-a}	40	
Hall Amp Input Voltage		V_H	0 to V_{CC1}	V
Direction Voltage		V_D	0 to V_{CC1}	V
Control Voltage		V_{CTL}	0 to V_{CC1}	V
Junction Temperature		T_j	150	$^\circ\text{C}$
Operating Junction Temperature Range		T_{jop}	-20 to +125	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	-55 to +125	$^\circ\text{C}$

2. See the derating curve of Fig. 1

Notes) 1. Recommended Operating Voltage

	min	typ	max	Unit
V_{CC1}	4.5	5.0	5.5	V
V_{CC2}	10.2	12	13.8	V

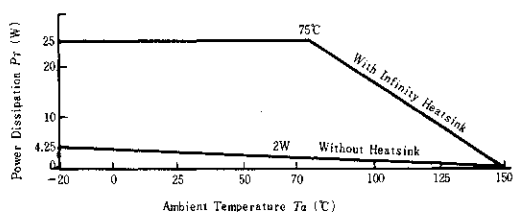


Fig. 1

■ ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$, $V_{CC1}=5\text{V}$, $V_{CC2}=12\text{V}$)

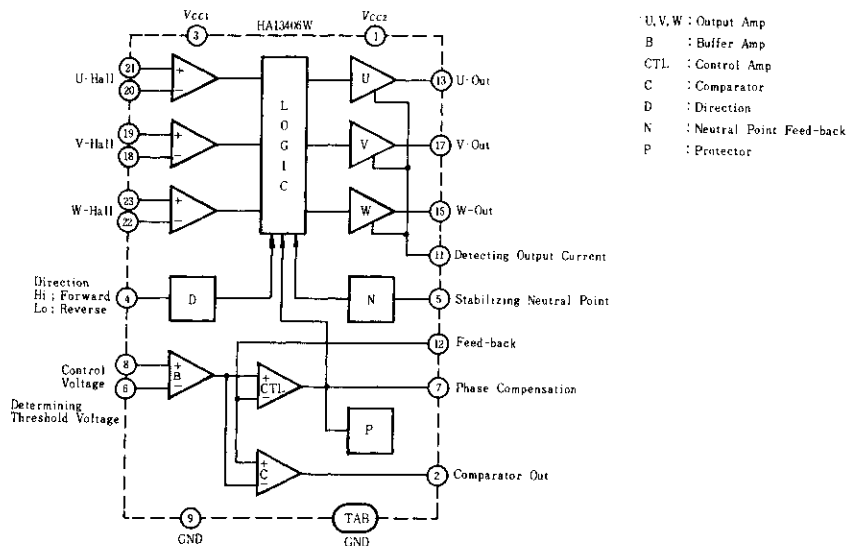
Item		Test Conditions		min	typ	max	Unit	Test Terminal	Note
Total	Quiescent Current	$V_{CTL}=0\text{V}$	V_{CC1}	—	10	15	mA	3	
			V_{CC2}	—	10	15	mA	1	
		$V_{CTL}=V_{CC1}$ $R_L=\text{Open}$	V_{CC1}	—	10	15	mA	3	
			V_{CC2}	—	105	150	mA	1	
	Thermal Shut-Down Temperature	$V_{CTL}=V_{CC1}$, $I_O=0.1\text{A}$		—	150	—	$^{\circ}\text{C}$		1
Hall Amp to Logic	Input Bias Current			—	—	± 50	μA	18~23	
	Input Common-mode Voltage Range			2.0		3.0	V	Ditto	
	Hysteresis width	$R_F=220\Omega$		15	—	30	mV	Ditto	
Output	Sustaining Voltage	$I_C=20\text{mA}$		15	—	—	V	13, 15, 17	
	Leak Current	$V_{CE}=15\text{V}$		—	—	10	mA	Ditto	
	Saturating Voltage	$V_{CTL}=V_{CC1}$, $I_O=2.8\text{A}$		—	2.8	3.8	V	Ditto	2
Buffer	Internal Reference Voltage			2.35	2.5	2.65	V	6	
	Output Resistance of Reference				2.5	—	k Ω	Ditto	
	Threshold Voltage	$I_O=20\text{mA}$		—	100	—	mV	8	3
	Input Current	$V_{CTL}=5\text{V}$		—	0	± 10	μA	Ditto	
		$V_{CTL}=1\text{V}$		—	—3	± 10	μA	Ditto	
	Voltage Gain	$I_O=0.8\text{A}$, $f=500\text{Hz}$		—	0	—	dB	11	
Control Amp	Input Offset Voltage	$I_O=20\text{mA}$		—	100	—	mV	12	
	Voltage Gain	$I_O=0.8\text{A}$, $f=500\text{Hz}$		—	0	—	dB	11	
Comparator	Leak Current	$V_{CE}=15\text{V}$		—	—	1.0	mA	2	
	Saturation Voltage	$I_C=20\text{mA}$		—	1.0	1.5	V	Ditto	
Direction	Voltage Range for Forward Mode			2.0	—	5	V	4	
	Voltage Range for Reverse Mode			0	—	0.7	V	Ditto	
	Input Current	$V_D=\text{GND}$		—	1.2	—	mA	Ditto	
		$V_D=5\text{V}$		—	0	—	mA	Ditto	

Notes) 1. The specification indicates the temperature of the case.

2. The specification shows the sum of the upper and lower saturation voltage.

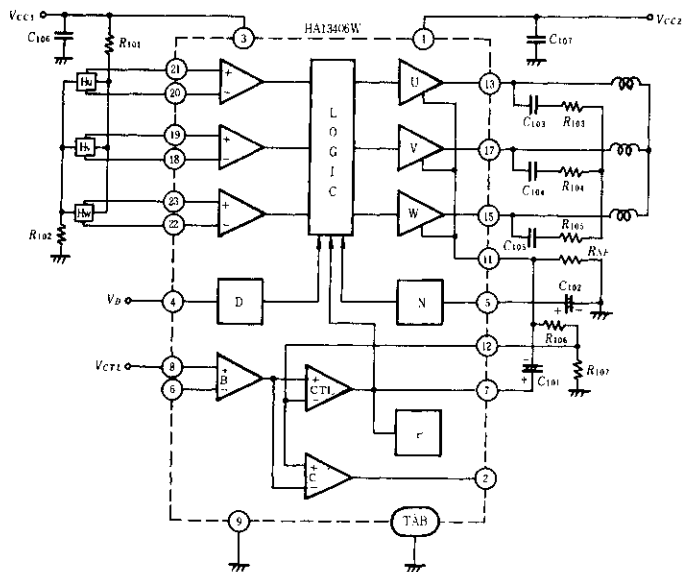
3. Reference to pin 6.

■ BLOCK DIAGRAM



■ APPLICATION

● **LINEAR DRIVE**



Description:

As the output stage is always saturated, the loss is less than the case in the application of Linear Drive and the efficiency of the system may be increased.

The comparator, C oscillates automatically and its ON-OFF duty is controlled by the control voltage V_{CTL} . Consequently, the ON-OFF duty of the external switching transistor Q_1 is also controlled by V_{CTL} . That results to so-called PWM control of power supply, which means that one pin voltage of IC's is controlled.

To the comparator C, the voltage which appears at current detection resistor R_{NF} feedbacks, so that the relationship between the current which flows the motor coil, I_o and the control voltage V_{CTL} is also shown in the equation (1).

The automatic oscillating frequency, f_c is mostly determined by the external constant on around the duty of 50%.

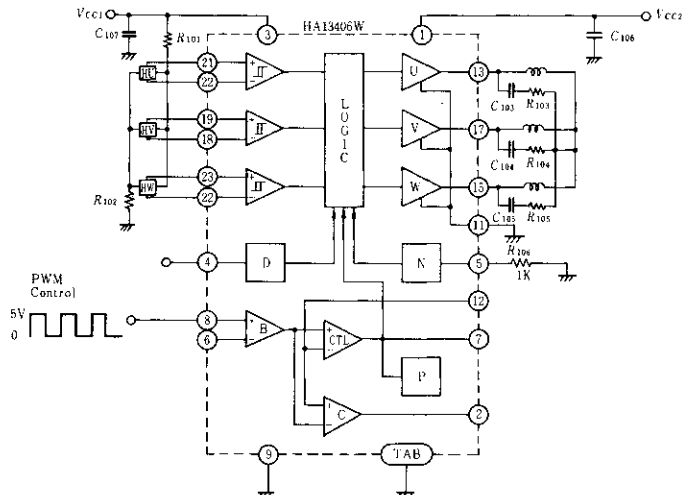
$$f_c \approx \frac{R_{NF} R_{110}}{4 L_t R_{106}} \quad (3)$$

The f_c is recommended to be set in the range between 20k and 100 kHz.

External Components

Parts No.	Recommended Value	Purpose	Note
R_{101}, R_{102}	—	For hall elements bias	
$R_{103}, R_{104}, R_{105}$	10Ω (1/4W)	For stability	1
R_{106}, R_{107}	—	For determining the control	
R_{108}	2.2kΩ (1/4W)	For preventing from error-operation caused by the leak current	
R_{109}	2.2kΩ (1/4W)	For limiting output current of comparator	
R_{110}	—	For determining the hysteresis of comparator	
R_{111}	4.7kΩ	For bias of Neutral Point Feedback Circuit	
R_{NF}	0.22Ω (2W)	For detecting output current	
C_{101}	100μF/16WV	Low pass filter	
$C_{103}, C_{104}, C_{105}$	0.1μF	For stability	1
C_{107}, C_{108}	0.1μF	For power supply by-passing	
L_1	1mH	Low pass filter	
Q_1	—	For switching power supply	
D_1	—	Fly Wheel Diode	

Note) 1. If no oscillation occurs, it may be deleted.

● HIGH FREQUENCY DRIVE

Description :

As the output stage is always saturated, the loss is less than case in the application (1) and the efficiency of the system may be increased.

In this application, output transistors are saturated or shut off. Output transistors switch on (saturated) at control input

“H”, switch off at the state “Lo”. That is, Motor speed can be controlled by PWM (Pulse Width Modulation)

Frequency range from 1 kHz to 20 kHz is recommended for the fundamental frequency.

External Components

Parts No.	Recommended Value	Purpose	Note
R101, R102	—	For Hall elements bias	
R103, R104, R105	10Ω (1/4W)	For stability	1
R106	1kΩ	For output stage bias	
C103, C104, C105	0.1μF	For stability	
C106, C107	0.1μF	For power supply by-passing	

Notes) 1. If no oscillation occurs, it may be deleted.

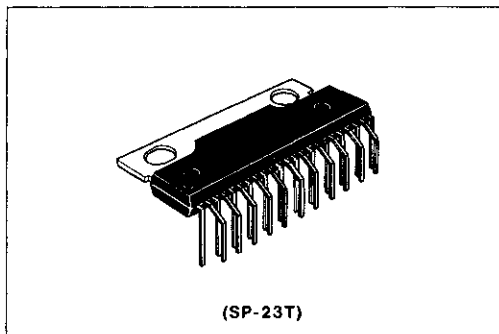
HA13408 ● 9-channel Power Driver

HA13408 is 9-channel Power Driver IC, designed for head driver of dot printer. This IC enables to drive 9 dot printers without using any other external components or IC's.

HA13408 can be used for 2 system four-phase step drive, as every channel is used independently.

■ FEATURES

- High output Current (MAX 1.5A/channel)
- High Sustaining Voltage (MIN 50V)
- Low Saturation Voltage
- Low Supply Current
- Low Input Current
- Compatible with TTL, LSTTL & 5V-C-MOS
- Low Thermal Resistance Package
- With Zener Diode

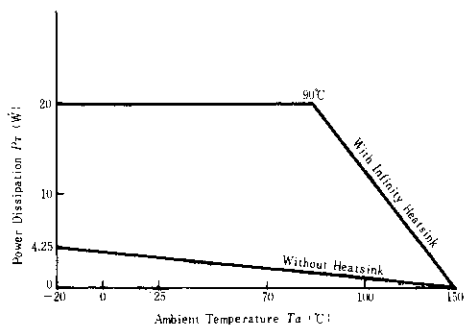


■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Rating	Unit	Note
Supply Voltage	V_{CC1}	7.0	V	
Input Voltage	V_i	V_{CC1}	V	
Output Voltage	$V_{CE(sat)}$	50	V	
Output Current	I_o	1.5	A	
Power Dissipation	P_T	20	W	1
Junction Temperature	T_j	150	$^\circ\text{C}$	
Operating Junction Temperature Range	T_{op}	-20 to $+125$	$^\circ\text{C}$	
Storage Temperature Range	T_{stg}	-55 to $+125$	$^\circ\text{C}$	

Note 1) See the Derating Curve of Fig.1.
 Thermal Resistance $\theta_j \leq 40^\circ\text{C/W}$
 $\theta_{js} \leq 3^\circ\text{C/W}$

Fig.1

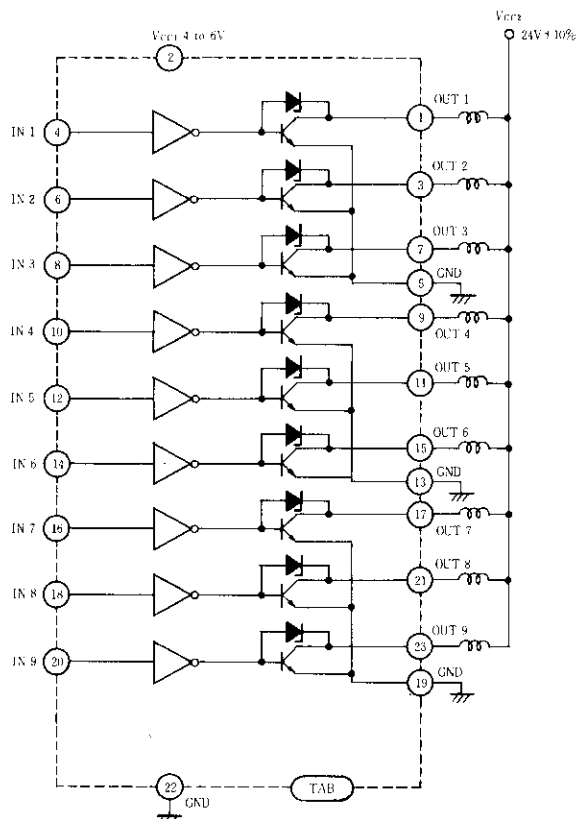


ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$, $V_{CC1}=5\text{V}$)

Test Item	Symbol	Test Conditions	min	typ	max	Unit	Note
Input Low Voltage	V_{IL}	$V_{CC1}=4.0\text{V}$	—	—	0.8	V	
Input High Voltage	V_{IH}	$V_{CC1}=6.0\text{V}$	2.0	—	—	V	
Input Low Current	I_{IL}	$V_I=0\text{V}$	-100	-15	+10	μA	
Input High Current	I_{IH}	$V_I=2.4\text{V}$	-10	0	+10	μA	
Supply Current	I_{CC0}	All $V_I=2.4\text{V}$	—	30	45	mA	
	I_{CC}	All $V_I=0\text{V}$	—	33	50	mA	
Output Cut Off Current	I_{CEO}	$V_{CC1}=6\text{V}$, $V_{CC2}=40\text{V}$, $V_I=2.0\text{V}$	—	—	1.0	mA	
Output Saturation Voltage	$V_{CE(sat)}$	$V_{CC1}=4\text{V}$, $I_O=1.0\text{A}$, $V_I=0.8\text{V}$	—	1.6	2.2	V	
Output Sustaining Voltage	$V_{CE(sus)}$	$I_O=1.0\text{A}$	50	—	—	V	1
Delay Time	t_{PLH}	Turn OFF	—	1.5	5	μs	
	t_{PHL}	Turn ON	—	0.3	5	μs	

Notes) 1. The conditions of Loading: Measure at $L_S=5\text{mH}$, $R_S=22\Omega$.

BLOCK DIAGRAM



TRUTH TABLE

Input	Output
LO	ON
HI	OFF
OPEN	OFF

■ PEAK CURRENT AND TURN-OFF TIME

The Fig. 1 shows waveforms of load current (I_{out}) and output terminal voltage (V_{out}) when driving inductive load.

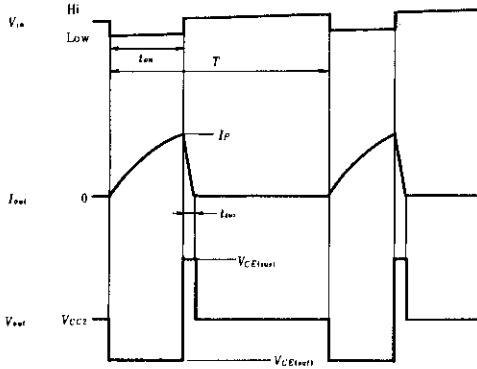


Fig.1

The peak value of output current (I_p) and sustaining time (t_{sus}) are obtained as follows;

$$I_p = \frac{V_{CC2} - V_{CE(sat)}}{R} \left(1 - e^{-\frac{R}{L} t_1} \right) \approx \frac{V_{CC2}}{R} \left(1 - e^{-\frac{R}{L} t_{on}} \right) \quad (1)$$

$$t_{sus} = \frac{L}{R} \ln \left(1 + \frac{I_p \cdot R}{V_{CE(sus)} - V_{CC2}} \right) \quad (2)$$

Where L is self-inductance of load and R is direct current resistance of load.

For example, under the following conditions;

$L = 5\text{mH}$, $R = 22\Omega$, Supply Voltage $V_{CC2} = 24\text{V}$,

The time to drive load = 0.42ms.

Peak Current (I_p) and sustaining time (t_{sus}) are obtained as follows;

$I_p = 0.87\text{ (A)}$

$t_{sus} = 0.118\text{ (ms)}$

where $V_{CE(sat)} = 1.3\text{V typ.}$ and $V_{CE(sus)} = 52\text{V typ.}$

■ POWER DISSIPATION

On the other hand, in case of driving inductive load, power dissipation is determined in the following.

At first, average power dissipation (P_{on}) per channel at t_{on} is obtained as follows;

$$P_{on} \approx V_{CE(sat)} I_p \left(\frac{V_{CC2}}{R \cdot I_p} - \frac{1}{t_{on}} \frac{L}{R} \right) \quad (3)$$

Average power dissipation (P_{sus}) at t_{sus} ;

$$P_{sus} \approx V_{CE(sus)} I_p \left(\frac{1}{t_{sus}} \frac{L}{R} - \frac{V_{CE(sus)} - V_{CC2}}{R \cdot I_p} \right) \quad (4)$$

Where I_p and t_{sus} are obtained in the equation (1) and (2).

Average power dissipation (P_T) per channel for a period is obtained as follows;

$$P_T = \frac{1}{T} (P_{on} \cdot t_{on} + P_{sus} \cdot t_{sus}) \quad (5)$$

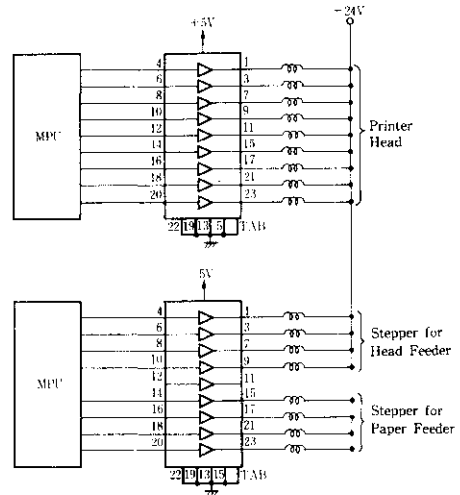
Where drive period is defined as T .

And power dissipation (P_T) when driving 9 channels at the same time;

$$P_T = \frac{9}{T} (P_{on} \cdot t_{on} + P_{sus} \cdot t_{sus}) \quad (6)$$

■ APPLICATION

● Dot Printer



HA13415 ● Quad. Solenoid Driver

The HA13415, a monolithic power IC, is a driver for inductive loads.

Packaged in Dual-in-Line 16 pin, contains four driving circuits of 0.6A.

Each driver has OCSD circuit to protect the IC from the short circuit of loads, and is best suited for drivers of solenoid, relay and stepping motors.

■ FUNCTIONS

- 0.6A Quad Driver
- With Clamp Diode
- With Chip Enable
- With OCSD (Over Current Shutdown)
- With Low Voltage Inhibit

■ FEATURES

- High Sustaining Voltage (50V)
- Low Saturation Voltage
- Compatible with TTL
- Low Input Current

■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Ratings	Units	Note
Supply Voltage	V_{CC}	-0.5 to 6	V	1
Input Voltage	V_{IN}	-0.5 to 6	V	
Output Voltage	V_{out}	50	V	
Output Current	I_o	0.6	A	
Power Dissipation	P_T	2.0	W	2
Junction Temperature	T_j	150	$^{\circ}\text{C}$	
Operating Junction Temperature Range	T_{op}	-40 to +125	$^{\circ}\text{C}$	
Storage Temperature Range	T_{stg}	55 to +150	$^{\circ}\text{C}$	

Notes: 1. Recommended Operating Voltage

$V_{CC} = 5\text{V} \pm 10\%$, 4.5 to 5.5V.

2. See the Derating Curve below.

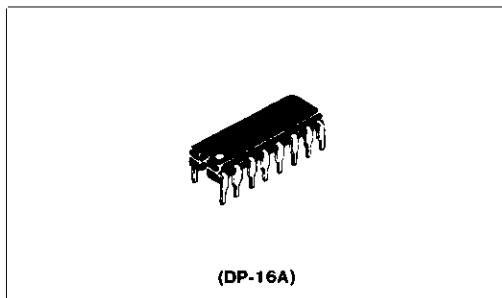
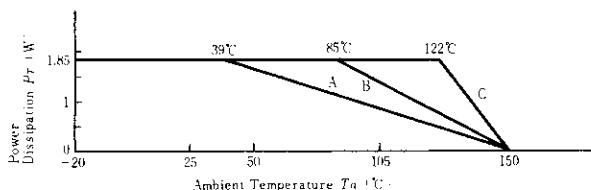
A: Soldered on a print circuit board. ($\theta_{JA} \leq 60^{\circ}\text{C/W}$).

B: Soldered on a print circuit covered with copper sufficiently.

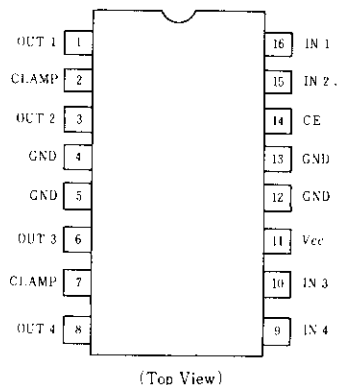
($\theta_{JA} \leq 35^{\circ}\text{C/W}$).

C: Soldered on pin 4, 5, 12, and 13 with an infinity heat sink.

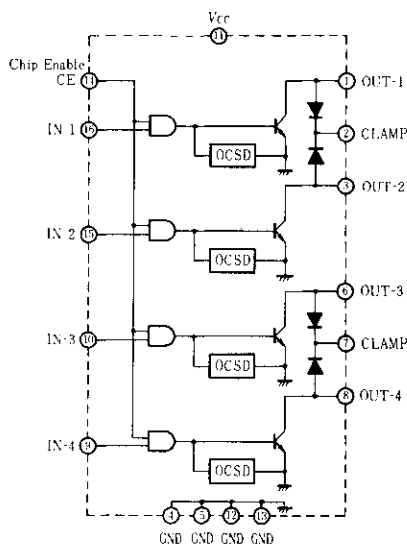
($\theta_{JA} \leq 15^{\circ}\text{C/W}$).



■ PIN ARRANGEMENT



■ BLOCK DIAGRAM



■ ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, $V_{CC}=5\text{V}$)

Item	Symbol	Test Conditions	min	typ	max	Units	Note
Supply Current	I_{CC}	CE=0.8V	—	6	—	mA	
		CE=IN=2.0V	—	60	80	mA	
Low Level Input Voltage	V_{IL}		0	—	0.8	V	
High Level Input Voltage	V_{IH}		2.0	—	—	V	
Low Level Input Current	I_{IL}	$V_i=0.8\text{V}$	-10	—	10	μA	
High Level Input Current	I_{IH}	$V_i=2.0$ to 5V	-10	—	10	μA	
Input Clamp Voltage	V_{IK}	$I_{IK}=-12\text{mA}$	—	-1.0	-1.5	V	1
Low Level Output Voltage	V_{OL}	$I_C=-0.3\text{A}$	—	0.20	0.4	V	
		$I_C=-0.6\text{A}$	—	0.40	0.7	V	
Output Leakage Current	I_{CEX}	$V_{CE}=50\text{V}$	—	—	100	μA	
Clamp Diode Forward Voltage	V_F	$I_F=0.4\text{A}$	—	1.1	—	V	
		$I_F=0.8\text{A}$	—	1.3	—	V	
Clamp Diode Reverse Current	I_R	$V_R=50\text{V}$	—	—	100	μA	
Turn On & Turn Off Delay	t_{pHL}	$R_L=56\Omega$	for IN	—	0.2	μs	
			for CE	—	0.4	μs	
	t_{pLH}	$R_L=56\Omega$	for IN	—	1.0	μs	
			for CE	—	1.5	μs	
Negative Output Current Test		$I_O=-100\text{mA}$					2
Output Short Test		$V_L=5.5\text{V}$, $R_L=3.5\Omega$					3
Capacitive Load Test		$V_L=17\text{V}$, $R_L=27\Omega$, $C_L=0.01\mu\text{F}$					4
Solenoid Survival Test		$V_L=32\text{V}$, $R_L=56\Omega$, $L_L=250\text{mH}$					5

Notes) 1. See Fig. 1.

2. Test Procedures are

(1) $V_{CC}=5.5\text{V}$ (2) Set all outputs "ON" with $I_C=250\text{mA}$ per output, then set $I_C=-100\text{mA}$ for one output. All remaining outputs shall remain "ON".(3) Set all outputs "OFF" then set $I_C=-100\text{mA}$ for one output. Each remaining Output shall not conduct more than 30mA .

(4) Perform test for each output.

3. See Fig. 2.

4. See Fig. 3.

5. See Fig. 4.

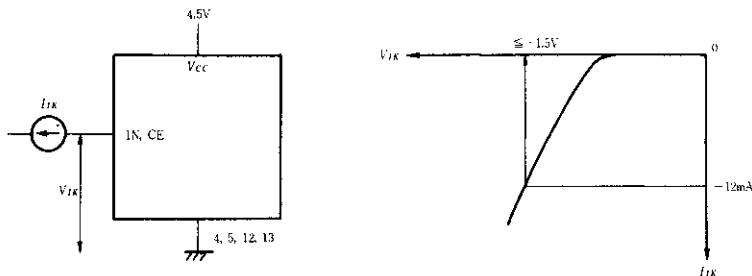


Fig. 1 Input Clamp Voltage

● Measure at pins 9, 10, 14, 15, 16.

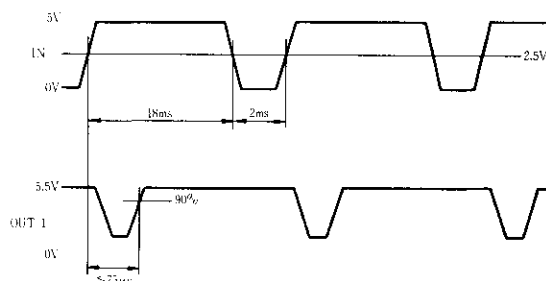
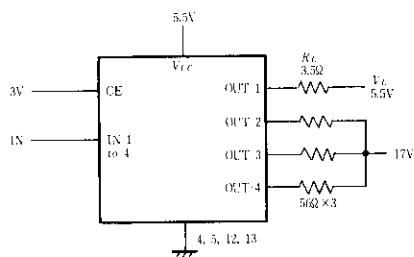


Fig. 2 Output Short Test

- Each unshorted output shall turn ON and remain ON with $I_C = 300\text{mA}$ per channel.
- Perform test for each output.

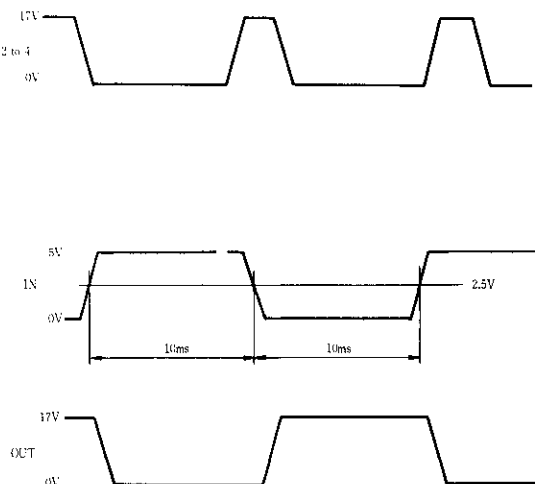
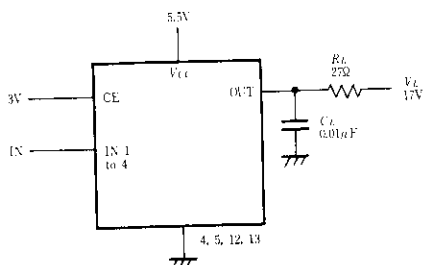


Fig. 3 Capacitive Load Test

- OCSD shall not become enabled and limit I_C or disable the output being tested during the cycling.
- Test each output, one ON at a time.

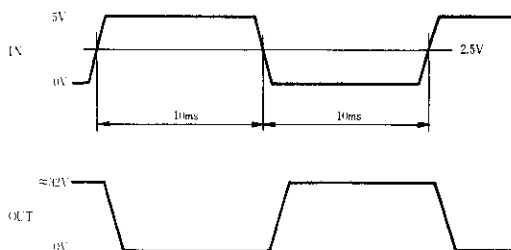
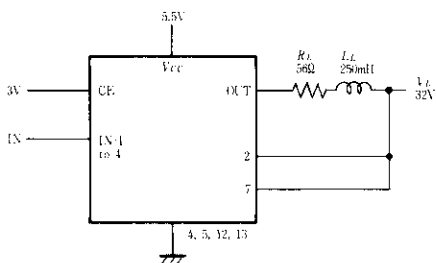


Fig. 4 Solenoid Survival Test

- Each output "ON" and "OFF".
- Test one output each time.

HA13421A, HA13421AMP ● Dual Bridge Drivers

HA13421A and HA1342AMP are monolithic power ICs, dual bridge drivers. The maximum driving current and voltage are 0.33A x 12V per bridge. Therefore, this value finds best use in the 2 phase bipolar stepping motor driving to head actuator of 3 to 5 1/4 inch FDD.

■ FEATURES

- 330mA Output Current Capability
- Dual Bridge Included
- With Power Save
- Single — Input Direction Control
- Low Output Saturation Voltage
- Low Supply Current
- Low Input Current
- Compatible with TTL, LSTTL & 5V CMOS
- With Thermal Shutdown

■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	HA13421A	HA13421AMP	Unit	Note
Logic Stage Supply Voltage	V_{CC}	7	7	V	1
Seeking Supply Voltage	V_{S1}	15	15	V	1
Holding Supply Voltage	V_{S2}	7	7	V	1
Input Voltage	V_i	0 to V_{CC}	0 to V_{CC}	V	
Peak Seeking Current	I_o (peak)	500	500	mA	2
Seeking Current(DC)	I_{oS}	330	330	mA	
Holding Current(DC)	I_{oH}	200	200	mA	
Power Dissipation	P_T	2.0	1.0	W	3
Junction Temperature	T_j	150	150	$^{\circ}\text{C}$	
Operating Junction Temperature Range	T_{jop}	-20 to +125	-20 to +125	$^{\circ}\text{C}$	
Storage Temperature Range	T_{sk}	-55 to +125	-55 to +125	$^{\circ}\text{C}$	

Notes 1) Recommended Operating Voltage

	MIN	TYP	MAX	UNIT
V_{CC}	4.5	5.0	5.5	V
V_{S1}	10.2	12.0	13.8	V
V_{S2}	4.5	5.0	5.5	V

2) $t \leq 5 \text{ ms}$

3) See the Derating Curve below.

A: Soldered on a print circuit board. ($\theta_{JA} \sim 60^{\circ}\text{C/W}$)

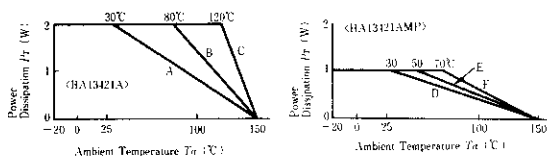
B: Soldered on a print circuit covered with copper sufficiently. ($\theta_{JA} \leq 35^{\circ}\text{C/W}$)

C: Soldered on pin 4, 5, 12, and 13 with an infinity heat sink. ($\theta_{JA} \leq 15^{\circ}\text{C/W}$)

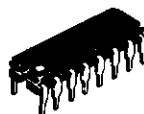
D: Soldered on glass epoxy circuit board with 10% printing ($\theta_{JA} \leq 120^{\circ}\text{C/W}$)

E: Soldered on glass epoxy circuit board with 30% printing ($\theta_{JA} \leq 100^{\circ}\text{C/W}$)

F: Soldered on a metal based circuit board ($\theta_{JA} \leq 80^{\circ}\text{C/W}$)



HA13421A



(DP-16A)

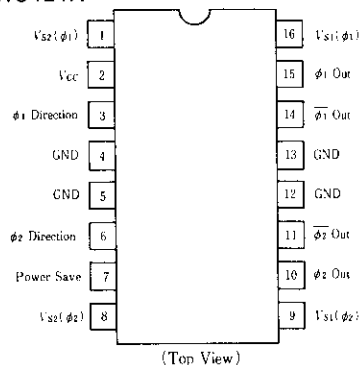
HA13421AMP



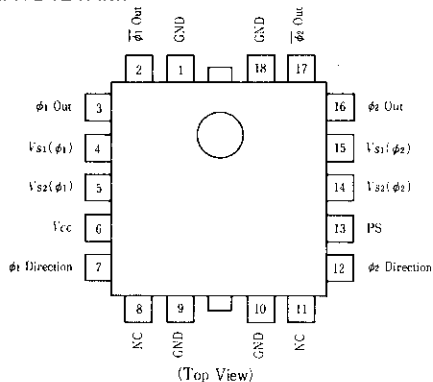
(MP-18)

■ PIN ARRANGEMENT

● HA13421A



● HA13421AMP



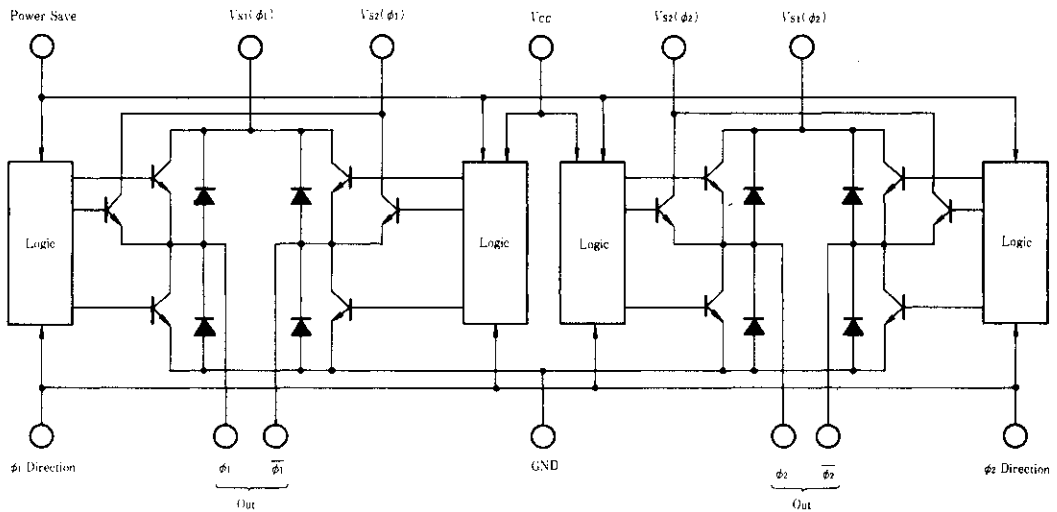
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, $V_{CC}=5\text{V}$, $V_{S2}=5\text{V}$, $V_{S1}=12\text{V}$)

Item	Symbol	Test Condition		min	typ	max	Unit	Note
Input Low Voltage	V_{IL}			—	—	0.8	V	
Input High Voltage	V_{IH}			2.0	—	—	V	
Input Low Current	I_{IL}	$V_I=0.8\text{V}$		—	—	± 10	μA	
Input High Current	I_{IH}	$V_I=2\text{V}$		—	1.0	10	μA	
Input High Current	I_{IH}	$V_I=5\text{V}$		—	0.3	1.0	mA	
Supply Current		$\text{PS}=0.8\text{V}$, $I_O=0$	V_{CC}	—	25	33	mA	
			V_{S1}	—	10	20	mA	1
			V_{S2}	—	—	1.0	mA	2
		$\text{PS}=2\text{V}$, $I_O=0$	V_{CC}	—	25	33	mA	
			V_{S1}	—	3	5	mA	1
			V_{S2}	—	5	10	mA	2
Output TRS Breakdown Voltage	BV_{CEB}	$I_C=10\text{mA}$	18	—	—	V		
V_{S1} Saturation Voltage	$V_{CE(sat)1}$	$\text{PS}=0.8\text{V}$, $I_O=330\text{mA}$	—	1.5	2.0	V	3	
V_{S2} Saturation Voltage	$V_{CE(sat)2}$	$\text{PS}=2.0\text{V}$, $I_O=130\text{mA}$	—	1.5	2.0	V	3	
Clamp Diode Forward Voltage	V_F	$I_F=330\text{mA}$	Upper	—	5	—	V	
			Lower	—	1.5	—	V	
Delay Time	t_{PLH}	$I_O=330\text{mA}$	—	1.0	5	μs		
Delay Time	t_{PHL}	$I_O=330\text{mA}$	—	1.0	5	μs		

Note 1) The specification indicates the sum of $V_{S1}(\phi_1)$ & $V_{S1}(\phi_2)$ current.

Note 2) The specification indicates the sum of $V_{S2}(\phi_1)$ & $V_{S2}(\phi_2)$ current.

Note 3) The specification indicates the sum of Upper & Lower saturation voltages.

BLOCK DIAGRAM


TRUTH TABLE

For Each Bridge

Power Save	Direction	ϕ -Out	$\bar{\phi}$ -Out
L	L	L	H'
L	H	H'	L
H	L	L	H'
H	H	H'	L

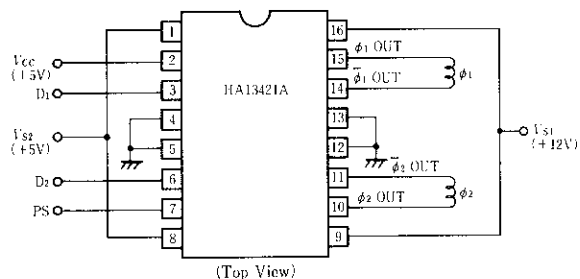
L = Low Voltage State

H' = High Voltage State (Seeking TRS On)

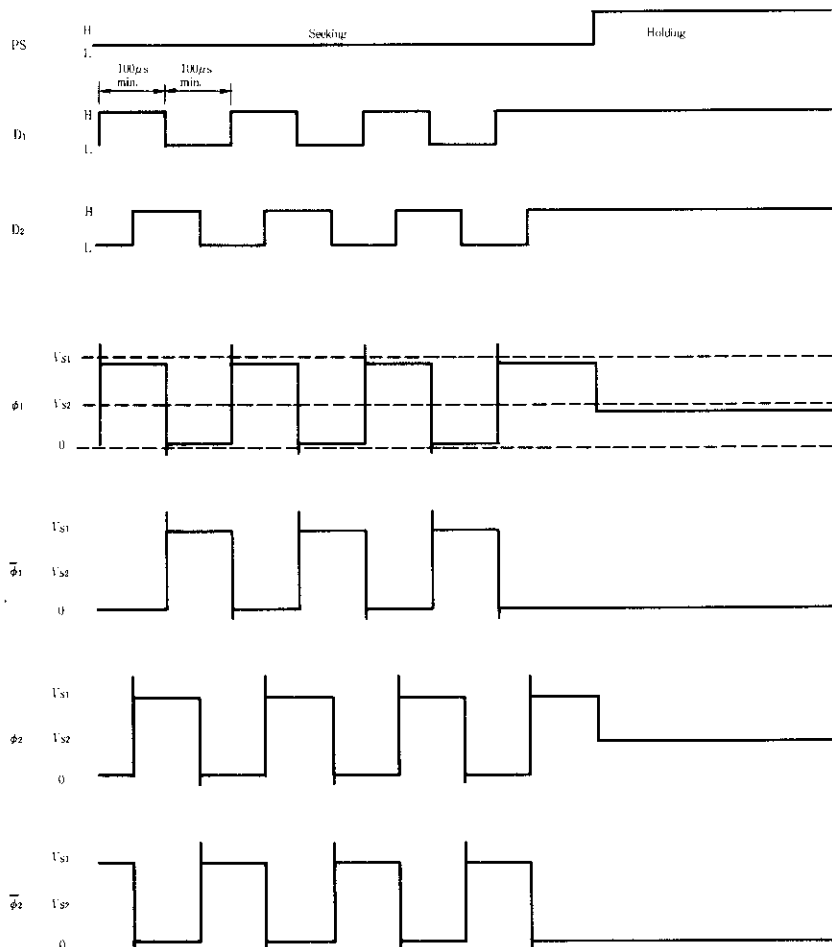
H'' = High Voltage State (Holding TRS On)

APPLICATION

2-phase Bipolar Stepping Motor Drive Circuit



TIMING CHART



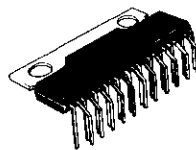
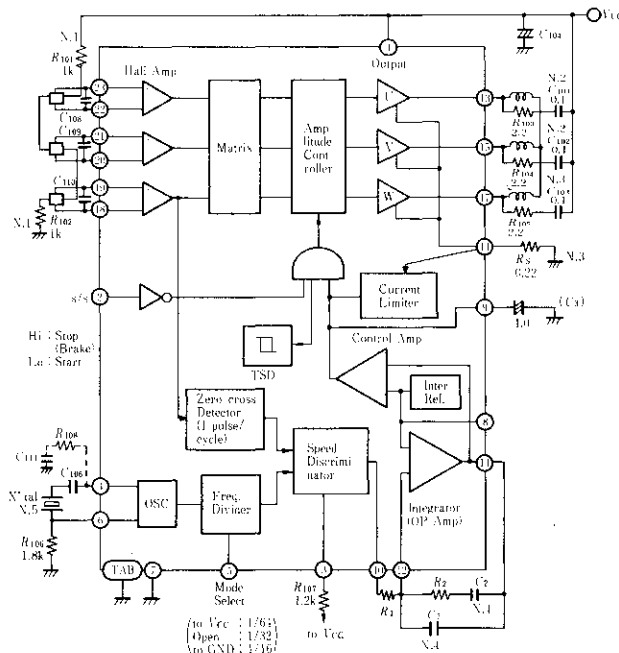
HA13426 ● Three-phase Motor Driver with Speed Discriminator

HA13426 is a power IC with a speed discriminator for the three-phase brushless motor driving of 5 1/4 inch-HDD (Hard Disk Drive). It is possible to construct a servo system with quartz resonator, requiring fewer external components. Especially EMI noise from motor driver is depressed because of a voltage drive system.

■ FEATURES

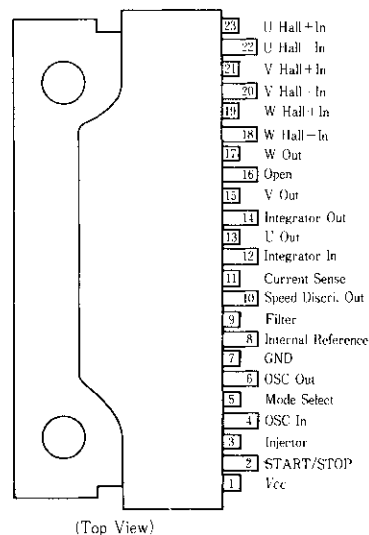
- Possible to construct a servo system on a single chip
- Large output current (3A)
- Require no adjustment because of digital servo system
- The voltage drive system (not supply voltage control) achieves almost no spike voltage at commutating, caused EMI (Electro-Magnetic Interference) conventionally.
- The START/STOP terminal of TTL level is attached.
- Load-short brake at STOP mode
- Maximum current at starting is depressed by the built-in current limiter.
- Wide selection for quartz resonator is permitted because of frequency divider.

■ BLOCK DIAGRAM



(SP-23T)

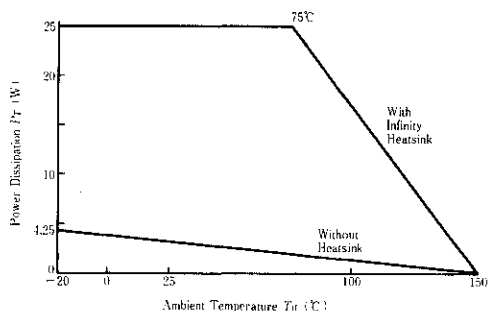
■ PIN ARRANGEMENT



■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Ratings	Unit	Note
Supply Voltage	V_{CC}	15	V	1
Input Voltage	V_{IN}	0 to V_{CC}	V	2
Output Current	I_O	3	A	
Power Dissipation	P_T	25	W	3
Junction Temperature	T_J	150	$^{\circ}\text{C}$	
Operating Junction Temperature Range	T_{JOP}	-20 to +125	$^{\circ}\text{C}$	
Storage Temperature Range	T_{STG}	-55 to +125	$^{\circ}\text{C}$	

- Note) 1. Recommended operating voltage
 $V_{CC}=12\text{V} \pm 15\%$ (10.2V to 13.8V)
 2. Applied to Hall Amp. mode select input.
 Maximum Input Voltage at start/stop is 6V.
 3. See the derating curve.
 $\theta_{JA} \leq 3^{\circ}\text{C/W}$
 $\theta_{JA} \leq 40^{\circ}\text{C/W}$



■ ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$, $V_{CC}=12\text{V}$)

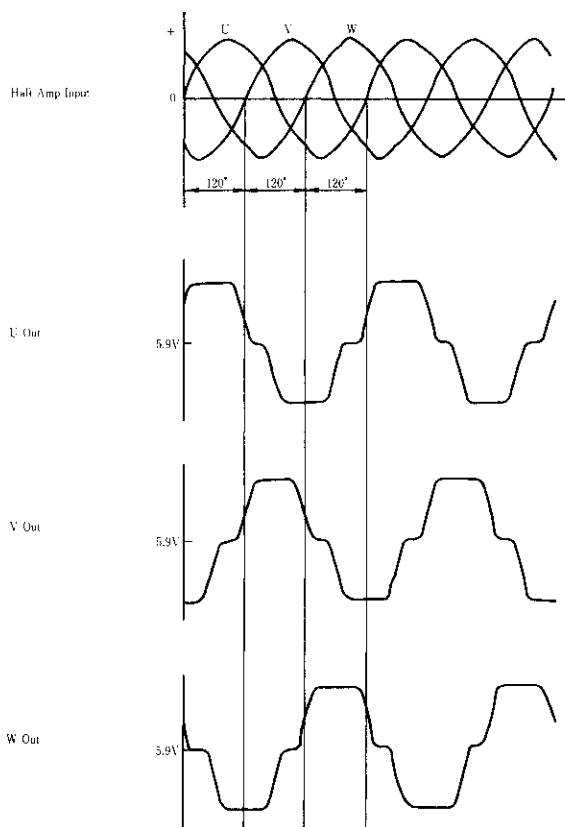
Item		Symbol	Test Condition	min	typ	max	Unit	Note
Total	Supply Current	I_{SO}	S/S=2.0V	—	50	70	mA	
		I_S	S/S=0.8V, R_L =Open	—	55	75	mA	
	Thermal Shutdown Temperature	T_{SD}	Shutdown	—	150	—	$^{\circ}\text{C}$	
		T_{HY}	Hysteresis	—	20	—	$^{\circ}\text{C}$	
Hall Amp	Input Bias Current	I_{IH}	$V_{IH}=6.0\text{V}$	—	2	10	μA	
	Input Common Mode Voltage Range	V_{IH}		2.0	—	10	V	
	Voltage Gain	G_{IH}		—	10	—	dB	
Output Stage	Quiescent Output Voltage	V_O		5.3	5.9	6.5	V	
	Difference Between Phase	ΔV_O		—	—	± 0.3	V	
	Saturation Voltage	$V_{CE(sat)}$	$I_O=2\text{A}$	—	2.4	3.2	V	1
	Output Impedance	R_O	$I_O=0.4\text{A}$	—	0.2	—	Ω	
Control Amp	Internal Ref. Voltage	V_{REF}		3.0	3.2	3.4	V	
	Voltage Gain (CTL Amp to Output)	G_{CTL}		21	24	27	dB	
	Difference of Gain	ΔG_{CTL}		—	—	± 2	dB	
Integrator	Input Bias Current	I_{IH}		—	—	± 0.1	μA	
	Output Voltage Swing	A_+	$I_O=0.3\text{mA}$	—	0.7	—	V	
		A_-	$I_O=-0.3\text{mA}$	—	0.7	—	V	

Note) 1. Sum of upper and lower TRS saturation voltages

(to be continued)

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, $V_{CC}=12\text{V}$)

Item		Symbol	Test Condition	min	typ	max	Unit	Note
Speed Discriminator	Output Voltage Swing	V_{OH}	$I_{IN}=-0.3\text{mA}$	5.8	6.1	-	V	
		V_{OL}	$I_{O}=-0.3\text{mA}$	-	-	0.2	V	
	Cutoff Current	I_{off}	Charge Pump Off State	-	-	± 0.1	μA	
	Operating Frequency	f_{CLK}		60	-	250	kHz	
Start/Stop	Count Number	N		-	1024	-		
	Input High Voltage	V_{IH}	Stop	2.0	-	-	V	
	Input Low Voltage	V_{IL}	Start	-	-	0.8	V	
	Input High Current	I_{IH}	$V_{IN}=2.0\text{V}$	-	-0.15	-0.5	mA	
Current Limiter	Input Low Current	I_{IL}	$V_{IL}=-0.8\text{V}$	-	-0.2	-0.5	mA	
	Reference Voltage			0.52	0.56	0.60	V	
Mode Select	1/16 Division Input Voltage	$V_{1/16}$		-	-	0.8	V	
	1/32 Division Input Voltage	$V_{1/32}$	Open	-	6.3	-	V	
	1/64 Division Input Voltage	$V_{1/64}$		11.2	-	-	V	
	1/16 Division Input Current	$I_{1/16}$	$V_{IS}=-0\text{V}$	-	-0.63	-1.3	mA	
	1/64 Division Input Current	$I_{1/64}$	$V_{IS}=12\text{V}$	-	1.0	1.5	mA	
Oscillator	Operating Frequency	f_{osc}		-	-	8.0	MHz	

TIMING CHART


EXTERNAL COMPONENTS

Parts No.	Recommended Value	Function	Note
R101	1k Ω	Hall Elements Bias	1
R102			
R103			
R104	2.2 Ω (0.5W)	Stability	
R105			
R106	1.8k Ω	OSC Bias	6
R107	1.2k Ω	Speed Descri. bias	
R108	470 Ω	Stability	6
R1, R2	See Application	Integral Constant	
R5		Current Sense	3
C101			
C102	0.1 μ F	Stability	2
C103			
C104	$\geq 0.1\mu$ F	V _{CC} By-passing	
C106	10pF	AC Coupling OSC	
C108, C109			
C110	$\geq 0.01\mu$ F	Stability	
C111	4700pF	Stability	6
C1, C2	See Application	Integral Constant	4
C3	See Application	Filter Constant	
X'tal		Resonator	5

Notes) 1. Set R101 and R102 at which output voltage of more than 50mVpp is applied to hall elements.

2. Use C101 to C103 which cause no 2nd resonance.

And connect the middle points of C101, C102 and C103 to the most stable one of those of V_{CC}, GND the middle point of coil.
(Requiring to use non-polar in case of connecting them to the middle point of coil.)

3. Output current is limited as shown below by RS valve.

$$I_{out} = \frac{0.56(V) \pm 10\%}{R_S(\Omega)}$$

For example, output current is limited to 2.55(A) $\pm 10\%$ at $R_S = 0.22\Omega$.

4. Need to use non-polar as to C1 and C2.

5. The relationship between Crystal Oscillation frequency, f_{osc} and the number of rotation, N is as follows.

$$N = \frac{60}{512} \cdot \frac{m \cdot f_{osc}}{P} \text{ (rpm)}$$

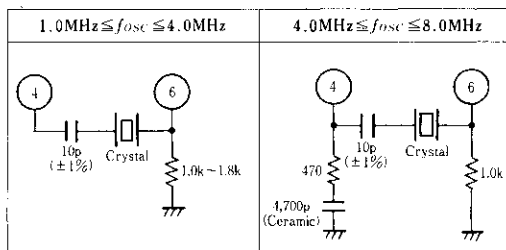
Where P is the number of pole of motor, and m is the division ratio of Frequency Divider and the latter is set at the following values by the voltage applied to Mode Select.

Mode Select	m
to GND	1/16
Open	1/32
to V _{CC}	1/64

For instance, the relationship between Mode Select and f_{osc} to rotate a 4-pole motor at 3600 rpm as shown below.

Mode Select	f_{osc} (MHz)
to GND	1.96608
Open	3.93216
to V _{CC}	7.86432

6. Determine external components of Oscillator as shown below in accordance with the frequency range.



HOW TO USE THE HA13426/431/432/432MP

1. Selection of Resonator

1.1 In HA13426

The oscillating frequency at synchronous, f_{osc} and the number of motor rotation N have a relationship shown below.

$$N = \frac{60}{512} \cdot \frac{m \cdot f_{osc}}{p} \text{ (rpm)} \quad (1)$$

where, the p is the number of motor poles and m is the dividing ratio of a divider. For the m, one of the following values is selected according to applied voltage at the mode select pin.

Mode Select	m
to GND	1/16
Open	1/32
to V _{CC}	1/64

For example, the values of f_{osc} to rotate 4-poles motor with 3600 rpm are;

Mode Select	f_{osc} (MHz)
to GND	1.96608
Open	3.93216
to V _{CC}	7.86432

1.2 In HA13431/432/432MP

The oscillating frequency at synchronous, f_{osc} and the FG frequency, f_{FG} have a relationship shown below.

$$f_{FG} = \frac{m \cdot f_{osc}}{1024} \quad (2)$$

where, m is the dividing ratio of a divider and takes one of the following values according to the applied voltage at the mode select pin.

Mode Select	m
to GND	1
Open	1/2
to V _{CC}	1/4

2. How to Determine the Integral Constants R_1 , R_2 , C_1 and C_2 , and the Filter Constant C_3

2.1 Block Diagram

Fig. 1 is the block diagram showing motor speed control by the HA13426/431/432/432MP. The part enclosed by dotted lines denotes the IC, and the $G_1(S)$ and the $G_2(S)$ indicate the transfer functions of an integrator and from control amp to output, respectively. Since these IC's are driven by voltage, items of the motor coil impedance and the kick-back voltage are contained in the loop.

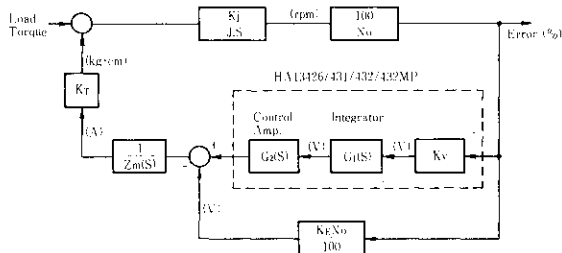


Fig. 1 Block Diagram

- K_j = Transfer constant, 9.55
 K_T = Torque constant (kg·cm/A)
 K_E = Kick-back constant (V/rpm)
 K_v = Speed discriminator gain (V/%)
 J = Moment of inertia (kg·cm·sec²)
 $Z_m(S)$ = Motor coil impedance (Ω)
 $G_1(S)$ = Transfer function of an integrator
 $G_2(S)$ = Transfer function from control amp to output
 N_o = Standard number of rotation

2.2 Resolution

In the Fig. 1, when

$$A(S) = \frac{K_j}{J \cdot S} \cdot \frac{100}{N_o} \quad (3)$$

$$\beta(S) = \frac{K_T}{Z_m(S)} \cdot (K_f \cdot G_1(S) \cdot G_2(S) + \frac{K_E \cdot N_o}{100}) \quad (4)$$

the Fig. 1 can be shown as Fig. 2.

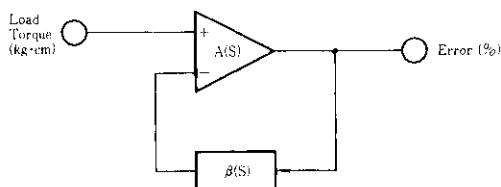


Fig. 2

On the other hand, the $Z_m(S)$, $G_1(S)$ and $G_2(S)$ are expressed as follows;

$$Z_m(S) = R_m(1 + S/\omega_m) \quad (5)$$

$$G_1(S) = \frac{R_2}{R_1} \frac{1 + \omega_2/S}{1 + S/\omega_1} \quad (6)$$

$$G_2(S) = \frac{G_{CTL}}{1 + S/\omega_3} \quad (7)$$

Then,

$$\omega_m = \frac{R_m}{L_m} \quad (8)$$

$$\omega_1 = \frac{1}{C_1 R_2} \quad (9)$$

$$\omega_2 = \frac{1}{C_2 R_2} \quad (10)$$

$$\omega_3 = \frac{1}{C_3 R_3} \quad (11)$$

The G_{CTL} and the R_3 are the internal constant of IC's.

Substituting the equations (5) to (11), to the equation (4), $\beta(S)$ is;

$$\begin{aligned}
 \beta(S) &= \frac{K_T}{R_m(1 + S/\omega_m)} \left(\frac{R_2 K_v G_{CTL}(1 + \omega_2/S)}{R_1(1 + S/\omega_1)(1 + S/\omega_3)} - \frac{K_E N_o}{100} \right) \\
 &= \frac{R_2 K_T K_v G_{CTL}}{R_1 R_m} \frac{1 + \omega_2/S}{(1 + S/\omega_m)(1 + S/\omega_1)(1 + S/\omega_3)} \\
 &\quad \left(\because \frac{R_2 K_v G_{CTL}}{R_1} \geq \frac{K_E N_o}{100} \right)
 \end{aligned} \quad (12)$$

To control speed with stability, $A(S)$ and $\beta(S)$ are required to have a relationship shown in Fig. 3. That is, the angular frequency of the cross point of $A(S)$ and $\beta(S)$, ω_0 should be put between the angular frequency of an integrator, ω_1 and ω_2 .

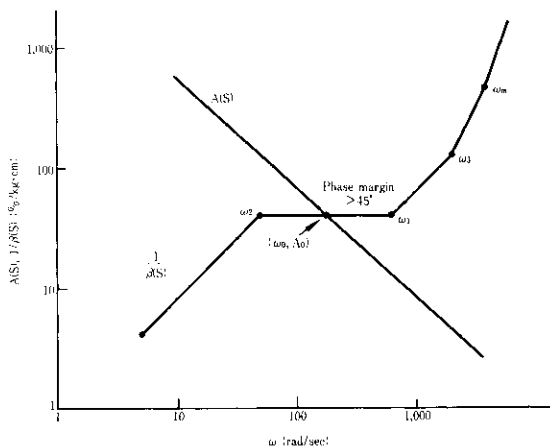


Fig. 3 Stable Relationship of $A(S)$ and $\beta(S)$

2.3 Design Procedure of the R_1 , R_2 , C_1 , C_2 and C_3

(1) Determining the ω_0

The ω_0 uses the value of 1/10 to 1/30 of the ω_m or the angular frequency of FG, ω_{FG} which is the lower. In HA13426, the angular frequency of the hall signal is used for ω_{FG} , and the ω_0 is the value of 1/30 to 1/100 of the ω_{FG} .

(2) Calculating the A_0

From the equation (3)

$$A_0 = \frac{K_f}{J \cdot \omega_0} \cdot \frac{100}{N_0} \quad (13)$$

(3) Designing R_1 and R_2

From the Fig. 3 and the equation (12),

$$\frac{R_2}{R_1} = \frac{R_m}{K_T \cdot K_V \cdot G_{CTL} \cdot A_0} \quad (14)$$

Each IC is designed to take the following K_V and G_{CTL} .

Type	K_V (V/%)	G_{CTL} (V/V)
HA13426	0.03	16 typ
HA13431	0.023	16 typ
HA13432/MP	0.023	8 typ

Small R_1 increases the C_1 and C_2 and large R_1 will cause speed error by the cutoff current of the speed discriminator and the input bias current of the integrator. Values of 10k ohms to 56k ohms are recommended.

(4) Determining ω_1 , ω_2 and ω_3

Will be determined as follows

$$\omega_1 \geq 3 \omega_0$$

$$\omega_2 \leq \omega_0/3$$

$$\omega_3 \geq 3 \omega_0$$

(5) Designing C_1 , C_2 , C_3

From the equations (9), (10), (11),

$$C_1 \approx 1/\omega_1 R_2$$

$$C_2 \approx 1/\omega_2 R_2$$

$$C_3 = 1/\omega_3 R_3$$

where the R_3 is designed to be 2.2k ohms.

3. When Using the External Clock

As shown in Fig. 4, external clock can be provided at the OSC input pin. But, applying too large input causes the miss-operation of IC's, the following resistor, R_s must be connected in series to control the current.

(1) In HA13426

$$R_s \geq 2.5(V_{IH} - 1.4) - 1.5 \quad (\text{k}\Omega)$$

$$R_s \leq 7.5(1.4 - V_{IL}) - 1.5 \quad (\text{k}\Omega)$$

A speeding-up capacitor parallel to R_s should be considered.

(2) In HA13431/432/432MP

$$R_s \geq 3.7(V_{IH} - 1.7) - 2 \quad (\text{k}\Omega)$$

$$R_s \leq 1.0(1.7 - V_{IL}) - 2 \quad (\text{k}\Omega)$$

Then, the input current I_{IH} and I_{IL} are restricted as follows and the external clock must have larger driving capacity.

$$I_{IH} = \frac{V_{IH} - 1.4}{R_s + R_i} \quad (\text{mA})$$

$$I_{IL} = \frac{1.4 - V_{IL}}{R_s + R_i} \quad (\text{mA})$$

where, the R_i is the input resistance of the OSC and is 1.5k ohms in HA13426 or 2k ohms in the others.

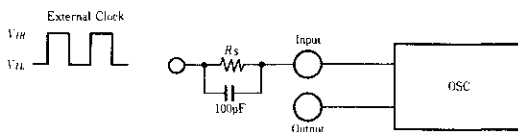


Fig. 4 Providing External Clock

4. Producing the Ready Signal

As shown in the Fig. 5, external comparator can produce the ready signal. Since the DC gain is extremely high (70dB or more), the rotation error, ΔN when the ready signal V_R becomes high is determined by the accuracy of the speed discriminator without the influence of the window of a comparator.

Open collector output type comparators are recommended.

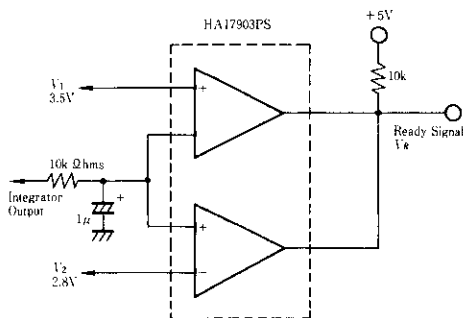


Fig. 5 Producing the Ready Signal

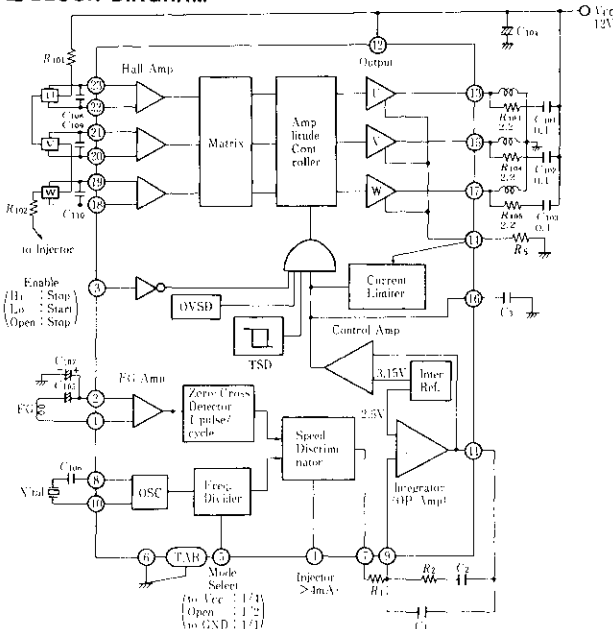
HA13431 ● Three-phase Motor Driver with Speed Discriminator

HA13431 is a monolithic power IC with a speed discriminator for the three-phase brushless DC motor driving of 5 1/4 inch FDD. It is possible to construct a servo system with quartz or ceramic resonator by fewer external components. Especially EMI noise from motor driver is depressed because of a voltage drive system.

■ FEATURES

- Possible to construct a servo system on a single chip
- Require no adjustment because of digital servo system
- The voltage drive system (not supply voltage control) achieves almost no spike voltage at commutating, caused EMI conventionally.
- The Enable terminal of TTL level is attached, and the current at the stop mode is less than 0.5mA
- Maximum current at starting is depressed by the built-in current limiter.
- Wide selection for quartz & ceramic resonator is permitted because of frequency divider

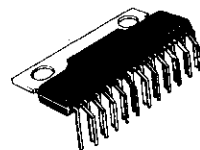
■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

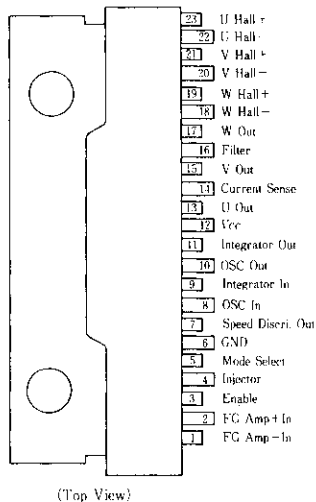
Item	Symbol	Ratings	Unit	Note
Supply Voltage	V _{CC}	20	V	1
Input Voltage	V _{IN}	0 to V _{CC}	V	2
Output Peak Current	I _{o peak}	1.5	A	
Output Current	I _o	1.0	A	
Power Dissipation	P _r	10	W	3
Junction Temperature	T _j	150	°C	
Operating Junction Temperature Range	T _{op}	-20 to +125	°C	
Storage Temperature Range	T _{stg}	55 to +125	°C	

- Notes: 1. Recommended operating voltage
V_{CC} = 12V ± 15%; 10.2V to 13.8V
2. Applied to Hall Amp, start stop and mode select input.
3. See the derating curve.
θ_{JA} ≤ 3°C/W
θ_{JA} ≤ 40°C/W

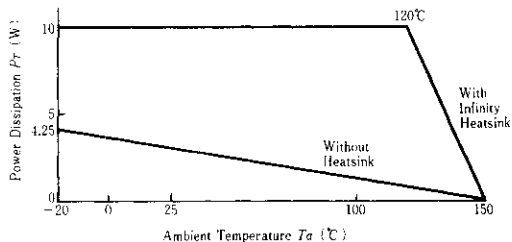


(SP-23T)

■ PIN ARRANGEMENT



(Top View)



■ ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, $V_{CC}=12\text{V}$)

	Item	Symbol	Test Condition	min	typ	max	Unit	Note
Total	Quiescent Current	I_Q	Enable=2.0V	—	0.2	0.5	mA	
			Enable=0.8V, R_L : Open	—	24	31	mA	
	Over Voltage Shutdown	V_{OL}	Shutdown Voltage	15	16	17	V	
		V_{HYS}	Hysteresis	0.5	0.8	1.2	V	
	Thermal Shutdown	T_{SD}	Shutdown	—	150	—	$^\circ\text{C}$	
		T_{HYS}	Hysteresis	—	25	—	$^\circ\text{C}$	
Hall Amp	Input Bias Current	I_{HB}	$V_H=6.0\text{V}$	—	1.0	5	μA	
	Input Common Mode Voltage Range	V_{IH}		1.5	—	10.5	V	
	Voltage Gain	G_{VH}		—	10	—	dB	
Output Stage	Quiescent Output Voltage	V_Q		5.1	5.7	6.3	V	
	Difference of Quiescent Voltage	ΔV_Q		—	—	± 0.3	V	
	Saturation Voltage	$V_{CE(sat)}$	$I_O=0.7\text{A}$	—	2.0	2.8	V	1
	Output Impedance	R_O	$I_O=0.2\text{A}$	—	0.3	—	Ω	
Control Amp	Internal Ref. Voltage	V_{REF1}		—	3.15	—	V	
	Voltage Gain (CTL Amp to Output)	G_{CTL}		—	24	—	dB	
	Difference of Gain	ΔG_{CTL}		—	—	± 2	dB	
Integrator	Internal Ref. Voltage	V_{REF2}		—	2.5	—	V	
	Input Bias Current	I_{BI}		—	—	± 0.1	μA	
	Output Voltage Swing	A_+	$I_O=+0.25\text{mA}$	—	1.3	—	V	
		A_-	$I_O=-0.25\text{mA}$	—	0.65	—	V	
Speed Discriminator	Unity Gain Band Width	BW	$B_V=0\text{dB}$	—	0.3	—	MHz	
	Injection Voltage	V_I	$I_I=6\text{mA}$	—	0.9	—	V	
	Output High Voltage	V_{OH}	$I_O=0.25\text{mA}$	4.4	4.7	—	V	
	Output Low Voltage	V_{OL}	$I_O=-0.25\text{mA}$	—	0.1	0.2	V	
	Cutoff Current	I_{OFF}	Charge Pump Off State	—	—	± 0.1	μA	
	Count Number			—	1024	—		
Enable	Input High Voltage	V_{IH}	Stop	2.0	—	—	V	
	Input Low Voltage	V_{IL}	Start	—	—	0.8	V	
	Input High Current	I_{IH}	$V_H=2.0\text{V}$	—	—	± 10	μA	
	Input Low Current	I_{IL}	$V_L=0.8\text{V}$	—	—	± 10	μA	
Current Limiter	Reference Voltage	V_{REF3}		0.36	0.4	0.44	V	
FG Amp	Input Voltage	$V_{IN(FG)}$	$f=200\text{Hz}$	2.0	—	20	mVpp	
OSC	Oscillation Frequency	f_{osc}		0.1	—	1.0	MHz	
Mode Select	No Division Input Voltage	$V_{1/1}$		—	—	0.8	V	
	1/2 Division Input Voltage	$V_{1/2}$	Open	—	6.3	—	V	
	1/4 Division Input Voltage	$V_{1/4}$		10	—	—	V	
	No Division Input Current	$I_{1/1}$	$V_{1/1}=0\text{V}$	—	—	1.0	mA	
	1/4 Division Input Current	$I_{1/4}$	$V_{1/4}=12\text{V}$	—	—	1.0	mA	

Note 1) Sum of upper and lower TRS saturation voltages.

EXTERNAL COMPONENTS

Parts No.	Recommended Value	Function	Note
R_{101}, R_{102}	—	Hall Elements Bias	1
$R_{103}, R_{104}, R_{105}$	2.2Ω	Stability	
R_S		Current Sense	3
R_1, R_2	See Application	Integral Constant	4
$C_{101}, C_{102}, C_{103}$	0.1μF	Stability	2
C_{104}	$\geq 0.1\mu\text{F}$	V_{CC} By-passing	
C_{105}	10μF	AC Coupling FG	
C_{106}	47pF	AC Coupling OSC	
C_{107}	10μF	Stability	
$C_{108}, C_{109}, C_{110}$	$\geq 0.01\mu\text{F}$	Stability	
C_1, C_2	See Application	Integral Constant	4
C_3	See Application	Filter Constant	4
X'tal	See Application	Resonator	4

Notes 1) Set R_{101} and R_{102} at which output voltage of 30 to 100mVpp.

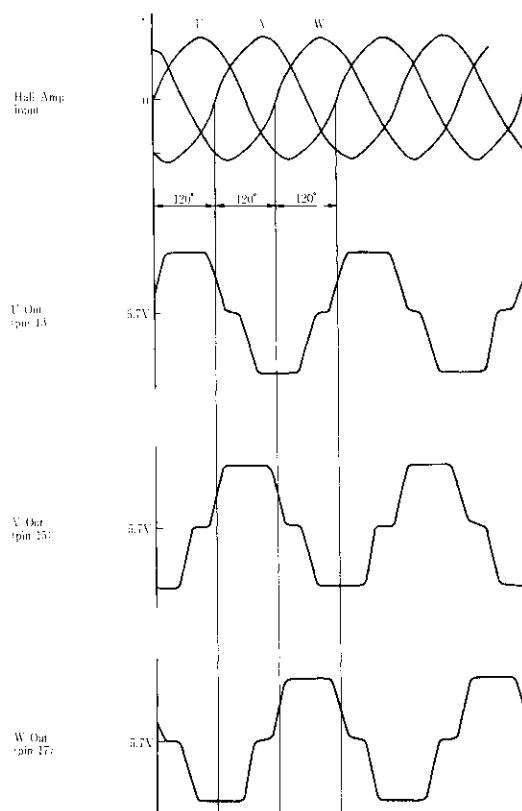
2) Use C_{101} to C_{103} which cause no 2nd resonance.

3) Output current is limited as shown below by R_S value.

$$I_{\text{limit}} = \frac{V_{\text{REF}}}{R_S}$$

4) See HA13426.

TIMING CHART



HA13432, HA13432MP ● Three-phase Motor Driver with Speed Discriminator

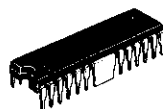
HA13432 and HA13432MP are monolithic power ICs with a speed discriminator for the three-phase brushless DC motor driving of micro or compact FDD. It is possible to construct a servo system with quartz or ceramic resonator, requiring fewer external components.

Especially EMI noise from motor driver is depressed because of a voltage drive system.

■ FEATURES

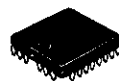
- Possible to construct a servo system on a single chip
- Require no adjustment because of digital servo system
- The voltage drive system (not supply voltage control) achieves almost no spike voltage at commutating, caused EMI (Electro-Magnetic Interference) conventionally.
- The Enable terminal of TTL level is attached, and the current at the stop mode is less than 0.5mA.
- Maximum current at starting is depressed by the built-in current limiter
- Wide selection for quartz & ceramic resonator is permitted because of frequency divider.

HA13432



(DIP-24TS)

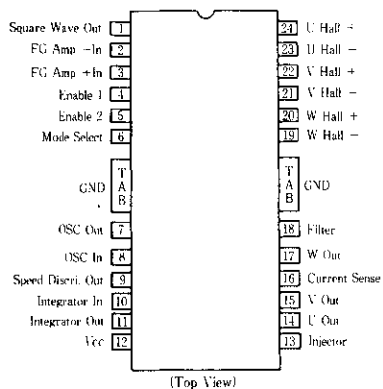
HA13432MP



(MP-28)

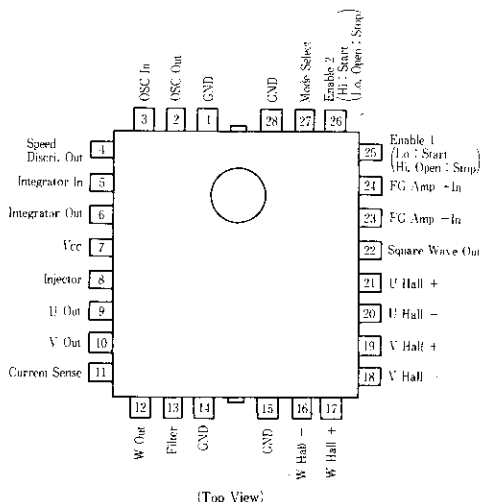
■ PIN ARRANGEMENT

● HA13432

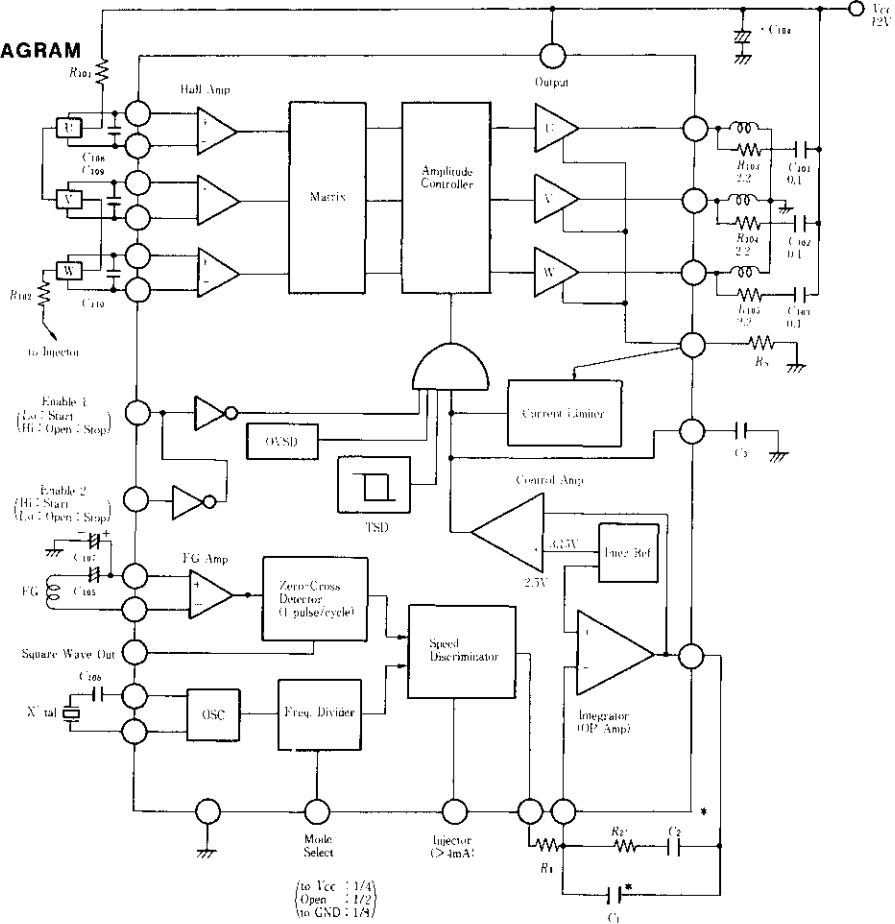


Enable	Hi	Open	Lo
1	Stop	Stop	Start
2	Start	Stop	Stop

● HA13432MP



■ BLOCK DIAGRAM

■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

Item	Symbol	HA13432	HA13432MP	Unit	Note
Supply Voltage	V_{CC}	20	20	V	1
Input Voltage	V_{IN}	0 to V_{CC}	0 to V_{CC}	V	2
Output Peak Current	$I_{O(peak)}$	0.75	0.75	A	
Output Current	I_O	0.5	0.5	A	
Power Dissipation	P_T	2.5	1.5	W	3
Junction Temperature	T_J	150	150	$^\circ\text{C}$	
Operating Junction Temperature Range	T_{OP}	-20 to +125	-20 to +125	$^\circ\text{C}$	
Storage Temperature Range	T_{STG}	-55 to +125	-55 to +125	$^\circ\text{C}$	

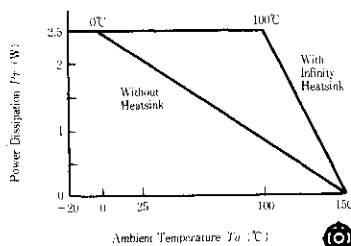
Notes) 1. Recommended operating voltage $V_{CC}=12\text{V} \pm 15\%$ (10.2 to 13.8V)

2. Applied to Hall Amp, start-stop and mode select input

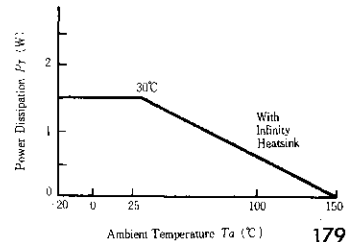
3. See the derating curves.

The right below figure shows the relationship between P_T and T_a (the derating curve) in the case that HA13432MP is mounted on the surface of a metal base substrate.

■ HA13432



■ HA13432MP



■ ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, $V_{CC}=12\text{V}$)

	Item	Symbol	Test Condition	min	typ	max	Unit	Note
Total	Quiescent Current	I_Q	Enable 1 & 2 Open	—	0.2	0.5	mA	
			Enable 1=0.8V R _L Open	—	19	24	mA	
	Over Voltage Shutdown	V_{od}	Shutdown Voltage	15	16	17	V	
		V_{hys}	Hysteresis	0.5	0.8	1.2	V	
	Thermal Shutdown	T_{sd}	Shutdown	—	150	—	°C	
Hall Amp		T_{hys}	Hysteresis	—	25	—	°C	
	Input Bias Current	I_{IH}	$V_H=6.0\text{V}$		1.0	5	μA	
	Input Common Mode Voltage Range	V_H		1.5	—	10.5	V	
Output Stage	Voltage Gain	G_{VH}		—	10	—	dB	
	Quiescent Output Voltage	V_Q		5.1	5.7	6.3	V	
	Difference of Quiescent Voltage	ΔV_Q		—	—	±0.3	V	
	Saturation Voltage	$V_{CE(sat)}$	$I_Q=0.35\text{A}$		2.0	2.8	V	*
	Output Impedance	R_O	$I_Q=0.1\text{A}$	—	0.45	—	Ω	
Control Amp	Internal Ref. Voltage	V_{REF1}			3.15	—	V	
	Voltage Gain (CTL Amp to Output)	G_V		15	18	21	dB	
	Difference of Gain	ΔG_V		—	—	±2	dB	
Integrator	Internal Ref. Voltage	V_{REF2}			2.5	—	V	
	Input Bias Current	I_{BI}		—	—	±0.1	μA	
	Output Voltage Swing	A_1	$I_O=+0.25\text{mA}$	—	1.3	—	V	
		A_2	$I_O=-0.25\text{mA}$	—	0.65	—	V	
	Unity Gain Band Width	BW	$G_V=0\text{dB}$		0.3	—	MHz	
Speed Discriminator	Injection Voltage	V_i	$I_i=6\text{mA}$	—	0.9	—	V	
	Output High Voltage	V_{OH}	$I_O=0.25\text{mA}$	4.4	4.7	—	V	
	Output Low Voltage	V_{OL}	$I_O=-0.25\text{mA}$	—	0.1	0.2	V	
	Cutoff Current	I_{off}	Charge Pump Off State	—	—	±0.1	μA	
	Count Number				1024	—		
Enable	Input High Voltage	V_{IH}		2.0	—	—	V	
	Input Low Voltage	V_{IL}		—	—	0.8	V	
	Input High Current	I_{IH}	$V_H=2.0\text{V}$	Enable 1	—	±10	μA	
				Enable 2	50	120	μA	
	Input Low Current	I_{IL}	$V_L=0.8\text{V}$	Enable 1	—	±10	μA	
Current Limiter				Enable 2	—	+40	μA	
	Reference Voltage	V_{REF3}		0.36	0.4	0.44	V	
FG Amp	Input Voltage	$V_{(a+FG)}$	$f=200\text{Hz}$	2.0	—	20	mV _{pp}	
OSC	Oscillation Frequency	f_{osc}		0.1	—	1.0	MHz	
Mode Select	No Division Input Voltage	$V_{1/1}$		—	—	0.8	V	
	1/2 Division Input Voltage	$V_{1/2}$	Open	—	6.3	—	V	
	1/4 Division Input Voltage	$V_{1/4}$		10	—	—	V	
	No Division Input Current	$I_{1/1}$	$V_{IN}=0\text{V}$	—	—	1.0	mA	
	1/4 Division Input Current	$I_{1/4}$	$V_{IN}=12\text{V}$	—	—	1.0	mA	

Note *) Sum of upper and lower TRS saturation voltages

External Components

Parts No.	Recommended Value	Function	Note
R ₁₀₁ , R ₁₀₂	—	Hall Elements Bias	1
R ₁₀₃ , R ₁₀₄ , R ₁₀₅	2.2Ω	Stability	
R _s	—	Current Sense	3
R ₁ , R ₂	See Application	Integral Constant	4
C ₁₀₁ , C ₁₀₂ , C ₁₀₃	0.1μF	Stability	2
C ₁₀₄	≧ 0.1μF	Vcc By-passing	
C ₁₀₅	10μF	AC Coupling FG	
C ₁₀₆	47pF	AC Coupling OSC	
C ₁₀₇	10μF	Stability	
C ₁₀₈ , C ₁₀₉ , C ₁₁₀	≧ 0.01μF	Stability	
C ₁ , C ₂	See Application	Integral Constant	4
C ₃	See Application	Filter Constant	4
X'tal	See Application	Resonator	4

Note 1. Set R₁₀₁ and R₁₀₂ at which output voltage of 30 to 100 mVpp

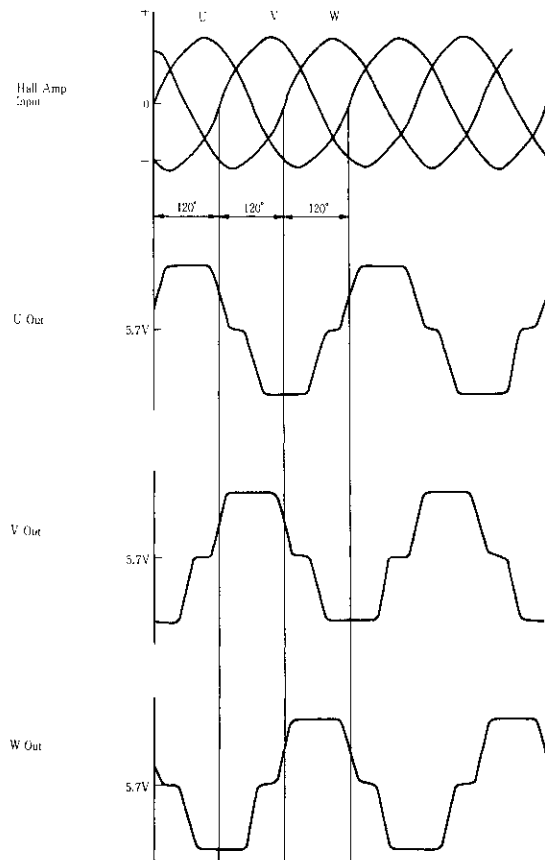
Note 2. Use C₁₀₁ to C₁₀₃ which cause no 2nd resonance.

Note 3. Output current is limited as shown below by R_s value.

$$I_{\text{limit}} = \frac{V_{\text{REG}}}{R_s}$$

Note 4. See HA13426.

TIMING CHART



HC16701 ● Thermal Head Driver

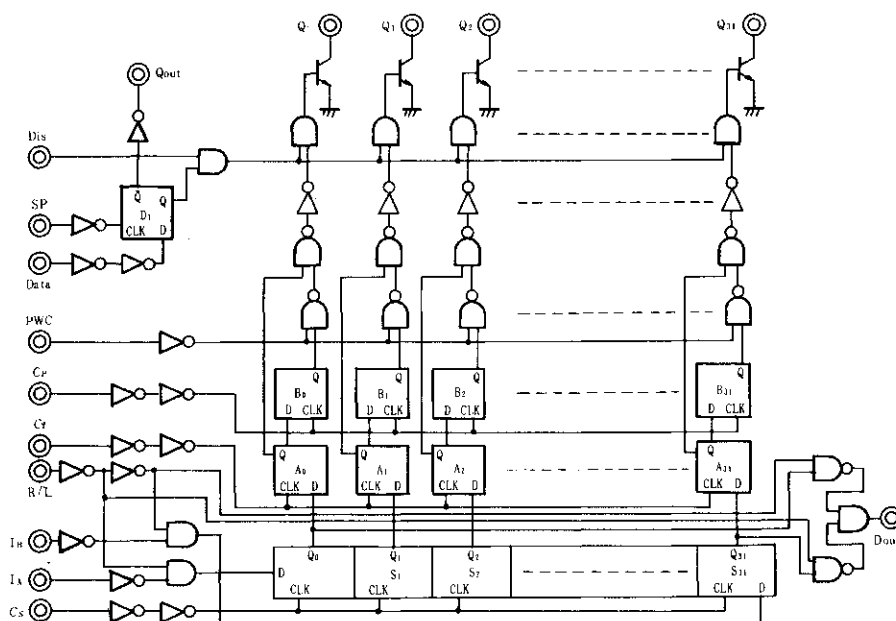
HC16701 has a function of serial-in-parallel-out plus 32ch driver, bi-directional shift register, two stage latches, strobe gate and large current driver. Logic circuits are composed of IIL and output 32ch driver

has a capability of driving large current. HC16701 is suitable for applications of thermal head driver and LED display driver.

■ FEATURES

- Each driver of built-in 32ch drivers (NPN Open Collector) has a capability of driving 70mA.
- Enable to shift the shift register in right and left directions by mode select terminals.
- Every channel has two stage latches and is available with controlling output pulse width in the unit of channel.
- Enable to prohibit driver output by Dis terminal. Available with prohibition against driver output at power "ON".
- Built-in D-F/F for selecting chip is available with the application of chip selector in the system of using some HC16701 IC's.

■ BLOCK DIAGRAM



■ MAXIMUM RATINGS ($T_a = +25^\circ\text{C}$)

Item	Symbol	Rating	Unit	Remarks
Supply Voltage	V_{CC}	7	V	
Output Sink Current	I_{OL}	100	mA	1
Output Terminal Voltage	V_{OH}	+25	V	2
Power Dissipation	P_C	$T_{J, max} = 125^\circ\text{C}$		
Operating Temperature Range	$T_{a, op}$	-20 to +70	$^\circ\text{C}$	
Operating Junction Temperature Range	$T_{J, op}$	-20 to +100	$^\circ\text{C}$	
Storage Temperature Range	T_{STG}	-35 to +125	$^\circ\text{C}$	

Notes: 1. Applied to output driver terminal Q_0 to Q_{31} when output driver transistor "ON".
2. Applied to output driver terminal Q_0 to Q_{31} , when output driver terminal "OFF".

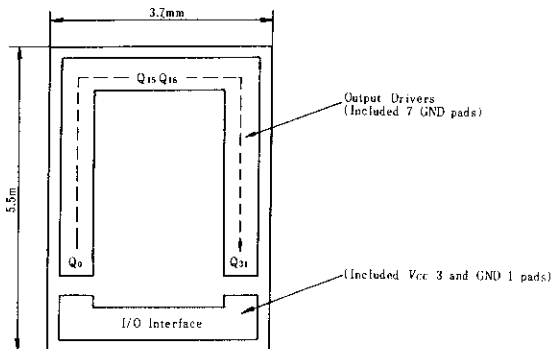
■ ELECTRICAL CHARACTERISTICS ($T_j = +25^\circ\text{C}$)

Item	Symbol	Test Condition	min	typ	max	Unit	Applicable Terminals
Operating Supply Voltage	V_{top}	$V_{\text{CC}} = 5.0\text{V}$, Driver: ON Duty 50%	4.5	5.0	5.5	V	V_{CC}
Quiescent Current	I_{CC}	$V_{\text{CC}} = 5.0\text{V}$, Driver: ON Duty 50%	—	120	160	mA	V_{CC}
Iinj Operating Voltage (Note 5)	V_{inj}		3.0	—	V_{CC}	V	I_{inj}
Injection Current	I_{inj}	$V_{\text{CC}} = 5.0\text{V}$, $V_{\text{inj}} = 5.0\text{V}$	—	30	—	mA	I_{inj}
Input High Voltage 1	V_{IH1}	$V_{\text{CC}} = 5.0\text{V}$	3.0	—	—	V	SP, PWC, CP, C _i
Input High Voltage 2	V_{IH2}	$V_{\text{CC}} = 5.0\text{V}$	2.5	—	—	V	CS, I _A , I _B , DATA
Input High Voltage 3	V_{IH3}	$V_{\text{CC}} = 5.0\text{V}$	3.0	—	—	V	D ₁ , R/L
Input Low Voltage 1	V_{IL1}	$V_{\text{CC}} = 5.0\text{V}$	—	—	0.3	V	SP, PWC, CP, C _i
Input Low Voltage 2	V_{IL2}	$V_{\text{CC}} = 5.0\text{V}$	—	—	0.8	V	CS, I _A , I _B , DATA
Input Low Voltage 3	V_{IL3}	$V_{\text{CC}} = 5.0\text{V}$	—	—	0.8	V	D ₁ , R/L
Input High Current 1	I_{IH1}	$V_{\text{CC}} = 5.0\text{V}$, CS, I _A , I _B = 5.0V	—	—	150	μA	CS, I _A , I _B
Input High Current 2	I_{IH2}	$V_{\text{CC}} = 5.0\text{V}$, DATA = 5.0V	—	—	150	μA	DATA
Input High Current 3	I_{IH3}	$V_{\text{CC}} = 5.0\text{V}$, D ₁ = 3.5V	—	—	150	μA	D ₁
Input High Current 4	I_{IH4}	$V_{\text{CC}} = 5.0\text{V}$, R/L = 3.5V	—	—	150	μA	R/L
Input High Current 5	I_{IH5}	$V_{\text{CC}} = 5.0\text{V}$, SP, PWC, CP, C _i = 3.5V	—	120	180	μA	SP, PWC, CP, C _i
Input Low Current 1	I_{IL1}	$V_{\text{CC}} = 5.5\text{V}$, CS, I _A , I _B = GND	−600	−400	—	μA	CS, I _A , I _B
Input Low Current 2	I_{IL2}	$V_{\text{CC}} = 5.5\text{V}$, DATA = GND	−600	−400	—	μA	DATA
Input Low Current 3	I_{IL3}	$V_{\text{CC}} = 5.5\text{V}$, D ₁ , R/L = GND	−20	—	—	μA	D ₁ , R/L
Input Low Current 4	I_{IL4}	$V_{\text{CC}} = 5.5\text{V}$, SP, PWC, CP, C _i = GND	−20	—	—	μA	SP, PWC, CP, C _i
Output Low Voltage 1 (Note 1)	V_{OL1}	$V_{\text{CC}} = 5.0\text{V}$, $I_{\text{OL}} = 10\text{mA}$	—	—	0.3	V	Q ₀ to Q ₃₁
Output Low Voltage 2 (Note 2)	V_{OL2}	$V_{\text{CC}} = 5.0\text{V}$, $I_{\text{OL}} = 0.6\text{mA}$	—	—	0.5	V	Q _{out}
Output Low Voltage 3 (Note 2)	V_{OL3}	$V_{\text{CC}} = 5.0\text{V}$, $I_{\text{OL}} = 1.2\text{mA}$	—	—	0.6	V	D _{out}
Output Current 1 (Note 3)	I_{OH1}	$V_{\text{CC}} = 4.5\text{V}$, D _{out} = 2.7V	300	500	—	μA	D _{out}
Output Current 2 (Note 3)	I_{OH2}	$V_{\text{CC}} = 4.5\text{V}$, Q _{out} = 2.7V	150	250	—	μA	Q _{out}
Output Leak Current (Note 4)	I_{leak}	$V_{\text{CC}} = 5.5\text{V}$, Q ₀ to Q ₃₁ = 25V	—	—	500	μA	Q ₀ to Q ₃₁

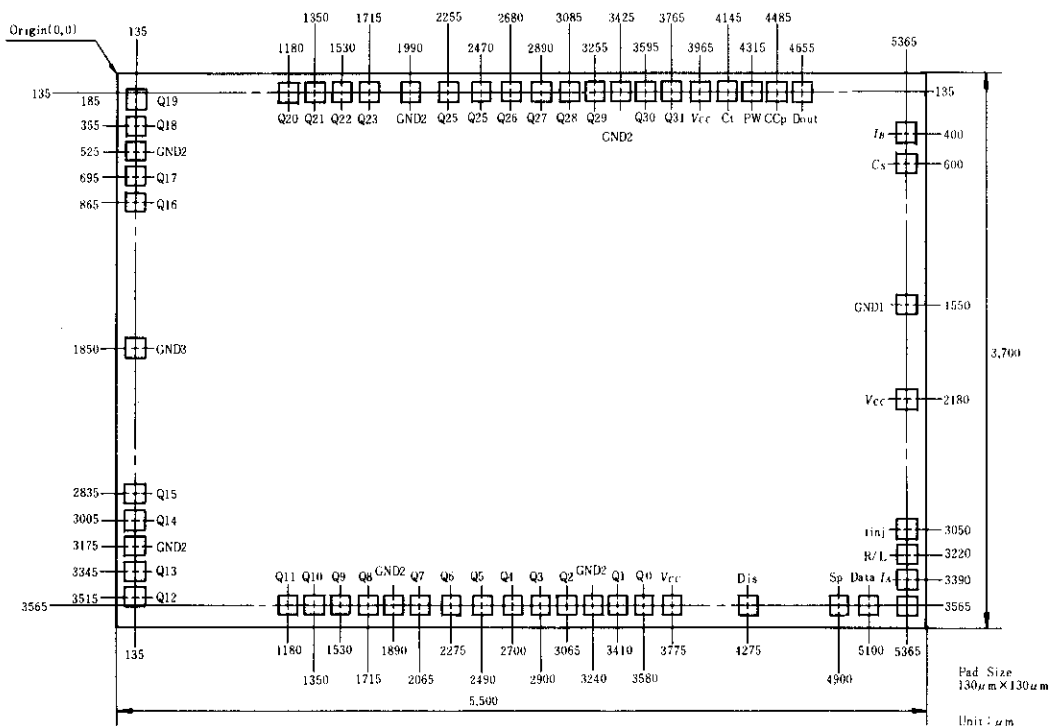
- Notes: 1. When setting the measuring output driver transistor "ON" and other thirty one output driver transistors "OFF".
 2. When setting the state of output "LOW".
 3. When setting the state of output "HIGH".
 4. When output transistor is "OFF".
 5. Iinj is pin for BL logic power supply.

■ PACKAGE (the chip product for sale)

- Chip size; 5.5 x 3.7mm
- The number of pads; 56 pcs. (output driver; 32 pcs. Vcc; 3 pcs. GND; 8 pcs. others; 13 pcs.)
- Pad Arrangement; See the following figure. (an outline)

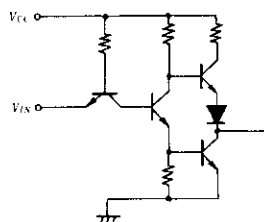


■ DICE DIMENSION

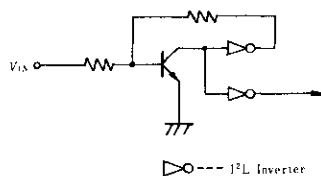


■ INPUT INTERFACE CIRCUIT

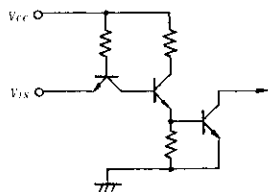
● C_s, I_a, I_b



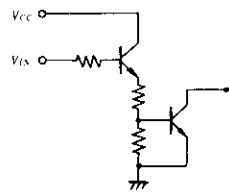
● S_r, C_r, C_p, PWC



● DATA

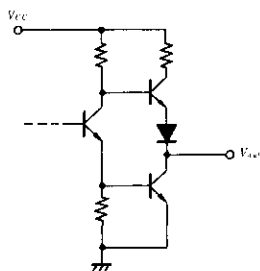


● $R/L, D_{11}$

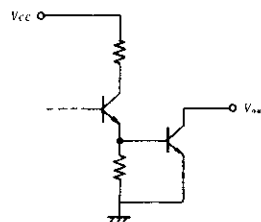


■ OUTPUT INTERFACE CIRCUIT

● D_{out}, Q_{out}



● $Q_0 \sim Q_{31}$



HA16628P ● 5-bit D/A Converter and Position Amplifier

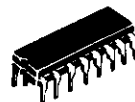
The HA16628P is a monolithic integrated circuit designed for use with the HA16629P to DC motor positioning system for applications such as carriage/daisy-wheel position Control in Typewrites.

■ FUNCTIONS

- 5 bit D/A Converter
- Error Amplifier
- Position Amplifier

■ FEATURES

- Single Supply Voltage 10V DC to 20V DC
- Compatible with TTL, LSTTL & C-MOS
- Low Input Current (D/A Converter)



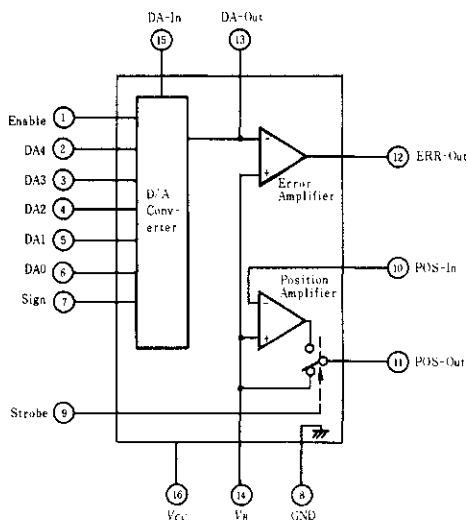
(DP-16)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

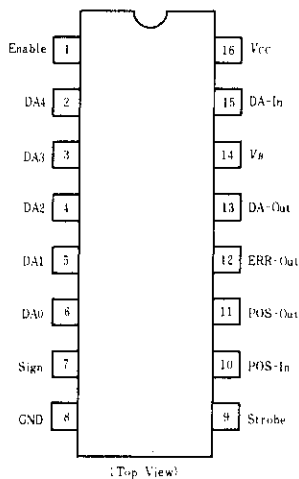
Item	Symbol	Rating	Unit	Note
Supply Voltage	V_{CC}	20	V	
Common Voltage	V_B	$0.55V_{CC}$	V	
Power Dissipation	P_T	450	mW	
Input Voltage	V_I	6	V	1
Output Current	I_O	± 5	mA	2
Operating Temperature Range	T_{op}	0 to $+70$	$^\circ\text{C}$	
Storage Temperature Range	T_{stg}	-50 to $+125$	$^\circ\text{C}$	

Notes: 1. Apply to DA₀~DA₄, Sign, ENABLE, STROBE
2. Apply to Pos-Out, ERR-Out

■ BLOCK DIAGRAM



■ PIN ARRANGEMENT



ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$, $V_{CC}=12\text{V}$, $V_B=5\text{V}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Supply Voltage	V_{CC}		10	—	20	V
Supply Current	I_{CC}	No Loads	—	—	10	mA
Supply Current of V_B (Pin 14)	I_B	No Loads	—	—	1	mA

●D/A Converter

Item	Symbol	Test Conditions	min	typ	max	Unit
Current Reference Input Range (Pin 15)	I_{DAIN}	all inputs $\bar{L}_J$	0.3	—	1	mA
Current Reference Off-set Voltage (Pin 15 to 14)	V_{IO}	$I_{DAIN}=0.3$ to 0.7mA	-20	—	20	mV
Output Current	$I_{DAout(1)}$	$I_{DAin}=0.516\text{mA}$, Sign= $\bar{H}_J$ Other input all $\bar{L}_J$	0.96	0.98	1.00	mA
	$I_{DAout(2)}$	$I_{DAin}=0.516\text{mA}$, Sign= $\bar{L}_J$ Other input all $\bar{L}_J$	-1.00	-0.98	-0.96	mA
Output Current (Output Offset Current)	$I_{DAout(3)}$	Sign= $\bar{L}_J$, Enable= $\bar{L}_J$ Other input all $\bar{H}_J$	-1	—	1	μA
	$I_{DAout(4)}$	Sign= $\bar{H}_J$, Enable= $\bar{L}_J$ Other input all $\bar{H}_J$	-1	—	1	μA
Low Level Input Voltage (Digital Inputs)	V_{IL}		—	—	0.8	V
High Level Input Voltage (Digital Inputs)	V_{IH}		2.0	—	—	V
Low Level Input Current (Digital Inputs)	I_{IL}	$V_{IL}=0\text{V}$	-1	—	—	μA
High Level Input Current (Digital Inputs)	I_{IH}	$V_{IH}=5\text{V}$	—	—	20	μA

●Error Amplifier

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Offset Voltage	V_{IO}	All inputs $\bar{H}_J$, DA-out to ERR-out	-5	—	5	mV
Output Voltage Swing	V_{out}	$I_{ERRout}=1\text{mA}$	$V_B-3.3$	—	$V_B+3.3$	V

●Position Amplifier

Item	Symbol	Test Conditions	min	typ	max	Unit
Low Level Input Voltage (Pin 9)	V_{IL}		—	—	0.8	V
High Level Input Voltage (Pin 9)	V_{IH}		2.0	—	—	V
Input Offset Voltage	$V_{IO(1)}$	Strobe= $\bar{L}_J$ POS-IN to POS-out	-10	—	10	mV
	$V_{IO(2)}$	Strobe= $\bar{H}_J$	-10	—	10	mV
Input Bias Current (Pin 10)	I_{IB}	Strobe= $\bar{L}_J$	-1	—	—	μA
Output Voltage Swing	V_{out}	$I_{POS-out}=1\text{mA}$, Strobe= $\bar{L}_J$	$V_B-3.3$	—	$V_B+3.3$	V

■D/A CONVERTER LOGIC FUNCTION

Digital word							Commands
Sign	DA4	DA3	DA2	DA1	DA0	ENABLE	
*	*	*	*	*	*	H	DAout = Zero
*	H	H	H	H	H	L	DAout = Zero
L	H	H	H	H	L	L	DAout = +min
L	L	L	L	L	L	L	DAout = +max
H	H	H	H	H	L	L	DAout = -min
H	L	L	L	L	L	L	DAout = -max

Notes: * = indifferent L = Low level H = High level
 +min, +max = Source Current
 -min, -max = Sink Current

HA16629P ● Tachometer Converter (F/V Converter)

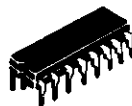
The HA16629P is a monolithic integrated circuit designed for use with the HA16628P to DC motor positioning System for applications such as carriage/daisy-wheel position control in Typewriters.

FUNCTIONS

- Tacho Voltage Generator (F/V converter)
- Reference Voltage Generator
- Position pulse Generator

FEATURES

- Single Supply Voltage 10V DC to 20V DC
- Position pulse output is open collector

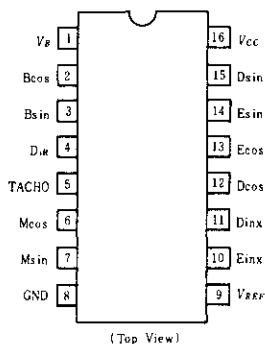


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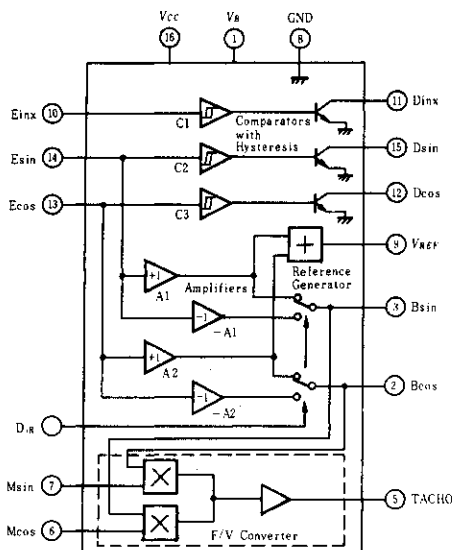
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Rating	Note
Supply Voltage	V_{CC}	20	V
Common Voltage	V_B	$0.55V_{CC}$	V
Input Voltage (Pin 4, 10, 13, 14)	$V_{I(1)}$	V_{CC}	V
Input Voltage (Pin 6, 7)	$V_{I(2)}$	$V_B \pm 5$	V
Output Voltage (Pin 11, 12, 15)	V_{out}	20	V
Output Current (Pin 11, 12, 15)	$I_{out(1)}$	5	mA
Output Current (Pin 2, 3, 5)	$I_{out(2)}$	± 1	mA
Output Current (Pin 9)	$I_{out(3)}$	-1.5	mA
Power Dissipation	P_T	450	mW
Operating Temperature Range	T_{opr}	0 to +70	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-50 to +125	$^\circ\text{C}$

PIN ARRANGEMENT



BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, $V_{CC}=12\text{V}$, $V_B=5\text{V}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Supply Voltage	V_{CC}		10	—	20	V
Supply Current	I_{CC}	no Loads	—	—	20	mA
Supply Current of V_B (Pin 1)	I_B	no Loads	-2	—	2	mA

Comparators with Hysteresis (C_1 , C_2 and C_3)

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Bias Current	I_{IB}	$V_{E1A} = V_{E1B} = V_{E2C} = 5\text{V}$	-2	—	—	μA
Input 'H' Level Threshold Voltage	V_{THH}	C_1 (Pin 10)	7.2	7.5	7.8	V
		C_2, C_3 (Pin 14, 13)	5.1	5.3	5.5	V
Input 'L' Level Threshold Voltage	V_{THL}	C_1	5.7	6.0	6.3	V
		C_2, C_3	4.5	4.7	4.9	V
Output 'L' Level Voltage	V_{OL}	$I_{OL}=2.5\text{mA}$	—	—	0.4	V
Output Leak Current	I_{OH}	$V_{OH}=5\text{V}$	—	—	2	μA

Amplifiers (A_1 , $-A_1$, A_2 and $-A_2$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Input 'L' Level Voltage (Pin 4)	V_{IL}		—	—	0.8	V
Input 'H' Level Voltage (Pin 4)	V_{IH}		2.0	—	—	V
Common Mode Input Voltage Range	V_{CM}		$V_B \pm 2.5$	—	$V_B \pm 3.5$	V
Output Offset Voltage (A_1 and A_2)	V_{OS1+2}	$D_{1K}=L$	-30	—	30	mV
Output Offset Voltage ($-A_1$ and $-A_2$)	V_{OS1-}	$D_{1K}=H$	-50	—	50	mV
Voltage gain (A_1 and A_2)	A_{VD1+2}	$D_{1K}=L$	—	1	—	V/V
Voltage gain ($-A_1$ and $-A_2$)	A_{VD1-}	$D_{1K}=H$	—	-1	—	V/V
Output Voltage Swing	V_{out}		$V_B - 3.3$	—	$V_B + 3.3$	V

Reference Generator

Item	Symbol	Test Conditions	min	typ	max	Unit
DC Reference Voltage (Pin 9)	V_{REF1}	$I_{REF} = -0.5\text{mA}$, Note (1)	7.5	8.0	8.5	V
	V_{REF2}	$I_{REF} = -0.5\text{mA}$, Note (2)	6.7	7.5	8.3	V

Note (1)

No.	Test Conditions		Unit
	$E \sin$	$E \cos$	
1	$V_B + \frac{3}{\sqrt{2}}$	$V_B + \frac{3}{\sqrt{2}}$	V_{DC}
2	$V_B + \frac{3}{\sqrt{2}}$	$V_B - \frac{3}{\sqrt{2}}$	V_{DC}
3	$V_B - \frac{3}{\sqrt{2}}$	$V_B + \frac{3}{\sqrt{2}}$	V_{DC}
4	$V_B - \frac{3}{\sqrt{2}}$	$V_B - \frac{3}{\sqrt{2}}$	V_{DC}

 $V_B=5\text{V}$

Note (2)

No.	Test Conditions		Unit
	$E \sin$	$E \cos$	
1	$V_B + 3$	V_B	V_{DC}
2	V_B	$V_B + 3$	V_{DC}

 $V_B=5\text{V}$

●F/V Converter

Item	Symbol	Test Conditions	min	typ	max	Unit
Input Bias Current	I_{IB}	$V_{M \sin} = V_{M \cos} = 5V$	—	5	15	μA
DC Output Voltage (Pin 5)	V_{TACHO1}	Note (1)	1.5	—	2.0	V_{DC}
	V_{TACHO2}	Note (2)	8.0	—	8.5	V_{DC}
Output Voltage Swing	V_{out}		$V_B - 3.3$	—	$V_B + 3.3$	V
Output Offset Voltage (Pin 5)	V_{IO}	$M_{sin} = M_{cos} = V_B$	-80	—	80	mV

	No.	C_{UND}	E sin	E cos	M sin	M cos
Note (1)	1		V_H	V_H	V_L	V_L
	2		V_H	V_L	V_L	V_L
	3		V_L	V_L	V_L	V_L
	4		V_L	V_H	V_L	V_L
Note (2)	5		V_H	V_H	V_L	V_L
	6		V_H	V_L	V_L	V_L
	7		V_L	V_L	V_L	V_L
	8		V_L	V_H	V_L	V_L

$$V_H = V_B + 1 \text{ (V)}$$

$$V_L = V_B - 1 \text{ (V)}$$

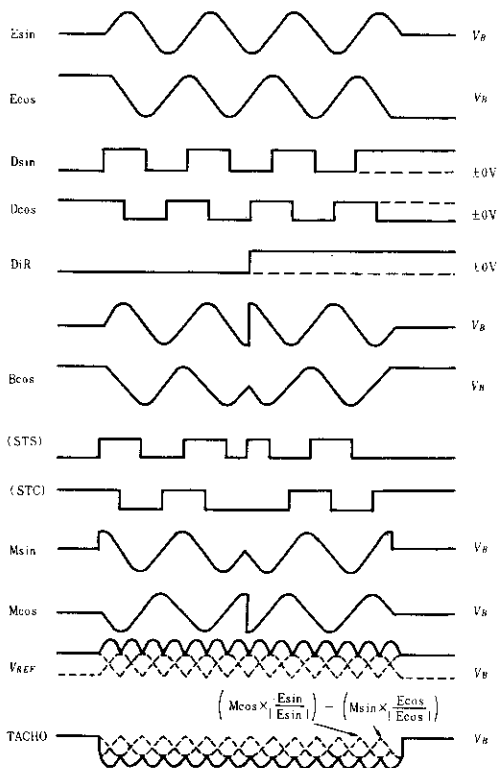
$$V_L = V_B + \frac{1.6}{\sqrt{2}} \text{ (V)}$$

$$V_L = V_B - \frac{1.6}{\sqrt{2}} \text{ (V)}$$

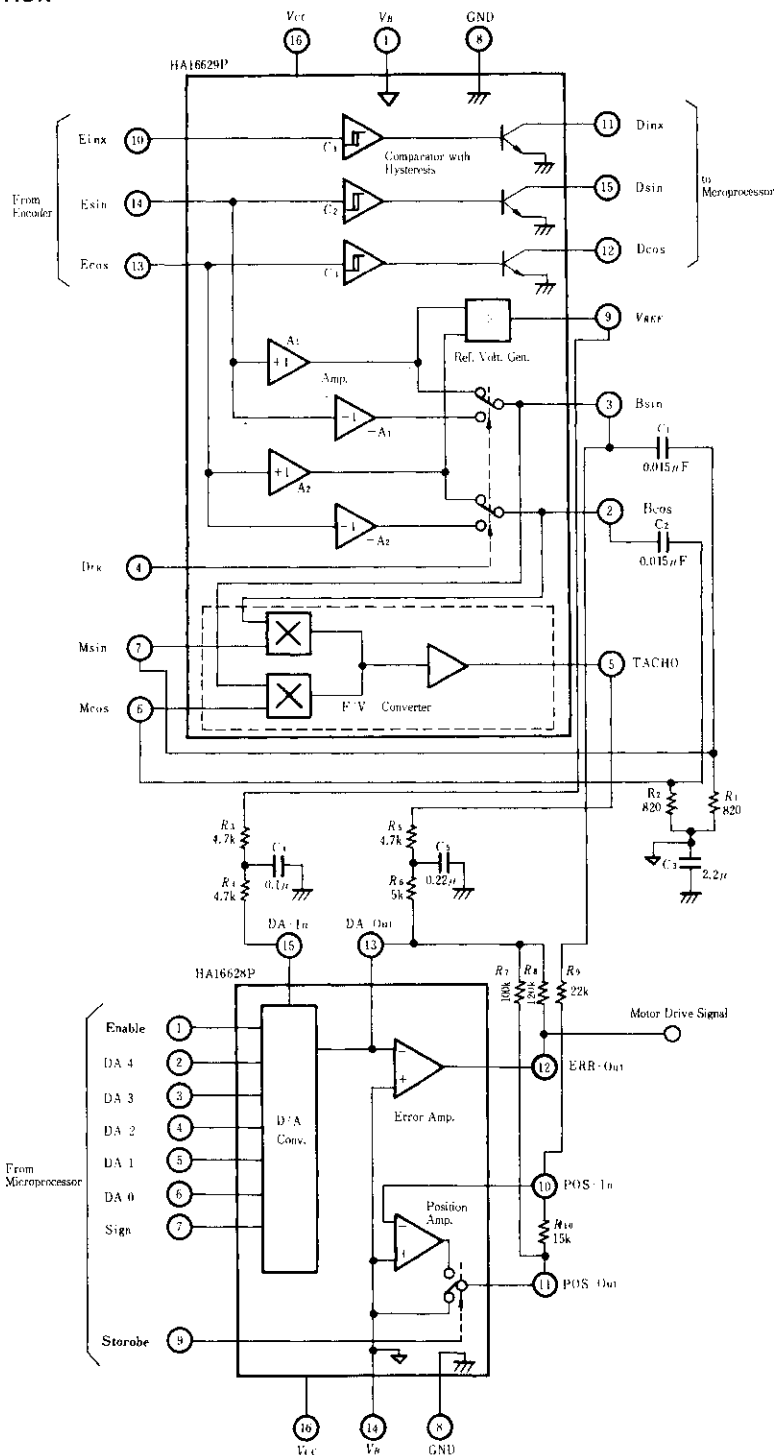
$$V_B = 5 \text{ (V)}$$

■ WAVEFORMS

●Clock Wise Direction



APPLICATION



HA16631P, HA16631MP ● Flexible Disk Read Amplifier

The HA16631P and the HA16631MP are monolithic read amplifiers for flexible disk drive, and provide wave-shaped output signals. The amplified signals from the magnetic head generate data pulses by differentiator, zero-volt comparator and waveform shaper section.

■ FEATURES

- Combined all the active circuit to perform the flexible disk read amplifier function in one chip.
- Direct connection with TTL's.

HA16631P



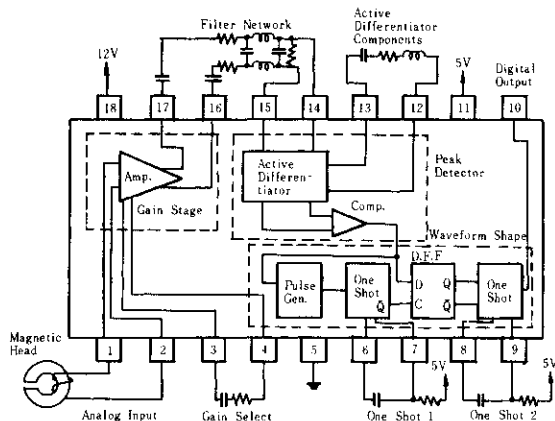
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HA16631MP



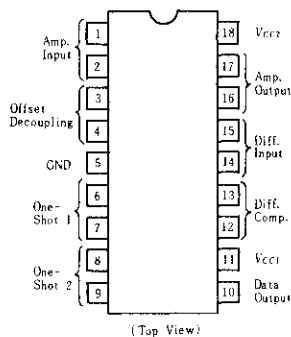
(MP-18)

■ BLOCK DIAGRAM

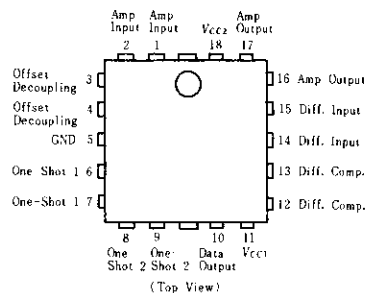


■ PIN ARRANGEMENT

● HA16631P



● HA16631MP



■ MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Rating	Unit
Power Supply Voltage (Pin 11)	V_{CC1}	7.0	V
Power Supply Voltage (Pin 18)	V_{CC2}	16	V
Input Voltage (Pins 1 and 2)	V_{IN}	-0.2 to +7.0	V
Output Voltage (Pin 10)	V_O	-0.2 to +7.0	V
Differential Input Voltage (Pins 1 and 2)	$V_{IN(diff)}$	0 to +5.0	V
Operating Temperature	T_{op}	0 to +70	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 to +125	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS

● Operating Power Supply Voltage Range ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Test Condition	min	typ	max	Unit	Test Circuit
Power Supply Voltage Range	V_{CC1R}		4.75	5.00	5.25	V	
Power Supply Voltage Range	V_{CC2R}		10.0	12.0	14.0	V	

● Amplifier Section ($T_a=25^{\circ}\text{C}$, $V_{CC1}=5.0\text{V}$, $V_{CC2}=12.0\text{V}$; unless otherwise specified)

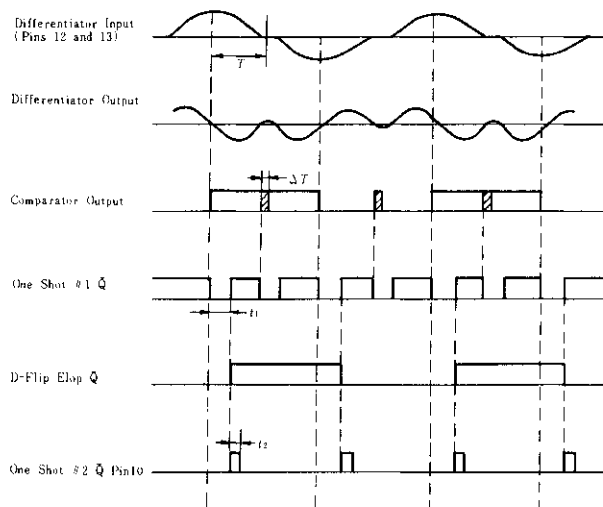
Item	Symbol	Test Condition	min	typ	max	Unit	Test Circuit
Differential Voltage Gain	A_{VD}	$f=250\text{kHz}$, $V_{IN}=5\text{mV}_{rms}$ V_{CC1R} V_{CC2R}	80	110	140	V/V	2
Input Bias Current	I_{IB}	$V_{CC2}=12\text{V}$, $V_{CM}=4\text{V}$	—	1	9	μA	4
Common Mode Voltage Range	V_{CM}		1.85	—	6.2	V	2
Output Distortion Ratio	THD	$f=1\text{kHz}$, $V_{IN}=25\text{mV}_{p-p}$ V_{CC1R} V_{CC2R}	—	1.5	5	%	2
Differential Output Voltage Swing	V_{OD}	V_{CC1R} V_{CC2R}	3.0	4.2	—	V _{p-p}	2
Output Source Current	I_O		—	8.0	—	mA	8
Output Sink Current (Pins 16 and 17)	I_{OS}	V_{CC1R} V_{CC2R}	2.8	4	—	mA	9
Input Resistance	r_{IN}		30	120	—	k Ω	5
Output Resistance	r_o		—	15	—	Ω	6
Common Mode Rejection Ratio	$CMRR$	$f=100\text{kHz}$, $V_{IN}=200\text{mV}_{p-p}$	50	—	—	dB	11
Power Supply Rejection Ratio V_{CC1}	$PSRR_1$	$V_{CC2}=12.0\text{V}$ $4.75\text{V} \leq V_{CC1} \leq 5.25\text{V}$	50	—	—	dB	10
Power Supply Rejection Ratio V_{CC2}	$PSRR_2$	$V_{CC1}=5.0\text{V}$ $10.0\text{V} \leq V_{CC2} \leq 14.0\text{V}$	60	—	—	dB	10
Differential Output Offset Voltage	V_{DO}		—	—	0.4	V	7
Common Mode Output Voltage	V_{CO}		—	3.1	—	V	7
Effective Differential Emitter Resistance (Pins 3 and 4)	R_{EFF}		370	570	770	Ω	3

● Peak Detector Section ($T_a=25^{\circ}\text{C}$, $V_{CC1}=5.0\text{V}$, $V_{CC2}=12.0\text{V}$; unless otherwise specified)

Item	Symbol	Test Condition	min	typ	max	Unit	Test Circuit
Sink Current (Pins 12 and 13)	I_{SD}		1.0	1.5	—	mA	12
Peak Shift	P_S	$f=250\text{kHz}$, $V_{IN}=1.0\text{V}_{p-p}$	—	—	5	%	13
Input Resistance	r_{ID}		—	30	—	k Ω	17
Output Resistance	r_{OP}		—	40	—	Ω	

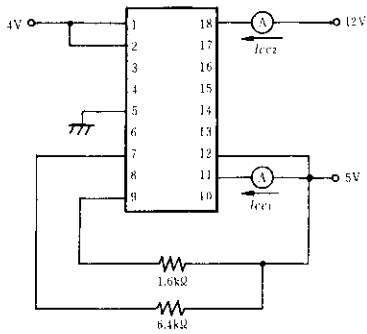
● Waveform Shaper Section ($T_a=25^\circ\text{C}$, V_{CC1R} , V_{CC2R} : unless otherwise specified)

Item	Symbol	Test Condition	min	typ	max	Unit	Test Circuit
Output Voltage H (Pin 10)	V_{OH}	$V_{CC1}=4.75\text{V}$ $V_{CC2}=12.0\text{V}$, $I_{OH}=-0.4\text{mA}$	2.7	—	—	V	15
Output Voltage L (Pin 10)	V_{OL}	$V_{CC1}=4.75\text{V}$ $V_{CC2}=12.0\text{V}$, $I_{OL}=8\text{mA}$	—	—	0.5	V	16
Rising Time (Pin 10)	t_{TLH}	$V_{CC1}=5.0\text{V}$, $V_{CC2}=12.0\text{V}$ $V_{in}=0.5\text{V}\rightarrow 2.7\text{V}$	—	—	25	ns	14
Falling Time (Pin 10)	t_{THL}	$V_{CC1}=5.0\text{V}$, $V_{CC2}=12.0\text{V}$ $V_{in}=2.7\text{V}\rightarrow 0.5\text{V}$	—	—	25	ns	14
Timing Range #1	$t_{1A, B}$	$f=125\text{kHz}$	600	—	2000	ns	
		$f=250\text{kHz}$	600	—	1000	ns	
Timing Accuracy #1	t_1	$t_1=0.625C_1R_1+150$ $C_1=200\text{pF}$, $R_1=6.8\text{k}\Omega$	850	1000	1150	ns	14
Timing Capacitance #1	C_1		150	—	680	pF	14
Timing Resistance #1	R_1		1.5	—	10	k Ω	14
Timing Range #2	$t_{2A, B}$	$f=125\text{kHz}$	150	—	1000	ns	
		$f=250\text{kHz}$	150	—	750	ns	
Timing Accuracy #2	t_2	$t_2=0.625C_2R_2$ $C_2=200\text{pF}$, $R_2=1.6\text{k}\Omega$	170	200	230	ns	14
Timing Capacitance #2	C_2		100	—	800	pF	14
Timing Resistance #2	R_2		1.5	—	10	k Ω	14

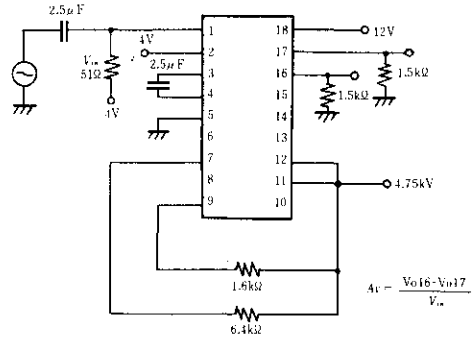
■ TIMING CHART


■ TEST CIRCUITS

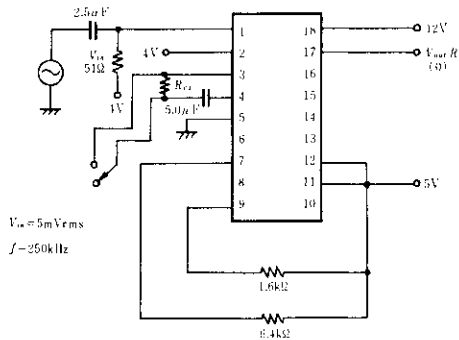
1. Power Supply Current



2. Voltage Gain, Band-width, Output Voltage Swing, Output Distortion Ratio



3. Pre-Amplifier Section Effective Emitter Resistance (Pins 3 and 4)



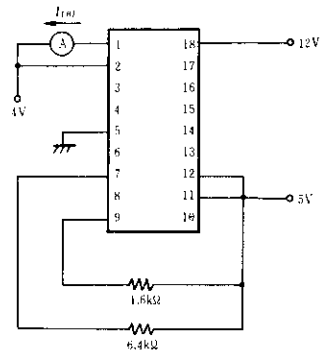
$$\frac{A_v}{2} = \frac{V_{out}}{V_{in}}$$

$$r_e + R_e = \frac{R_{ex}}{\frac{A_{vs}}{A_{vs}} - 1}$$

$$= \frac{500}{\frac{V_{out}(f)}{V_{in}(f)} - 1}$$

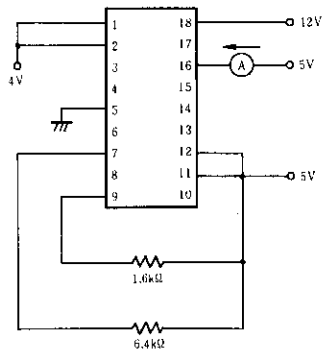
$$R_{ex} = 500\Omega$$

4. Input Bias Current



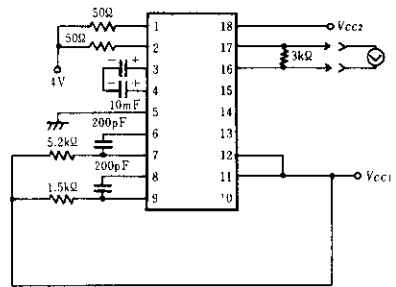
Measure I_{in2} in the same way.

9. Output Sink Current



Measure Pin12 in the same way.

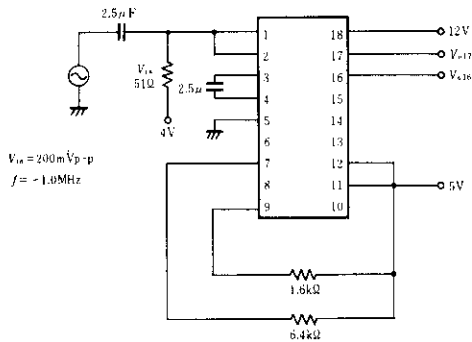
10. Power Supply Rejection Ratio



Fluke 8375A

Digital Multimeter

11. Common Mode Rejection Ratio

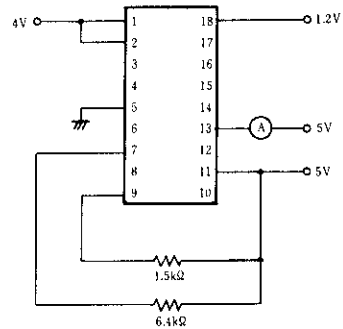


$V_{in} = 200\text{mV}_{p-p}$
 $f = 1.0\text{MHz}$

$$\text{CMRR} = 20 \log_{10} \frac{100 V_{in}}{V_{out17} - V_{out16}}$$

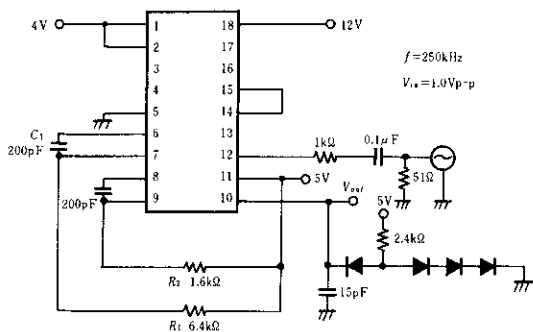
Measurement is performed using Vector Voltmeter hp8405A, or equivalent.

12. Differentiator Output Sink Current



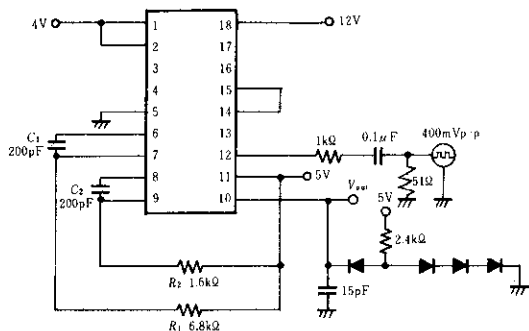
Measure Pin12 in the same way.

13. Peak Shift



$$PS = 1/2 \cdot \frac{t_{p1} - t_{p2}}{t_{p1} + t_{p2}} \times 100\%$$

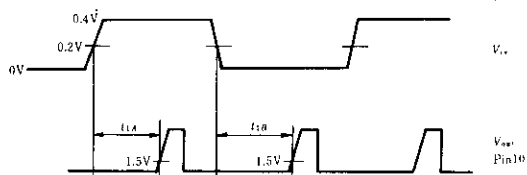
14. Timing Accuracy, Rising Time, Falling Time



$$t_{TLN} = t_{THL} = 10\text{ns}$$

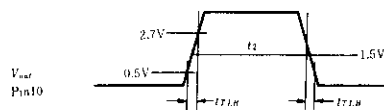
$$f = 250\text{kHz}$$

$$50\% \text{ Duty}$$



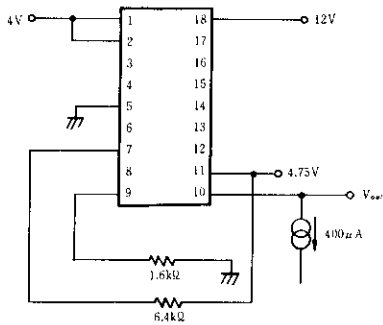
$$ET1A = \frac{t_{r1}}{1,000\text{ns}} \times 100\%$$

$$ET1B = \frac{t_{f1}}{1,000\text{ns}} \times 100\%$$

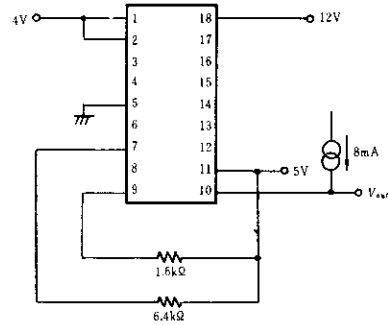


$$ET2 = \frac{t_2}{200\text{ns}} \times 100\%$$

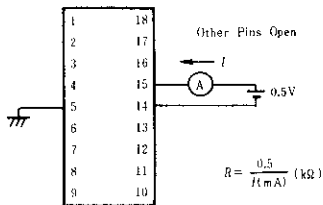
15. Output Voltage H (Pin 10)



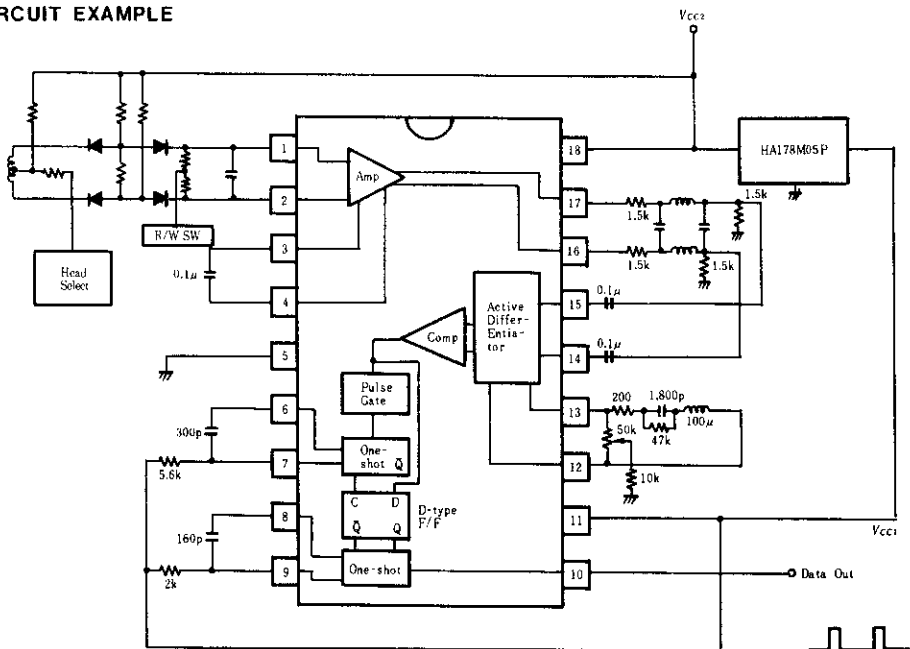
16. Output Voltage L (Pin 10)

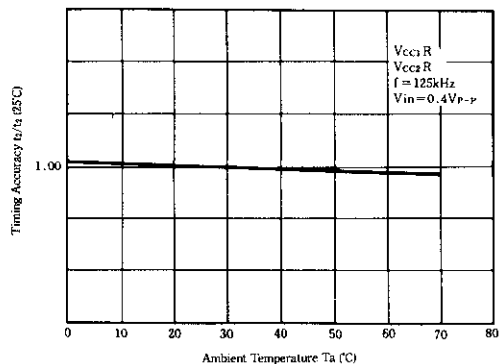
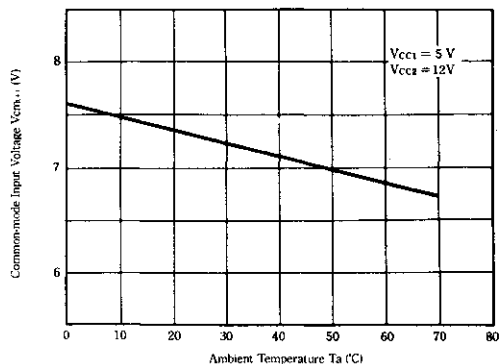
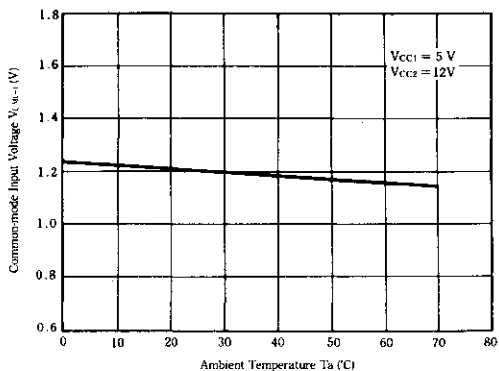


17. Input Resistance

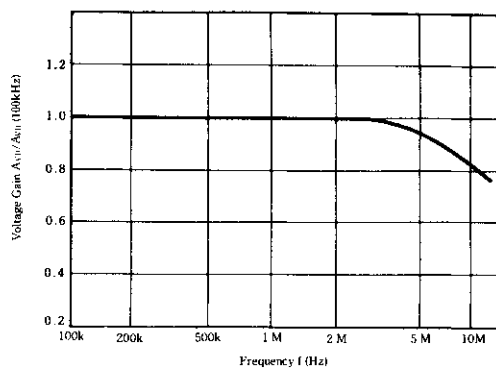
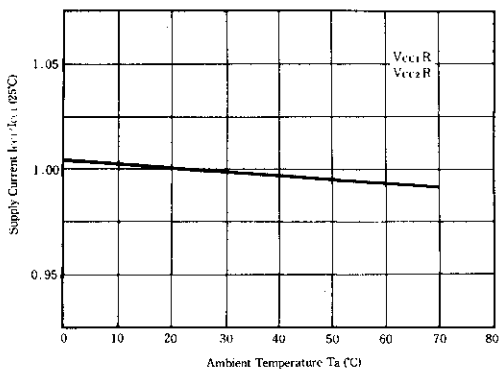
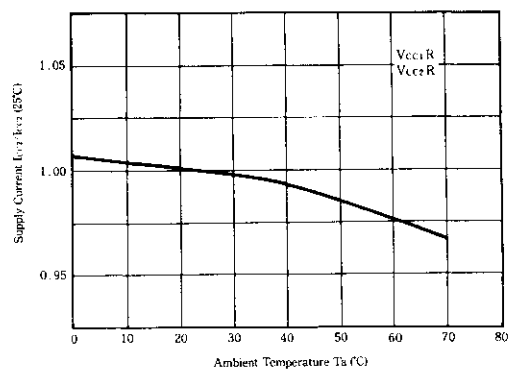


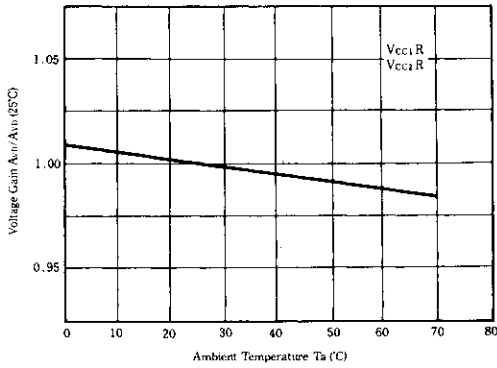
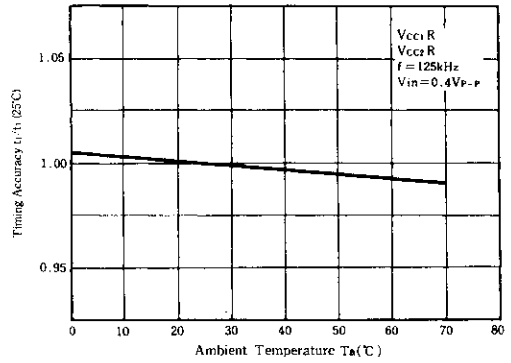
■CIRCUIT EXAMPLE



TIMING ACCURACY VS.
AMBIENT TEMPERATURECOMMON-MODE INPUT VOLTAGE
VS. AMBIENT TEMPERATURECOMMON-MODE INPUT VOLTAGE
VS. AMBIENT TEMPERATURE

VOLTAGE GAIN VS. FREQUENCY

SUPPLY CURRENT VS.
AMBIENT TEMPERATURE (1)SUPPLY CURRENT VS.
AMBIENT TEMPERATURE (2)

**VOLTAGE GAIN VS.
AMBIENT TEMPERATURE****TIMING ACCURACY VS.
AMBIENT TEMPERATURE**

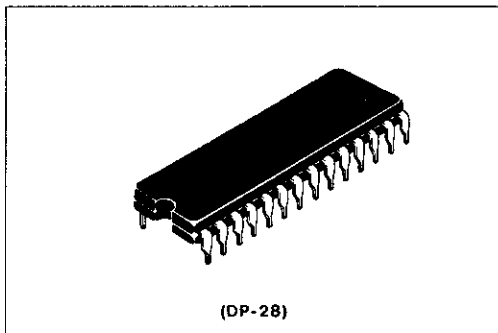
HA16632AP

● VFO IC for Flexible Disk Drive

The HA16632AP is a monolithic VFO IC for floppy disk interface. It is designed to accept the read out data from floppy disk drive, which includes jitter caused by the wow and flutter of the disk revolution, or peak shift by the magnetic effect on the disk. And it generates "Window" signals which are necessary to separate data pulse from clock pulse.

■ FEATURES

- Applicable to both the 8 inch disk and the 5.25 inch disk by changing the voltage level "high" or "low" on the control pin.
- Applicable to both the single density record format and the double density record format by changing the voltage level "high" or "low" on the control pin.
- Applicable to various floppy disk controllers such as FD1791, μ PD765 by changing the voltage level "high" or "low" on the control pin.
- Gate units in the IC chip are constructed by Low power schottky TTL circuits.



(DP-28)

■ MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

Item	Symbol	Rating	Unit
Power Supply Voltage 1	V_{CC}	7	V
Power Supply Voltage 2	V_{LNR}	7	V
Power Dissipation	P_T	750	mW
Operating Temperature Range	T_{a-op}	0 to +60	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +125	$^\circ\text{C}$

■ ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

Item	Symbol	Test Conditions	min	typ	max	Unit	Application Terminal	Note
Operating Power Supply Voltage	$V_{CC(oper)}$		4.75	5.00	5.25	V	V_{CC}, V_{LNR}	
Quiescent Current 1	I_{CC}	$V_{CC}=5.25\text{V}$	—	80	105	mA	V_{CC}	
Quiescent Current 2	I_{LNR}	$V_{CC}=5.25\text{V}$	—	28	37	mA	V_{LNR}	
Input High Current 1	I_{IH1}	$V_{CC}=5.25\text{V}, V_{IH}=2.7\text{V}$	—	—	20	μA	- RAW DATA - VFO SYNC - MFM	
Input High Current 2	I_{IH2}	$V_{CC}=5.25\text{V}, V_{IH}=5.25\text{V}, -\text{IRS}=3.0\text{V}$	—	—	50	μA	- 8 INCHI - FSHA	
Input High Current 3	I_{IH3}	$V_{CC}=5.25\text{V}, V_{IH}=5.25\text{V}$	—	—	260	μA	- IRS	
Input Low Current 1	I_{IL1}	$V_{CC}=5.25\text{V}, V_{IL}=0.4\text{V}$	-0.4	—	—	mA	- RAW DATA - VFO SYNC - MFM	
Input Low Current 2	I_{IL2}	$V_{CC}=5.25\text{V}, V_{IL}=0.4\text{V}, -\text{IRS}=3.0\text{V}$	-1.8	—	—	mA	- 8 INCHI - FSHA	
Input Low Current 3	I_{IL3}	$V_{CC}=5.25\text{V}, V_{IL}=0.4\text{V}$	-4.0	—	—	mA	- IRS	
Input Bias Current	I_{IB}	$V_{LNR}=5.25\text{V}, V_{IN}=2.4\text{V}$	—	—	20	μA	V_{IN}	
Output High Voltage 1	V_{OH1}	$V_{CC}=4.75\text{V}, I_{OH}=-280\mu\text{A}$	2.7	—	—	V	+ WIND - RD DATA	1
Output High Voltage 2	V_{OH2}	$V_{CC}=4.75\text{V}, I_{OH}=-400\mu\text{A}$	2.7	—	—	V	- PDL, - PDH	1
Output High Voltage 3	V_{OH3}	$V_{CC}=4.75\text{V}, I_{OH}=-100\mu\text{A}$	3.4	4.0	—	V	+ PUL	1

Note) 1. When setting the last output tap gate "High"

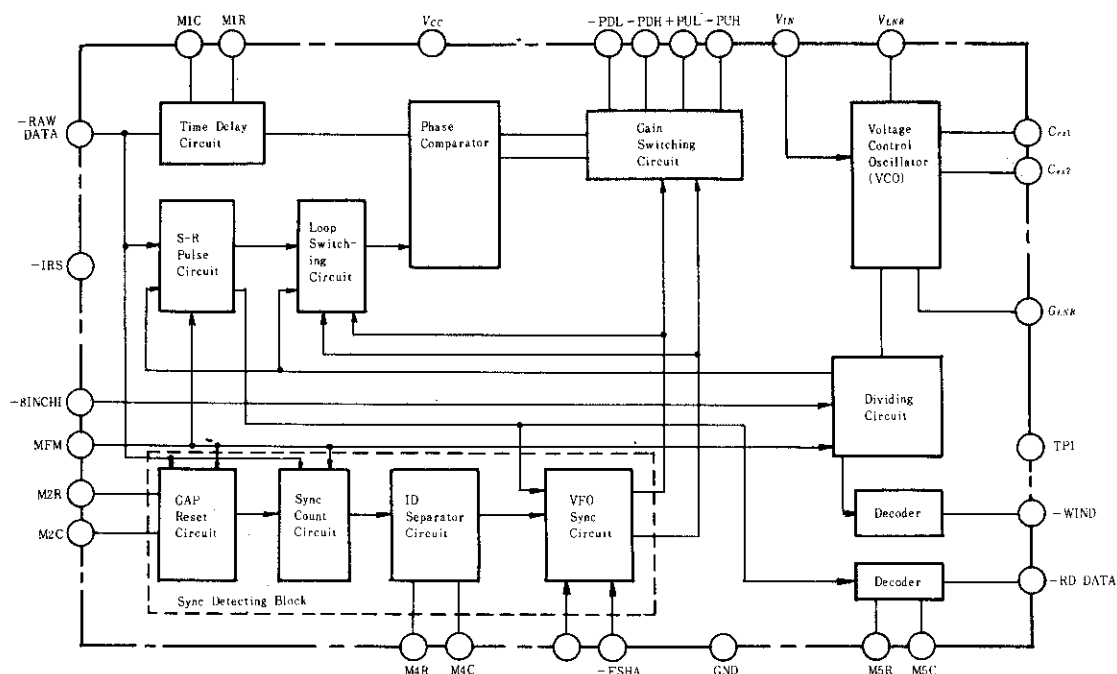
(to be continued)

■ ELECTRICAL CHARACTERISTICS (Continued) ($T_a=25^{\circ}\text{C}$)

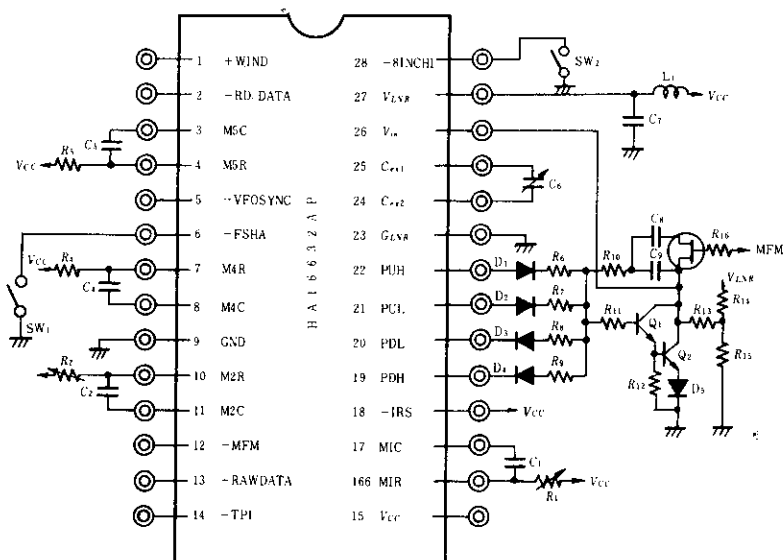
Item	Symbol	Test Conditions	min	typ	max	Unit	Application Terminal	Note
Output Low Voltage 1	V_{OL1}	$V_{CC}=4.75\text{V}$, $I_{OL}=1\text{mA}$	—	—	0.45	V	+WIND —RD DATA	2
Output Low Voltage 2	V_{OL2}	$V_{CC}=4.75\text{V}$, $I_{OL}=1\text{mA}$	—	—	0.45	V	—PDL	2
Output Low Voltage 3	V_{OL3}	$V_{CC}=4.75\text{V}$, $I_{OL}=100\mu\text{A}$	—	—	0.6	V	+PUL	2
Output Low Voltage 4	V_{OL4}	$V_{CC}=4.75\text{V}$, $I_{OL}=100\mu\text{A}$	—	—	0.6	V	+PUH	2
Output High Voltage 4	V_{OH4}	$V_{CC}=4.75\text{V}$, $I_{OH}=-4\text{mA}$	3.15	3.65	—	V	+PUH	1
Output Low Voltage 5	V_{OL5}	$V_{CC}=4.75\text{V}$, $I_{OL}=4\text{mA}$	—	—	0.55	V	—PDH	2
Output Short-circuit Current 1	I_{OS1}	$V_{CC}=5.25\text{V}$, +WIND, —RD DATA=GND	-70	—	-14	mA	+WIND —RD DATA	3
Output Short-circuit Current 2	I_{OS2}	$V_{CC}=5.25\text{V}$, —PDL, —PDH=GND	-100	—	-20	mA	—PDL —PDH	3
Output Short-circuit Current 3	I_{OS3}	$V_{CC}=5.25\text{V}$, +PUL, +PUH=GND	-100	—	-20	mA	+PUL +PUH	3
VCO Oscillation Frequency	f_{VCO}	$V_{LNR}=5\text{V}$, $C_{ex}=91\text{pF}$ $V_{IN}=2.4\text{V}$, —IRS=GND	—	4.0	—	MHz	—8 INCHII	
Maximum VCO Oscillation Frequency	f_{max}	$V_{LNR}=5\text{V}$, $C_{ex}=30\text{pF}$ $V_{IN}=4.0\text{V}$, —IRS=GND	10	—	—	MHz	—8 INCHI	
M1 Output Pulse Width 1	$t_{w1.8}$	$V_{CC}=5\text{V}$, $C_1=50\text{pF}$ VR 1 = 15k Ω , —IRS=GND	—	500	—	ns	+WIND	
M1 Output Pulse Width 2	$t_{w1.5}$	$V_{CC}=5\text{V}$, $C_1=62\text{pF}$ VR 1 = 30k Ω , —IRS=GND	—	1000	—	ns	+WIND	
M2 Output Pulse Width 1	$t_{w2.8}$	$V_{CC}=5\text{V}$, $C_2=240\text{pF}$ VR 2 = 25k Ω , —IRS=GND	—	2.50	—	μs	—RD DATA	
M2 Output Pulse Width 2	$t_{w2.5}$	$V_{CC}=5\text{V}$, $C_2=500\text{pF}$ VR 2 = 25k Ω , —IRS=GND	—	5.0	—	μs	—RD DATA	
M4 Output Pulse Width 1	$t_{w4.8}$	$V_{CC}=5\text{V}$, $C_4=34000\text{pF}$ VR 4 = 47k Ω , —IRS=GND	—	0.50	—	ms	TP 1	
M4 Output Pulse Width 2	$t_{w4.5}$	$V_{CC}=5\text{V}$, $C_4=68000\text{pF}$ VR 4 = 47k Ω , —IRS=GND	—	1.0	—	ms	TP 1	
M5 Output Pulse Width	t_{w5}	$V_{CC}=5\text{V}$, $C_5=12\text{pF}$ VR 5 = 15k Ω , —IRS = 3.0V	—	200	—	ns	—RD DATA	

Notes: 1. When setting the last output tap gate "High"
 2. When setting the last output tap gate "Low"
 3. When setting the last output tap gate "High"

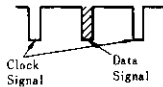
■ BLOCK DIAGRAM



■ PIN ARRANGEMENT

D₁ - D₄ : 1S2076Q₁, Q₂ : 2SC641

■ PIN EXPLANATION

Item	Pin Name	Signal	Remarks
Pin for Power Supply	V_{CC}	Power Supply for every block except VCO block	
	GND	GND for every block except VCO block	
	V_{LNR}	Power Supply for VCO block	
	G_{LNR}	GND for VCO block	
Pin for Input Signal	-RAW DATA	Raw read data signal from flexible disk drive, including signal components of clock signal and data signal.	
	-VFO SYNC	Input signal which shows detection of SYNC Byte (periodic signal). When -FSHA = "Low", this signal switches gain to lead-in loop. -VFO SYNC = "Low" → SYNC Byte detected -VFO SYNC = "High" → SYNC Byte undetected	
	-MFM	Mode select pin for MFM or FM -MFM = "Low" → MFM mode (double density) -MFM = "High" → FM mode (single density)	
	-8 INCHI / (-VCO)	1. Select pin for 8 inch FDD or 5 inch FDD (-IRS = "High") -8 INCHI = "Low" → 8 inch FDD -8 INCHI = "High" → 5 inch FDD 2. VCO oscillation output monitor pin (-IRS = "Low")	
	-FSHA	Select pin for the kinds of Flexible Disk Controller (FDC) -FSHA = "Low" → FD1791, MB8876, 8877 -FSHA = "High" → μ PD765AC	

■ PIN EXPLANATION (Continued)

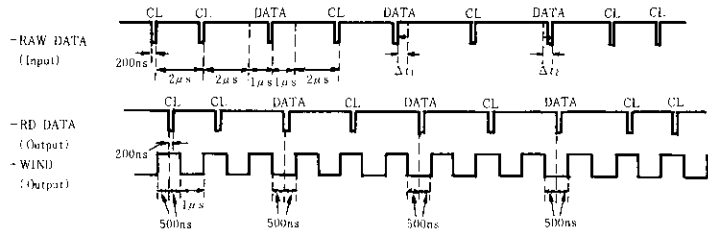
Item	Pin Name	Signal	Remarks
Pin for Input Signal	-IRS	Pin for testing IC's at using the packaged IC → -IRS = "High" at testing IC → -IRS = "Low"	
Input Pin	VIN	Control voltage input pin for VCO	
Pin for Output Signal	+WIND/(+M1Q)	1. Window signal output pin to distinguish data signal from signal which are included in -RAW DATA signal. +WIND = "High" → for distinguishing clock signal +WIND = "Low" → for distinguishing data signal (-IRS = "High") 2. Monostable Multivibrator Output Pulse Monitor pin for M1 (-IRS = "Low")	
	-RD DATA/(+M2Q)	1. Adjusted Read data output signal pin (-IRS = "High") 2. Monostable Multivibrator Output Pulse Monitor pin for M2 (-IRS = "Low")	
	-PDL	Output signal for charge pump down at Low Gain	
	-PDH	Output signal for charge pump down at High Gain	
	+PUL	Output signal for charge pump up at Low Gain	
	+PUH	Output signal for charge pump up at High Gain	
	TP1	IC test monitor pin	

■ PIN EXPLANATION

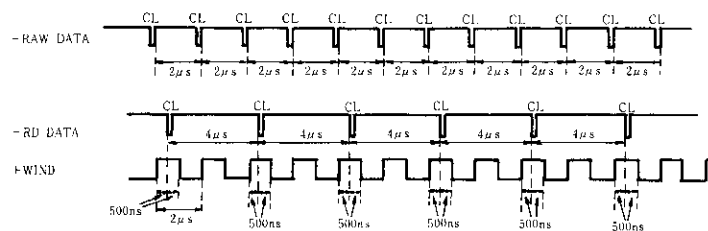
Item	Pin Name	Signal	Remarks
Resistor Capacitor	M1R	Ready access pin to capacitor and resistor M1	
	M1C	Ready access pin to capacitor for monostable multivibrator M1	
Ready Access Pin	M2R	Ready access pin to capacitor and resistor M2	
	M2C	Ready access pin to capacitor for monostable multivibrator M2	
	M4R	Ready access pin to capacitor and resistor M4	
	M4C	Ready access pin to capacitor for monostable multivibrator M4	
	M5R	Ready access pin to capacitor and resistor M5	
	M5C	Ready access pin to capacitor for monostable multivibrator M5	
	CEX1	Ready access pin to capacitor for VCO	
	CEX2	Ready access pin to capacitor for VCO	

TIME CHART

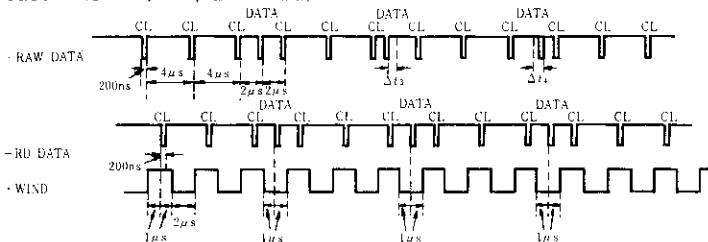
Case 1 (8 inch, MFM, LOW Gain)



Case 2 (8 inch, MFM, High Gain)..... SYNC Sig.



Case 3 (8 inch, FM, LOW Gain)



HA16636P ● Ground Fault Interrupter

The HA16636P is a monolithic circuit designed for ground fault protection. It's applied for amplifier section of ground fault interrupter, and consists of differential amplifier and mono-stable multivibrator.

■ FEATURES

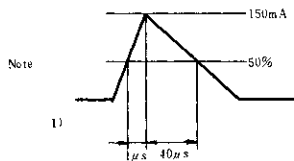
- Minimum external parts.
- Wide temperature range $-20^{\circ}\text{C} \sim +85^{\circ}\text{C}$
- High packing density for SIP-8 package.
- Output pulse from mono-stable multivibrator
 $t_{\text{ow}} = 55\text{ms typ, } C = 0.68\mu\text{F}$
- Temperature compensated for sensitivity of leakage current.
- High surge voltage and wide noise compensated.



(SP-8)

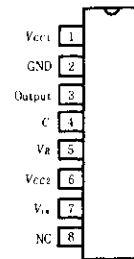
■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^{\circ}\text{C}$)

Item	Symbol	Rating	Unit	Note
Supply Current	I_{CC}	10	mA	
Excess Supply Current	I_Z	150	mA	1
Power Dissipation	P_T	100	mW	2
Operating Temperature Range	T_{op}	-20 to $+85$	$^{\circ}\text{C}$	
Storage Temperature Range	T_{stg}	-55 to $+125$	$^{\circ}\text{C}$	



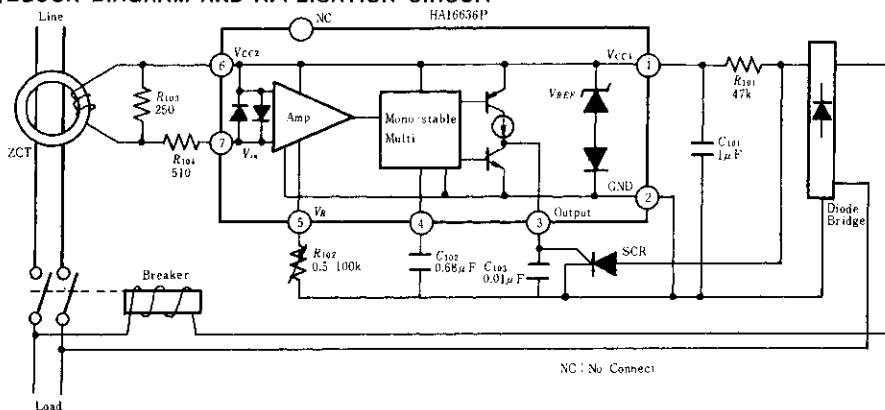
2. Temperature range T_{op}

■ PIN ARRANGEMENT



(Top View)

■ BLOCK DIAGRAM AND APPLICATION CIRCUIT



●Outline of the Function

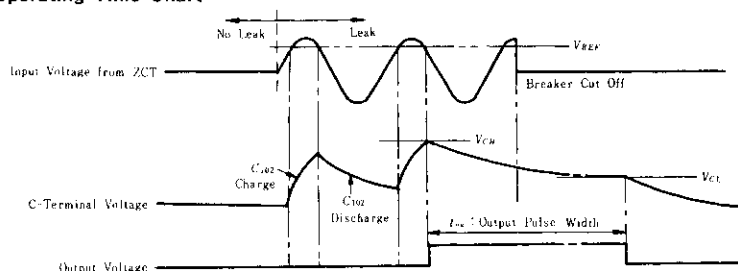
- Both input terminal "Vcc2" (6) and "Vin" (7) of a differential amplifier connected the secondary coil of the Zero-phase Current Transformer (ZCT) that detect a leakage current. And further, "Vcc1" (1) and "Vcc2" (6) connected to each other inner this IC.
So, if the appointed current are supplied, the terminal voltage of "Vcc1" (1) could fix the constant voltage by the zener diode.
- Sensitivity of a leakage detection can be adjusted by the external variable resistance (R102) that connected to the

terminal "VR". (5)

- The signal that amplified by the differential amplifier integrated by the capacitor (R102) that connected to the terminal "C". (4)

If the terminal voltage of "C" (4) amounted to the threshold voltage of the mono-stable multivibrator, a output pulse would generate with the capacitor C102 and the internal resistance and so, this pulse drive SCR that connected to the output terminal. (3)

●Operating Time Chart

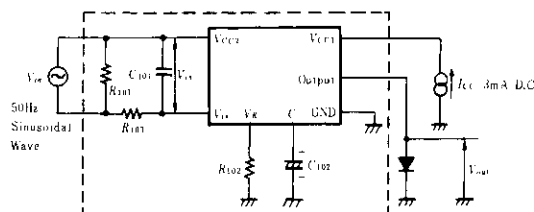


■ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Item	Symbol	Test Conditions	min	typ	max	Unit
Operating Supply Current Range	I_{CC}		1.3	—	10	mA
Reference Voltage	V_{REF}	$I_{CC} = 1.3\text{mA}$, $V_C = 2\text{V}$, $V_{OH} = 0.8\text{V}$	5.6	6.3	6.8	V
Output Source Current	$I_{SOURCE1}$	$I_{CC} = 1.3\text{mA}$, $V_{OH} = 0.8\text{V}$	245	400	—	μA
	$I_{SOURCE2}$	$T_a = -20^\circ\text{C}$, $I_{CC} = 1.3\text{mA}$, $V_{OH} = 0.9\text{V}$	290	500	—	μA
Output Voltage	V_{OL1}	$I_{CC} = 1.3\text{mA}$, $I_{load} = 2\text{mA}$	—	0.1	0.2	V
	V_{OL2}	$I_{CC} = 3\text{V}$, $I_{load} = 300\mu\text{A}$	—	0.05	0.2	V
	V_{OH}	$I_{CC} = 1.3\text{mA}$, No-Load	3.5	—	—	V
Output Pulse Width	t_{PW}	$I_{CC} = 1.3\text{mA}$, $C = 0.68\mu\text{F}$	30	55	100	ms
Temperature Characteristic	V_{REF} Ta 1	$T_a = -20^\circ\text{C}$, $I_{CC} = 3\text{mA}^*$	-12	—	12	%
	V_{REF} Ta 2	$T_a = 70^\circ\text{C}$, $I_{CC} = 3\text{mA}^*$	-12	—	12	%
	V_{REF} Ta 3	$T_a = 85^\circ\text{C}$, $I_{CC} = 3\text{mA}^*$	-18	—	18	%

* refer to measuring circuit

■MEASURING CIRCUIT



●External Parts Constant

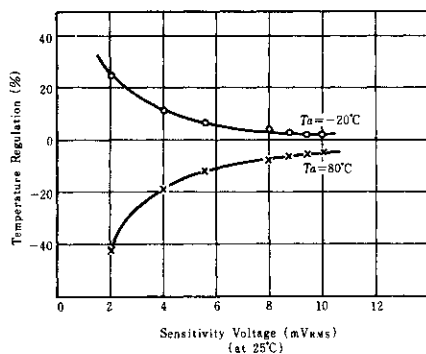
- R101 = 250Ω ± 1% (Carbon Film Resistor)
- R102 = Adjusted Resistance ± 5% (Carbon Film Resistor)
- R103 = 510Ω ± 1% (Carbon Film Resistor)
- C101 = 0.47μF ± 1% (Tantalum Electrolytic Capacitor)
- C102 = 0.68μF ± 1% (Tantalum Electrolytic Capacitor)

●Temperature Coefficient

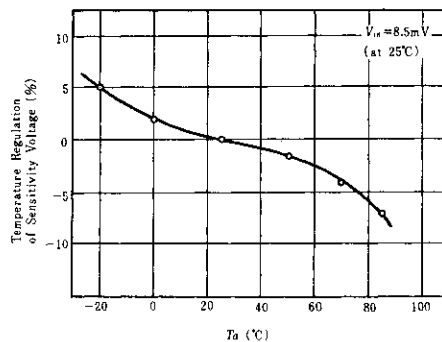
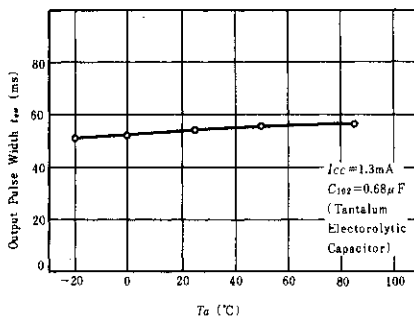
$$= \frac{V_{in}(T_a) - V_{in}(25^\circ\text{C})}{V_{in}(25^\circ\text{C})} \times 100[\%]$$

(Ta = -20°C, 70°C, 85°C)

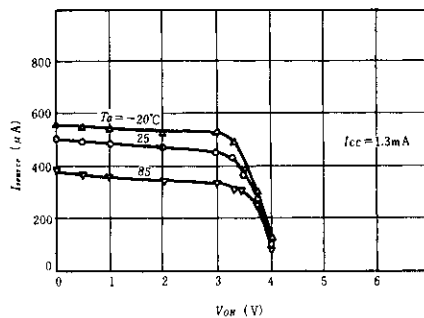
SENSITIVITY VOLTAGE CHARACTERISTICS



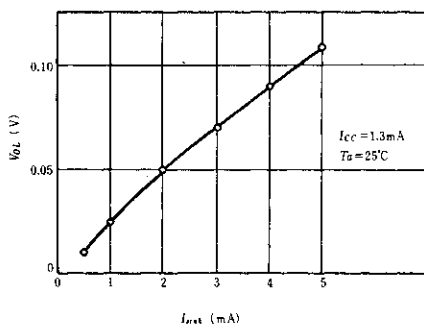
TEMPERATURE REGULATION OF SENSITIVITY VOLTAGE CHARACTERISTICS

T_{OW}-T_a CHARACTERISTICS

OUTPUT CHARACTERISTICS



OUTPUT CHARACTERISTICS



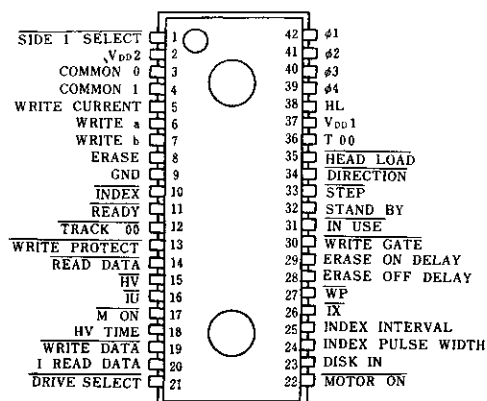
HA16640NT ● Write/Mechanism Controller for Floppy Disk Drive

This IC can provide WRITE + MECHANISM CONTROL function in one chip for FLOPPY DISK DRIVE

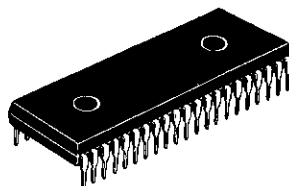
■ FEATURES

- WRITE Circuit includes COMMON, WRITE, ERASE drivers, and has capability of application for many kind of FDDs.
- WRITE Circuit also includes tripple power supply monitor circuits, so can protect the Disk from abnormal writing or erasing at ON, OFF of supply voltage.
- The delay time between write gate and erase gate timing is generated by internal MONO MULTI Circuit, so this IC is able to apply for many kind of FDDs and HEAD components.
- The function of MECHANISM CONTROL circuit conforms to the standard FDD's interface.
- MECHANISM CONTROL Circuit has a power save function, and at the stand-by mode in operation, power save circuit protects the equipment from internal temperature increasing by inhibiting the load current in external components, and also reduces the power dissipation in IC chip.
- The output interface has capability of large drive current, and internal logic circuit has low power consumption by means of Bi-CMOS technology. Especially, in the output interface circuit, it is not necessary to have any external TTL ICs because of including line drivers into IC chip.
- With this device, it is able to design the print circuit board without TTL ICs, and to reduce many external components, also to shrink an area of print circuit board.
- Signal processing and control circuit in FDD are able to be constructed with only two ICs and some external discrete devices by connecting with FDD READ IC, HA16631P/MP.

■ PIN ARRANGEMENT

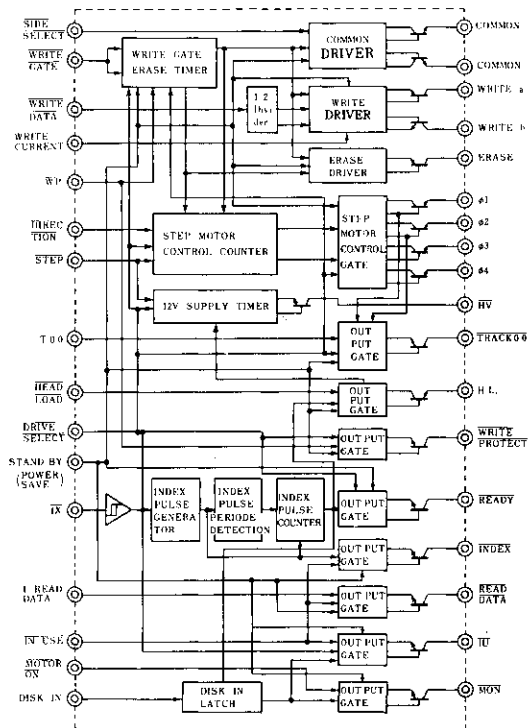


(Top View)



(DP-42S)

■ BLOCK DIAGRAM



- * In the WRITE CIRCUIT, power supply monitor circuits are included to watch the line voltage of 5V and 12V. When the line voltage goes down to abnormal value, the COMMON, WRITE, ERASE drivers are all inhibited rapidly.

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit	Applicable Terminal
Supply Voltage	V_{DD1}	-0.3, +7.0	V	V_{DD1}
Supply Voltage	V_{DD2}	-0.3, +14.0	V	V_{DD2}
Interface Input Voltage	V_{IN1}	-0.3 to V_{DD1}	V	Note 1
Interface Input Voltage	V_{IN2}	-0.3 to V_{DD2}	V	Note 2
Interface Output Current	I_{OL1}	50	mA	Note 3
IU Terminal Output Current	I_{OL2}	20	mA	IU
HV Terminal Output Current	I_{OL3}	15	mA	HV
MON Terminal Output Current	I_{OL4}	5	mA	MON
HL Terminal Output Current	I_{OH5}	10	mA	HL
STEP Terminal Output Current	I_{OH6}	5	mA	$\phi 1 \phi 2 \phi 3 \phi 4$
COMMON Drive Current (WRITE MODE)	I_{OCW}	100	mA	COMMON 0, 1
COMMON Drive Current (READ MODE)	I_{OCR}	5	mA	COMMON 0, 1
WRITE Drive Current	I_{OWW}	10	mA	WRITE a,b
ERASE Drive Current	I_{OEW}	85	mA	ERASE
Input Current on the WRITE Current Set Terminal	I_{WC}	2.5	mA	WRITE CURRENT
Power Dissipation	P_D	850 (0 to 50°C)	mW	
Operating Temperature Range	T_{OP}	0 to +70	$^\circ\text{C}$	
Storage Temperature Range	T_{stg}	-55 to +125	$^\circ\text{C}$	

Notes 1. Applicable Terminal: SIDE SELECT, WRITE DATA, STEP, DIRECTION, IN USE, MOTOR ON, HEAD LOAD, STAND BY, WRITE GATE, DRIVE SELECT, I READ DATA

2. Applicable Terminal: T00, DISK IN, WP, IX and also Terminals from MM circuit connecting with the external C, R time constant.

3. Except for IU, HV, MON, HL, $\phi 1 \phi 2 \phi 3 \phi 4$.

■ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

	Circuit Block	Item	Symbol	Test Condition	min	typ	max	Unit
WRITE Circuit	Supply Voltage	Supply Voltage Range	V_{DD1}		4.5	5.0	5.5	V
		Supply Voltage Range	V_{DD2}		10.8	12.0	13.2	V
	COMMON Driver	Output Voltage at Selected WRITE Mode	V_{OCW}	$V_{DD2} = 12\text{V}$ $I_{OCW} = -100\text{mA}$	-	10.7	-	V
		Output Voltage at Unselected WRITE Mode	V_{OCWU}	$V_{DD2} = 12\text{V}$ Unselected	-	-	0.7	V
		Output Voltage at Selected READ Mode	V_{OCR}	$V_{DD2} = 12\text{V}$ $I_{OCR} = -5\text{mA}$	-	4.7	-	V
		Output Voltage at Unselected READ Mode	V_{OCRU}	$V_{DD2} = 12\text{V}$ Unselected	-	-	0.7	V
		Output Current Range	I_{COM}		-	-	100	mA
	WRITE Driver	Input Current Range on the WRITE Current Set Terminal	I_{WC}		0	-	2.5	mA
		WRITE Current Accuracy	I_{OWW}	WRITE Driver output voltage = 10V $I_{WC} = 1\text{mA}$	3.6	4.0	4.4	mA
		WRITE Current Temperature Coefficient	TCI_{OW}	$I_{WC} = 1\text{mA}$ $T_a = 0 \text{ to } 70^\circ\text{C}$	-	± 0.05	-	$\%/^\circ\text{C}$
		WRITE Current Symmetry	ΔI_{OW}	$V_{DD1} = 5\text{V}$, $V_{DD2} = 12\text{V}$ $I_{owa}I_{owb}$	-1	-	+1	%
		Output Leak Current	I_{LKW}	$V_{DD1} = 5\text{V}$, $V_{DD2} = 12\text{V}$ $V_{OW} = 20\text{V}$	-	-	100	μA
	ERASE Driver	Output Low Voltage	V_{OLER}	$V_{DD1} = 4.5\text{V}$, $I_{OE} = 80\text{mA}$	-	-	0.6	V
		Output Leak Current	I_{LKER}	$V_{DD1} = 5.5\text{V}$, $V_{OER} = 20\text{V}$	-	-	200	μA
	Lower Line Voltage Protector	12V Detection Voltage	V_{PRV12}		-	8.1	-	V
		5V Detection Voltage	V_{PRV5}		-	3.8	-	V

(to be continued)

	Circuit Block	Item	Test Condition	Symbol	min	typ	max	Unit
Mechanism Control Circuit	Signal Interface (Note 1)	High Level Input Voltage	$V_{DD1} = 5.0V$	V_{IHI}	2.4	—	—	V
		Low Level Input Voltage	$V_{DD1} = 5.0V$	V_{ILI}	—	—	0.8	V
	Signal Interface (Note 1)	High Level Input Current	$V_{DD1} = 5.5V$ $V_{IH} = 5.5V$	I_{HI}	—	—	10	μA
		Low Level Input Current	$V_{DD1} = 5.5V$ $V_{IL} = 0V$	I_{ILI}	-10	—	—	μA
	Sensor Interface (Note 2)	High Level Input Voltage	$V_{DD1} = 5.0V$	V_{IHS}	3.3	—	—	V
		Low Level Input Voltage	$V_{DD1} = 5.0V$	V_{ILS}	—	—	1.7	V
		High Level Input Current	$V_{DD1} = 5.5V$ $V_{IH} = 5.5V$	I_{IHS}	—	—	10	μA
		Low Level Input Current	$V_{DD1} = 5.5V$ $V_{IL} = 0V$	I_{ILS}	-10	—	—	μA
	Index Input Interface	Higher Threshold Voltage	$V_{DD1} = 5V$	V_{TH+IX}	—	3.5	—	V
		Lower Threshold Voltage	$V_{DD1} = 5V$	V_{TH-IX}	—	2.0	—	V
		Hysteresis	$V_{DD1} = 5V$	V_{HYS}	—	1.5	—	V
		Input Current	$V_{DD1} = 4.5V$ $V_{IH} = 2.6V$	I_{IHIX}	-50	—	80	μA
	Signal Output Interface	Low Level Output Voltage	$V_{DD1} = 4.5V$ $I_{OL} = 48mA$	V_{OLI}	—	—	0.4	V
		High Level Output Current	$V_{DD1} = 5.5V$ $V_{OH} = 5.5V$	I_{OHI}	—	—	250	μA
	IU Output	Low Level Output Voltage	$V_{DD1} = 4.5V$ $I_{OL} = 10mA$	V_{OLIU}	—	—	0.5	V
		High Level Output Current	$V_{DD1} = 5.5V$ $V_{OH} = 5.5V$	I_{OHIU}	—	—	100	μA
	HV Output	Low Level Output Voltage	$V_{DD1} = 4.5V$ $I_{OL} = 15mA$	V_{OLHV}	—	—	0.5	V
		High Level Output Current	$V_{DD1} = 5.5V$ $V_{OH} = 13.2V$	I_{OHHV}	—	—	100	μA
	MON Output	Low Level Output Voltage	$V_{DD1} = 4.5V$ $I_{OL} = 5mA$	V_{OLMN}	—	—	0.4	V
		High Level Output Current	$V_{DD1} = 5.5V$ $V_{OH} = 5.5V$	I_{OHMN}	—	—	50	μA
	HL Output	High Level Output Voltage	$V_{DD1} = 5V$ $I_{OH} = -10mA$	V_{OHHL}	3.6	—	—	V
		Low Level Output Current	$V_{DD1} = 5.5V$ $V_{OL} = 0V$	I_{OLHL}	-20	—	—	μA
	STEP Output	High Level Output Voltage	$V_{DD1} = 5V$ $I_{OH} = -5mA$	V_{OHSTP}	3.6	—	—	V
		Low Level Output Current	$V_{DD1} = 5.5V$ $V_{OL} = 0V$	I_{OLSTP}	-20	—	—	μA
	ERASE Timer	ERASE ON DELAY	$C_{ex} = 0.033\mu F$ $R_{ex} = 33k\Omega$	t_{EN}	0.44	0.52	0.60	ms
		ERASE OFF DELAY	$C_{ex} = 0.069\mu F$ $R_{ex} = 33k\Omega$	t_{EF}	0.91	1.07	1.23	ms
	INDEX, READY Circuit	Index Output Pulse Width	$C_{ex} = 0.033\mu F$ $R_{ex} = 220k\Omega$	t_{IXW}	2.61	3.08	3.55	ms
		Index Detection Period	$C_{ex} = 0.22\mu F$ $R_{ex} = 390k\Omega$	t_{IXI}	31.1	36.6	42.1	ms
	12V Hold Timer	Hold Period at 12V	$C_{ex} = 2.3\mu F$ $R_{ex} = 56k\Omega$	t_{HV}	47.1	55.5	63.9	ms
	Dissipation Current	Supply Current 1	$V_{DD1} = 5.5V$, $V_{DD2} = 13.2V$ No Load	I_{DD1}	—	—	65	mA
		Supply Current 2	$V_{DD1} = 5.5V$, $V_{DD2} = 13.2V$ No Load	I_{DD2}	—	—	10	mA

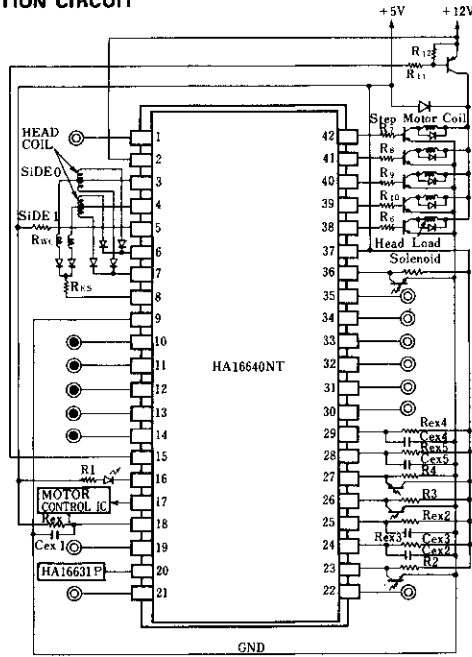
■ Pin Description

Symbol	Name	Description
COM 0	Common Driver 0	Output terminal of Common Driver (SIDE 0). During the Head Select signal is selecting SIDE 0, a common voltage appears on this terminal. The voltage value at WRITE Mode and that READ Mode are shown in the Electrical Characteristics. This terminal supplies a current which equals to write current + erase current. When the SIDE 0 is unselected, a common voltage doesn't appear, and this terminal is pulled down to ground by a internal resistor with high resistance.
COM 1	Common Driver 1	Output terminal of Common Driver. (SIDE 1). The function is as same as that of SIDE 0.
SIDE SELECT	Side Select	Input terminal for Head Select signal. This signal selects the SIDE 0 or SIDE 1 of the common driver.
WRITE a, b	Write Driver a, b	Output terminal of Write Driver. The current multiplied by 4 with the determined current at the WRITE CURRENT terminal is sunked. WRITE a and WRITE b turn on alternately according to the Write Data "1" or "0".
ERASE	Erase Driver	Output terminal of Erase Driver. The drive transistor turns on during the period of Erase Gate signal keeping low, and the Erase Gate timing is generated by write Gate signal in IC circuit. This terminal has open collector NPN transistor, and erase current must be determined by an external resistor.
WRITE CURRENT	Write Current	The terminal to determine the Write Current. The Write current is determined with connecting an external resistor to +5V supply. The Write Current on the WRITE a, b terminals is multiplied by 4 with the current on the WRITE CURRENT terminal, as follow equation. $I_{OWW} = \frac{3.38}{R_{ex}} \times 4 \text{ (mA)}$ where, I_{OWW} : WRITE CURRENT on the WRITE a, b terminals. Rex: External pull up resistor on the WRITE CURRENT terminal, and use the value in kΩ unit.
WRITE DATA	Write Data Input	Write Data input terminal. The signal is divided through the F/F circuit in IC, and drives the Write Driver.
WRITE GATE	Write Gate	Input terminal for Write Gate signal. The write gate is enable at input Low, and allows data writing. Erase Gate signal is generated with the determined delay from the negative and positive edge of Write Gate signal, and drives an erase driver.
WP	Write Protect Input	Input terminal for the detected write protect signal from the Disk. Common, Write, Erase drivers are all inhibited at input low, and WRITE PROTECT driver turns ON.
ERASE ON DELAY	Erase ON Timer	Terminal for connecting the external time contact Cex, Rex of internal Mono Multi circuit to determine the delay time between the both negative edge of write Gate and Erase Gate signal. It is necessary to determine the delay time for the fittest value according to the kind of FDD and HEAD component.
ERASE OFF DELAY	Erase OFF Timer	As same as above, but the delay time is determined between the both positive edge of Write Gate signal and Erase Gate signal.
STEP	Step Signal Input	Terminal for step pulse input to drive the stepping motor to seek tracks. With each one step pulse input, the driver outputs $\phi_1, \phi_2, \phi_3, \phi_4$ change sequentially.
DIRECTION	Direction Input	Input terminal for Direction signal to determine the direction of stepping motor revolution. Output drivers change with the direction of $\phi_1 \rightarrow \phi_2 \rightarrow \phi_3 \rightarrow \phi_4$ at the input low, and $\phi_1 \rightarrow \phi_4 \rightarrow \phi_3 \rightarrow \phi_2$ at the input High.
$\phi_1, \phi_2, \phi_3, \phi_4$	4 Phase Stepper Drive Output	Output terminals to drive the stepping motor coil. With each step pulse input, outputs change with the direction determined by Direction signal. Output driver has emitter follower construction, but the driver cannot drive the stepping motor coil directly. It is necessary to have external driver devices such as discrete transistors.
HV	Voltage Change Timer	Timer output terminal to drive an external transistors which switches supply voltage 12V to 5V each other for stepping motor coil. With each step pulse input or each head load execution, the output turns ON during the determined period. It is enable to switch supply voltage 12V to 5V alternately and to supply 12V for the stepping motor coil during the period of Low level on this terminal.
HV TIME	HV Timer	Terminal for connecting the external time constant of internal Mono Multi circuit to determine the period of keeping the HV output Low level.
WRITE PROTECT	Write Protect Output	When the input level of WP turns Low and the drive select is executed, this output turns ON.

(to be continued)

Symbol	Name	Description
T00	Track 00 Input	Input terminal for 00 track detection. High level input makes the 00 track detection.
TRACK 00	Track 00 Output	Output terminal for 00 track detection. When the input level of T00 is High, and the both output ϕ_1 , ϕ_2 are High, this output turns ON.
IX	Index Input	Input terminal for the detected Index hole signal from the DISK. Input Low shows the hole detection.
INDEX	Index Output	Output for the Index pulse. With each input of the detected Index pulse at the IX terminal, the width formed pulse appears on this terminal as a Index pulse.
INDEX PULSE WIDTH	Index Pulse Width Set	Terminal for connecting the external time constant of the internal Mono Multi circuit to determine the output pulse width on INDEX. It is enable to adjust the pulse width independently to the diameter of the DISK hole.
READY	Ready Output	Output of the Ready signal. When the disk revolution gets to the normal, after counting three index pulses, the output on this terminal turns ON, and shows FDD has gone into READY state. If the revolution goes down under the normal value, the output turns OFF rapidly and shows NOT READY state. And also the output shows High level continuously when Drive unit is not selected.
INDEX INTERVAL	Index Interval	Terminal for connecting the external time constant of the internal Mono Multi circuit to determine the reference index period corresponding to the standard revolution number of the DISK. In case of the FDD equipment having another revolution number, it is easier to adjust reference period by changing the time constant.
DRIVE SELECT	Drive Select Input	Input terminal for Drive select signal. Input low makes the selected operation, and Write function, output interface, IU output are all enable.
STAND BY	Stand by Input	Input terminal for Power Save Signal to reduce the power consumption in FDD equipment and LSI. Input high inhibits all output terminals in Write and Mechanism control circuit except common driver, so power consumption in external circuit is reduced and this LSI makes itself into sleep mode. At the same time, common driver turns the READ mode.
HEAD LOAD	Head Load	Input terminal for Head Load signal. When READY is low and operation is under the not stand-by mode, head load is enable at the input low.
HL	Head Load Output	Terminal for Head Load output. Circuit has a emitter follower construction. But this terminal cannot drive the coil of head load solenoid directly. It is necessary to have an external driving transistor.
IN USE	In Use Input	Input terminal for IN USE signal. When the DISK is charged and the DRIVE equipment is selected, and also the operation is under the not stand-by mode, IU output is enable with the input low.
IU	In Use Output	In Use Output. Circuit has a open collector NPN transistor, and can drive LED directly.
I READ DATA	Read Data Input	Input terminal for Read Data from READ circuit such as HA16631P/MP. When both DRIVE SELECT and STAND BY are Low, inverted read data pulses appear on the READ DATA terminal.
READ DATA	Read Data Output	Output terminal for Read Data. Circuit has an open collector driver, and negative data pulses appear on this terminal.
DISK IN	Disk in Input	Input terminal for Disk charge detection signal. Input High shows the charged state. When the charged Disk is detected, MON output turns ON and the motor starts, and also IU output turns ON too. This function does not depend on the input level of MOTOR ON and IN USE. When the Disk revolution gets to normal state, after counting eight Index pulses, both MON and IU outputs turns OFF, so the motor stops and IN USE LED turns OFF. After this operation, both MON and IU outputs depend on the input level of MOTOR ON and IN USE. If the Disk is discharged, the motor stops and IU output is inhibited rapidly.
MOTOR ON	Motor On	Input terminal for the motor ON, OFF, control signal. MON is enable at the input Low. Under the condition of the charged Disk and not-stand by, MON output turns ON with the MOTOR ON input Low.
MON	Motor On Output	Output terminal for the motor ON, OFF, control signal. Circuit has an open collector NPN driving transistor. Output Low makes the motor ON and High makes OFF. Also this terminal is able to connect to the motor control IC, such as HA13431 and HA13432/MP.
VDD1	5V Power Supply	5V Power Supply.
VDD2	12V Power Supply	12V Power Supply.
GND	Ground	System ground

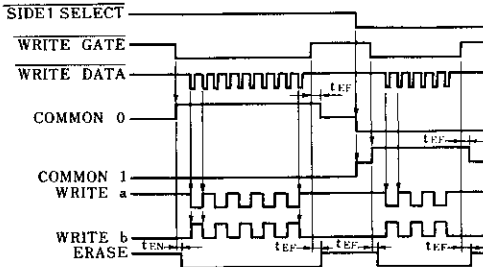
■ EXAMPLE OF APPLICATION CIRCUIT



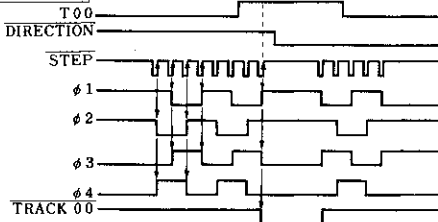
⊙ Input terminals from FDC
⊙ Output terminals for FDC

■ TIME CHART

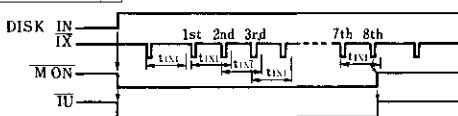
HEAD OUTPUT



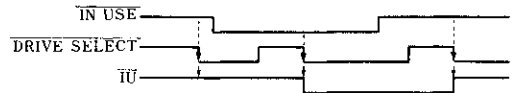
STEP OUTPUT



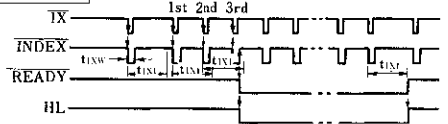
DISK IN STARTING



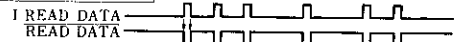
IU OUTPUT



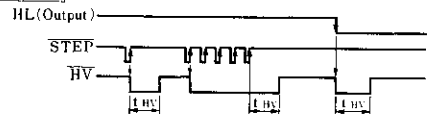
READY, HL OUTPUT



READ DATA OUTPUT



HV OUTPUT



HA16642MP, HA16642NT

● Read/Write Functions
for Floppy Disk Drive

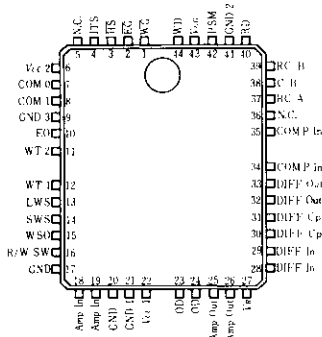
This IC can provide READ and WRITE functions in one chip for Floppy Disk Drive.

■ FEATURES

- Read Amplifier has a differential voltage gain of 200 typ., which is available to adjust by gain select terminal.
- READ Circuit can be applied for the signal amplitude of 0.5mVpp to 10mVpp which is read out from HEAD COIL, so that this IC has superior capability to apply for a FDD less than 5 inches.
- In the read circuit, the peak shift is less than 1% for the signal amplitude, 0.5mVpp to 10mVpp, at the Amp input.
- In the WRITE circuit, the COMMON DRIVER, the WRITE DRIVER, and the ERASE DRIVER can provide a large current capability, so that can be applied to various kinds of FDD's.
- Write current can be established at any value according to the external resistor. The write current is independent of the supply voltage drift and temperature drift, with the built-in stabilizing circuit.
- This IC provides a function to reduce the write current at the inner track on the disk with a external switching signal. The reduce ratio of the write current can be established at any value with the external resistor.
- The WRITE GATE signal and the ERASE GATE signal can be applied independently each other.
- A dual-mode supply voltage monitor circuit is built-in, to inhibit a miss writing and a miss erasing at the power supply timing, ON and OFF, and the abnormal supply voltage.
- READ and WRITE functions are integrated in one chip, resulting in broad reduction of external components.

■ PIN ARRANGEMENT

● HA16642MP



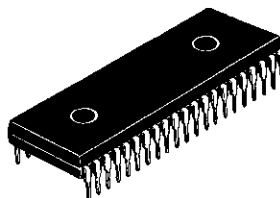
(Top View)

HA16642MP



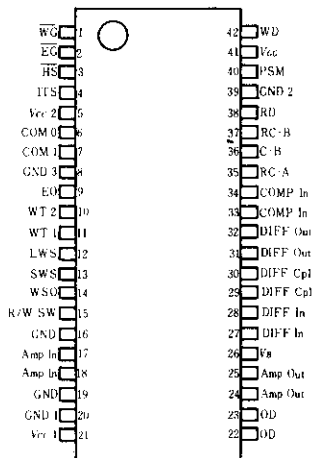
(MP-44)

HA16642NT



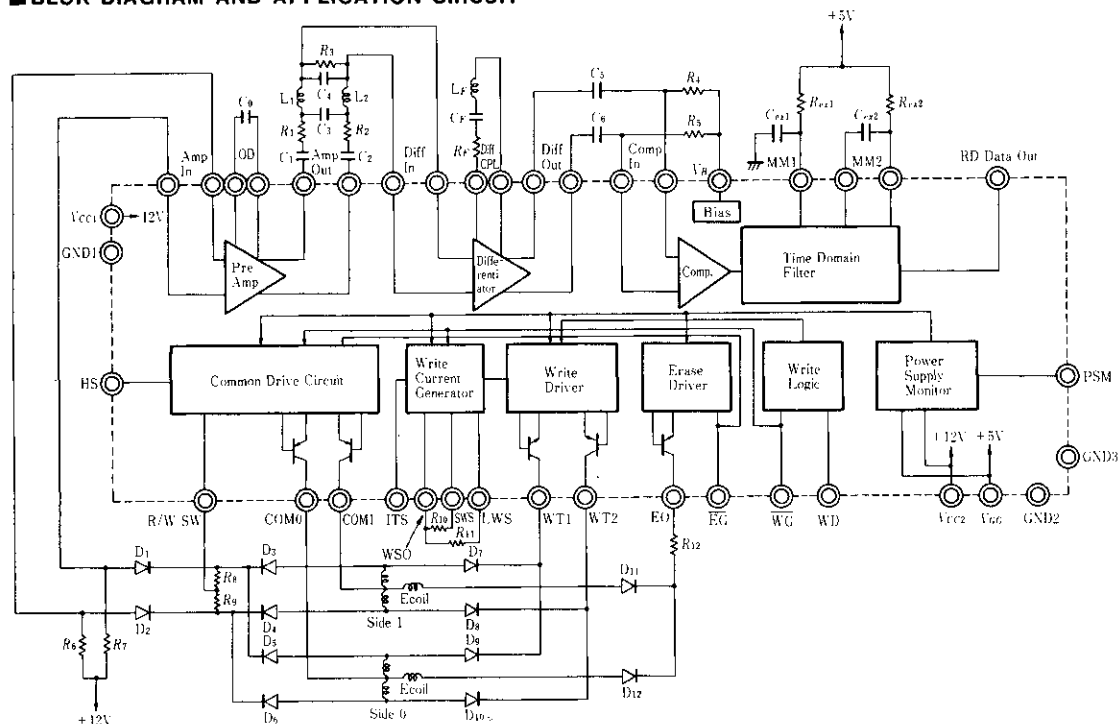
(DP-42S)

● HA16642NT



(Top View)

■ BLOK DIAGRAM AND APPLICATION CIRCUIT



Integrated Blocks

R_8, R_9 : To determine a bias current for read mode

R_{10} : To determine the increase ratio of a write current at the inner track.

R_{11} : To determine a write current at the outer track.

(Write current at the inner track is a summation of the currents determined by R_{10} and R_{11} respectively.)

■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

Item	Symbol	Ratings	Unit	Applicable Terminal
Supply Voltage	V_{CC1}	7.0	V	V_{CC1}
Supply Voltage	V_{CC2}	16.0	V	V_{CC2}
Input Voltage	V_{IN}	-0.2 to +7.0	V	AMP IN
Differential Input Voltage	$V_{IN(diff)}$	0 to +5.0	V	AMP IN
Output Voltage	V_{out}	-0.2 to +7.0	V	RD DATA OUT
Common Drive Current	I_{COM}	150	mA	COM 0, COM 1
Write Drive Current	I_{WR}	15	mA	WT 1, WT 2
Erase Drive Current	I_{ER}	120	mA	EO
Power Dissipation	P_T	800	mW	V_{CC1}, V_{CC2}, V_{GC}
Operating Temperature Range	T_{opr}	0 to +70	$^\circ\text{C}$	
Storage Temperature Range	T_{stg}	-55 to +125	$^\circ\text{C}$	

■ ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

Circuit Block	Item	Symbol	Test Condition	min	typ	max	Unit
	Supply Voltage Range	V_{LG}		4.5	5.0	5.5	V
		$V_{CC1,2}$		10.5	12.0	13.5	V
Pre Amp.	Differential Voltage Gain	A_{VD}	$f=250\text{kHz}$, $V_{in}=5\text{mVrms}$	—	200	—	V/V
	Input Bias Current	I_{IB}		—	—	15	μA
	Common Mode Input Voltage Range	V_{CM}		2.0	2.7	3.4	V
	Output Harmonic Distortion	THD	$f=1\text{kHz}$, $V_{in}=10\text{mVpp}$			5	%
Peak Detector	Peak Shift	PS	$f=250\text{kHz}$, $V_{in}=0.5$ to 10mVpp	—	—	2.5	%
Read Data Processor	Output Voltage	V_{OH}	$V_{GG}=4.75\text{V}$, $I_{OH}= -400\mu\text{A}$	2.7	—	—	V
		V_{OL}	$V_{GG}=4.75\text{V}$, $I_{OL}= -4\text{mA}$	—	—	0.4	V
	Rising Time	t_{FLH}	$V_{GG}=5\text{V}$, $V_{OH}=0.4$ to 2.7V	—	30	—	ns
	Falling Time	t_{FHL}	$V_{GG}=5\text{V}$, $V_{OL}=2.7$ to 0.4V	—	15	—	ns
	Timing Range #1	t_{LAB}	$f=125\text{kHz}$	1.3	—	4	μs
			$f=250\text{kHz}$	1.3	—	2	
	Timing Range #2	t_{2AB}	$f=125\text{kHz}$	0.15	—	1.5	μs
			$f=250\text{kHz}$	0.15	—	0.75	
Common Driver	Output Voltage at selected Write Mode	V_{WCMs}	$V_{CC2}=12\text{V}$, $I_{COM}=120\text{mA}$	—	11	—	V
	Output Voltage at unselected Write Mode	V_{WCMs}	$V_{CC2}=12\text{V}$, at unselected	—	—	0.7	V
	Output Voltage at selected Read Mode	V_{RCMs}	$V_{CC2}=12\text{V}$, $I_{COM}=1\text{mA}$	—	2.7	—	V
	Output Voltage at unselected Read Mode	V_{RCMs}	$V_{CC2}=12\text{V}$, at unselected	—	—	0.75	V
	Output Current Range	I_{COM}		—	—	150	mA
Erase Driver	Output Low Voltage	V_{OLE}	$V_{GG}=5\text{V}$, $I_{OL}=100\text{mA}$	—	—	0.5	V
	Output Leak Current	I_{OHE}	$V_{OH}=12\text{V}$, $V_{GG}=5\text{V}$	—	—	100	μA
	Erase Current Range	I_{ER}		—	—	120	mA
Write Driver	Write Current Accuracy	A_{CDW}	$V_{GG}=5\text{V}$, $V_{CC2}=12\text{V}$	-7	—	+7	%
	Write Current-Supply Voltage Sensitivity	P_{SDW}	$V_{GG}=5\text{V}$, $V_{CC2}=10.8$ to 13.2V	—	± 1.5	—	%/V
	Write Current-Temperature Coefficient	T_{CDW}	$V_{GG}=5\text{V}$, $V_{CC2}=12\text{V}$, $T_a=0$ to $+70^\circ\text{C}$	—	± 0.05	—	%/°C
	Write Current Symmetry	ΔI_{WT}	$V_{GG}=5\text{V}$, $V_{CC2}=12\text{V}$, $I_{WT1}=I_{WT2}$	-1	—	+1	%
	Write Current Range	I_{WT}	$V_{GG}=5\text{V}$, $V_{CC2}=12\text{V}$	1	—	10	mA
	Leak Current at Off Driver	I_{ohs1}	$V_{GG}=5\text{V}$, $V_{CC2}=12\text{V}$, $V_{hT}=20\text{V}$	—	—	50	μA
Supply Voltage Monitor	Detection Voltage for 5V Supply	V_{MON1}	$V_{CC2}=12\text{V}$	3.5	~ 3.9	4.3	V
	Detection Voltage for 12V Supply	V_{MON2}	$V_{GG}=5\text{V}$	8.0	9.0	9.8	V
Logic Input Gate	Input High Voltage	V_{IH}	$V_{GG}=5\text{V}$	2.0	—	—	V
	Input Low Voltage	V_{IL}	WG, EG	—	—	0.8	V
Schmitt Type Logic Input Gate	Input High Voltage	V_{IHS}	$V_{CC}=5\text{V}$	2.0	—	—	V
	Input Low Voltage	V_{ILS}	HS, WD	—	—	0.5	V
Dissipation Current	12V Supply	I_{CC}	$V_{CC}=13.5\text{V}$	Read	25	40	mA
				Write	—	16	
	5V Supply	I_{CG}	$V_{CC}=5.5\text{V}$	Read	—	36	mA
				Write	—	33	

■ PIN DESCRIPTION

Symbol	Name	Description
AMP IN	Pre Amp Input	Terminal for differential input of pre amplifier in read circuit. A signal voltage picked up through R/W coil is applied.
OD	Gain Select	Terminal for DC offset compensation of pre amp, and for gain selection. The amp gain is available to be changed by connecting a resistor to the compensation capacitor in series.
AMP OUT	Pre Amp Output	Terminal for differential output of the pre amp in read circuit. A low pass filter is connected between the input terminal of differentiator and this terminal.
DIFF IN	Differentiator Input	Input terminal of differentiator in read circuit. Output voltage from the pre amp is applied to this terminal through the low pass filter.
DIFF CPL	Differential Coupling	Terminal for connecting a capacitor for differentiation. R_F , C_F and L_F are connected in series, as shown in the block diagram.
DIFF OUT	Differentiator Output	Output terminal of the differentiator. The differentiated signal is appeared on this terminal with the phase shifted by 90° . The output is coupled through the capacitor and is applied to the comparator input.
COMP IN	Comparator Input	Input terminal of the comparator in read circuit. A signal with the phase shifted by 90° through the differentiator is applied, and the zero-crossing point is detected. This terminal is pulled up to the bias source by the external resistor.
MM1	Mono Multi 1	A capacitor and a resistor are connected to these terminals. The capacitance and the resistance determine the output pulse width of the Pre Mono Multi Vibrator in the Time Domain Filter Circuit.
MM2	Mono Multi 2	A capacitor and a resistor are connected these terminals. The capacitance and the resistance determine the output pulse width of the Post Mono Multi Vibrator in the Time Domain Filter Circuit.
RD DATA OUT	READ Output	Output terminal of the read circuit. A pulse which is synchronized to the peak position of the read out signal from head coil is obtained. The output pulse width is determined by the external capacitor and resistor of MM 2. The signal output level is TTL compatible.
COM 0	Common Driver 0	Output terminal of Common Driver (SIDE 0). During the Head Select signal is selecting SIDE 0, a common voltage is appeared on this terminal. The voltage value at Write Mode and that at Read Mode are shown in the Electrical Characteristics. A current which equals to Write Current + Erase Current flows out from this terminal. When the SIDE 0 is unselected, a common voltage is not appeared, and this terminal is pulled down to ground by a high resistance in the IC.
COM 1	Common Driver 1	Output terminal of Common Driver (SIDE 1). The function is as same as that of COM 0.
HS	Head Select	Input terminal for Head Select signal. This signal selects the SIDE 0 or SIDE 1 of the common driver. This terminal is consisted of Schmitt type input circuits. Input Low selects COM 1.
R/W SW	R/W Switch	A transistor output for switching the bias state in head coil and in diode SW circuit, according to READ/WRITE switching. This terminal is pulled down to ground level in READ Mode, and it is pulled up to 12V in WRITE Mode.
WSO	WRITE Regulated Voltage Output	Output from regulated supply source in Write Current Setting Circuit.
LWS	Low Current Set	Terminal to set a low level write current. The current is determined by connecting an external resistor R_{11} between terminal WSO and this terminal.
SWS	Difference Current Set	Terminal to set the current difference (I_{WDF}) between high level write current and low level write current. The difference current is determined by connecting an external resistor R_{10} between terminal WHO and this terminal. $I_{WDF} = (\text{High Level Write Current} - \text{Low Level Write Current})$ $I_{WH} = I_{WL} + I_{WDF}$ Where; I_{WH} is high level write current, and I_{WL} is low level write current. I_{WH} -to- I_{WL} current ratio is; $I_{WH}/I_{WL} = 1 + I_{WDF}/I_{WL}$ It can be set at any value by R_{10} and R_{11} .
ITS	Current Switch Signal Input	Input terminal for Write Current SW signal at inner & outer tracks. High Level Write Current is selected at input Low, and Low Level Write Current at input High.
WD	Write Data Input	Write Data Input Terminal. The signal is divided through the F/F circuit in the IC, and drives the Write Driver.

(to be continued)

Symbol	Name	Description
WT 1, 2	Write Driver 1, 2	Output terminal of Write Driver. The current determined by external resistors at terminal SWS and terminal MWS is sunk. WT 1 and WT 2 turns on alternately, according to the Write Data "1" or "0".
WG	Write Gate	Input terminal for Write Gate signal. The write gate is enable at input Low, and allows data writing.
EG	Erase Gate	Input terminal for Erase Gate signal. The erase gate is enable at input Low, and allows erasing.
EO	Erase Driver	Output terminal of Erase Driver. It turns on at erase gate input LOW. The output on this terminal is an open collector output of NPN transistor, and the erase current is determined by external resistor R_{12} .
PSM	Power Supply Monitor	The monitor circuit monitors the V_{GG} (+5V) and V_{CC2} (+12V), and will inhibit the common driver, the write driver and the erase driver when the supply voltage becomes abnormally low, and the FLAG signal will appear on this terminal PSM. The Driver Inhibit is released only when both V_{GG} and V_{CC2} are more that the specified voltages, regardless of the supply sequence.
V_{CC1}	Amp Voltage	Voltage for Pre Amp in read circuit.
V_{CC2}	Voltage for 12V	Another Voltage (Excepting for Pre Amp.)
V_{GG}	Voltage for 5V	
GND 1	Amp GND	GND for Pre Amp read circuit.
GND 2		GND for read circuit. (Excepting for Pre Amp.)
GND 3		GND for write circuit.

HA1835P ● Voltage Regulator Control with Fail Detector for Digital System

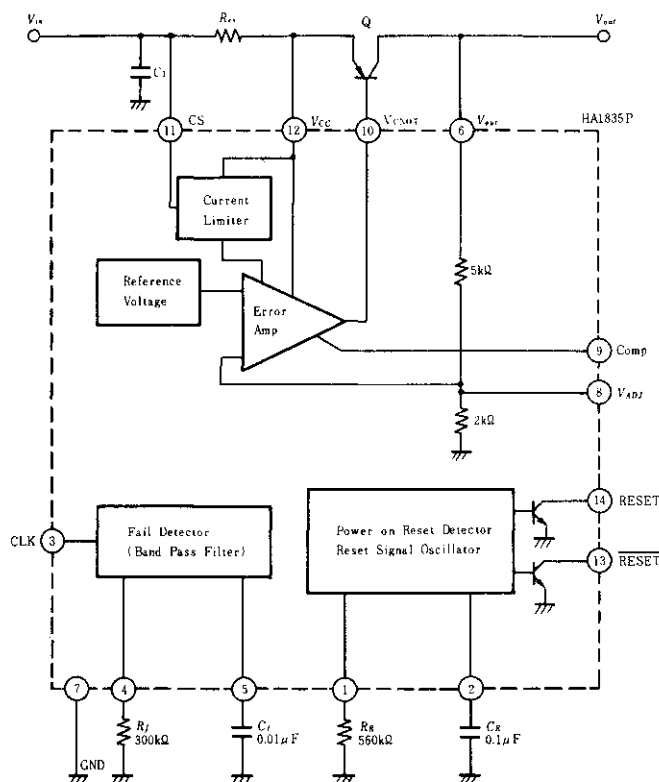
The HA1835P is a monolithic voltage regulator control designed for microcomputer system. In addition to voltage regulator, it includes watch dog timer function and power on reset function.

In various microcomputer system, this IC's every function can operate with a few external parts.

■ FEATURES

- 5V Regulated power supply control circuit
 - Voltage drop can minimize with external PNP-type transistor.
 - Internal over current protection circuit for external PNP-type transistor.
- Watch dog timer
 - Internal Digital band pass filter control circuit of pulse width detect type and Oscillation control circuit of constant current charge-discharge type, so Watch dog timer function controlled by microcomputer's software.
 - Band pass filter characteristic and Oscillation characteristic can also set up at will with external circuit.
- Power on automatic RESET pulse generator

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Rating	Unit
Supply Voltage	V_{CC}	30	V
Input Voltage	V_{CLK}	-0.3 to V_{out}	V
Output Voltage	V_{RESET}	17.5	V
	$\overline{V}_{RESET}$	17.5	V
Output Current	I_{RESET}	2	mA
	$\overline{I}_{RESET}$	2	mA
Control Terminal Voltage	V_{CONT}	V_{CC}	V
Control Terminal Current	I_{CONT}	20	mA
Power Dissipation	P_T^*	400	mW
Operating Temperature Range	T_{opr}	-40 to +85	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-50 to +125	$^{\circ}\text{C}$
Operating Supply Voltage Range	$V_{CC(OPR)}$	6 to +17.5	V
Soldering Temperature	T_{sld}	260 ($T < 10\text{sec}$)	$^{\circ}\text{C}$

* Value under $T_o \leq 77^{\circ}\text{C}$. In case of more than it, 8.3mW/ $^{\circ}\text{C}$ derating shall be done.

■ ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$, $V_{CC}=12\text{V}$, $V_{out}=5\text{V}$ unless otherwise noted)

Item	Symbol	Conditions	min	typ	max	Unit
Supply Current	I_{CC}	$V_{CC}=17.5\text{V}$, with PNP Transistor	—	6.3	12	mA

● Voltage Regulator Control

Output Voltage	V_{out1}	$V_{CC}=6\sim 17.5\text{V}$ $T_a=40\sim +85^{\circ}\text{C}$, $I_{out}=0.5\text{A}$	4.75	5	5.25	V
	V_{out2}	$V_{CC}=6\sim 17.5\text{V}$ $T_a=-40\sim +85^{\circ}\text{C}$, $I_{out}=1\text{A}$	4.70	5	5.30	V
Line Regulation	$V_{out(1\text{line})}$	$V_{CC}=6\sim 17.5\text{V}$, $I_{out}=0.5\text{A}$	50	—	+50	mV
Load Regulation	$V_{out(load)}$	$V_{CC}=13.3\text{V}$, $I_{out}=10\text{mA}\sim 0.5\text{A}$	-100	—	+100	mV
Ripple Rejection	R_{REJ}	$e_i=0.5\text{Vrms}$, $f_i=1\text{kHz}$	45	75	—	dB
Limiter Operating Current	I_{CS}	$R_{CS}=0.2\Omega$	1.0	—	2.0	A
Output Voltage Temperature Coefficient	$\delta V_{out}/\sigma T$		—	-0.6	—	mV/ $^{\circ}\text{C}$

● Watch Dog Timer

"L"-level input Current	I_{LL}	$V_{LL}=0\text{V}$	-120	-60	—	μA
"L"-level input Voltage	V_{LL}		—	—	0.8	V
"H"-level input Voltage	V_{HH}		2.0	—	—	V
"H"-level input Current	I_{HH}	$V_{CC}=13.3\text{V}$, $V_{out}=5\text{V}$, $V_{HH}=5\text{V}$	—	1.8	3.0	mA

● Power on Reset

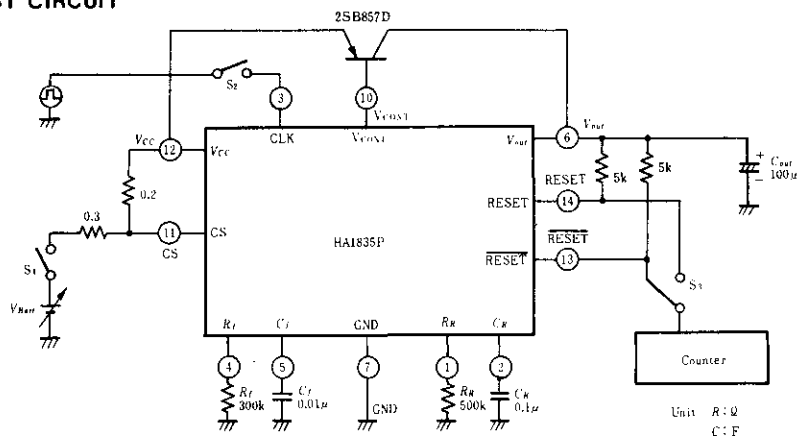
"RESET" Terminal Low-Voltage	V_{OL1}	$I_{OL}=2\text{mA}$	—	—	0.4	V
"RESET" Terminal Leakage Current	I_{OH1}	$V_{OH}=5\text{V}$	—	—	5	μA
"RESET" Terminal Leakage Current	I_{OH3}	$V_{OH}=17.5\text{V}$	—	—	30	μA

Item	Symbol	Conditions	min	typ	max	Unit
●Reset Time						
Power on Reset Time	t_{PR}	$R_f=300k\Omega$, $R_R=560k\Omega$, $C_f=0.01\mu F$, $C_R=0.1\mu F$	80	130	200	ms
CLK off Reset Time	t_{OFF}		60	130	220	ms
Reset Pulse Low Level Time	t_{RL}		40	80	160	ms
Reset Pulse High Level Time	t_{RH}		50	100	200	ms

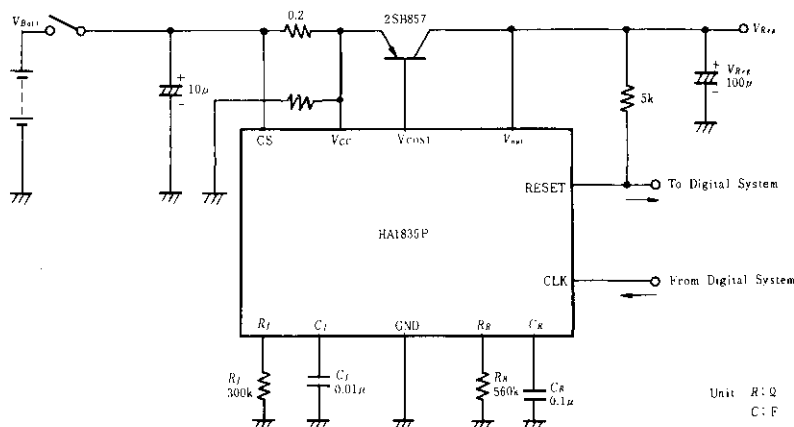
■ TERMINAL'S FUNCTION

Terminal No.	Symbol	Function
1	R_R	Connect the resistor " R_R ". Reset pulse width depended on " R_R ".
2	C_R	Connect the capacitor " C_R ". Reset pulse width depended on " C_R ".
3	CLK	Clock pulse input terminal for watch dog timer.
4	R_f	Connect the resistor " R_f ". Frequency band width of filter circuit depended on " R_f ".
5	C_f	Connect the capacitor " C_f ". Frequency band width of filter circuit depended on " C_f ".
6	V_{out}	Connect the external PNP-type transistor's collector. This terminal supply 5V regulated voltage for internal circuit.
7	GND	Ground.
8	V_{adj}	Output voltage fine tuning terminal.
9	COMP	Phase compensate terminal. Phase compensate could obtained by the capacitor less than 100pF connected between V_{CC} terminal.
10	V_{CON1}	The external PNP-type transistor's base control terminal.
11	C_s	The current sense resistor that protect the external PNP-type transistor connected between V_{CC} terminal.
12	V_{CC}	Supply voltage terminal. Operating supply voltage range is 6V to 17.5V.
13	$\overline{RESET}$	$\overline{RESET}$ pulse output terminal for "L" level reset type microcomputer.
14	RESET	RESET pulse output terminal for "H" level reset type microcomputer.

Note*) $\overline{RESET}$ and RESET terminal are open collector output type.
So both terminal should connect the pull-up resistor about 5k Ω .

■ TEST CIRCUIT

APPLICATION CIRCUIT



OUTLINE OF THE FUNCTION

(1) Voltage Regulator

- Wide operational supply voltage range. 5V regulated output voltage realized wide Vcc range. (Vcc = 6 ~ 17.5V)
- The external PNP-type transistor should be selected by supply current value that flows the system.
- For the realization of 5V regulated output voltage, connect the more than 100μF capacitor between Vout terminal and GND terminal.

(2) Method of Output Voltage Fine Tuning

- Output voltage fine tuning could be obtained by the resistor connected from Vadj terminal to Vout terminal or GND terminal.
- The resistor connected between Vadj terminal and Vout terminal could decrease output voltage.
- The resistor connected between Vadj terminal and GND terminal could increase output voltage.

(3) Current Limiter

- For the protection of the external transistor from over current, connect the current sense resistor between Cs terminal and Vcc terminal.

The value of current sense resistor is given by the expression:

$$I_{out}(\text{limit}) \approx \frac{0.3V}{R_{cs}}$$

(4) Power on Reset

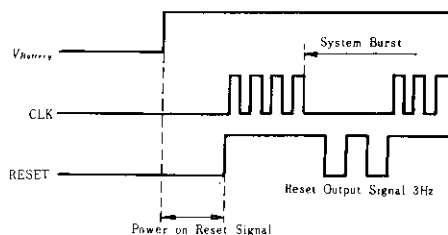
- The reset pulse could output for the microcomputer reset start when power on.
- Reset time for microcomputer system reset when

power on could set external parts resistor "R_t" and capacitor "C_t".

(5) Watch Dog Timer (Prevent function of system run-away)

- Watch dog timer is fail-safe function. This function could reset the microcomputer system when system run-away.
- The pulse that output from microcomputer's software would be detected by this IC's internal band pass filter. If the pulse frequency is off the normal microcomputer's frequency band, then this IC outputs the reset pulse.
- The internal band pass filter's characteristics could set external parts "R_t" and "C_t".

Remarks: RESET terminal and $\overline{\text{RESET}}$ terminal are open collector output type. So both terminal should connect the pull-up resistor about 5kΩ.



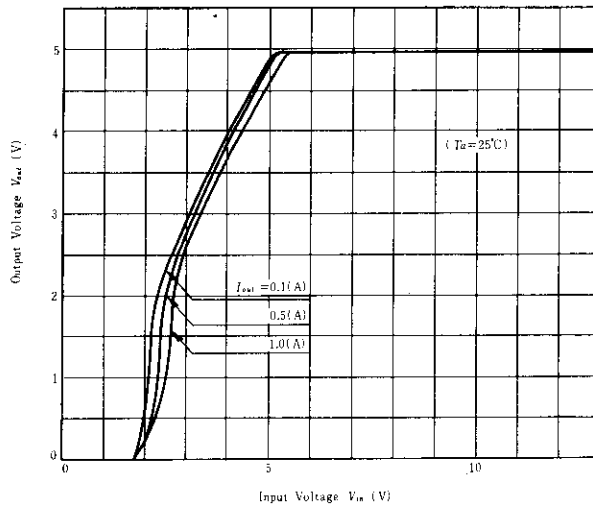


Fig. 1 Vin-Vout Characteristics

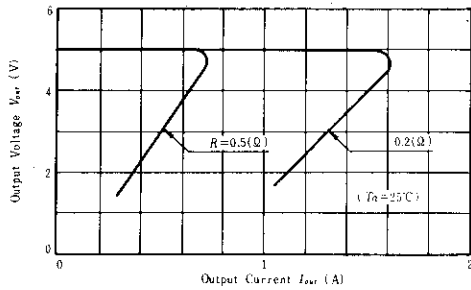
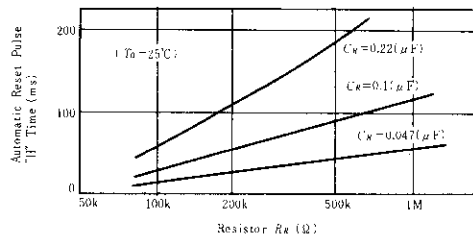
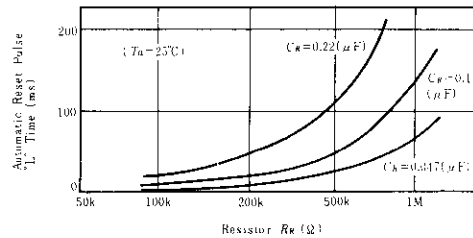
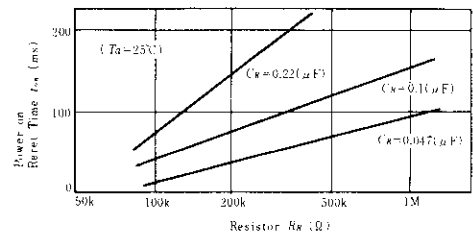


Fig. 2 Current Limit Operation Characteristics

Fig. 3 R_L -Reset "H" Time CharacteristicsFig. 4 R_L -Reset "L" Time CharacteristicsFig. 5 R_L -ton Characteristics

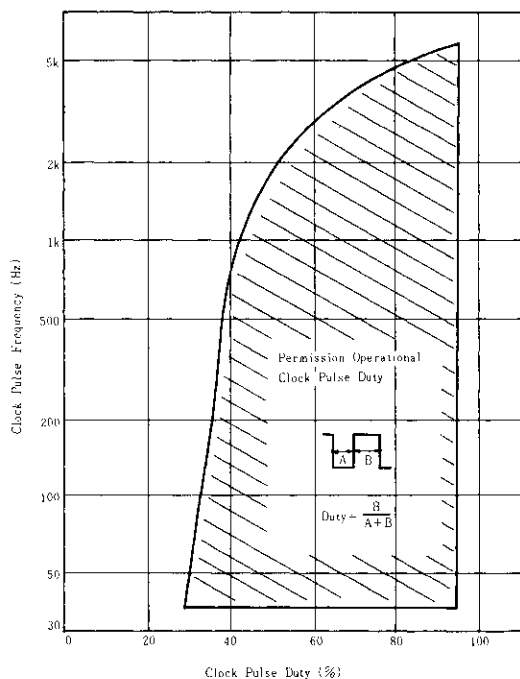


Fig. 6 Permission Operational Clock Pulse Duty VS. Frequency

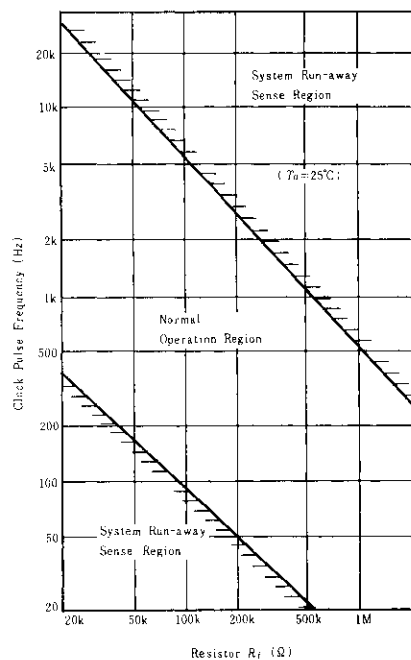


Fig. 7 Clock Pulse Frequency Input Range VS. R_1

Other Functions

HA17733G, HA17733P, HA17733 ● Differential Video Amplifier

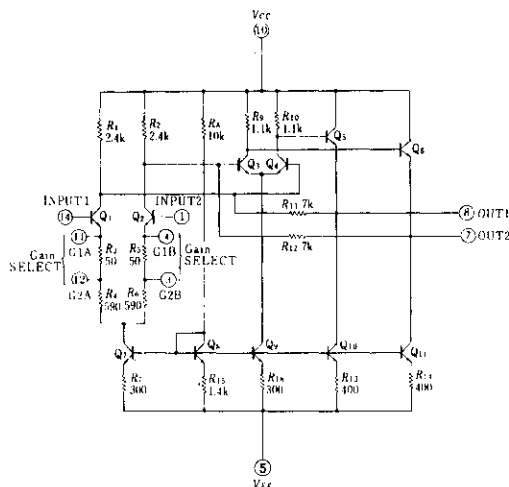
HA17733 is a video amplifier for wide band with small phase-delay and excellent gain stability. This amplifier eliminates external phase compensation and can fix the gain 10, 100 or 400 without using external elements. If some external elements are used, any gain from 10 to 400 is available. It finds main application in terminal units of computers, interface or video amplifiers.

Industrial Use: HA17733G, HA17733P
Commercial Use: HA17733

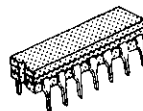
■ FEATURES

- Wide Band Width 120MHz
- Good Response
- Gain is Easily Adjusted in the Range of 10 to 400
- Eliminates External Phase Compensation

■ CIRCUIT SCHEMATIC

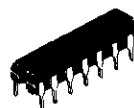


HA17733G



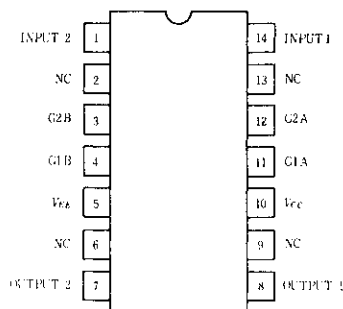
(DG-14)

HA17733P, HA17733



(DP-14)

■ PIN ARRANGEMENT



(Top View)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA17733G	HA17733P	HA17733	Unit
Supply Voltage	V_{CC}	+8	+8	+8	V
	V_{EE}	-8	-8	-8	V
Common Mode Input Voltage	$V_{in(CM)}$	± 6	± 6	± 6	V
Differential Input Voltage	$V_{in(diff)}$	± 5	± 5	± 5	V
Output Current	I_{out}	10	10	10	mA
Power Dissipation	P_T	625 *1	625 *2	625 *2	mW
Operating Temperature	T_{opr}	-20 to +75	-20 to +75	0 to +70	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	-65 to +150	-55 to +125	$^\circ\text{C}$

* 1 When T_a is 70°C or more, the derating curve will be $7.6\text{mW}/^\circ\text{C}$.

* 2 When T_a is 50°C or more, the derating curve will be $8.3\text{mW}/^\circ\text{C}$.

RECOMMENDED OPERATING CONDITIONS ($T_a=25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	5.0	6.0	7.0	V
	V_{EE}	-5.0	-6.0	-7.0	V

ELECTRICAL CHARACTERISTICS-1 ($V_{CC}=-V_{EE}=6.0\text{V}$, $T_a=25^\circ\text{C}$)

Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Operating Supply Voltage Range	V_{CC}	Note 1	3	—	8	V
	V_{EE}		-3	—	-8	V
Differential Voltage Gain	Gain 1	A_{VD}	Note 2	250	400	600
	Gain 2		Note 3	80	100	120
	Gain 3		Note 4	8	10	12
Bandwidth	Gain 1	BW	$R_L=50\ \Omega$	—	40	—
	Gain 2			—	90	—
	Gain 3			—	120	—
Rise Time	Gain 1	t_r	$R_L=50\ \Omega$, $V_{out}=1V_{pp}$	—	10.5	—
	Gain 2			—	4.5	12
	Gain 3			—	2.5	—
Propagation Delay Time	Gain 1	t_p	$R_L=50\ \Omega$, $V_{out}=1V_{pp}$	—	7.5	—
	Gain 2			—	6.0	10
	Gain 3			—	3.6	—
Input Resistance	Gain 1	R_{in}		—	4.0	—
	Gain 2			10	30	—
	Gain 3			—	250	—
Input Capacitance	Gain 2	C_{in}		—	2.0	—
Input Offset Current		I_{IO}		—	0.4	5.0
Input Bias Current		I_I		—	9.0	30
Input Noise Voltage		$V_{n, rms}$	$R_L=50\ \Omega$, $BW=1\text{kHz to }10\text{MHz}$	—	12	—
Input Voltage Range		V_I		± 1.0	—	—
Common Mode Rejection Ratio	Gain 2	CMR	$V_{CM}=\pm 1\text{V}$	$f=100\text{kHz}$	60	86
				$f=5\text{MHz}$	—	60
Power Supply Rejection Ratio	Gain 2	$PSRR$	$\Delta V_{CC}=\pm 0.5\text{V}$, $\Delta V_{EE}=\pm 0.5\text{V}$	50	70	—
Input Offset Voltage	Gain 1	$V_{os, off}$		—	0.6	1.5
	Gain 2, 3			—	0.35	1.5
Output Common Mode Voltage		$V_{o, CM}$		2.4	2.9	3.4
Peak to Peak Output Voltage		V_{opp}		3.0	4.0	—
Output Sink Current		I_{out}		2.5	3.6	—
Output Resistance		R_{out}		—	20	—
Supply Current		I_{CC}		—	18	24

■ ELECTRICAL CHARACTERISTICS-2 ($V_{CC} = -V_{EE} = 6.0V$, $T_a = 0$ to $+70^\circ C$)

Item		Symbol	Test Conditions	Min	Typ	Max	Unit
Differential Voltage Gain	Gain 1	A_{VD}	Note 2	250	—	600	
	Gain 2		Note 3	80	—	120	
	Gain 3		Note 4	8	—	12	
Input Offset Current		I_{IO}		—	—	6.0	μA
Input Bias Current		I_I		—	—	40	μA
Input Voltage Range		V_i		± 1.0	—	—	V
Common Mode Rejection Ratio	Gain 2	CMR	$V_{CM} = \pm 1V$, $f \leq 100kHz$	50	—	—	dB
Power Supply Rejection Ratio	Gain 2	$PSRR$	$\Delta V_{CC} = \pm 0.5V$, $\Delta V_{EE} = \pm 0.5V$	50	—	—	dB
Input Offset Voltage	All Gain	V_{off}		—	—	1.5	V
Peak to Peak Output Voltage		V_{opp}		2.8	—	—	V _{pp}
Output Sink Current		I_{out}		2.5	—	—	mA
Supply Current		I_{CC}		—	—	27	mA
Input Resistance	Gain 2	R_{in}		8.0	—	—	Ω

■ ELECTRICAL CHARACTERISTICS-3 ($V_{CC} = -V_{EE} = 6.0V$, $T_a = -20$ to $+75^\circ C$)

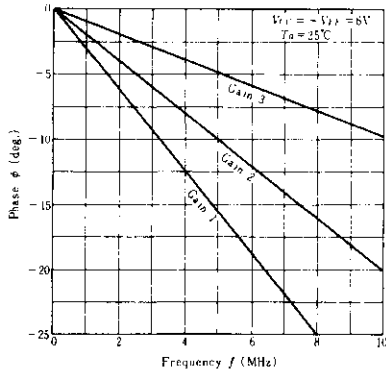
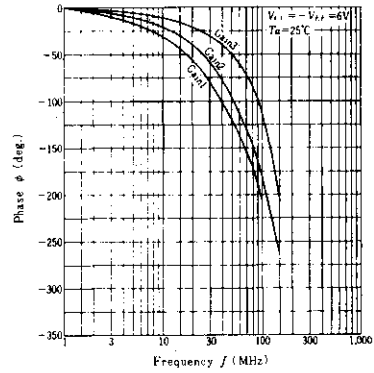
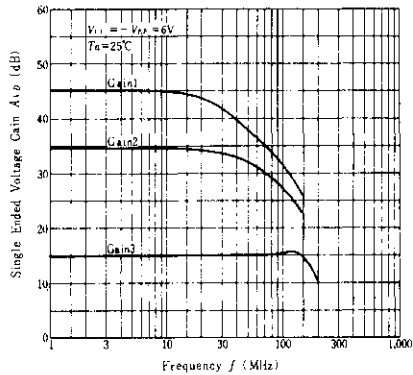
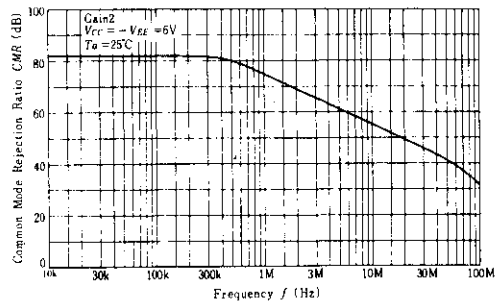
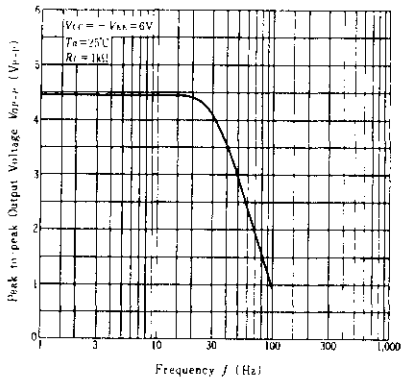
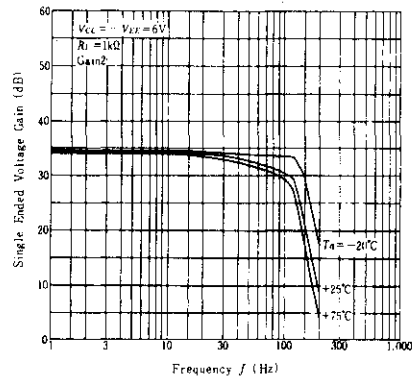
Item		Symbol	Test Conditions	Min	Typ	Max	Unit
Differential Voltage Gain	Gain 1	A_{VD}	Note 2	200	—	700	
	Gain 2		Note 3	70	—	130	
	Gain 3		Note 4	7	—	13	
Input Offset Current		I_{IO}		—	—	7	μA
Input Bias Current		I_I		—	—	50	μA
Input Voltage Range		V_i		± 1.0	—	—	V
Common Mode Rejection Ratio	Gain 2	CMR	$V_{CM} = \pm 1V$, $f \leq 100kHz$	46	—	—	dB
Power Supply Rejection Ratio	Gain 2	$PSRR$	$\Delta V_{CC} = \pm 0.5V$, $\Delta V_{EE} = \pm 0.5V$	46	—	—	dB
Output Offset Voltage	All Gain	V_{off}		—	—	1.5	V
Peak to Peak Output Voltage		V_{opp}		2.8	—	—	V _{pp}
Output Sink Current		I_{out}		2.5	—	—	mA
Supply Current		I_{CC}		—	—	29	mA
Input Resistance	Gain 2	R_{in}		7.0	—	—	k Ω

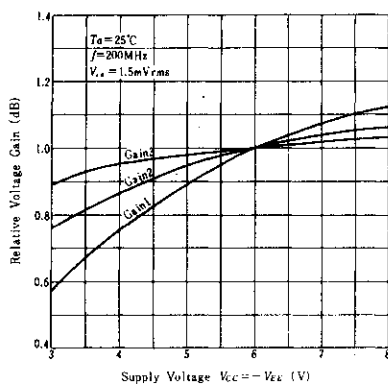
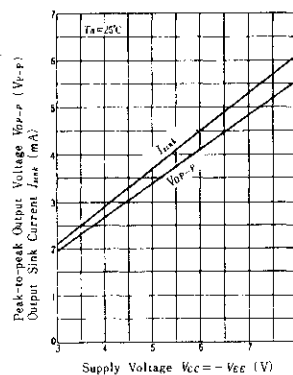
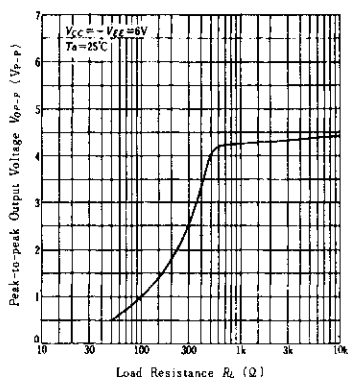
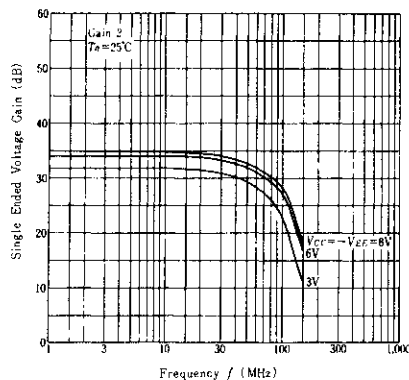
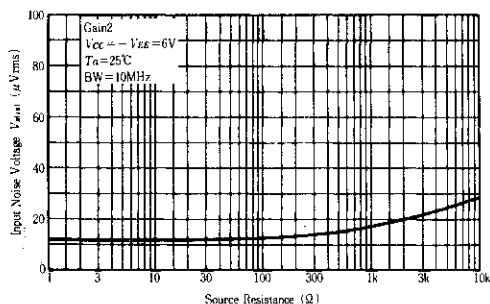
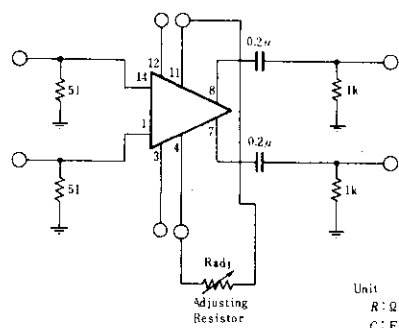
Note 1. In this range, the amplifier can be operating.

2. Connect G_{11} and G_{10} .

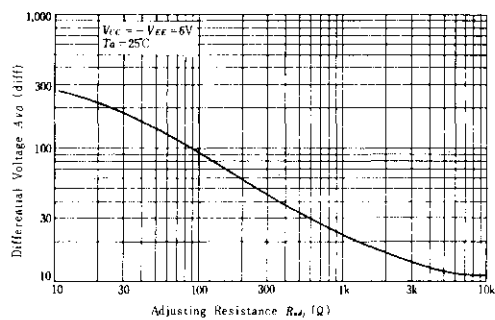
3. Connect G_{12} and G_{13} .

4. Open all of the terminals for gain select.

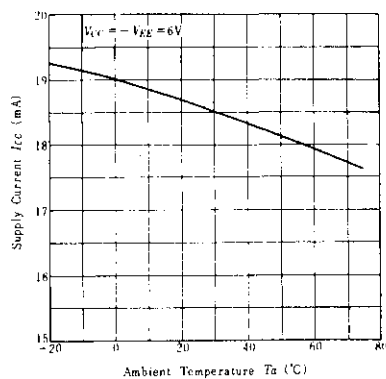
PHASE VS. FREQUENCY (1)

PHASE VS. FREQUENCY (2)

SINGLE ENDED VOLTAGE GAIN VS. FREQUENCY

COMMON MODE REJECTION RATIO VS. FREQUENCY

PEAK-TO-PEAK OUTPUT VOLTAGE VS. FREQUENCY

SINGLE ENDED VOLTAGE GAIN VS. FREQUENCY


**RELATIVE VOLTAGE GAIN VS.
SUPPLY VOLTAGE**

**PEAK-TO-PEAK OUTPUT VOLTAGE, OUTPUT
SINK CURRENT VS. SUPPLY VOLTAGE**

**PEAK-TO-PEAK OUTPUT VOLTAGE VS.
LOAD RESISTANCE**

**SINGLE ENDED VOLTAGE GAIN VS.
FREQUENCY**

**INPUT NOISE VOLTAGE VS.
SOURCE RESISTANCE**

**DIFFERENTIAL VOLTAGE GAIN
ADJUSTING CIRCUIT**


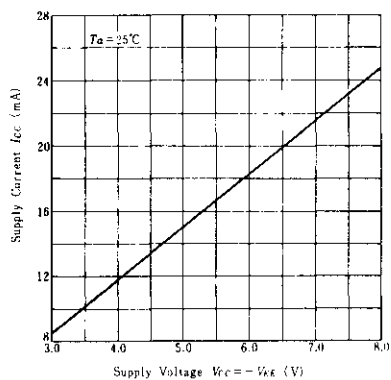
DIFFERENTIAL VOLTAGE GAIN VS. ADJUSTING RESISTANCE



SUPPLY CURRENT VS. AMBIENT TEMPERATURE

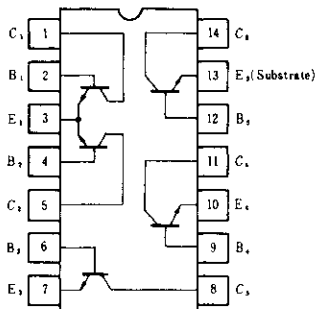


SUPPLY CURRENT VS. SUPPLY VOLTAGE



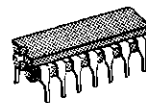
HA1127 ●5 Transistor Arrays

PIN ARRANGEMENT



(Top View)

Note) Use pin-13 as the lowest potential of this IC.



(DG-14)

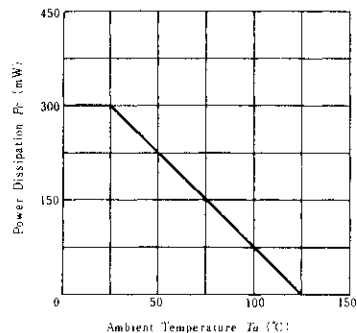
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA1127	Unit
Collector-Base Voltage	V_{CBV}	20	V
Collector-Substrate Voltage	V_{CSV}	20	V
Collector-Emitter Voltage	V_{CEV}	15	V
Emitter-Base Voltage	V_{EBV}	5	V
Collector Current	I_C	50	mA
Collector Power Dissipation	P_C^*	300	mW
Collector Power Dissipation	P_C^{**}	750	mW
Operating Temperature	T_{op}	-55 to $+125$	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to $+150$	$^\circ\text{C}$

* per transistor

** per package

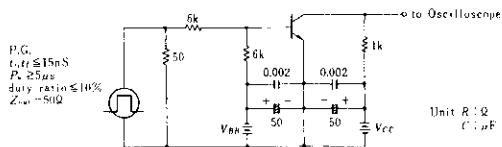
CHANGE IN THE COLLECTOR-POWER DISSIPATION BY THE AMBIENT TEMPERATURE



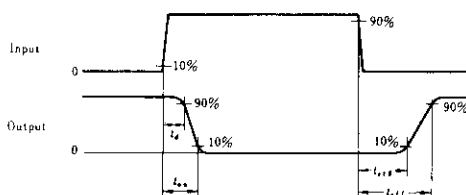
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	V_{CBV}	$I_C = 10\mu\text{A}$, $I_E = 0$	20			V
Collector-Emitter Breakdown Voltage	V_{CEV}	$I_C = 1\text{mA}$, $R_{th} = \infty$	15			V
Collector-Substrate Breakdown Voltage	V_{CSV}	$I_C = 10\mu\text{A}$, $I_E = 0$, $I_B = 0$	20			V
Emitter-Base Breakdown Voltage	V_{EBV}	$I_E = 10\mu\text{A}$, $I_C = 0$	5			V
Collector Breakdown Voltage	I_{CBV}	$V_{CB} = 10\text{V}$, $I_E = 0$	—	0.002	40	nA
	I_{CEV}	$V_{CE} = 10\text{V}$, $R_{th} = \infty$	—	—	0.5	μA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 10\text{mA}$, $I_E = 1\text{mA}$	—	0.17	—	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = 3\text{V}$, $I_C = 1\text{mA}$	—	0.72	—	V
		$V_{CE} = 3\text{V}$, $I_C = 10\text{mA}$	—	0.80	—	
Forward Current Transfer Ratio	h_{FE}	$V_{CE} = 3\text{V}$, $I_C = 1\text{mA}$	40	140	—	
		$V_{CE} = 3\text{V}$, $I_C = 10\text{mA}$	—	120	—	
Gain Bandwidth Product	f_T	$V_{CE} = 3\text{V}$, $I_C = 3\text{mA}$	—	460	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CE} = 3\text{V}$, $I_E = 0$, $f = 1\text{MHz}$	—	1.7	—	pF
Emitter Input Capacitance	C_{ie}	$V_{CE} = 3\text{V}$, $I_E = 0$, $f = 1\text{MHz}$	—	2.0	—	pF
Switching Time	t_{on}	$V_{CE} = 10\text{V}$	—	35	—	ns
	t_{off}	$I_C = 10\text{mA}$, $I_{B1} = 10\text{mA}$	—	130	—	ns
	t_{stg}	$I_C = 10\text{mA}$, $I_{B1} = 10\text{mA}$	—	75	—	ns

SWITCHING TIME MEASURING CIRCUIT

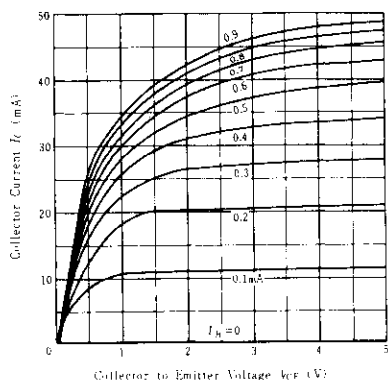
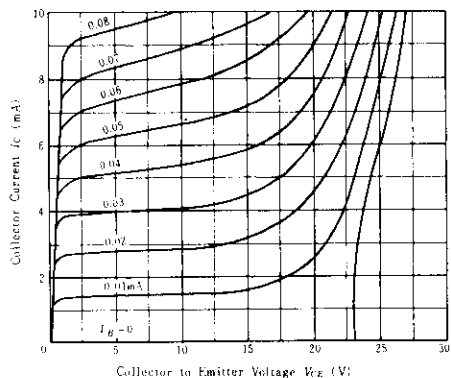
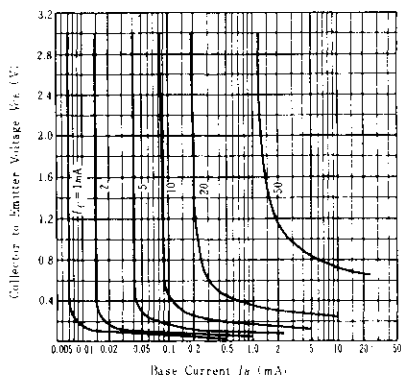
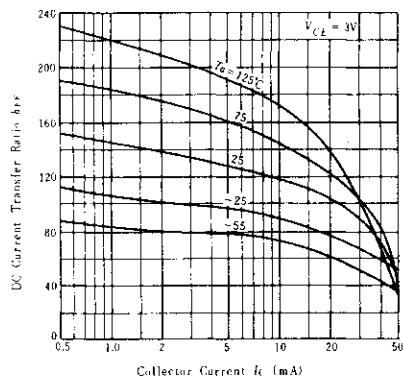


RESPONSE WAVEFORM

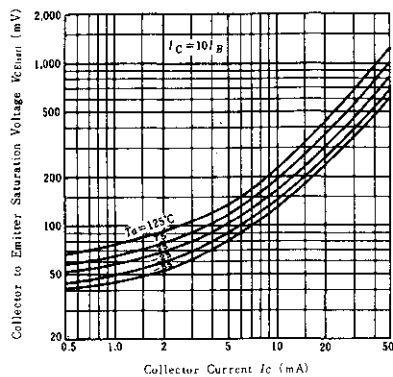


OPERATING CONDITIONS

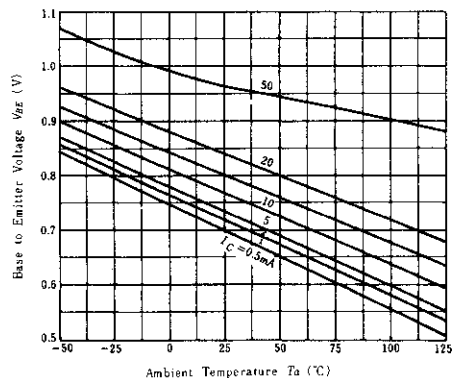
Symbol	I_C	I_{B1}	I_{B2}	V_{CE}	V_{BH}	V_{CS}
Unit	mA	mA	mA	V	V	V
Bias	10	~ 1.0	~ 1.0	10.3	~ 6.0	$+13.0$

EMITTER GROUNDED STATIC
OUTPUT CHARACTERISTICS(1)EMITTER GROUNDED STATIC
OUTPUT CHARACTERISTICS(2)COLLECTOR-EMITTER VOLTAGE VS.
BASE CURRENTFORWARD CURRENT TRANSFER RATIO VS.
COLLECTOR CURRENT

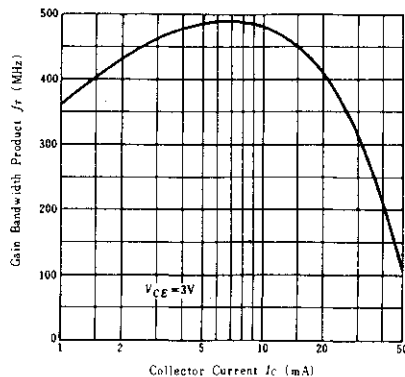
COLLECTOR TO EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT



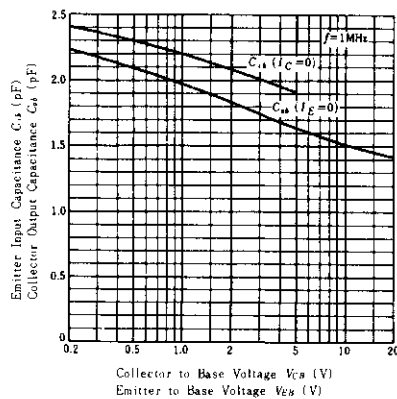
BASE TO EMITTER VOLTAGE VS. AMBIENT TEMPERATURE



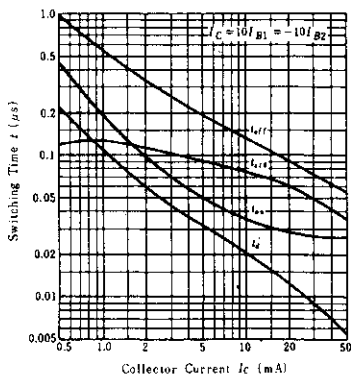
GAIN BANDWIDTH PRODUCT VS. COLLECTOR CURRENT



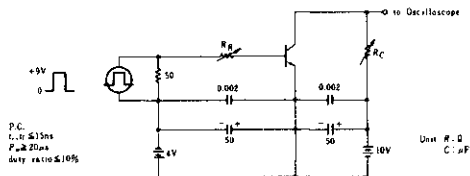
INPUT OUTPUT CAPACITANCE VS. VOLTAGE



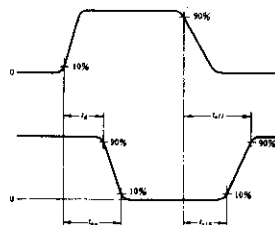
SWITCHING TIME VS. COLLECTOR CURRENT



SWITCHING TIME MEASURING CIRCUIT



RESPONSE WAVEFORM



HA17555GS, HA17555PS, HA17555

● Precision Timer

HA17555 is an IC designed for accurate time delays or oscillations.

It provides both of trigger terminal and reset terminal in order to enable a wide scope of application including Mono Multi Vibrator and Astable Multi Vibrator, and the number of external components is fewer. Further, it's compatible with NE555 of Signetics.

Industrial Use: HA17555GS, HA17555PS

Commercial Use: HA17555

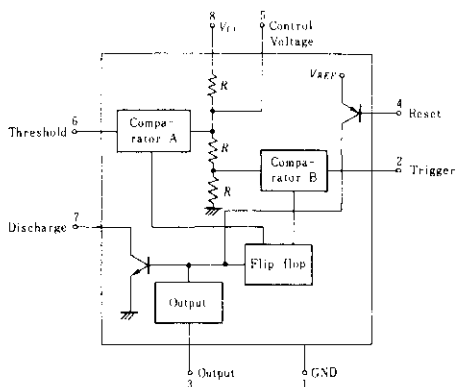
■ FEATURES

- Mono Multi Vibrator can be constructed with one resistor and one capacitor.
- Astable Multi Vibrator can be constructed with two resistors and one capacitor.
- Delay time can be established widely from several μ seconds to several hours.
- Pulse Duty can be controlled.
- The maximum value of both sink current and source current is 200mA.
- Direct connection of output to TTL is possible.
- Temperature/delay time ratio is 50ppm/ $^{\circ}$ C (typ).
- Output is normally in the ON and OFF states.

■ APPLICATIONS

- Delay Time Generator (Mono Multi Vibrator)
- Pulse Generator (Astable Multi Vibrator)
- Pulse Width Modulator
- Pulse Location Modulator
- Miss Pulse Detector

■ BLOCK DIAGRAM



HA17555GS



(DG-8)

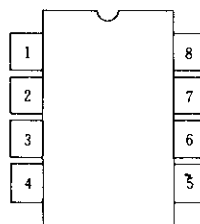
HA17555PS

HA17555



(DP-8)

■ PIN ARRANGEMENT



(Top View)

1	GND Terminal
2	Trigger Terminal
3	Output Terminal
4	Reset Terminal
5	Control Voltage Terminal
6	Threshold Terminal
7	Discharge Terminal
8	V _{CC} Terminal

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	1)HA17555GS	2)HA17555PS	2)HA17555	Unit
Supply Voltage	V_{CC}	18	18	18	V
Discharge Current	I_L	200	200	200	mA
Output Source Current	I_{source}	200	200	200	mA
Output Sink Current	I_{sink}	200	200	200	mA
Power Dissipation	P_T^*	600	600	600	W
Operating Temperature	T_{op}	-20 to +75	-20 to +75	0 to +70	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	-55 to +125	-55 to +125	$^\circ\text{C}$

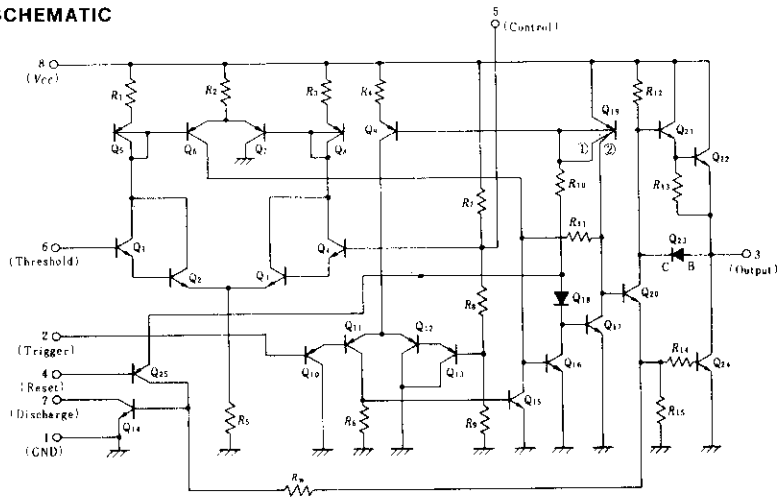
*1): Value under the condition of $T_a \leq 35^\circ\text{C}$. In case of more than it, 6.7mW/ $^\circ\text{C}$ derating shall be performed.2): Value under the condition of $T_a \leq 60^\circ\text{C}$. In case of more than it, 6.7mW/ $^\circ\text{C}$ derating shall be performed.■ ELECTRICAL CHARACTERISTICS ($V_{CC} = 5$ to 15V, $T_a = 25^\circ\text{C}$)

Item		Symbol	Test Condition	Min	Typ	Max	Unit		
Supply Voltage		V_{CC}		4.5	—	16	V		
Supply Current *		I_{CC}	$V_{CC}=5V, R_L=\infty$	—	3.0	6.0	mA		
			$V_{CC}=15V, R_L=\infty$	—	10	15			
Timing Error **	Inherent Error	E_t			1.0	—	$\%$		
	T_a Dependency		$T_a=-20$ to $+75^{\circ}C$	—	50	—	ppm/ $^{\circ}C$		
	Voltage Dependency		$V_{CC}=5$ to 15V	—	0.01	—	$\%/V$		
Threshold Voltage		V_{th}		—	2/3	—	$\times V_{CC}$		
Trigger Voltage		V_T	$V_{CC}=15V$	—	5.0	—	V		
			$V_{CC}=5V$	—	1.67	—			
Trigger Current		I_T		—	0.5	—	μA		
Reset Voltage		V_R		0.2	0.5	1.0	V		
Reset Current		I_R		—	0.1	—	mA		
Threshold Current		I_{th}^{***}		—	0.1	0.25	μA		
Control Voltage		V_{CL}	$V_{CC}=15V$	9	10	11	V		
			$V_{CC}=5V$	2.6	3.33	4.0			
Output Voltage		V_{OL}	$V_{CC}=15V$	$I_{sink}=10mA$	—	0.1	0.25	V	
				$I_{sink}=50mA$	—	0.4	0.75		
				$I_{sink}=100mA$	—	2.0	2.5		
				$I_{sink}=200mA$	—	2.5	—		
		V_{OH}	$V_{CC}=5V, I_{source}=5mA$	—	0.25	0.35	—	V	
				$V_{CC}=15V$	$I_{source}=200mA$	—	12.5		—
					$I_{source}=100mA$	12.75	13.3		—
Output Rise Time		t_r	No loading	—	100	—	ns		
Output Fall Time		t_f		—	100	—	ns		
Oscillation Pulse Width		t_w	*****	10.0	—	—	μs		

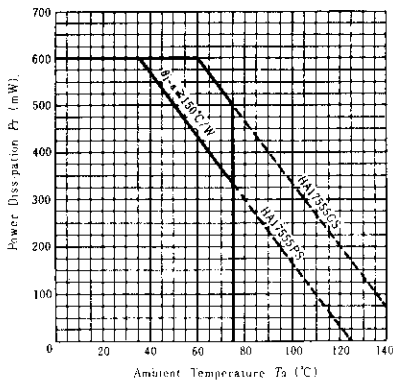
* When output is Low (When it is high, I_L is lower by 1mA typically.)** R_L : $R_L = 1\text{k}$ to $100\text{k}\Omega$, $C = 0.1\mu\text{F}$, $V_{CC} = 5\text{V}$ or 15V *** $(R_L = R_{TH})$ at $V_{CC} = 15\text{V}$ is determined by the value of I_{th} . It is $20\text{M}\Omega$ max.

**** Output pulse width at mono multi circuit. Output high level pulse width at astable circuit

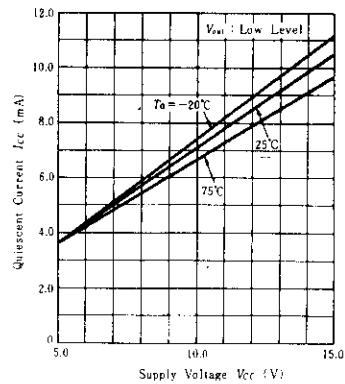
CIRCUIT SCHEMATIC



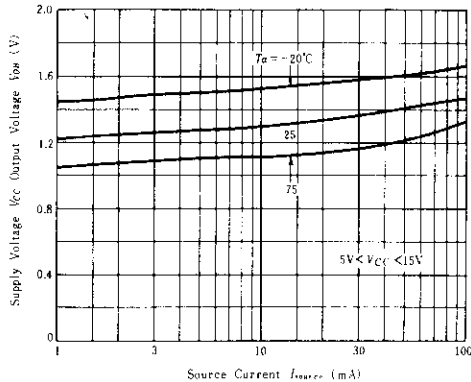
DERATING CURVE



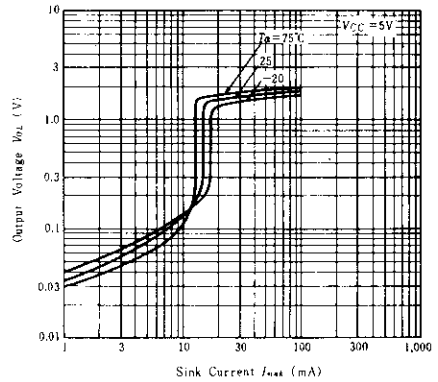
QUIESCENT CURRENT VS. SUPPLY VOLTAGE



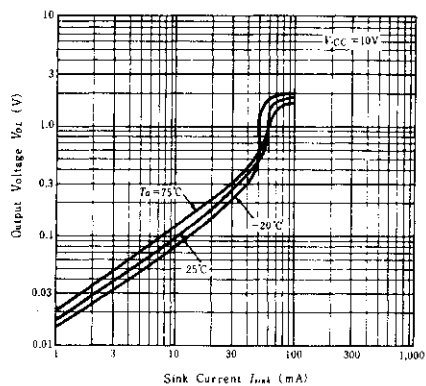
SUPPLY VOLTAGE (V<sub>CC</sub>)-OUTPUT VOLTAGE (V<sub>OH</sub>) VS. SOURCE CURRENT



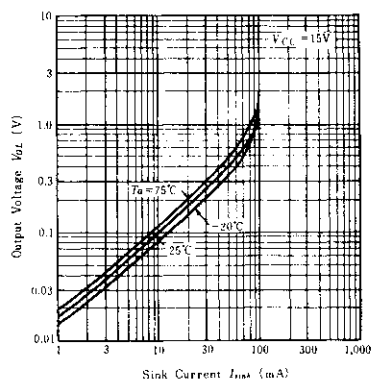
OUTPUT VOLTAGE (V<sub>OL</sub>) VS. SINK CURRENT (I)



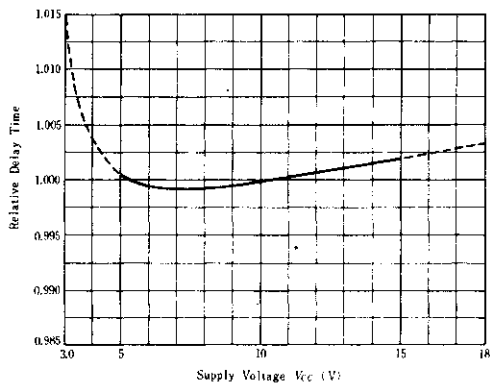
OUTPUT VOLTAGE (V_{OL}) VS.
SINK CURRENT (2)



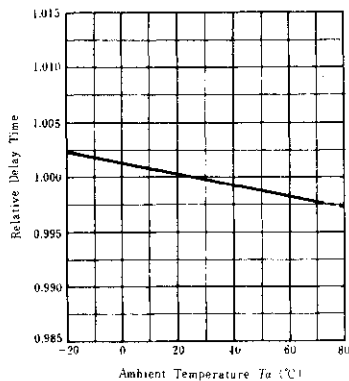
OUTPUT VOLTAGE (V_{OL}) VS.
SINK CURRENT (3)



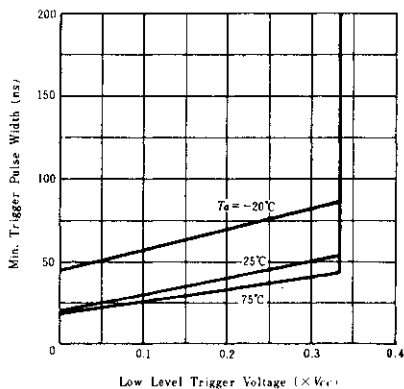
RELATIVE DELAY TIME VS.
AMBIENT TEMPERATURE



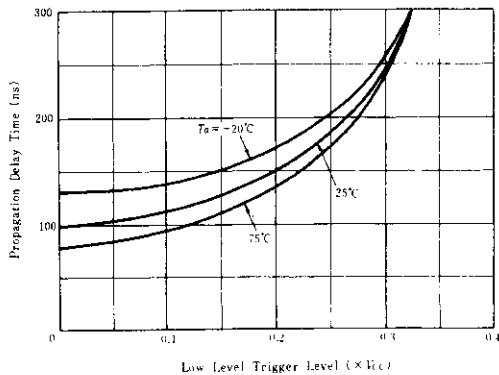
RELATIVE DELAY TIME VS.
SUPPLY VOLTAGE



MINIMUM TRIGGER PULSE WIDTH VS.
LOW LEVEL TRIGGER VOLTAGE



PROPAGATION DELAY TIME VS.
LOW LEVEL TRIGGER VOLTAGE



■ DESCRIPTION OF HA17555 OPERATION

HA17555 is an Integrated circuit which can provide accurate a time delay and oscillation. As for time delay or mono multi operation, output pulse width can be determined by an external resistor and a capacitor. At astable operation, oscillation frequency and duty cycle can be controlled by two external resistors and an external capacitor separately. It is possible to attract and induce 200mA current by output. And also, operating voltage can be used at a wide range of supply voltage, 5 to 15V. Particularly when supply voltage is 5V, output level is compatible with TTL input. HA17555 consists of reference voltage circuit, two kinds of comparators, flip-flop, output circuit, reset and discharge circuits.

1. Reference Voltage Circuit

Supply voltage is divided into three by 5k Ω resistance of R_7 , R_8 and R_9 . The edge of (2/3) V_{cc} is connected to comparator A, the edge of (1/3) V_{cc} is connected to comparator B. And (2/3) V_{cc} is drawn out as a control terminal. By impressing bias at (2/3) V_{cc} from the outside, it is possible to change threshold level and trigger level of comparator.

2. Comparator A

Comparator A consists of Q_1 and Q_8 , R_1 , R_2 , R_3 and R_5 . The base of Q_4 is connected to reference voltage (2/3) V_{cc} . It switches when voltage of threshold terminal switches (2/3) V_{cc} off. In other words, when voltage of threshold terminal is beyond (2/3) V_{cc} , Q_1 and Q_2 which have been cut off is turned "ON", and Q_3 and Q_4 are turned "OFF". So, Q_6 is turned "ON" and resets flip-flop.

3. Comparator B

Comparator B consists of Q_9 through Q_{13} , R_4 and R_6 . The base of Q_{13} is connected to reference voltage (1/3) V_{cc} , it switches when voltage of trigger terminal cuts (1/3) V_{cc} off. In other words, when voltage of trigger terminal decreased to less than (1/3) V_{cc} , Q_{10} and Q_{11} which have been cut off are turned "ON". Q_{12} and Q_{13} are turned "OFF". So, trigger is supplied to the set side of flip-flop from the collector of Q_{11} , and flip-flop is set.

4. Flipflop

PS flip-flop consists of Q_{16} through Q_{19} , R_{10} and R_{11} . It is stabilized when Q_{16} is turned "ON" and Q_{17} "OFF", by reset signal from comparator A. On the other hand, it is stabilized when Q_{16} is turned "OFF" and Q_{17} "ON", by set signal from comparator A.

5. Output Circuit

Output circuit consists of Q_{20} through Q_{24} , R_{12} through R_{15} . Output level is determined, according to the state of output transistor Q_{17} of flip-flop. When Q_{17} is "ON", output level is "Higg", and when Q_{17} is "OFF", it is "Low".

6. Reset

By making reset terminal "Low" level, prior to any other input, the reset function can make it "Low" level and starting point of a new cycle.

7. Discharge Circuit

Discharge circuit can discharge or charge timing constant connected to the both edges, by "ON" or "OFF" of Q_{14} . Q_{14} is turned "ON" and discharged at "Low" level or when the above reset is made.

■ AN EXAMPLE OF OPERATING CIRCUIT

1. Mono Multi Operation

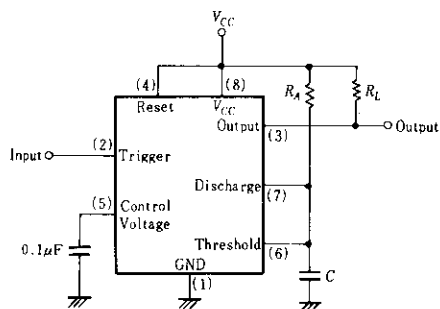


Fig.1 Mono Multi Circuit

= $R_A C$. When voltage at both edges of capacitor C reach threshold voltage of comparator A, flip-flop is reset and Q_{14} is conducted, capacitor C is discharged. So, output is returned to "Low". Mono multi operation is occurred when negative-going input pulse reaches trigger level. When once mono multi operation is occurred, re-trigger could be made, even if re-trigger signal is added during this period.

According to Fig. 1 and Fig. 2, output pulse width is determined to be $t_w = 1.1 R_A C$. If negative-going pulse is added to reset and trigger terminals at the same time during mono multi operation, capacitor C is discharged and mono multi operation is occurred again at positive edge of reset pulse. Output remains "Low" as long as reset terminal is "Low". When the reset terminal is not used, it is better to connect reset terminal to V_{CC} in order to prevent miss operation. Fig. 2 shows the characteristics of output pulse width when the values of R_A and C are changed. Operating waveform is shown in Fig. 3. If the reset terminal is connected to mono multi circuit subordinately, it is possible to make sequential timer.

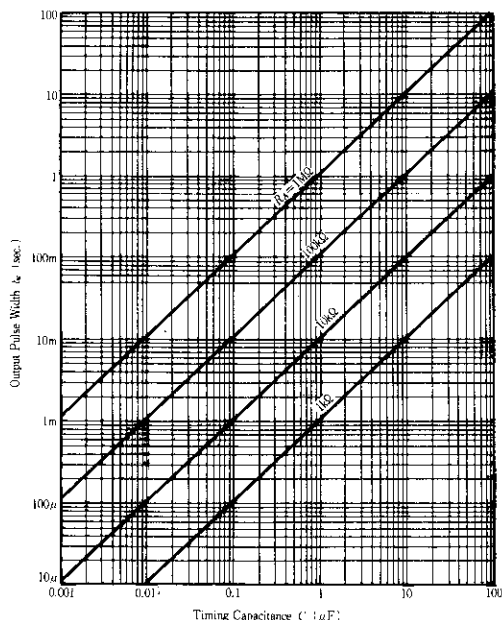


Fig.2 Output Pulse Width vs. Timing Capacitance

Fig. 1 shows a mono multi circuit using HA17555. It is assumed that the external capacitor C is discharged by discharge transistor Q_{14} inside IC in the beginning.

By adding trigger terminal to negative-going input trigger pulse, flip-flop is set and Q_{14} is turned "OFF". Output is driven to "High".

Capacitor C is charged through resistor R_A at time constant τ

2. Astable Operation

If the second resistor R_B is added to the circuit shown in Fig. 1 and threshold terminal is connected to trigger terminal, HA17555 operates as an astable circuit. Fig. 4 shows the circuit construction of HA17555.

Capacitor C is charged through R_A and R_B , discharged through R_B in this circuit. Therefore, duty cycle can be controlled by R_A and R_B . In Fig. 4, capacitor C charges and discharges between threshold voltage (about $0.67 V_{CC}$) and trigger voltage level (about $0.33 V_{CC}$). Fig. 5 shows a typical example of astable operation. In this figure, time (t_H) when output is "High" level, time (t_L) when output is "Low", oscillation frequency (f) and duty cycle (D) are calculated as follows;

$$t_H = 0.693(R_A + R_B)C$$

$$t_L = 0.693R_B \cdot C$$

$$f = \frac{1.44}{(R_A + 2R_B)C}$$

$$\text{Duty Cycle } D = \frac{R_B}{(R_A + 2R_B)}$$

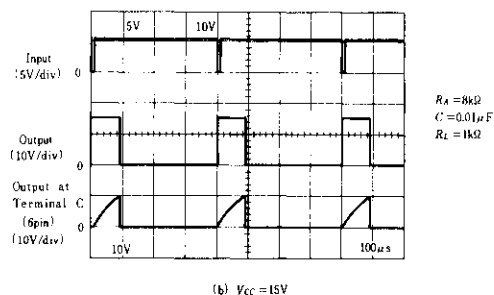
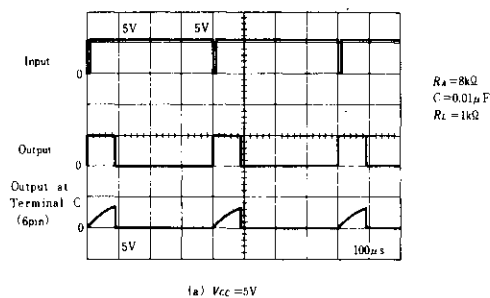


Fig.3 Operation Waveform of Mono multi circuit

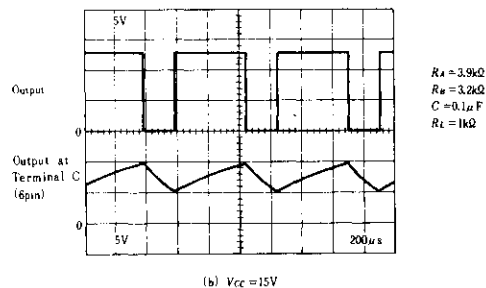
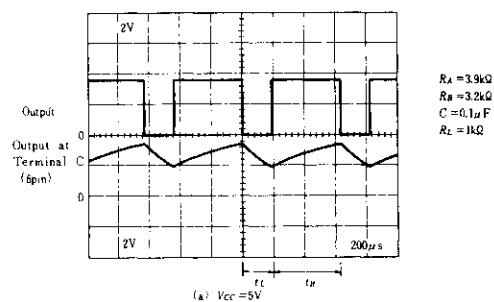


Fig.5 Operation Waveform of Astable Circuit

3. Cautions in Use

Such integrated circuit for timer as HA17555 type may produce switching noise on power supply and GND line during usage. In this case, abnormal output waveform may be produced by impedance inside power supply or impedance between power supply and GND. So, please take consideration in order to make impedance of each wiring less than the following value at packaging.

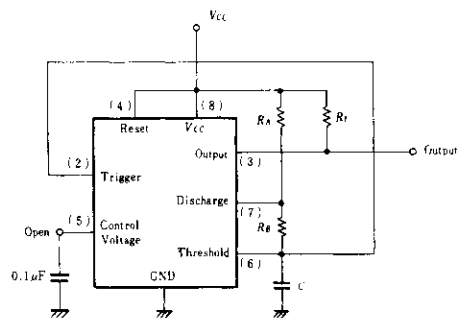
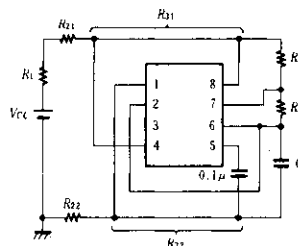


Fig.4 Astable Circuit



R_1 : Power supply output impedance

$$R_1 \leq 50m\Omega$$

R_{21}, R_{22} : Lead wiring resistor

$$R_{21} + R_{22} \leq 100m\Omega$$

R_{31}, R_{32} : Substrate wiring resistor

$$R_{31} + R_{32} \leq 20m\Omega$$

HA16605W ● Burner Controller

Recently burner control equipment has been improved and required to obtain small outline, high performance and multi functions. And now, electronic burner controller is going to become more popular to save energy and to have better safety functions.

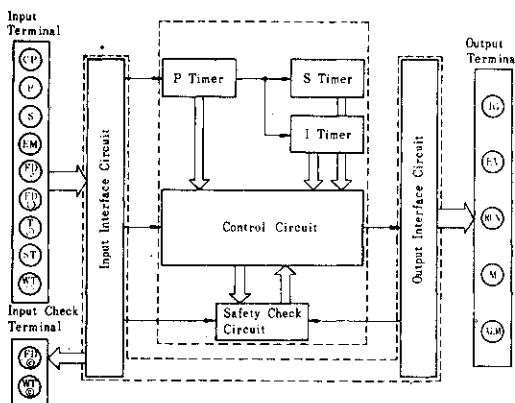
The HA16605W is a one chip monolithic IC, integrated of the sequential control part in the burner control equipment. This IC has four sequence control modes, so that it can provide functions for various burner systems.

In each mode, fail-safe functions are provided. And this IC has capability of drive relays directly.

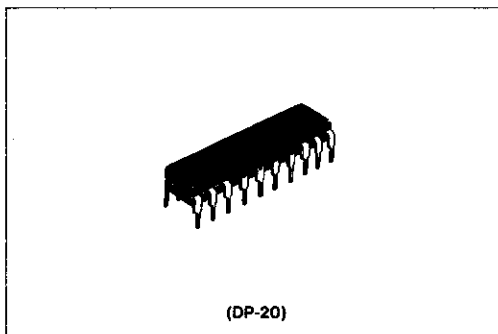
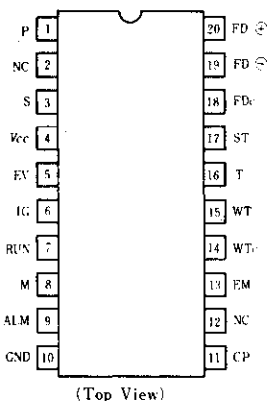
■ FEATURES

- Four kinds of fixed control sequence
- Commercial frequency 50/60Hz can be used for the clock pulse of internal timer.
- Transistors which can drive the power relay directly are built in.
- Comparators are built in.
- Provides safety functions.

■ BLOCK DIAGRAM



■ PIN ARRANGEMENT



■ PIN DESCRIPTION

Pin No.	Symbol	Description
1	$\overline{P}$	Decoder input to discriminate four kinds of control sequence.
2	NC	Non Connect
3	S	Decoder input to discriminate four kinds of control sequence.
4	V _{cc}	Power Supply
5	EV*	Power transistor output for driving the magnetic-valve.
6	IG*	Power transistor output for driving the ignition equipment
7	RUN*	Power transistor output for driving the operation lamp
8	M*	Power transistor output for driving the blower motor
9	ALM*	Power transistor output for driving the alarm lamp
10	GND	GND
11	CP	Clock signal(50/50Hz)input
12	NC	Non connect
13	EM	Emergency stop signal input
14	WT _c	Output of the water temperature detection signal
15	WT	Input of the water thermo signal
16	T	Input of the reference voltage for the water thermo and for the safety thermo
17	ST	Input of the safety thermo signal
18	FD _c	Output of the flame detection signal
19	FD _⊖	Input of the flame detection signal
20	FD _⊕	Input of the reference signal for the flame detection

*Open collector output of NPN transistor

■ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

Item	Symbol	Rating	Unit	Applied Terminal	Note
Supply Voltage	V_{CC}	7.0	V	V_{CC}	
Input Voltage	V_{IN}	-0.5 to $V_{CC}-5.0$	V	CP, EM	1
		-0.5 to $V_{CC}-1.0$		P, S	
		-0.5 to $V_{CC}+3.0$		FD $\pm$, FD $\bar{C}$, T, ST, WT	
Output Voltage	V_{OUT}	-0.5 to $V_{CC}+3.0$	V	FD $\bar{C}$, WT $\bar{C}$	2
		-0.5 to $+25$		IG, EV, RUN, M, ALM	
Output Current	I_{OUT}	2	mA	FD $\bar{C}$, WT $\bar{C}$	3
		75		IG, EV, M, ALM	
		100		RUN	
Power Dissipation	P_T	500	mW		
Operating Temperature Range	T_{opr}	-20 to $+75$	$^{\circ}\text{C}$		
Storage Temperature Range	T_{stg}	-55 to $+125$	$^{\circ}\text{C}$		

Notes: 1. Internal impedance of the drive source should be more than $1\text{k}\Omega$.

2. Allowable value when the output transistor is in OFF state.

3. Allowable value when the output transistor is in ON state.

■ELECTRICAL CHARACTERISTICS

Item	Symbol	Test Condition	min	max	Unit	Application Terminal	Note
Input Voltage	Low	V_{IL}	—	0.6	V	CP, EM	1
	High	V_{IH}	2.8	—			
Input Clamp Voltage	V_{IC}	$I_{IC}=-12\text{mA}$	-1.5	—	V	CP, EM	
Output Voltage (Low Level)	V_{OL}	$V_{CC}=4.5\text{V}$, $I_{OL}=2\text{mA}$	—	0.3	V	FD $\bar{C}$, WT $\bar{C}$	
		$V_{CC}=4.5\text{V}$, $I_{OL}=75\text{mA}$	—	0.7	V	IG, EV, M, ALM	
		$V_{CC}=4.5\text{V}$, $I_{OL}=100\text{mA}$	—	0.7	V	RUN	
Input Current	Low	I_{IL}	$V_{CC}=5.5\text{V}$, $V_{IL}=0\text{V}$	-200	μA	CP, EM	
	High	I_{IH}	$V_{CC}=5.5\text{V}$, $V_{IH}=5.5\text{V}$	—	100		
Output Current (High Level)	I_{OH}	$V_{CC}=5.5\text{V}$, $V_{OH}=8.5\text{V}$	—	0.2	μA	FD $\bar{C}$, WT $\bar{C}$	
		$V_{CC}=5.5\text{V}$, $V_{OH}=20\text{V}$	—	50	μA	IG, EV, RUN, M	
		$V_{CC}=5.5\text{V}$, $V_{OH}=25\text{V}$	—	1.0	mA	ALM	
Comparator Input Bias Current	I_{IB}	$V_{CC}=5.5\text{V}$, $V_I=0\text{V}$	-250	—	nA		2
Comparator Input Offset Voltage	V_{IO}	$V_{CC}=5.0\text{V}$, $V_{ref}=1.4\text{V}$	—	10	mV		3
Comparator Common Mode Input Voltage	V_{CM}		0	$V_{CC}-1.6$	V		3
Supply Current	I_{CC}	$V_{CC}=5.0\text{V}$	—	70	mA		
Power Supply Voltage	V_{CC}		4.5	5.5	V		
Maximum Clock Frequency	f_{CP}		10	—	kHz		

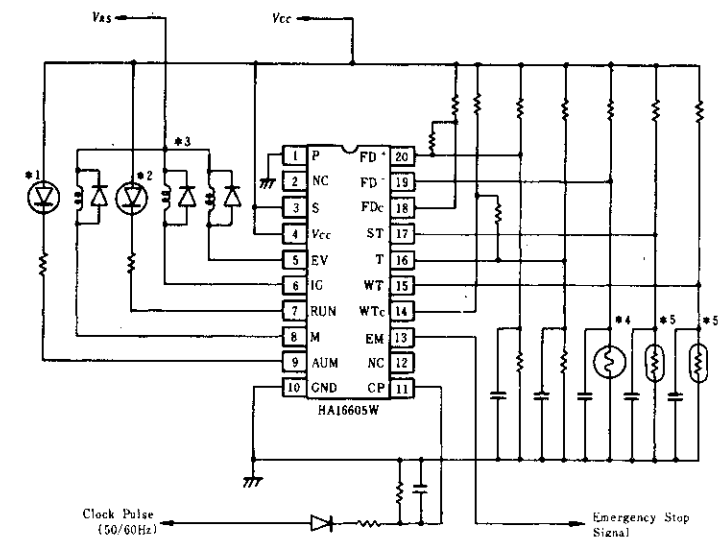
Notes: 1. Low and High signal levels applied to terminals CP and EM.

2. This item is applied to the inputs of comparators, FD $\bar{C}$, FD $\bar{C}$, T, ST and WT.3. These items are applied to FD $\bar{C}$ and FD $\bar{C}$, T and ST and T and WT of the comparators.

SIGNAL STATES AND LEVELS OF I/O INTERFACE

Interface Block	Terminal Name	Signal State	Signal Level
Decoder	P	Connect to V_{CC} at "1" level input, and to GND at "0" level input.	$V_{IH} \geq 4.0V$ $V_{IL} \leq 2.0V$
	S		
Clock Interface	CP		$V_{IH} \geq 2.8V$ $V_{IL} \leq 0.6V$
Emergency Input	EM	Emergency state is detected at Low level input on this terminal, and ALM output turns ON.	
Comparator	FD $\oplus$	High level on this terminal turns the sequence to the flame detected state.	$0 \leq V_{CM} \leq V_{CC} - 1.6V$
	ST	Low level on the inverting input turns the ALM output ON.	
	WT	Low level on the inverting input turns the all sequence Reset.	
Driver	EV, IG, RUN, M, ALM	Output OFF equals to "1" level. Output ON equals to "0" level.	

SYSTEM CONNECTION



- * 1 LED for alarm lamp.
- * 2 LED for operation monitor lamp.
- * 3 Relay coils to drive the electromagnetic-valve, the ignition equipment and the blower motor.
- * 4 Device for flame detection (e. g. Cds)
- * 5 Thermistors for detection of water temperature.

SEQUENCE TIME TABLE

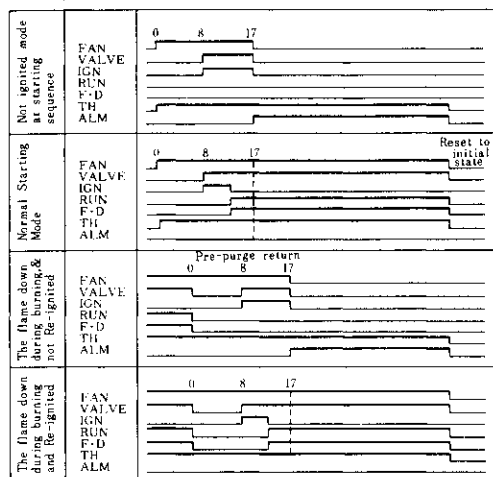
Item	Sequence Code		P	0	P	1	P	0	P	1
			S	0	S	0	S	1	S	1
Pre-purge Timing			8 sec		17 sec		17 sec		68 sec	
Ignition Timing *1			9 MAX		4 MAX		8 MAX		—	
Post-ignition Timing			—		—		17		170	
Safety Switch Timing			9		4		8		—	
Ignition Return			None		None		Possible		—	
Pre-purge Return			Provided		Provided		Provided		—	

Note) *1 Ignition should be turned off at the same time of flame ON.

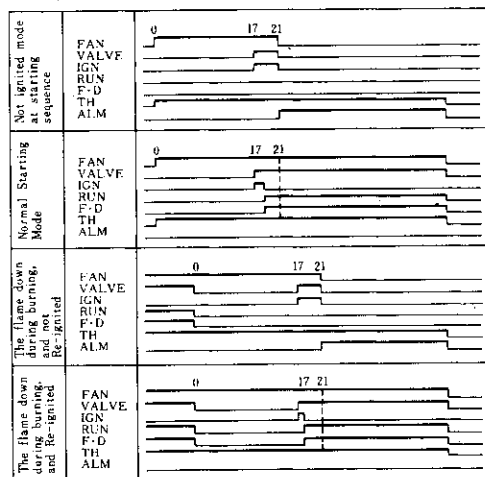
*2 All values shown in this table are measured under the condition of that:
clock input : f = 60Hz (commercial frequency)

SEQUENCE CHART

●P:0, S:0

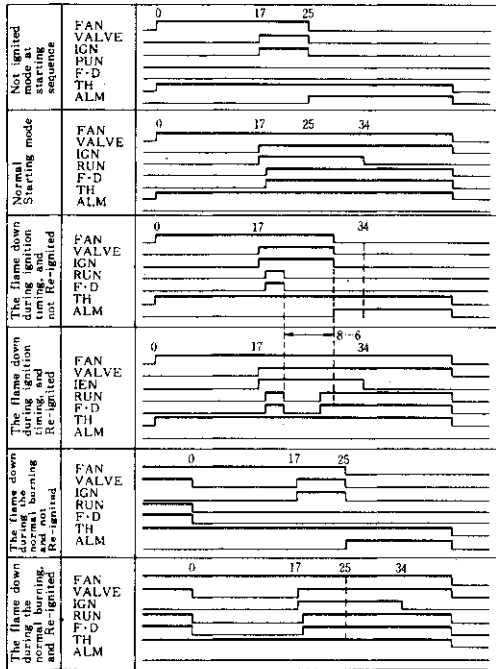


●P:1, S:0

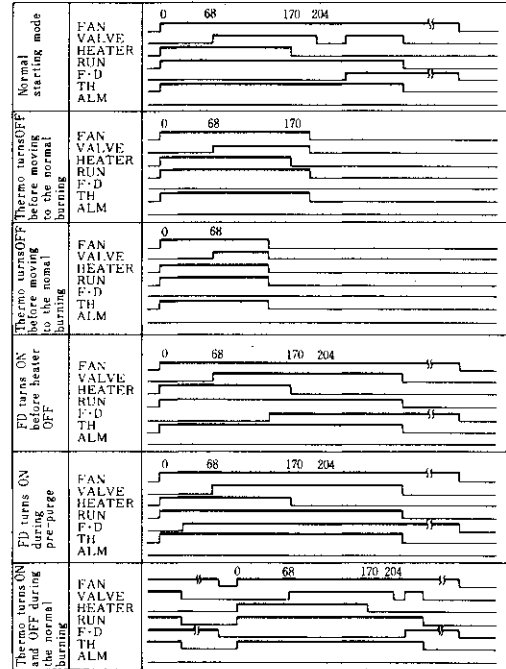


Note) The values in the Time Chart show the operating time (in seconds) at f = 60Hz clock input.

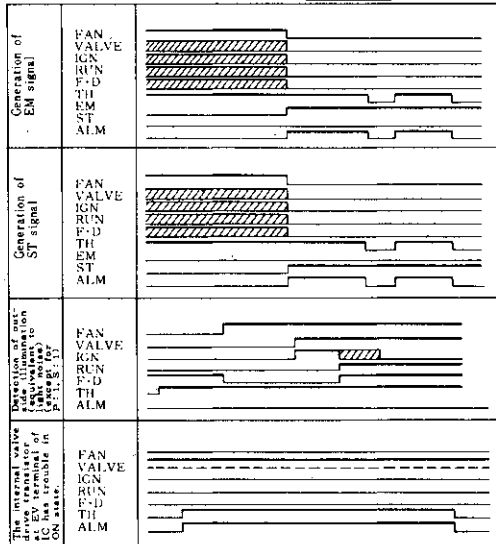
●P:0, S:1



●P:1, S:1



●P:*, S:*(in abnormal conditions)

 : don't care


HA16617P, HA16619P ●Fluorescent Display Drivers

HA16617P and HA16619P are fluorescent display drivers operating in high voltage which use positive and negative power source, respectively.

■ FEATURES

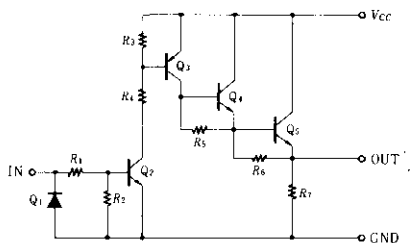
- Capable of driving fluorescent display tube directly because of the built-in 8 circuits and the built-in pull down resistors at output.
- For the inputs, CMOS or TTL accepted.
- The output pulse is non-inverted or inverted from the input pulse in HA16617P or HA16619P, respectively.



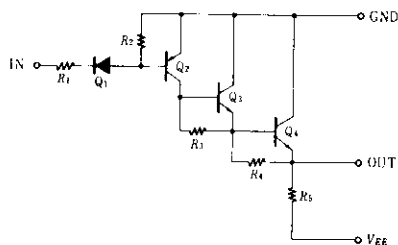
(DP-18)

■ CIRCUIT SCHEMATIC (1/8)

● HA16617P

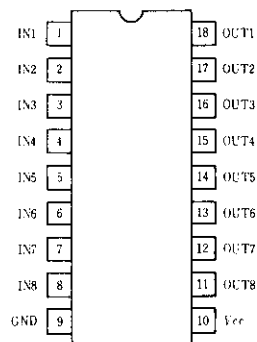


● HA16619P



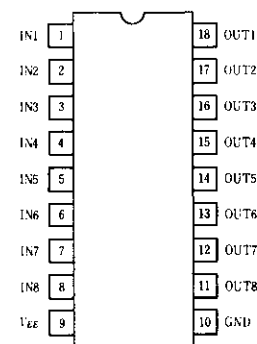
■ PIN ARRANGEMENT

● HA16617P



(Top View)

● HA16619P



(Top View)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA16617P	HA16619P	Unit
Supply Voltage	V_{EE}	-0.3 to +65	+0.3 to -65	V
Input Voltage	V_{in}	-0.5 to +10	+0.5 to -10	V
Output Voltage	V_{out}	-0.3 to +65	+0.3 to -65	V
Output Current*	I_{out}	-45	-45	mA
Power Dissipation**	P_T	625	625	mW
Operating Temperature	T_{op}	-20 to +75	-20 to +75	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +125	-55 to +125	$^\circ\text{C}$

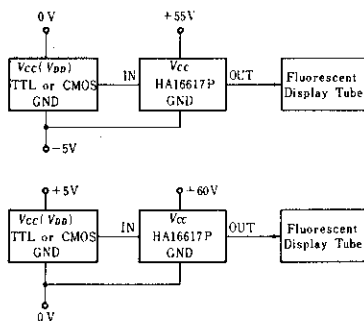
* When only one circuit turns ON.

** Value when $T_a \leq 50^\circ\text{C}$. Derating curve above $T_a = 50^\circ\text{C}$ shall be $8.3\text{mW}/^\circ\text{C}$.■ ELECTRICAL CHARACTERISTICS ($T_a = -20$ to $+75^\circ\text{C}$)

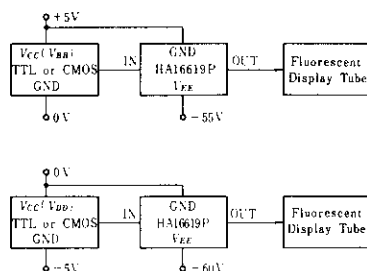
Item	Symbol	Test Conditions	HA16617P			HA16619P			Unit
			min	typ	max	min	typ	max	
Input Voltage	V_{IH}	$V_{CC} = 60\text{V}, V_O \geq 57\text{V}$	2.4	—	—	—	—	—	V
		$V_{EE} = -60\text{V}, V_O \leq -55\text{V}$	—	—	—	—	—	-1.5	V
	V_{IL}	$V_{CC} = 60\text{V}, V_O \leq 3\text{V}$	—	—	0.4	—	—	—	V
		$V_{EE} = -60\text{V}, V_O \geq -3\text{V}$	—	—	—	-4	—	—	V
Input Current	I_{IH}	$V_{CC} = 60\text{V}, V_{in} = 2.4\text{V}$	—	—	0.22	—	—	—	mA
		$V_{CC} = 60\text{V}, V_{in} = 5\text{V}$	—	—	0.45	—	—	—	mA
		$V_{EE} = -60\text{V}, V_{in} = -1.5\text{V}$	—	—	—	-280	—	—	μA
	I_{IL}	$V_{CC} = 60\text{V}, V_{in} = 0.4\text{V}$	—	—	80	—	—	—	μA
		$V_{EE} = -60\text{V}, V_{in} = -4\text{V}$	—	—	—	-1.2	—	—	mA
		$V_{EE} = -60\text{V}, V_{in} = -7\text{V}$	—	—	—	2.6	—	—	mA
Output Voltage	V_{OH}	$V_{CC} = 60\text{V}, V_{in} = 2.4\text{V}, I_O = -40\text{mA}$	57	58.5	—	—	—	—	V
		$V_{EE} = -60\text{V}, V_{in} = -4\text{V}, I_O = -40\text{mA}$	—	—	—	-3	-1.5	—	V
	V_{OL}	$V_{CC} = 60\text{V}, V_{in} = 0.4\text{V}$	—	—	3.0	—	—	—	V
		$V_{EE} = -60\text{V}, V_{in} = -1.5\text{V}$	—	—	—	-55	—	—	V
Quiescent Current	$I_{CC(Off)}$	$V_{CC} = 60\text{V}, \text{all Circuit } V_{in} = 0.4\text{V}$	—	0.04	0.4	—	—	—	mA
	$I_{EE(Off)}$	$V_{EE} = -60\text{V}, \text{All Circuit } V_{in} = -1.5\text{V}$	—	—	—	-1.3	—	—	mA
	$I_{CC(On)}$	$V_{CC} = 60\text{V}, \text{One Circuit } V_{in} = 2.4\text{V}$	—	—	4.0	—	—	—	mA
	$I_{EE(On)}$	$V_{CC} = -60\text{V}, \text{All Circuit } V_{in} = -4\text{V}$	—	—	—	-12	—	—	mA

■ APPLICATIONS

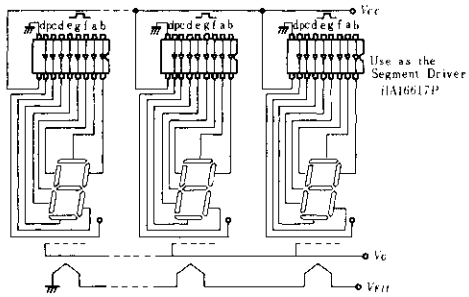
● HA16617P



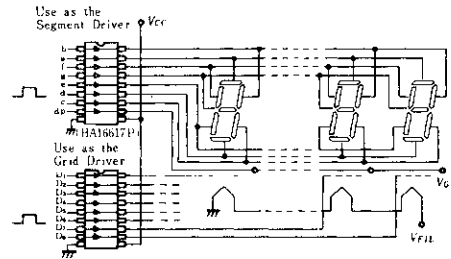
● HA16619P



■ BASIC CIRCUIT



(a) Static Type



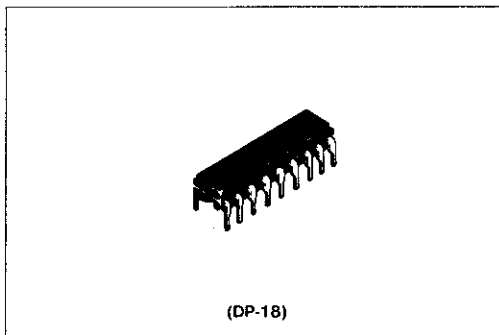
(b) Dynamic Type

HA16617PJ, HA16619PJ ● Fluorescent Display Drivers

HA16617PJ and HA16619PJ are fluorescent display drivers operating in high voltage which use positive and negative power source, respectively.

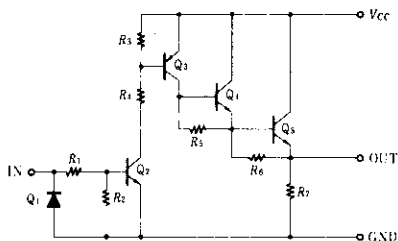
■ FEATURES

- Capable of driving fluorescent display tube directly because of the built-in 8 circuits and the built-in pull down resistors at output.
- For the inputs, CMOS or TTL accepted.
- The output pulse is non-inverted or inverted from the input pulse in 16617PJ or HA16619PJ, respectively.

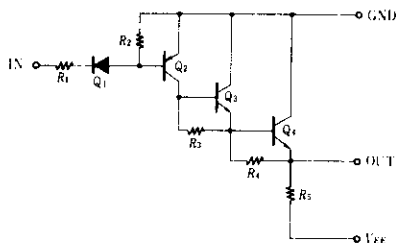


■ CIRCUIT SCHEMATIC (1/8)

● HA16617PJ

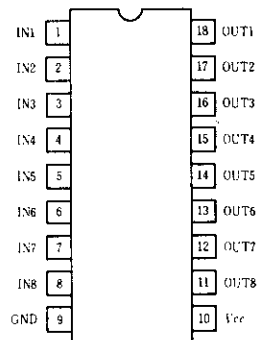


● HA16619PJ



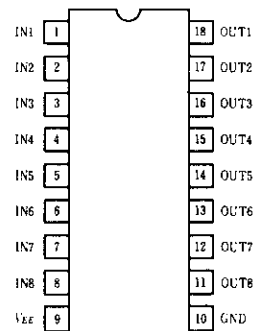
■ PIN ARRANGEMENT

● HA16617PJ



(Top View)

● HA16619PJ



(Top View)

■ ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Item	Symbol	HA16617PJ	HA16619PJ	Unit
Supply Voltage	V_{EE}	-0.3 to +65	+0.3 to -65	V
Input Voltage	V_{in}	-0.5 to +10	+0.5 to -10	V
Output Voltage	V_{out}	-0.3 to +65	+0.3 to -65	V
Output Current *	I_{out}	-45	-45	mA
Power Dissipation **	P_T	625	625	mW
Operating Temperature	T_{opr}	-40 to +85	-45 to +85	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +125	-55 to +125	$^\circ\text{C}$

* When only one circuit turns ON

** Value when $T_a \leq 50^\circ\text{C}$. Derating curve above $T_a = 50^\circ\text{C}$ shall be $8.3\text{mW}/^\circ\text{C}$.

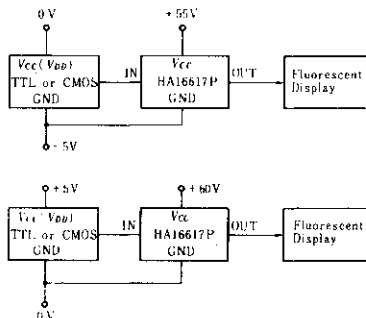
■ ELECTRICAL CHARACTERISTICS ($T_a = -45$ to $+85^\circ\text{C}$)

Item	Symbol	Test Conditions	HA16617PJ			HA16619PJ			Unit
			Min	Typ	Max	Min	Typ	Max	
Input Voltage	V_{IH}	$V_{CC} = 60\text{V}$, $V_{OL} \geq 57\text{V}$	2.5	—	—	—	—	—	V
		$V_{EE} = -60\text{V}$, $V_{OH} \leq -55\text{V}$	—	—	—	—	—	-1.4	V
	V_{IL}	$V_{CC} = 60\text{V}$, $V_{OH} \leq 3\text{V}$	—	—	0.4	—	—	—	V
		$V_{EE} = -60\text{V}$, $V_{OL} \geq -3\text{V}$	—	—	—	-4.3	—	—	V
Input Current	I_{IH}	$V_{CC} = 60\text{V}$, $V_{in} = 2.5\text{V}$	—	—	0.22	—	—	—	mA
		$V_{CC} = 60\text{V}$, $V_{in} = 5\text{V}$	—	—	0.45	—	—	—	mA
		$V_{EE} = -60\text{V}$, $V_{in} = -1.4\text{V}$	—	—	-280	-280	—	—	mA
	I_{IL}	$V_{CC} = 60\text{V}$, $V_{in} = 0.4\text{V}$	—	—	80	—	—	—	μA
		$V_{EE} = -60\text{V}$, $V_{in} = -4.3\text{V}$	—	—	—	-1.2	—	—	mA
		$V_{EE} = -60\text{V}$, $V_{in} = -7\text{V}$	—	—	—	-2.6	—	—	mA
Output Voltage	V_{OH}	$V_{CC} = 60\text{V}$, $V_{in} = 2.5\text{V}$ $I_O = -40\text{mA}$	57	58.5	—	—	—	—	V
		$V_{EE} = -60\text{V}$, $V_{in} = -4.3\text{V}$ $I_O = -40\text{mA}$	—	—	—	-3	-1.5	—	V
	V_{OL}	$V_{CC} = 60\text{V}$, $V_{in} = 0.4\text{V}$	—	—	3.0	—	—	—	V
		$V_{EE} = -60\text{V}$, $V_{in} = -1.4\text{V}$	—	—	—	-55	—	—	V
Quiescent Current	$I_{CC(OFF)}$	$V_{CC} = 60\text{V}$, All Circuit $V_{in} = 0.4\text{V}$	—	0.04	0.4	—	—	—	mA
	$I_{EE(OFF)}$	$V_{EE} = -60\text{V}$, All Circuit $V_{in} = -1.4\text{V}$	—	—	—	-1.3	—	—	mA
	$I_{CC(ON)}$	$V_{CC} = 60\text{V}$, One Circuit $V_{in} = 2.5\text{V}$	—	—	4.0	—	—	—	mA
	$I_{EE(ON)}$	$V_{EE} = -60\text{V}$, All Circuit $V_{in} = -4.3\text{V}$	—	—	—	12	—	—	mA

■ APPLICATIONS

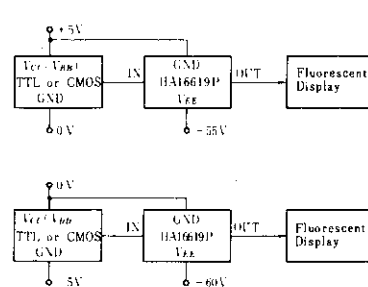
● HA16617PJ

Input voltage within 0 to +7V shall be used with regard to GND.

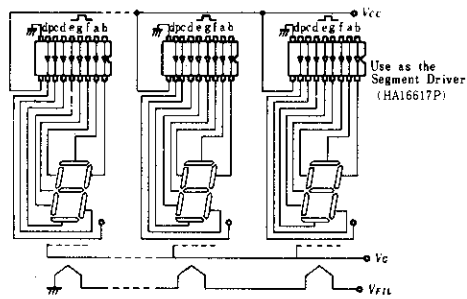


● HA16619PJ

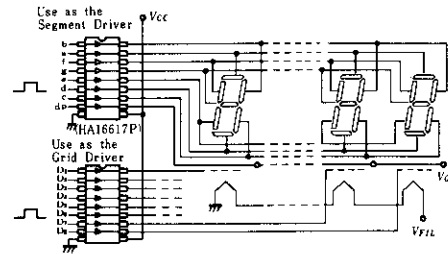
Input voltage within 0 to -7V shall be used with regard to GND.



■ BASIC CIRCUIT



(a) Static Type



(b) Dynamic Type

MEMO

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